# NANO- AND Microelectromechanical Systems

Fundamentals of Nano- and Microengineering A book in the Nano- and Microscience, Engineering, Technology and Medicine Series

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Fundamentals of Nano- and Microengineering

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#### PREFACE

This book is designed for a one-semester course on Nano- and Microelectromechanical Systems or Nano- and Microengineering. A typical background needed includes calculus, electromagnetics, and physics. The purpose of this book is to bring together in one place the various methods, techniques, and technologies that students and engineers need in solving a wide array of engineering problems in formulation, modeling, analysis, design, and optimization of high-performance microelectromechanical and nanoelectromechanical systems (MEMS and NEMS). This book is not intended to cover fabrication aspects and technologies because a great number of books are available. At the same time, extremely important issues in analysis, design, modeling, optimization, and simulation of NEMS and MEMS have not been comprehensively covered in the existing literature.

Twenty first century nano- and microtechnology revolution will lead to fundamental breakthroughs in the way materials, devices, and systems are understood, designed, function, manufactured, and used. Nanoengineering and nanotechnology will change the nature of the majority of the humanmade structures, devices, and systems. Current technological needs and trends include technology development and transfer, manufacturing and deployment, implementation and testing, modeling and characterization, design and optimization, simulation and analysis of complex nano- and microscale devices (for example, molecular computers, logic gates and switches, actuators and sensors, digital and analog integrated circuits, et cetera). Current developments have been focused on analysis and synthesis of molecular structures and devices which will lead to revolutionary breakthroughs in the data processing and computing, data storage and imaging, quantum computing and molecular intelligent automata, etc. Micro- and nanoengineering and science lead to fundamental breakthroughs in the way materials, devices and systems are understood, designed, function, manufactured, and used. High-performance MEMS and NEMS, micro- and nanoscale structures and devices will be widely used in nanocomputers, medicine (nanosurgery and nanotherapy, nonrejectable artificial organ design and implants, drug delivery and diagnosis), biotechnology (genome synthesis), etc.

New phenomena in nano- and microelectromechanics, physics and chemistry, benchmarking nanomanufacturing and control of complex molecular structures, design of large-scale architectures and optimization, among other problems must be addressed and studied. The major objective of this book is the development of basic theory (through multidisciplinary fundamental and applied research) to achieve full understanding, optimize, and control properties and behavior of a wide range of NEMS and MEMS. This will lead to new advances and will allow the designer to comprehensively solve a number of long-standing problems in analysis and control, modeling and simulation, structural optimization and virtual prototyping, packaging and fabrication, as well as implementation and deployment of novel NEMS and MEMS. In addition to technological developments and manufacturing (fabrication), the ability to synthesize and optimize NEMS and MEMS depends on the analytical and numerical methods, and the current concepts and conventional technologies cannot be straightforwardly applied due to the highest degree of complexity as well as novel phenomena. Current activities have been centered in development and application of a variety of experimental techniques trying to attain the characterization of mechanical (structural and thermal), electromagnetic (conductivity and susceptibility, permittivity and permeability, charge and current densities, propagation and radiation), optical, and other properties of NEMS and MEMS. It has been found that CMOS, surface micromachining and photolithography, near-field optical microscopy and magneto-optics, as well as other leading-edge technologies and processes to some extent can be applied and adapted to manufacture nano- and microscale structures and devices. However, advanced interdisciplinary research must be carried out to design, develop, and implement high-performance NEMS and MEMS. Our objectives are to expand the frontiers of the NEMS- and MEMS-based research through pioneering fundamental and applied multidisciplinary studies and developments. Rather than designing nano- and microscale components (integrated circuits and antennas, electromechanical and optoelectromechanical actuators and sensors), the emphasis will be given to the synthesis of the integrated large-scale systems. It must be emphasized that the author feels quite strongly that the individual nano- and microscale structures must be synthesized, thoroughly analyzed, and studied. We will consider NEMS and MEMS as the large-scale highly coupled systems, and the synthesis of groups of cooperative multi-agent NEMS and MEMS can be achieved using hierarchical structural and algorithmic optimization methods. The optimality of NEMS and MEMS should be guaranteed with respect to a certain performance objectives (manufacturing and packaging, cost and maintenance, size and weight, efficiency and performance, affordability and reliability, survivability and integrity, et cetera).

Nanoengineering is a very challenging field due to the complex multidisciplinary nature (engineering and physics, biology and chemistry, technology and material science, mathematics and medicine). This book introduces the focused fundamentals of nanoelectromechanics to initiate and stress, accelerate and perform the basic and applied research in NEMS and MEMS. Many large-scale systems are too complex to be studied and optimized analytically, and usually the available information is not sufficient to derive and obtain performance functionals. Therefore, the stochastic gradient descent and nonparametric methods can be applied using the decision variables with conflicting specifications and requirements imposed. In many applications there is a need to design high-performance intelligent NEMS and MEMS to accomplish the following functions:

- programming and self-testing;
- collection, compiling, and processing information (sensing data accumulation (storage) processing);
- multivariable embedded high-density array coordinated control;
- calculation and decision making with outcomes prediction;
- actuation and control.

The fundamental goal of this book is to develop the basic theoretical foundations in order to design and develop, analyze and prototype highperformance NEMS and MEMS. This book is focused on the development of fundamental theory of NEMS and MEMS, as well as their components and structures, using advanced multidisciplinary basic and applied developments. In particular, it will be illustrated how to perform the comprehensive studies with analysis of the processes, phenomena, and relevant properties at nano- and micro-scales, development of NEMS and MEMS architectures, physical representations, structural design and optimization, etc. It is the author's goal to substantially contribute to these basic issues, and the integration of these problems in the context of specific applications will be addressed. The primary emphasis will be on the development of basic theory to attain fundamental understanding of NEMS and MEMS, processes in nano- and micro-scale structures, as well as the application of the developed theory. Using the molecular technology, one can design and manufacture the atomic-scale devices with atomic precision using the atomic building blocks, design nano-scale devices ranging from electromechanical motion devices (translational and rotational actuators and sensors, logic and switches, registers) to nano-scale integrated circuits (diodes and transistors, logic gates and switches, resistors and inductors, capacitors). These devices will be widely used in medicine and avionics, transportation and power, and many other areas.

The leading-edge research in nanosystems is focused on different technologies and processes. As an example, the discovery of carbon-based nanoelectronics (carbon nanotubes are made from individual molecules) is the revolutionary breakthrough in nanoelectronics and nanocomputers, information technology and medicine, health and national security. In particular, fibers made using carbon nanotubes (molecular wires) more than 100 times stronger than steel and weighing 5 times less, have conductivity 5 times greater than silver, and transmit heat better than diamond. Carbon nanotubes are used as the molecular wires. Furthermore, using carbon molecules, first single molecule transistors were built. It should be emphasized that the current technology allows one to fill carbon nanotubes with other media (metals, organic and inorganic materials, et cetera).

The research in nano- and microtechnologies will lead to breakthroughs in information technology and manufacturing, medicine and health, environment and energy, avionics and transportation, national security and other areas of the greatest national importance. Through interdisciplinary synergism, this book is focused on fundamental studies of phenomena and processes in NEMS and MEMS, synthesis of nano- and micro-scale devices and systems, design of building blocks and components (which will lead to efficient and affordable manufacturing of high-performance NEMS and MEMS), study of molecular structures and their control, NEMS and MEMS architectures, etc. We will discuss the application and impact of nano- and micro-scale structures, devices, and systems to information technology, nanobiotechnology and medicine, nanomanufacturing and environment, power and energy systems, health and national security, avionics and transportation.

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#### CHAPTER 1

# NANO- AND MICROENGINEERING, AND NANO- AND MICROTECHNOLOGIES

#### **1.1. INTRODUCTION**

The development and deployment of NEMS and MEMS are critical to the U.S. economy and society because nano- and microtechnologies will lead to major breakthroughs in information technology and computers, medicine and health, manufacturing and transportation, power and energy systems, and avionics and national security. NEMS and MEMS have important impacts in medicine and bioengineering (DNA and genetic code analysis and synthesis, drug delivery, diagnostics, and imaging), bio and information technologies, avionics, and aerospace (nano- and microscale actuators and sensors, smart reconfigurable geometry wings and blades, space-based flexible structures, and microgyroscopes), automotive systems and transportation (sensors and actuators, accelerometers), manufacturing and fabrication, public safety, etc. During the last years, the government and the high-technology industry have heavily funded basic and applied research in NEMS and MEMS due to the current and potential rapidly growing positive direct and indirect social and economic impacts.

Nano- and microengineering are the fundamental theory, engineering practice, and leading-edge technologies in analysis, design, optimization, and fabrication of NEMS and MEMS, nano- and microscale structures, devices, and subsystems. The studied nano- and microscale structures and devices have dimensions of nano- and micrometers.

To support the nano- and microtechnologies, basic and applied research and development must be performed. Nanoengineering studies nano- and microscale-size materials and structures, as well as devices and systems, whose structures and components exhibit novel physical (electromagnetic and electromechanical), chemical, and biological properties, phenomena, and processes. The dimensions of nanosystems and their components are  $10^{-10}$  m (molecule size) to  $10^{-7}$  m; that is, 0.1 to 100 nanometers. Studying nanostructures, one concentrates one's attention on the atomic and molecular levels, manufacturing and fabrication, control and dynamics, augmentation and structural integration, application and large-scale system synthesis, et cetera. Reducing the dimensions of systems leads to the application of novel materials (carbon nanotubes, quantum wires and dots). The problems to be solved range from mass-production and assembling (fabrication) of nanostructures at the atomic/molecular scale (e.g., nanostructured electronics and actuators/sensors) with the desired properties. It is essential to design novel nanodevices such as nanotransistors and nanodiodes, nanoswitches and nanologic gates, in order to design nanoscale computers with terascale capabilities. All living biological systems function due to molecular interactions of different subsystems. The molecular building blocks (proteins and nucleic acids, lipids and carbohydrates, DNA and RNA) can be viewed as inspiring possible strategy on how to design high-performance NEMS and MEMS that possess the properties and characteristics needed. Analytical and numerical methods are available to analyze the dynamics and three-dimensional geometry, bonding, and other features of atoms and molecules. Thus, electromagnetic and mechanical, as well as other physical and chemical properties can be studied.

Nanostructures and nanosystems will be widely used in medicine and health. Among possible applications of nanotechnology are: drug synthesis and drug delivery (the therapeutic potential will be enormously enhanced due to direct effective delivery of new types of drugs to the specified body sites), nanosurgery and nanotherapy, genome synthesis and diagnostics, nanoscale actuators and sensors (disease diagnosis and prevention), nonrejectable nanoartificial organs design and implant, and design of high-performance nanomaterials.

It is obvious that nano- and microtechnologies drastically change the fabrication and manufacturing of materials, devices, and systems through:

- predictable properties of nano composites and materials (e.g., light weight and high strength, thermal stability, low volume and size, extremely high power, torque, force, charge and current densities, specified thermal conductivity and resistivity, et cetera),
- virtual prototyping (design cycle, cost, and maintenance reduction),
- improved accuracy and precision, reliability and durability,
- higher degree of efficiency and capability, flexibility and integrity, supportability and affordability, survivability and redundancy,
- improved stability and robustness,
- higher degree of safety,
- environmental competitiveness.

Foreseen by Richard Feyman, the term "nanotechnology" was first used by N. Taniguchi in his 1974 paper, "On the basic concept of nanotechnology." In the last two decades, nanoengineering and nanomanufacturing have been popularized by Eric Drexler through the Foresight Institute.

Advancing miniaturization towards the molecular level with the ultimate goal to design and manufacture nanocomputers and nanomanipulators (nanoassemblers), large-scale intelligent NEMS and MEMS (which have nanocomputers as the core components), the designer faces a great number of unsolved problems.

Possible basic concepts in the development of nanocomputers are listed below. Mechanical "computers" have the richest history traced thousand years back. While the most creative theories and machines have been developed and demonstrated, the feasibility of mechanical nanocomputers is questioned by some researchers due to the number of mechanical components (which are needed to be controlled), as well as due to unsolved manufacturing (assembling) and technological difficulties. Chemical nanocomputers can be designed based upon the processing information by making or breaking chemical bonds, and storing the information in the resulting chemical. In contrast, in quantum nanocomputers, the information can be represented by a quantum state (e.g., the spin of the atom can be controlled by the electromagnetic field).

Electronic nanocomputers can be designed using conventional concepts tested and used for the last thirty years. In particular, molecular transistors or quantum dots can be used as the basic elements. The nanoswitches (memoryless processing elements), logic gates, and registers must be manufactured on the scale of a single molecule. The so-called quantum dots are metal boxes that hold the discrete number of electrons which is changed applying the electromagnetic field. The quantum dots are arranged in the quantum dot cells. Consider the quantum dot cells which have five dots and two quantum dots with electrons. Two different states are illustrated in Figure 1.1.1 (the dashed dots contain the electron, while the white dots do not contain the electron). It is obvious that the quantum dots can be used to synthesize the logic devices.



Figure 1.1.1. Quantum dots with states "0" and "1", and "1 1" configuration

It was emphasized that as conventional electromechanical systems, nanoelectromechanical systems (actuators and other molecular devices) are controlled by changing the electromagnetic field. It becomes evident that other nanoscale structures and devices (nanodiodes and nanotransistors) are also controlled by applying the electromagnetic field (recall that the voltage and current result due to the electromagnetic field).

#### **1.2. BIOLOGICAL ANALOGIES**

Coordinated behavior and motion, visualization and sensing, motoring and decision making, memory and learning of living organisms are the results of the electrical (electromagnetic) transmission of information by neurons. One cubic centimeter of the brain contains millions of nerve cells, and these cells communicate with thousands of neurons creating data processing (communication) networks. The information from the brain to the muscles is transmitted within the milliseconds, and the baseball and football, basketball,

and tennis players calculate the speed and velocity of the ball, analyze the situation, make the decision, and respond (e.g., run or jump, throw or hit the ball, et cetera). Human central nervous system, which includes brain and spinal cord, serves as the link between the sensors (sensor receptors) and motors peripheral nervous system (effector, muscle, and gland cells). It should be emphasized that the nervous system has the following major functions: sensing, integration and decision making (computing), and motoring (actuation). Human brain consists of hindbrain (controls homeostasis and coordinate movement), midbrain (receiving, integration, and processing the sensory information), and forebrain (neural processing and integration of information, image processing, short- and long-term memories, learning functions, decision making and motor command development). The peripheral nervous system consists of the sensory system (sensory neurons transmit information from internal and external environment to the central nervous system, and motor neurons carry information from the brain or spinal cord to effectors), which supplies information from sensory receptors to the central nervous system, and the motor nervous system feeds signals (commands) from the central nervous system to muscles (effectors) and glands. The spinal cord mediates reflexes that integrate sensor inputs and motor outputs, and through the spinal cord the neurons carry information to and from the brain. The transmission of electrical signals along neurons is a very complex phenomenon. The membrane potential for a nontransmitting neuron is due to the unequal distribution of ions (sodium and potassium) across the membrane. The resting potential is maintained due to the differential ion permeability and the so-called  $Na^+ - K^+$  pump. The stimulus changes the membrane permeability, and ion can depolarize or hyperpolarize the membrane resting potential. This potential (voltage) change is proportional to the strength of the stimulus. The stimulus is transmitted due to the axon mechanism. The nervous system is illustrated in Figure 1.2.1.



Figure 1.2.1. Vertebrate nervous system: high-level functional diagram There is a great diversity of the nervous system organizations. The cnidarian (*hydra*) nerve net is an organized system of nerves with no central control, and a simple nerve net can perform elementary tasks (jellyfishes swim). Echinoderms have a central nerve ring with radial nerves (for example, sea stars have central and radial nerves with nerve net). Planarians have small brains that send information through two or more nerve trunks, as illustrated in Figure 1.2.2.



Figure 1.2.2. Overview of invertebrate nervous systems

## **1.3. NANO- AND MICROELECTROMECHANICAL SYSTEMS**

Through biosystems analogy, variety of а great man-made electromechanical systems have been designed and made. To analyze, design, develop, and deploy novel NEMS and MEMS, the designer must synthesize advanced architectures, integrate the latest advances in nano- and microscale actuators/sensors (transducers) and smart structures, integrated circuits (ICs) and multiprocessors, materials and fabrications, structural design and optimization, modeling and simulation, et cetera. It is evident that novel optimized NEMS and MEMS architectures (with processors or multiprocessors, memory hierarchies and multiple parallelism to guarantee high-performance computing and decision making), new smart structures and actuators/sensors, ICs and antennas, as well as other subsystems play a critical role in advancing the research, developments, and implementation. In this book we discuss optimized architectures, and the research in architecture optimization will provide deep insights into how intelligent large-scale integrated NEMS and MEMS can be synthesized.

Electromechanical systems, as shown in Figure 1.3.1, can be classified as

- conventional electromechanical systems,
- microelectromechanical systems (MEMS),
- nanoelectromechanical systems (NEMS).



Figure 1.3.1. Classification of electromechanical systems

The operational principles and basic foundations of conventional electromechanical systems and MEMS are the same, while NEMS are studied using different concepts and theories. In fact, the designer applies the classical Lagrangian and Newtonian mechanics as well as electromagnetics (Maxwell's equations) to study conventional electromechanical systems and MEMS. In contrast, NEMS are studied using quantum theory and nanoelectromechanical concepts. Figure 1.3.2 documents the fundamental theories to study the processes and phenomena in conventional, micro, and nanoelectromechanical systems.



Figure 1.3.2. Fundamental theories in electromechanical systems

NEMS and MEMS integrate different structures, devices, and subsystems. The research in integration and optimization (optimized architectures and structural optimization) of these subsystems has not been instituted and performed, and end-to-end (processors – networks – input/output subsystems – ICs/antennas – actuators/sensors) performance and behavior must be studied. Through this book we will study different NEMS and MEMS architectures, and fundamental and applied theoretical concepts will be developed and documented in order to design next generation of superior high-performance NEMS and MEMS.

The large-scale NEMS and MEMS, which can integrate processor (multiprocessor) and memories, high-performance networks and input-output (IO) subsystems, are of far greater complexity than MEMS commonly used today. In particular, the large-scale NEMS and MEMS can integrate:

- thousands of nodes of high-performance actuators/sensors and smart structures controlled by ICs and antennas;
- high-performance processors or superscalar multiprocessors;
- multi-level memory and storage hierarchies with different latencies (thousands of secondary and tertiary storage devices supporting data archives);
- interconnected, distributed, heterogeneous databases;
- high-performance communication networks (robust, adaptive intelligent networks).

It must be emphasized that even the simplest nanosystems (for example, pure actuator) usually cannot function alone. For example, at least the internal or external source of energy is needed.

The complexity of large-scale NEMS and MEMS requires new fundamental and applied research and developments, and there is a critical need for coordination across a broad range of hardware and software. For example, design of advanced nano- and microscale actuators/sensors and smart structures, synthesis of optimized (balanced) architectures, development of new programming languages and compilers, performance and debugging tools, operating system and resource management, high-fidelity visualization and data representation systems, design of high-performance networks, et cetera. New algorithms and data structures, advanced system software and distributed access to very large data archives, sophisticated data mining and visualization techniques, as well as advanced data analysis are needed. In addition, advanced processor and multiprocessors are needed to achieve sustained capability required of functionally *usable* large-scale NEMS and MEMS.

The fundamental and applied research in NEMS and MEMS has been dramatically affected by the emergence of high-performance computing. Analysis and simulation of NEMS and MEMS have significant outcomes. The problems in analysis, modeling, and simulation of large-scale NEMS and MEMS that involves the complete molecular dynamics cannot be solved because the classical quantum theory cannot be feasibly applied to complex molecules or simplest nanostructures (1 nm cube of nanoactuator has thousands of molecules). There are a number of very challenging research problems in which advanced theory and high-end computing are required to advance the theory and engineering practice. The multidisciplinary fundamentals of nanoelectromechanics must be developed to guarantee the possibility to synthesize, analyze, and fabricate high-performance NEMS and MEMS with desired (specified) performance characteristics. This will dramatically shorten the time and cost of developments of NEMS and MEMS for medical and biomedical, aerospace and automotive, electronic and manufacturing systems.

The importance of mathematical model developments and numerical analysis has been emphasized. Numerical simulation enhances, but does not substitute for fundamental research. Furthermore, meaningful and explicit simulations should be based on reliable fundamental studies and must be validated through experiments. However, it is evident that simulations lead to understanding of performance of complex NEMS and MEMS (nano- and microscale structures, devices, and sub-systems), reduce the time and cost of deriving and leveraging the NEMS and MEMS technologies from concept to device/system, and from device/system to market. Fundamental and applied research is the core of the simulation, and focused efforts must be concentrated on comprehensive modeling and advanced efficient computing.

To comprehensively study NEMS and MEMS, advanced modeling and computational tools are required primarily for 3D+ (three-dimensional geometry dynamics in time domain) data intensive modeling and simulations to study the end-to-end dynamic behavior of actuators and sensors. The mathematical models of NEMS, MEMS, and their components (structures, devices, and subsystems) must be developed. These models (augmented with efficient computational algorithms, terascale computers, and advanced software) will play the major role to simulate the design of NEMS and MEMS from virtual prototyping standpoints.

There are three broad categories of problems for which new algorithms and computational methods are critical:

- 1. Problems for which basic fundamental theories are developed, but the complexity of solutions is beyond the range of current and near-future computing technologies. For example, the conceptually straightforward classical quantum mechanics and molecular dynamics cannot be applied even for nanoscale actuators. In contrast, it will be illustrated that it is possible to perform robust predictive simulations of molecular-scale behavior for nano- and microscale actuators/sensors and smart structures which might contain millions of molecules.
- 2. Problems for which fundamental theories are not completely developed to justify direct simulations, but can be advanced or developed by advanced basic and numerical methods.
- 3. Problems for which the developed advanced modeling and simulation methods will produce major advances and will have a major impact. For example, 3D+ transient end-to-end behavior of NEMS and MEMS.

For NEMS and MEMS, as well as for their devices and subsystems,

high-fidelity modeling and massive computational simulations (mathematical models designed with developed intelligent libraries and databases/archives, intelligent experimental data manipulation and storage, data grouping and correlation, visualization, data mining and interpretation) offer the promise of developing and understanding the mechanisms, phenomena and processes in order to improve efficiency and design novel high-performance NEMS and MEMS. Predictive model-based simulations require terascale computing and an unprecedented level of integration between engineering and science. These modeling and simulations will lead to new fundamental results. To model and simulate NEMS and MEMS, we augment modern quantum mechanics, electromagnetics, and electromechanics at the nano- and microscale. In particular, our goal is to develop the nanoelectromechanical theory.

One can perform the steady-state and dynamic analysis. While steady-state analysis is important, and the structural optimization to comprehend the actuators/sensors, smart structures, and antennas design can be performed, NEMS and MEMS must be analyzed in the time domain. The long-standing goal of nanoelectromechanics is to develop the basic fundamental conceptual theory in order to determine and study the interactions between actuation and sensing, computing and communication, signal processing and hierarchical data storage (memories), and other processes and phenomena in NEMS and MEMS. Using the concept of strong electromagnetic-electromechanical interactions, the fundamental nanoelectromechanical theory will be developed and applied to nanostructures and nanodevices, NEMS and MEMS to predict the performance through analytical solutions and numerical simulations. Dynamic macromodels of nodes can be developed, and single and groups of molecules can be studied. It is critical to perform this research in order to determine a number of the parameters to make accurate performance evaluation and to analyze the phenomena performing simulations and comparing experimental, modeling and simulation results.

Current advances and developments in modeling and simulation of complex phenomena in NEMS and MEMS are increasingly dependent upon new approaches to robustly map, compute, visualize, and validate the results clarifying, correlating, defining, and describing the limits between the numerical results and the qualitative-quantitative analytic analysis in order to comprehend, understand, and grasp the basic features. Simulations of NEMS and MEMS require terascale computing that will be available within a couple of years. The computational limitations and inability to develop explicit mathematical models (some nonlinear phenomena cannot be comprehended, fitted, and precisely mapped) focus advanced studies on the basic research in robust modeling and simulation under uncertainties. Robust modeling, simulation, and design are critical to advance and foster the theoretical and engineering enterprises. We focus our research on the development of the nanoelectromechanical theory in order to model and simulate large-scale NEMS and MEMS. At the subsystem level, for example, nano- and microscale actuators and sensors will be modeled and analyzed in 3D+ (three-dimensional geometry dynamics in time domain) applying advanced numerical robust methods and algorithms. Rigorous methods for quantifying uncertainties for robust analysis should be developed. Uncertainties result due to the fact that it is impossible to explicitly comprehend the complex interacted subsystems and processes in NEMS and MEMS (actuators/sensors and smart structures, antennas, digital and analog ICs, data movement, storage and management across multilevel memory hierarchies, archives, networks and periphery), structural and environmental changes, unmeasured and unmodeled phenomena, et cetera.

To design NEMS and MEMS, we will develop analytical mathematical models. There are a number of areas where the advances must be made in order to realize the promises and benefits of modern theoretical developments recently made. For example, to perform 3D+ modeling and data intensive simulations of actuators/sensors and smart structures, we will use advanced analytical and numerical methods and algorithms (novel methods and algorithms in geometry and mesh generation, data assimilation, and dynamic adaptive mesh refinement) as well as the computationally efficient and robust MATLAB environment. There are fundamental and computational problems that have not been addressed, formulated and solved due to the complexity of largescale NEMS and MEMS (e.g., large-scale hybrid models, limited ability to generate and visualize the massive amount of data, et cetera). Other problems include nonlinearities and uncertainties which imply fundamental limits to formulate, set up, and solve analysis and design problems. Therefore, one should develop rigorous methods and algorithms for quantifying and modeling uncertainties, 3D+ geometry and mesh generation techniques, as well as methods for adaptive robust modeling and simulations under uncertainties. A broad class of fundamental and applied problems ranging from fundamental theories (quantum mechanics and electromagnetics, electromechanics and thermodynamics, structural synthesis and optimization, optimized architecture design and control, modeling and analysis, et cetera) and numerical computing (to enable the major progress in design and virtual prototyping through the large scale simulations, data intensive computing, and visualization) will be addressed and thoroughly studied in this book. Due to the obvious limitations and the scope of this book, a great number of problems and phenomena will not be addressed and discussed (among them, fabrication and manufacturing, chemistry and material science).

#### 1.4. APPLICATIONS OF NANO- AND MICROELECTROMECHANICAL SYSTEMS

Depending upon the specifications and requirements, objectives and applications, NEMS and MEMS must be designed. Usually, NEMS are faster and simpler, more efficient and reliable, survivable and robust compared with MEMS. However, due to the limited size and functional capabilities, one might not attain the desired characteristics. For example, consider nanoand microscale actuators. The actuator size is determined by the force or torque densities. That is, the size is determined by the force or torque requirements and materials used. As one uses NEMS or MEMS as the logic devices, the output electric signal (voltage or current) or electromagnetic field (intensity or density) must have the specified value.

Although NEMS and MEMS have the common features, the differences must be emphasized as well. Currently, the research and developments in NEMS and molecular nanotechnology are primarily concentrated on design, modeling, simulation, and fabrication of molecular-scale devices. In contrast, MEMS are usually fabricated using other technologies, for example, complementary metal oxide semiconductor (CMOS) and lithography. The direct chip attaching technology was developed and widely deployed. Flip-chip assembly replaces wire banding to connect ICs with micro- and nanoscale actuators and sensors. The use of flip-chip technology allows one to eliminate parasitic resistance, capacitance, and inductance. This results in improvements of performance characteristics. In addition, flip-chip assembly offers advantages in the implementation of advanced flexible packaging, improving reliability and survivability, reduces weight and size, et cetera. The flip-chip assembly involves attaching actuators and sensors directly to ICs. The actuators and sensors are mounted face down with bumps on the pads that form electrical and mechanical joints to the ICs substrate. The under-fill encapsulate is then added between the chip surface and the flex circuit to achieve the high reliability demanded. Figure 1.4.1 illustrates flip-chip MEMS.



Figure 1.4.1. Flip-chip monolithic MEMS with actuators and sensors

The large-scale integrated MEMS (a single chip that can be mass-produced using the complementary metal oxide semiconductor (CMOS), photolithography, and other technologies at low cost) integrates:

- N nodes of actuators/sensors, smart structures,
- ICs and antennas,
- processor and memories,
- interconnection networks (communication busses),
- input-output (IO) systems. Different architectures can be synthesized, and this problem is discussed

and covered in Chapter 2. One uses NEMS and MEMS to control complex systems, processes, and phenomena. A high-level functional block diagram of large-scale MEMS is illustrated in Figure 1.4.2.



Figure 1.4.2. High-level functional block diagram of large-scale MEMS with rotational and translational actuators and sensors

Actuators are needed to actuate dynamic systems. Actuators respond to command stimulus (control signals) and develop torque and force. There is a great number of biological (e.g., human eye and locomotion system) and manmade actuators. Biological actuators are based upon electromagneticmechanical-chemical phenomena and processes. Man-made actuators (electromagnetic, electric, hydraulic, thermo, and acoustic motors) are devices that receive signals or stimulus (stress or pressure, thermo or acoustic, et cetera) and respond with torque or force.

Consider the flight vehicles. The aircraft, spacecraft, missiles, and interceptors are controlled by displacing the control surfaces as well as by changing the control surface and wing geometry. For example, ailerons, elevators, canards, flaps, rudders, stabilizers and tips of advanced aircraft can be controlled by nano-, micro-, and miniscale actuators using the NEMS- and MEMS-based smart actuator technology. This NEMS- and MEMS-based smart actuator technology is uniquely suitable in the flight actuator applications. Figure 1.4.3 illustrates the aircraft where translational and rotational actuators are used to actuate the control surfaces, as well as to change the wing and control surface geometry.



Figure 1.4.3. Aircraft with NEMS- and MEMS-based translational and rotational flight actuators

Sensors are devices that receive and respond to signals or stimulus. For example, the loads (which the aircraft experience during the flight), vibrations, temperature, pressure, velocity, acceleration, noise, and radiation can be measured by micro- and nanoscale sensors, see Figure 1.4.4. It should be emphasized that there are many other sensors to measure the electromagnetic interference and displacement, orientation and position, voltages and currents in power electronic devices, et cetera.



Figure 1.4.4. Application of nano- and microscale sensors in aircraft

Usually, several conversion processes are involved to produce electric, electromagnetic, or mechanical output sensor signals. The conversion of energy is our particular interest. Using the energy-based analysis, the general theoretical fundamentals will be thoroughly studied.

The major developments in NEMS and MEMS have been fabrication technology driven, and the applied research has been performed mainly to manufacture structures and devices, as well as to analyze some performance characteristics. For example, mini- and microscale smart structures as well as ICs have been studied in details, and feasible manufacturing technologies, materials, and processes have been developed. Recently, carbon nanotubes were discovered, and molecular wires and molecular transistors were built. However, to our best knowledge, nanostructures and nanodevices, NEMS and MEMS, have not been comprehensively studied at the nanoscale, and the efforts to develop the fundamental theory have not been reported. In this book, we will apply the quantum theory and charge density concept, advanced electromechanics and Maxwell's equations, as well as other cornerstone methods, to model nanostructures and nanodevices (ICs and actuators and sensors, et cetera). In particular. the antennas, nanoelectromechanical theory will be developed. A large variety of actuators and sensors, antennas and ICs with different operating features are modeled and simulated. To perform high-fidelity integrated 3D+ data intensive modeling with post-processing and animation, the partial and ordinary nonlinear differential equations are solved.

#### **1.5. NANO- AND MICROELECTROMECHANICAL SYSTEMS**

In general, monolithic MEMS are integrated microassembled structures (electromechanical microsystems on a single chip) that have both electricalelectronic (ICs) and mechanical components. To manufacture MEMS, advanced modified microelectronics fabrication techniques, technologies, and materials are used. Actuation and sensing cannot be viewed as the peripheral function in many applications. Integrated sensors-actuators (usually motion microstructures) with ICs compose the major class of MEMS. Due to the use of CMOS lithography-based technologies in fabrication actuators and sensors, MEMS leverage microelectronics in important additional areas that revolutionize the application capabilities. In fact, MEMS have considerably leveraged the microelectronics industry beyond ICs. The needs for augmented motion microstructures (actuators and sensors) and ICs have been widely recognized. Simply scaling conventional electromechanical motion devices and augmenting them with ICs have not met the needs, and theory and fabrication processes have been developed beyond component replacement. Dual power operational amplifiers (e.g., Motorola TCA0372, DW Suffix plastic package case 751G, DP2 Suffix plastic package case 648 or DP1 Suffix plastic package case 626) as monolithic ICs can be used to control DC micro electric machines (motion microstructures), as shown in Figure 1.5.1.



Figure 1.5.1. Application of monolithic IC to control DC micromachines (motion microstructures)

Only recently has it become possible to manufacture MEMS at low cost. However, there is a critical demand for continuous fundamental, applied, and technological improvements, and multidisciplinary activities are required. The general lack of synergy theory to augment actuation, sensing, signal processing, and control is known, and these issues must be addressed through focussed efforts. The set of long-range goals that challenge the analysis, design, development, fabrication, and deployment of high-performance MEMS are:

- advanced materials and process technology,
- microsensors and microactuators (motion microstructures), sensing and actuation mechanisms, sensors-actuators-ICs integration and MEMS configurations,
- fabrication, packaging, microassembly, and testing,
- MEMS analysis, design, optimization, and modeling,
- MEMS applications and their deployment.

Significant progress in the application of CMOS technology enables the industry to fabricate microscale actuators and sensors with the corresponding ICs, and this guarantees the significant breakthrough. The field of MEMS has been driven by the rapid global progress in ICs, VLSI, solid-state devices, materials, microprocessors, memories, and DSPs that have revolutionized instrumentation, control, and systems design philosophy. In addition, this progress has facilitated explosive growth in data processing and communications in high-performance systems. In microelectronics, many emerging problems deal with nonelectric effects, phenomena and processes (thermal and structural analysis and optimization, stress and ruggedness, packaging, et cetera). It has been emphasized that ICs are the necessary components to perform control, data acquisition, and decision making. For example, control signals (voltage or currents) are computed, converted, modulated, and fed to actuators. It is evident that MEMS have found applications in a wide array of microscale devices (accelerometers, pressure sensors, gyroscopes, et cetera) due to extremely-high level of integration of electromechanical components with low cost and maintenance, accuracy, efficiency, reliability, ruggedness, and survivability. Microelectronics with integrated sensors and actuators are batch-fabricated as integrated assemblies.

Therefore, MEMS can be defined as *batch-fabricated microscale* devices (ICs and motion microstructures) that convert physical parameters to electrical signals and vice versa, and in addition, microscale features of mechanical and electrical components, architectures, structures, and parameters are important elements of their operation and design.

The manufacturability issues in NEMS and MEMS must be addressed. One can design and manufacture individually-fabricated devices and subsystems (ICs and motion microstructures). However, these individuallyfabricated devices and subsystems are unlikely can be used due to very high cost.

Integrated MEMS combine mechanical structures (microfabricated smart multifunctional materials are used to manufacture microscale actuators and sensors, pumps and valves, optical devices) and microelectronics (ICs). The number of transistors on a chip is frequently used by the microelectronic industry, and enormous progress in achieving nanoscale transistor dimensions

(less than 100 nm) was achieved. However, large-scale MEMS operational capabilities are measured by the intelligence, system-on-a-chip integration, integrity, cost, performance, efficiency, size, reliability, and other criteria. There are a number of challenges in MEMS fabrication because conventional CMOS technology must be modified and integration strategies (to integrate mechanical structures and ICs) are needed to be developed. What (ICs or mechanical micromachined structure) should be fabricated first? Fabrication of ICs first faces challenges because to reduce stress in the thin films of polysilicon (multifunctional material to build motion microstructures), a hightemperature anneal at 1000<sup>°</sup>C is needed for several hours. The aluminum ICs interconnect will be destroyed (melted), and tungsten can be used for interconnected metallization. This process leads to difficulties for commercially manufactured MEMS due to high cost and low reproducibility. Analog Devices fabricates ICs first up to metallization step, and then, mechanical structures (polysilicon) are built using high-temperature anneal (micromachines are fabricated before metallization), and finally, ICs are interconnected. This allows the manufacturer to use low-cost conventional aluminum interconnects. The third option is to fabricate mechanical structures, and then ICs. However, to overcome step coverage, stringer, and topography problems, motion mechanical microstructures can be fabricated in the bottoms of the etched shallow trenches (packaged directly) of the wafer. These trenches are filled with a sacrificial silicon dioxide, and the silicon wafer is planarized through chemical-mechanical polishing.

The motion mechanical microstructures can be protected (sensor applications, e.g., accelerometers and gyroscopes) and unprotected (actuator and interactive environment sensor applications). Therefore, MEMS (mechanical structure – ICs) can be encased in a clean, hermetically sealed package or some elements can be unprotected to interact with environment. This creates challenges in packaging. It is extremely important to develop novel electromechanical motion microstructures and microdevices (sticky multilayers, thin films, magnetoelectronic, electrostatic, and quantum-effect-based devices) and sense their properties. Microfabrication of very large scale integrated circuits (VLSI), MEMS, and optoelectronics must be addressed. Fabrication processes include lithography, film growth, diffusion, ion implantation, thin film deposition, etching, metallization, et cetera. Furthermore, ICs and motion microstructures (microelectromechanical motion devices) must be connected. Complete microfabrication processes with integrated process steps must be developed.

Microelectromechanical systems integrate microscale subsystems (at least ICs and motion structure). It was emphasized that microsensors sense the physical variables, and microactuators control (actuate) real-world systems. These microactuators are regulated by ICs. It must be emphasized that ICs also performed computations, signal conditioning, decision making, and other

functions. For example, in microaccelerometers, the motion microstructure displaces. Using this displacement, the acceleration can be calculated. In microaccelerometers, computations, signal conditioning, data acquisition, and decision making are performed by ICs. Microactuators inflate air-bags if car crashes (high g acceleration measured).

Microelectromechanical systems contain microscale subsystems designed and manufactured using different technologies. Single silicon substrate can be used to fabricate microscale actuators, sensors, and ICs (monolithic MEMS) using CMOS microfabrication technology. Alternatively, subsystem can be assembled, connected and packaged, and different microfabrication techniques for MEMS components and subsystems exist. Usually, monolithic MEMS are compact, efficient, reliable, and guarantee superior performance.

Typically, MEMS integrate the following subsystems: microscale actuators (actuate real-world systems), microscale sensors (detect and measure changes of the physical variables), and microelectronics/ICs (signal processing, data acquisition, decision making, et cetera).

Microactuators are needed to develop force or torque (mechanical variable). Typical examples are microscale drives, moving mirrors, pumps, servos, valves, et cetera. A great variety of methods for achieving actuation are well-known, e.g., electromagnetic (electrostatic, magnetic, piezoelectric), hydraulic, and thermal effects. This book covers electromagnetic microactuators, and the so-called comb drives (surface micromachined motion microstructures) have been widely used. These drives have movable and stationary plates (fingers). When the voltage is applied, an attractive force is developed between two plates, and the motion results. A wide variety of microscale actuators have been fabricated and tested. The common problem is the difficulties associated with coil fabrication. The choice of magnetic materials (permanent magnets) is limited to those that can be micromachined. Magnetic actuators typically fabricated through the photolithography technology using nickel (ferromagnetic material). Piezoelectric microactuators have found wide applications due to simplicity and ruggedness (force is generated if one applies the voltage across a film of piezoelectric material). The piezoelectric-based concept can be applied to thin silicon membranes, and if the voltage is applied, the membrane deforms. Thus, silicon membranes can be used as pumps.

Microsensors are devices that convert one physical variable (quantity) to another. For example, electromagnetic phenomenon can be converted to mechanical or optic effects. There are a number of different types of microscale sensors used in MEMS. For example, microscale thermosensors are designed and built using the thermoelectric effect (the resistivity varies with temperature). Extremely low cost thermoresistors (thermistors) are fabricated on the silicon wafer, and ICs are built on the same substrate. The thermistor resistivity is a highly nonlinear function of the temperature, and the compensating circuitry is used to take into account the nonlinear effect. Microelectromagnetic sensors measure electromagnetic fields, e.g., the Hall

effect sensors. Optical sensors can be fabricated on crystals that exhibit a magneto-optic effect, e.g., optical fibers. In contrast, the quantum effect sensors can sense extremely weak electromagnetic fields. Silicon-fabricated piezoresistors (silicon doped with impurities to make it n- or p-type) belong to the class of mechanical sensors. When the force is applied to the piezoelectric, the charge induced (measured voltage) is proportional to the applied force. Zinc oxide and lead zirconate titanate (PZT, PbZrTiO<sub>3</sub>), which can be deposited on microstructures, are used as piezoelectric crystals. In this book, the microscale accelerometers and gyroscopes, as well as microelectric machines will be studied. Accelerometers and gyroscopes are based upon capacitive sensors. In two parallel conducting plates, separated by an insulating material, the capacitance between the plates is a function of distance between plates (capacitance is inversely proportional to the distance). Thus, measuring the capacitance, the distance can be easily calculated. In accelerometers and gyroscopes, the proof mass and rotor are suspended. It will be shown that using the second Newton's law, the acceleration is proportional to the displacement. Hence, the acceleration can be calculated. Thin membranes are the basic components of pressure sensors. The deformation of the membrane is usually sensed by piezoresistors or capacitive microsensors.

We have illustrated the critical need for physical- and system-level concepts in NEMS and MEMS analysis and design. Advances in physical-level research have tremendously expanded the horizon of NEMS and MEMS technologies. For example, magnetic-based (magnetoelectronic) memories have been thoroughly studied (magnetoelectronic devices are grouped in three categories based upon the physics of their operation: all-metal spin transistors and valves, hybrid ferromagnetic semiconductor structures, and magnetic tunnel junctions). Writing and reading the cell data are based on different physical mechanisms, and high or low cost, densities, power, reliability and speed (write/read cycle) memories result. As the physical-level analysis and design are performed, the system-level analysis and design must be accomplished because the design of integrated large-scale NEMS and MEMS is the final goal.

# 1.6. INTRODUCTION TO MEMS FABRICATION, ASSEMBLING, AND PACKAGING

Two basic components of MEMS and microengineering are microelectronics (to fabricate ICs) and micromachining (to fabricate motion microstructures). Using CMOS or VLSI technology, microelectronics (ICs) fabrication can be performed. Micromachining technology is needed to fabricate motion microstructures to be used as the MEMS mechanical subsystems. It was emphasized that one of the main goals of microengineering is to integrate microelectronics with micromachined

mechanical structures in order to produce completely integrated monolithic high-performance MEMS. To guarantee low cost, reliability, and manufacturability, the following must by guaranteed: the fabrication process has a high yield and batch processing techniques are used for as much of the process as possible (large numbers of microscale structures/devices per silicon wafer and large number of wafers are processed at the same time at each fabrication step). Assembling and packaging must be automated, and the most promising avenues are auto- or self-alignment and self assembly. Some MEMS subsystems (actuator and interactive environment sensors) must be protected from mechanical damage, and in addition, protected from contamination. Wear tolerance, electromagnetic and thermo isolation, among other problems have always challenged MEMS. Different manufacturing technologies must be applied to attain the desired performance level and cost. Microsubsystems can be coated directly by thin films of silicon dioxide or silicon nitride which are deposited using plasma enhanced chemical vapor deposition. It is possible to deposit (at 700<sup>6</sup>C to 900<sup>6</sup>C) films of diamond which have superior wear capabilities, excellent electric insulation and thermal characteristics. It must be emphasized that diamond like carbon films can be also deposited.

Microelectromechanical systems are connected (interfaced) with realworld systems (control surfaces of aircraft, flight computer, communication ports, et cetera). Furthermore, MEMS are packaged to protect systems from harsh environments, prevent mechanical damage, minimize stresses and vibrations, contamination, electromagnetic interference, et cetera. Therefore, MEMS are usually sealed. It is impossible to specify a generic MEMS package. Through input-output connections (power and communication bus) one delivers the power required, feeds control (command) and test (probe) signals, receives the output signals and data. Packages must be designed to minimize electromagnetic interference and noise. Heat, generated by MEMS, must be dissipated, and the thermal expansion problem must be solved. Conventional MEMS packages are usually ceramic and plastic. In ceramic packages, the die is bonded to a ceramic base, which includes a metal frame and pins for making electric outside connections. Plastic packages are connected in the similar way. However, the package can be molded around the microdevice.

Silicon and silicon carbide micromachining are the most developed micromachining technologies. Silicon is the primary substrate material which is used by the microelectronics industry. A single crystal ingot (solid cylinder 300 mm diameter and 1000 mm length) of very high purity silicon is grown, then sawed with the desired thickness and polished using chemical and mechanical polishing techniques. Electromagnetic and mechanical wafer properties depend upon the orientation of the crystal growth, concentration and type of doped impurities. Depending on the silicon substrate, CMOS processes are used to manufacture ICs, and the process is classified as *n-well*, *p-well*, or *twin-well*. The major steps are diffusion, oxidation, polysilicon gate formations, photolithography, masking, etching, metallization, wire bonding, et cetera. To fabricate motion microstructures (microelectromechanical motion devices),

CMOS technology must be modified. High-resolution photolithography is a technology that is applied to produce moulds for the fabrication of micromachined mechanical components and to define their three-dimensional shape (geometry). That is, the micromachine geometry is defined photographically. First, a mask is produced on a glass plate. The silicon wafer is then coated with a polymer which is sensitive to ultraviolet light (photoresistive layer is called photoresist). Ultraviolet light is shone through the mask onto the photoresist to build the mask to the photoresist layer. The positive photoresist becomes softened, and the exposed layer can be removed. In general, there are two types of photoresist, e.g., positive and negative. Where the ultraviolet light strikes the positive photoresist, it weakens the polymer. Hence, when the image is developed, the photoresist is washed where the light struck it. A high-resolution positive image results. In contrast, if the ultraviolet light strikes negative photoresist, it strengthens the polymer. Therefore, a negative image of the mask results. Chemical process is used to remove the oxide where it is exposed through the openings in the photoresist. When the photoresist is removed, the patterned oxide appears. Alternatively, electron beam lithography can be used. Photolithography requires design of masks. The design of photolithography masks for micromachining is straightforward, and computer-aided-design (CAD) software is available and widely applied.

There are a number of basic surface silicon micromachining technologies that can be used in order to pattern thin films that have been deposited on a silicon wafer, and to shape the silicon wafer itself forming a set of basic microstructures. Three basic steps associated with silicon micromachining are:

- deposition of thin films of materials;
- removal of material (patterning) by wet or dry techniques;
- doping.

Different microelectromechanical motion devices (motion microstructures) can be designed, and silicon wafers with different crystal orientations are used. Reactive ion etching (dry etching) is usually applied. Ions are accelerated towards the material to be etched, and the etching reaction is enhanced in the direction of ion traveling. Deep trenches and pits of desired shapes can be etched in a variety of materials including silicon, oxide, and nitride. A combination of dry and wet etching can be embedded in the process.

Metal films are patterned using the lift off stenciling technique. A thin film of the assisting material (oxide) is deposited, and a layer of photoresist is put over and patterned. The oxide is then etched to undercut the photoresist. The metal film is then deposited on the silicon wafer through evaporation process. The metal pattern is stenciled through the gaps in the photoresist, which is then removed, lifting off the unwanted metal. The assisting layer is then stripped off, leaving the metal film pattern.

The anisotropic wet etching and concentration dependent etching are

called bulk silicon micromachining because the microstructures are formed by etching away the bulk of the silicon wafer. Surface micromachining forms the structure in layers of thin films on the surface of the silicon wafer or other substrate. Hence, the surface micromachining process uses thin films of two different materials, e.g., structural (usually polysilicon) and sacrificial (oxide) materials. Sacrificial layers of oxide are deposited on the wafer surface, and dry etched. Then, the sacrificial material is wet etched away to release the structure. A variety of different complex motion microstructures with different geometry have been fabricated using the surface micromachining technology.

Micromachined silicon wafers must be bonded together. Anodic (electrostatic) bonding technique is used to bond silicon wafer and glass substrate. In particular, the silicon wafer and glass substrate are attached, heated, and electric field is applied across the join. These result in extremely strong bonds between the silicon wafer and glass substrate. In contrast, the direct silicon bonding is based upon applying pressure to bond silicon wafer and glass substrate. It must be emphasized that to guarantee strong bonds, the silicon wafer and glass substrate surfaces must be flat and clean.

The MEMCAD<sup>™</sup> software (current version is 4.6), developed by Microcosm, is widely used to design, model, simulate, characterize, and package MEMS. Using the built-in Microcosm Catapult<sup>™</sup> layout editor, augmented with materials database and components library, three-dimensional solid models of motion microstructures can be developed. Furthermore, customizable packaging is fully supported.

#### CHAPTER 2

# MATHEMATICAL MODELS AND DESIGN OF NANO- AND MICROELECTROMECHANICAL SYSTEMS

#### 2.1. NANO- AND MICROELECTROMECHANICAL SYSTEMS ARCHITECTURE

A large variety of nano- and microscale structures and devices, as well as NEMS and MEMS (systems integrate structures. devices. and subsystems), have been widely used, and a worldwide market for NEMS and MEMS and their applications will be drastically increased in the near future. The differences in NEMS and MEMS are emphasized, and NEMS are smaller than MEMS. For example, carbon nanotubes (nanostructure) can be used as the molecular wires and sensors in MEMS. Different specifications are imposed on NEMS and MEMS depending upon their applications. For example, using carbon nanotubes as the molecular wires, the current density is defined by the media properties (e.g., resistivity and thermal conductivity). It is evident that the maximum current is defined by the diameter and the number of layers of the carbon nanotube. Different molecular-scale nanotechnologies are applied to manufacture NEMS (controlling and changing the properties of nanostructures), while analog, discrete, and hybrid MEMS have been mainly manufactured using surface micro-machining. silicon-based technology (lithographic processes are used to fabricate CMOS ICs). To deploy and commercialize NEMS and MEMS, a spectrum of problems must be solved, and a portfolio of software design tools needs to be developed using a multidisciplinary concept. In recent years much attention has been given to MEMS fabrication and manufacturing, structural design and optimization of actuators and sensors, modeling, analysis, and optimization. It is evident that NEMS and MEMS can be studied with different level of detail and comprehensiveness, and different application-specific architectures should be synthesized and optimized. The majority of research papers study either nano- and microscale actuators-sensors or ICs that can be the subsystems of NEMS and MEMS. A great number of publications have been devoted to the carbon nanotubes (nanostructures used in NEMS and MEMS). The results for different NEMS and MEMS components are extremely important and manageable. However, the comprehensive systems-level research must be performed because the specifications are imposed on the systems, not on the individual elements, structures, and subsystems of NEMS and MEMS. Thus, NEMS and MEMS must be developed and studied to attain the comprehensiveness of the analysis and design.

For example, the actuators are controlled changing the voltage or current (by ICs) or the electromagnetic field (by nano- or microscale antennas). The

ICs and antennas (which should be studied as the subsystems) can be controlled using nano or micro decision-making systems, which can include central processor and memories (as core), IO devices, etc. Nano- and microscale sensors are also integrated as elements of NEMS and MEMS, and through molecular wires (for example, carbon nanotubes) one feeds the information to the IO devices of the nano-processor. That is, NEMS and MEMS integrate a large number of structures and subsystems which must be studied. As a result, the designer usually cannot consider NEMS and MEMS as six-degrees-of-freedom actuators using conventional mechanics (the linear or angular displacement is a function of the applied force or torque), completely ignoring the problem of how these forces or torques are generated and regulated. In this book, we will illustrate how to integrate and study the basic components of NEMS and MEMS.

The design and development, modeling and simulation, analysis and prototyping of NEMS and MEMS must be attacked using advanced theories. The systems analysis of NEMS and MEMS as systems integrates analysis and design of structures, devices and subsystems used, structural optimization and modeling, synthesis and optimization of architectures, simulation and virtual prototyping, etc. Even though a wide range of nanoscale structures and devices (e.g., molecular diodes and transistors, machines and transducers) can be fabricated with atomic precision, comprehensive systems analysis of NEMS and MEMS must be performed before the designer embarks in costly fabrication because through optimization of architecture, structural optimization of subsystems (actuators and sensors. ICs and antennas), modeling and simulation, analysis and visualization, the rapid evaluation and prototyping can be performed facilitating cost-effective solution reducing the design cycle and cost, guaranteeing design of high-performance NEMS and MEMS which satisfy the requirements and specifications.

The large-scale integrated MEMS (a single chip that can be mass-produced using the CMOS, lithography, and other technologies at low cost) integrates:

- N nodes of actuators/sensors, smart structures, and antennas;
- processor and memories,
- interconnected networks (communication busses),
- input-output (IO) devices,
- etc.

Different architectures can be implemented, for example, linear, star, ring, and hypercube are illustrated in Figure 2.1.1.



Figure 2.1.1. Linear, star, ring, and hypercube architectures

More complex architectures can be designed, and the hypercubeconnected-cycle node configuration is illustrated in Figure 2.1.2.



Figure 2.1.2. Hypercube-connected-cycle node architecture

The nodes can be synthesized, and the elementary node can be simply pure smart structure, actuator, or sensor. This elementary node can be controlled by the external electromagnetic field (that is, ICs or antenna are not a part of the elementary structure). In contrast, the large-scale node can integrate processor (with decision making, control, signal processing, and data acquisition capabilities), memories, IO devices, communication bus, ICs and antennas, actuators and sensors, smart structures, etc. That is, in addition to actuators/sensors and smart structures), processor (to control ICs and antennas), memories and interconnected networks, IO devices, as well as other subsystems can be integrated. Figure 2.1.3 illustrates large-scale and elementary nodes.



Figure 2.1.3. Large-scale and elementary nodes

As NEMS and MEMS are used to control physical dynamic systems (immune system or drug delivery, propeller or wing, relay or lock), to illustrate the basic components, a high-level functional block diagram is shown in Figure 2.1.4.


Figure 2.1.4. High-level functional block diagram of large-scale NEMS and MEMS

For example, the desired flight path of aircraft (maneuvering and landing) is maintained by displacing the control surfaces (ailerons and elevators, canards and flaps, rudders and stabilizers) and/or changing the control surface and wing geometry. Figure 2.1.5 documents the application of the NEMS- and MEMS-based technology to actuate the control surfaces. It should be emphasized that the NEMS and MEMS receive the digital signal-level signals from the flight computer, and these digital signals are converted into the desired voltages or currents fed to the microactuators or electromagnetic flux intensity to displace the actuators. It is also important that NEMS- and MEMS-based transducers can be used as sensors, and, as an example, the loads on the aircraft structures during the flight can be measured.



Figure 2.1.5. Aircraft with MEMS-based flight actuators

# Microelectromechanical and Nanoelectromechanical Systems

Microelectromechanical systems are integrated microassembled structures (electromechanical microsystems on a single chip) that have both electrical-electronic (ICs) and mechanical components. To manufacture MEMS, modified advanced microelectronics fabrication techniques and materials are used. It was emphasized that sensing and actuation cannot be viewed as the peripheral function in many applications. Integrated actuators/sensors with ICs compose the major class of MEMS. Due to the use of CMOS lithography-based technologies in fabrication actuators and sensors, MEMS leverage microelectronics (signal processing, computing, and control) in important additional areas that revolutionize the application capabilities. In fact, MEMS have been considerably leveraged the microelectronics industry beyond ICs. The needs to augmented actuators, sensors, and ICs have been widely recognized. For example, mechatronics concept, used for years in conventional electromechanical systems, integrates all components and subsystems (electromechanical motion devices, power converters, microcontrollers, et cetera). Simply scaling conventional electromechanical motion devices and augmenting them with ICs have not met the needs, and theory and fabrication processes have been developed beyond component replacement. Only recently it becomes possible to manufacture MEMS at very low cost. However, there is a critical demand for continuous fundamental, applied, and technological improvements, and multidisciplinary activities are required. The general lack of synergy theory to augment actuation, sensing, signal processing, and control is known, and these issues must be addressed through focussed efforts. The set of longrange goals has been emphasized in Chapter 1. The challenges facing the development of MEMS are

- advanced materials and process technology,
- microsensors and microactuators, sensing and actuation mechanisms, sensors-actuators-ICs integration and MEMS configurations,
- packaging, microassembly, and testing,
- MEMS modeling, analysis, optimization, and design,
- MEMS applications and their deployment.

Significant progress in the application of CMOS technology enable the industry to fabricate microscale actuators and sensors with the corresponding ICs, and this guarantees the significant breakthrough. The field of MEMS has been driven by the rapid global progress in ICs, VLSI, solid-state devices, and that microprocessors. memories. DSPs have revolutionized instrumentation and control. In addition, this progress has facilitated explosive growth in data processing and communications in highperformance systems. In microelectronics, many emerging problems deal with nonelectric phenomena and processes (thermal and structural analysis and optimization, packaging, et cetera). It has been emphasized that ICs is the necessary component to perform control, data acquisition, and decision making. For example, control signals (voltage or currents) are computer, converted, modulated, and fed to actuators. It is evident that MEMS have found application in a wide array of microscale devices (accelerometers, pressure sensors, gyroscopes, et cetera) due to extremely-high level of integration of electromechanical components with low cost and maintenance, accuracy, reliability, and ruggedness. Microelectronics with integrated sensors and actuators are batch-fabricated as integrated assemblies.

Therefore, MEMS can be defined as

batch-fabricated microscale devices (ICs and motion microstructures) that convert physical parameters to electrical signals and vise versa, and in addition, microscale features of mechanical and electrical components, architectures, structures, and parameters are important elements of their operation and design.

The manufacturability issues in NEMS and MEMS must be addressed. It was shown that one can design and manufacture individually-fabricated devices and subsystems. However, these devices and subsystems are unlikely will be used due to very high cost.

Piezoactuators and permanent-magnet technology has been used widely, and rotating and linear electric transducers (actuators and sensors) are designed. For example, piezoactive materials are used in ultrasonic motors. Frequently, conventional concepts of the electric machinery theory (rotational and linear direct-current, induction, and synchronous machine) are used to design and analyze MEMS-based machines. The use of piezoactuators is possible as a consequence of the discovery of advanced materials in sheet and thin-film forms, especially PZT (lead zirconate titanate) and polyvinylidene fluoride. The deposition of thin films allows piezo-based electric machines to become a promising candidate for microactuation in lithography-based fabrication. In particular, microelectric machines can be fabricated using a deep x-ray lithography and electrodeposition process. Two-pole synchronous and induction micromotors have been fabricated and tested.

To fabricate nanoscale structures, devices, and NEMS, molecular manufacturing methods and technologies must be developed. Self- and positional-assembly concepts are the preferable technologies compared with individually-fabricated in the synthesis and manufacturing of To perform self- and positional-assembly, molecular structures. complementary pairs (CP) and molecular building blocks (MBB) should be designed. These CP or MBB, which can be built from a couple to thousands atoms, can be studied and designed using the DNA analogy. The nucleic acids consist of two major classes of molecules (DNA and RNA). Deoxvribonucleic acid (DNA) and ribonucleic acid (RNA) are the largest and most complex organic molecules which are composed of carbon. oxygen, hydrogen, nitrogen, and phosphorus. The structural units of DNA and RNA are nucleotides, and each nucleotide consists of three components (nitrogen-base, pentose and phosphate) joined by dehydration synthesis. The double-helix molecular model of DNA was discovered by Watson and Crick in 1953. The DNA (long double-stranded polymer with double chain of nucleotides held together by hydrogen bonds between the bases), as the genetic material (genes), performs two fundamental roles. It replicates (identically reproduces) itself before a cell divides, and provides pattern for protein synthesis directing the growth and development of all living organisms according to the information DNA supports. The DNA architecture provides the mechanism for the replication of genes. Specific pairing of nitrogenous bases obey base-pairing rules and determine the combinations of nitrogenous bases that form the rungs of the double helix. In contrast, RNA carries (performs) the protein synthesis using the DNA information. Four DNA bases are: A (adenine), G (guanine), C (cytosine), and T (thymine). The ladder-like DNA molecule is formed due to hydrogen bonds between the bases which paired in the interior of the double helix (the base pairs are 0.34 nm apart and there are ten pairs per turn of the helix). Two backbones (sugar and phosphate molecules) form the uprights of the DNA molecule, while the joined bases form the rungs. Figure 2.1.6 illustrates that the hydrogen bonding of the bases are: A bonds to T, G bonds to C. The complementary base sequence results.



Figure 2.1.6. DNA pairing due to hydrogen bonds

In RNA molecules (single strands of nucleotides), the complementary bases are A bonds to U (uracil), and G bonds to C. The complementary base bonding of DNA and RNA molecules gives one the idea of possible stickyended assembling (through complementary pairing) of NEMS structures and devices with the desired level of specificity, architecture, topology, and organization. In structural assembling and design, the key element is the ability of CP or MBB (atoms or molecules) to associate with each other (recognize and identify other atoms or molecules by means of specific base pairing relationships). It was emphasized that in DNA, A (adenine) bonds to T (thymine) and G (guanine) bonds to C (cytosine). Using this idea, one can design the CP such as A<sub>1</sub>-A<sub>2</sub>, B<sub>1</sub>-B<sub>2</sub>, C<sub>1</sub>-C<sub>2</sub>, etc. That is, A<sub>1</sub> pairs with A<sub>2</sub>, while  $B_1$  pairs with  $B_2$ . This complementary pairing can be studied using electromagnetics (Coulomb law) and chemistry (chemical bonding, for example, hydrogen bonds in DNA between nitrogenous bases A and T, G and C). Figure 2.1.7 shows how two nanoscale elements with sticky ends form the complementary pair. In particular, "+" is the sticky end and "-" is its complement. That is, the complementary pair  $A_1$ - $A_2$  results.



Figure 2.1.7. Sticky ended electrostatically complementary pair A<sub>1</sub>-A<sub>2</sub>

An example of assembling a ring is illustrated in Figure 2.1.8. Using the sticky ended segmented (asymmetric) electrostatically CP, self-assembling of

nanostructure is performed in the XY plane. It is evident that threedimensional structures can be formed through the self-assembling.



Figure 2.1.8. Ring self-assembling

It is evident that there are several advantages to use sticky ended electrostatic CP. In the first place, the ability to recognize (identify) the complementary pair is clear and reliably predicted. The second advantage is the possibility to form stiff, strong, and robust structures.

Self-assembled complex nanostructures can be fabricated using subsegment concept to form the branched junctions. This concept is welldefined electrostatically and geometrically through Coulomb law and branching connectivity. Using the subsegment concept, ideal objects (e.g., cubes, octahedron, spheres, cones, et cetera) can be manufactured. Furthermore, the geometry of nanostructures can be easily controlled by the number of CP and pairing MBB. It must be emphasized that it is possible to generate a quadrilateral self-assembled nanostructure by using four and more different CP. That is, in addition to electrostatic CP, chemical CP can be used. Single- and double-stranded structures can be generated and linked in the desired topological and architectural manners. The self-assembling must be controlled during the manufacturing cycle, and CP and MBB, which can be paired and topologically/architecturally bonded, must be added in the desired sequence. For example, polyhedral and octahedral synthesis can be performed when building elements (CP or MBB) are topologically or geometrically specified. The connectivity of nanostructures determines the minimum number of linkages that flank the branched junctions. The synthesis of complex three-dimensional nanostructures is the design of topology, and the structures are characterized by their branching and linking.

## Linkage Groups in Molecular Building Blocks

The hydrogen bonds, which are weak, hold DNA and RNA strands. Strong bonds are desirable to form stiff, strong, and robust nano- and microstructures. Using polymer chemistry, functional groups which couple monomers can be designed. However, polymers made from monomers with only two linkage groups do not exhibit the desired stiffness and strength. Tetrahedral MBB structures with four linkage groups result in stiff and robust structures. Polymers are made from monomers, and each monomer reacts with two other monomers to form linear chains. Synthetic and organic polymers (large molecules) are nylon and dacron (synthetic), and proteins and RNA, respectively.

There are two major ways to assemble parts. In particular, self assembly and positional assembly. Self-assembling is widely used at the molecular scale, and the DNA and RNA examples were already emphasized. Positional assembling is widely used in manufacturing and microelectronic manufacturing. The current inability to implement positional assembly at the molecular scale with the same flexibility and integrity that it applied in microelectronic fabrication limits the range of nanostructures which can be manufactured. Therefore, the efforts are focused on developments of MBB, as applied to manufacture nanostructures, which guarantee:

- mass-production at low cost and high yield;
- simplicity and predictability of synthesis and manufacturing;
- high-performance, repeatability, and similarity of characteristics;
- stiffness, strength, and robustness;
- tolerance to contaminants.

It is possible to select and synthesize MBB that satisfy the requirements and specifications (non-flammability, non-toxicity, pressure, temperatures, stiffness, strength, robustness, resistivity, permiability, permittivity, et cetera). Molecular building blocks are characterized by the number of linkage groups and bonds. The linkage groups and bonds that can be used to connect MBB are:

- dipolar bonds (weak),
- hydrogen bonds (weak),
- transition metal complexes bonds (weak),
- amide and ester linkages (weak and strong).

It must be emphasized that large molecular building blocks (LMMB) can be made from MBB. There is a need to synthesize robust three-dimensional structures. Molecular building blocks can form planar structures with are strong, stiff, and robust in-plane, but weak and compliant in the third dimension. This problem can be resolved by forming tubular structures. It was emphasized that it is difficult to form three-dimensional structures using MBB with two linkage groups. Molecular building blocks with three linkage groups form planar structures, which are strong, stiff, and robust in plane but bend easily. This plane can be rolled into tubular structures to guarantee stiffness. Molecular building blocks with four, five, six, and twelve linkage groups form strong, stiff, and robust three-dimensional structures needed to synthesize robust nano- and microstructures.

Molecular building blocks with L linkage groups are paired forming Lpair structures, and planar and non-planar (three-dimensional) nano- and microstructures result. These MBB can have in-plane linkage groups and outof-plane linkage groups which are normal to the plane. For example, hexagonal sheets are formed using three in-plane linkage groups (MBB is a single carbon atom in a sheet of graphite) with adjacent sheets formed using two out-of-plane linkage groups. It is evident that this structure has hexagonal symmetry.

Molecular building blocks with six linkage groups can be connected together in the cubic structure. These six linkage groups corresponding to six sides of the cube or rhomb. Thus, MBB with six linkage groups form solid three-dimensional structures as cubes or rhomboids. It should be emphasized that buckyballs ( $C_{60}$ ), which can be used as MMB, are formed with six functional groups. Molecular building blocks with six in-plane linkage groups form strong planar structures. Robust, strong, and stiff cubic or hexagonal closed-packed crystal structures are formed using twelve linkage groups. Molecular building blocks synthesized and applied should guarantee the desirable performance characteristics (stiffness, strength, robustness, resistivity, permiability, permittivity, et cetera) as well as manufacturability. It is evident that stiffness, strength, and robustness are predetermined by bonds (weak and strong), while resistivity, permiability and permittivity are the functions of MBB compounds and media.

# 2.2. ELECTROMAGNETICS AND ITS APPLICATION FOR NANO-AND MICROSCALE ELECTROMECHANICAL MOTION DEVICES

To study NEMS and MEMS actuators and sensors, smart structures, ICs and antennas, one applies the electromagnetic field theory. Electric force holds atoms and molecules together. Electromagnetics plays a central role in molecular biology. For example, two DNA (deoxyribonucleic acid) chains wrap about one another in the shape of a *double helix*. These two strands are held together by electrostatic forces. Electric force is responsible for energy-transforming processes in all living organisms (*metabolism*). Electromagnetism is used to study protein synthesis and structure, nervous system, etc.

Electrostatic interaction was investigated by Charles Coulomb.

For charges  $q_1$  and  $q_2$ , separated by a distance x in free space, the magnitude of the electric force is

$$F = \frac{|q_1 q_2|}{4\boldsymbol{p}\boldsymbol{e}_0 \boldsymbol{x}^2}$$

where  $\mathbf{e}_0$  is the permittivity of free space,  $\mathbf{e}_0 = 8.85' \, 10^{-12} \text{ F/m or } \text{C}^2/\text{N-m}^2$ ,  $\frac{1}{10^{-12}} = 9' \, 10^9 \text{ N-m}^2/\text{C}$ 

The unit for the force is the newton N, while the charges are given in coulombs, C.

The force is the vector, and we have

$$\vec{F} = \frac{q_1 q_2}{4 \boldsymbol{p} \boldsymbol{e}_0 \boldsymbol{x}^2} \vec{a}_x \,,$$

where  $\vec{a}_x$  is the unit vector which is directed along the line joining these two charges.

The capacity, elegance and uniformity of electromagnetics arise from a sequence of fundamental laws linked one to other and needed to study the field quantities.

Using the Gauss law and denoting the vector of electric flux density as  $\vec{D}$  [F/m] and the vector of electric field intensity as  $\vec{E}$  [V/m or N/C], the total electric flux F [C] through a closed surface is found to be equal to the total force charge enclosed by the surface. That is, one finds

$$\mathbf{F} = \mathop{\bullet}\limits_{s} \vec{D} \times d\vec{s} = Q_s , \ \vec{D} = \mathbf{e}\vec{E} ,$$

where  $d\vec{s}$  is the vector surface area,  $d\vec{s} = ds\vec{a}_n$ ,  $\vec{a}_n$  is the unit vector which is normal to the surface;  $\boldsymbol{e}$  is the permittivity of the medium;  $Q_s$  is the total charge enclosed by the surface.

Ohm's law relates the volume charge density  $\vec{J}$  and electric field intensity  $\vec{E}$ ; in particular,

$$\vec{J} = \boldsymbol{S}\vec{E}$$
,

where **s** is the conductivity [A/V-m], for copper  $s = 5.8 \cdot 10^7$ , and for aluminum  $s = 3.5 \cdot 10^7$ .

The current *i* is proportional to the potential difference, and the resistivity  $\mathbf{r}$  of the conductor is the ratio between the electric field  $\vec{E}$  and the current density  $\vec{J}$ . Thus,

$$\mathbf{r} = \frac{\vec{E}}{\vec{J}}$$
.

The resistance r of the conductor is related to the resistivity and conductivity by the following formulas

$$r = \frac{\mathbf{r}l}{A}$$
 and  $r = \frac{l}{\mathbf{s}A}$ ,

where l is the length; A is the cross-sectional area.

It is important to emphasize that the parameters of NEMS and MEMS vary. Let us illustrate this using the simplest nano-structure used in NEMS and MEMS. In particular, the molecular wire. The resistances of the ware vary due to heating. The resistivity depends on temperature T [°C], and

$$\boldsymbol{r}(T) = \boldsymbol{r}_0 \Big[ 1 + \boldsymbol{a}_{r1} \big( T \cdot T_0 \big) + \boldsymbol{a}_{r2} \big( T \cdot T_0 \big)^2 + \dots \Big],$$

where  $a_{r1}$  and  $a_{r2}$  are the coefficients.

As an example, over the small temperature range (up to 160°C) for copper (the wire is filled with copper) at  $T_0 = 20$ °C, we have

$$\mathbf{r}(T) = 1.7 \cdot 10^{-8} [1 + 0.0039 (T - 20)].$$

To study NEMS and MEMS, the basic principles of electromagnetic theory should be briefly reviewed.

The total magnetic flux through the surface is given by

$$\mathsf{F} = \mathbf{\dot{O}}^{\vec{B}} \times d\vec{s}$$

where  $\vec{B}$  is the magnetic flux density.

The Ampere circuital law is

$$\dot{\mathbf{O}}_{l}^{\vec{B}} \times d\vec{l} = \mathbf{m}_{0} \dot{\mathbf{O}}_{s}^{\vec{J}} \times d\vec{s}$$

where  $\mathbf{m}_{p}$  is the permeability of free space,  $\mathbf{m}_{p} = 4p' 10^{-7}$  H/m or T-m/A.

For the filamentary current, Ampere's law connects the magnetic flux with the algebraic sum of the enclosed (linked) currents (*net current*)  $i_n$ , and

$$\dot{\mathbf{O}}_{l}^{\vec{B}} \times d\vec{l} = \mathbf{m}_{b} i_{n}.$$

The time-varying magnetic field produces the electromotive force (emf), denoted as  $\mathbf{J}$ , which induces the current in the closed circuit. Faraday's law

relates the *emf*, which is merely the induced voltage due to conductor motion in the magnetic field, to the rate of change of the magnetic flux F penetrating in the loop. In approaching the analysis of electromechanical energy transformation in NEMS and MEMS, Lenz's law should be used to find the direction of *emf* and the current induced. In particular, the *emf* is in such a direction as to produce a current whose flux, if added to the original flux, would reduce the magnitude of the *emf*. According to Faraday's law, the induced *emf* in a closed-loop circuit is defined in terms of the rate of change of the magnetic flux F as

$$\mathbf{J} = \underbrace{\partial}_{l} \vec{E}(t) \times d\vec{l} = -\frac{d}{dt} \underbrace{\partial}_{s} \vec{B}(t) \times d\vec{s} = -N \frac{d\mathbf{F}}{dt} = -\frac{d\mathbf{y}}{dt},$$

where N is the number of turns; y denotes the flux linkages.

This formula represents the Faraday law of induction, and the induced *emf* (*induced voltage*), as given by

$$\mathbf{J} = -\frac{d\mathbf{y}}{dt} = -N\frac{d\mathbf{F}}{dt},$$

is a particular interest

The current flows in an opposite direction to the flux linkages. The electromotive force (*energy-per-unit-charge quantity*) represents a magnitude of the potential difference V in a circuit carrying a current. One obtains,

$$V = -ir + \mathbf{J} = -ir - \frac{d\mathbf{y}}{dt}$$

The unit for the *emf* is volts.

The Kirchhoff voltage law states that around a closed path in an electric circuit, the algebraic sum of the *emf* is equal to the algebraic sum of the voltage drop across the resistance.

Another formulation is: the algebraic sum of the voltages around any closed path in a circuit is zero.

The Kirchhoff current law states that the algebraic sum of the currents at any node in a circuit is zero.

The magnetomotive force (*mmf*) is the line integral of the time-varying magnetic field intensity  $\vec{H}(t)$ ; that is,

$$mmf = \overleftarrow{O}_{l}\vec{H}(t) \times d\vec{l}$$
.

One concludes that the induced *mmf* is the sum of the induced current and the rate of change of the flux penetrating the surface bounded by the contour. To show that, we apply Stoke's theorem to find the integral form of Ampere's law (second Maxwell's equation), as given by

$$\dot{\mathbf{p}}_{l}^{\vec{H}}(t) \times d\vec{l} = \dot{\mathbf{p}}_{s}^{\vec{I}}(t) \times d\vec{s} + \dot{\mathbf{p}}_{s}^{dD(t)} d\vec{s} ,$$

where  $\vec{J}(t)$  is the time-varying current density vector.

The unit for the magnetomotive force is amperes or ampere-turns The duality of the *emf* and *mmf* can be observed using

$$\mathbf{J} := \mathbf{\partial} \vec{E}(t) \times d\vec{l} \text{ and } mmf = \mathbf{\partial} \vec{H}(t) \times d\vec{l} .$$

The inductance (the ratio of the total flux linkages to the current which they link,  $L = \frac{NF}{i}$ ) and reluctance (the ratio of the *mmf* to the total flux,  $\hat{A} = \frac{mmf}{E}$ ) are used to find *emf* and *mmf*.

Using the following equation for the self-inductance  $L = \frac{y}{i}$ , we have

$$\mathbf{J} = -\frac{d\mathbf{y}}{dt} = -\frac{d(Li)}{dt} = -L\frac{di}{dt} - i\frac{dL}{dt}$$

If 
$$L = const$$
, one obtains

$$\mathbf{J} = -L\frac{di}{dt}$$

That is, the self-inductance is the magnitude of the self-induced *emf* per unit rate of change of current.

#### Example 2.2.1.

Find the self-inductances of a nano-solenoid with air-core and filled-core ( $m = 100 m_o$ ). The solenoid has 100 turns (N = 100), the length is 20 nm (l=20 nm), and the uniform circular cross-sectional area is 5′10<sup>-18</sup> m<sup>2</sup> ( $A = 5′10^{-18}$  m<sup>2</sup>).

Solution. The magnetic field inside a solenoid is given by  $B = \frac{\mathbf{m}_0 N i}{l}$ .

By using 
$$\mathbf{J} = -N \frac{d\mathbf{F}}{dt} = -L \frac{di}{dt}$$
 and applying  $\mathbf{F} = BA = \frac{\mathbf{m}_0 NiA}{l}$ ,

one obtains

$$L = \frac{\boldsymbol{m}_0 N^2 A}{l}.$$

Then,  $L = 3.14' \, 10^{-12} \, \text{H}.$ 

If solenoid is filled with a magnetic material, we have

$$L = \frac{m N^2 A}{l}$$
, and  $L = 3.14^{\prime} 10^{-9}$  H.

Example 2.2.2.

Derive a formula for the self-inductance of a torroidal solenoid which has a rectangular cross section  $(2a \ b)$  and mean radius *r*.

Solution. The magnetic flux through a cross section is found as

$$F = \underbrace{\overset{r+a}{\mathbf{o}}}_{r-a} Bbdr = \underbrace{\overset{r+a}{\mathbf{o}}}_{r-a} \frac{\mathbf{m}Ni}{2\mathbf{p}r} bdr = \frac{\mathbf{m}Nib}{2\mathbf{p}} \underbrace{\overset{r+a}{\mathbf{o}}}_{r-a} \frac{1}{r} dr = \frac{\mathbf{m}Nib}{2\mathbf{p}} \ln\underbrace{\overset{\mathbf{a}}{\mathbf{e}}}_{r-a} \frac{\mathbf{a}}{\dot{\mathbf{o}}}.$$
  
Hence,  $L = \frac{NF}{i} = \frac{\mathbf{m}N^2b}{2\mathbf{p}} \ln\underbrace{\overset{\mathbf{a}}{\mathbf{e}}}_{r-a} \frac{\mathbf{a}}{\dot{\mathbf{o}}}.$ 

By studying the electromagnetic torque  $\vec{T}$  [N-m] in a current loop, one obtains the following equation

$$\vec{T} = \vec{M} \,\, \check{} \,\, \vec{B} \,,$$

where  $\vec{M}$  denotes the magnetic moment.

Let us examine the torque-energy relations in nano- and microscale actuators. Our goal is to study the magnetic field energy. It is known that the energy stored in the capacitor is  $\frac{1}{2}CV^2$ , while energy stored in the inductor is  $\frac{1}{2}Li^2$ . Observe that the energy in the capacitor is stored in the electric field between plates, while the energy in the inductor is stored in the magnetic field within the coils.

Let us find the expressions for energies stored in electrostatic and magnetic fields in terms of field quantities. The total potential energy stored in the electrostatic field is found using the potential difference *V*, and we have

$$W_e = \frac{1}{2} \mathop{\mathbf{or}}_{v} V dv$$
 [J]

where  $\mathbf{r}_{v}$  is the volume charge density [C/m<sup>3</sup>],  $\mathbf{r}_{v} = \mathbf{\vec{N}} \times \mathbf{\vec{D}}$ ,  $\mathbf{\vec{N}}$  is the curl operator.

This expression for  $W_e$  is interpreted in the following way. The potential energy should be found using the amount of work which is required to position the charge in the electrostatic field. In particular, the work is found as the product of the charge and the potential. Considering the region with a continuous charge distribution ( $\mathbf{r}_v = const$ ), each charge is replaced by

 $\mathbf{r}_{v}dv$ , and hence the equation  $W_{e} = \frac{1}{2} \overleftarrow{\mathbf{r}}_{v}Vdv$  results.

In the Gauss form, using  $\mathbf{r}_v = \mathbf{\vec{N}} \times \mathbf{\vec{D}}$  and making use  $\mathbf{\vec{E}} = -\mathbf{\vec{N}}V$ , one obtains the following expression for the energy stored in the electrostatic field

$$W_e = \frac{1}{2} \overleftrightarrow{D} \times \vec{E} dv$$
,

and the electrostatic volume energy density is  $\frac{1}{2}\vec{D}\times\vec{E}$  [J/m<sup>3</sup>].

For a linear isotropic medium  $W_e = \frac{1}{2} \bigotimes_{v} \left| \vec{E} \right|^2 dv = \frac{1}{2} \bigotimes_{v} \frac{1}{e} \left| \vec{D} \right|^2 dv$ .

The electric field  $\overline{E}(x,y,z)$  is found using the scalar electrostatic potential function V(x,y,z) as

 $\vec{E}(x,y,z) = -\vec{N}V(x,y,z) .$ 

In the cylindrical and spherical coordinate systems, we have

$$\vec{E}(r, f, z) = - \tilde{N}V(r, f, z)$$
 and  $\vec{E}(r, q, f) = - \tilde{N}V(r, q, f)$ .

Using  $W_e = \frac{1}{2} \bigotimes_{v} V dv$ , the potential energy which is stored in the

electric field between two surfaces (for example, in capacitor) is found to be

$$W_e = \frac{1}{2}QV = \frac{1}{2}CV^2$$
.

Using the principle of virtual work, for the lossless conservative system, the differential change of the electrostatic energy  $dW_e$  is equal to the differential change of mechanical energy  $dW_{mec}$ ; that is

$$dW_e = dW_{mec}$$

For translational motion

$$dW_{mec} = \vec{F}_e \times d\vec{l}$$

where  $d\vec{l}$  is the differential displacement.

One obtains  $dW_e = \vec{N}W_e \times d\vec{l}$ .

Hence, the force is the gradient of the stored electrostatic energy,  $\vec{F}_{e} = \vec{N} W_{e}$ .

In the Cartesian coordinates, we have

$$F_{ex} = \frac{\varPi W_e}{\varPi x}, F_{ey} = \frac{\varPi W_e}{\varPi y}$$
 and  $F_{ez} = \frac{\varPi W_e}{\varPi z}$ .

# Example 2.2.3.

Consider the capacitor (the plates have area A and they are separated by x), which is charged to a voltage V. The permittivity of the dielectric is e. Find the stored electrostatic energy and the force  $F_{ex}$  in the x direction.

*Solution*. Neglecting the fringing effect at the edges, one concludes that the electric field is uniform, and  $E = \frac{V}{r}$ . Therefore, we have

$$W_{e} = \frac{1}{2} \bigotimes_{v} \left| \vec{E} \right|^{2} dv = \frac{1}{2} \bigotimes_{v} \bigotimes_{v} \bigotimes_{v} \bigotimes_{v} \bigotimes_{v} \bigotimes_{v} \partial^{2} dv = \frac{1}{2} \mathbf{e} \frac{V^{2}}{x^{2}} Ax = \frac{1}{2} \mathbf{e} \frac{A}{x} V^{2} = \frac{1}{2} C(x) V^{2}.$$

Thus, the force is

$$F_{ex} = \frac{\P W_e}{\P x} = \frac{\P \left(\frac{1}{2}C(x)V^2\right)}{\P x} = \frac{1}{2}V^2 \frac{\P C(x)}{\P x}$$

To find the stored energy in the magnetostatic field in terms of field quantities, the following formula is used

$$W_m = \frac{1}{2} \overset{\bullet}{O} \vec{B} \times \vec{H} dv$$

The magnetic volume energy density is  $\frac{1}{2}\vec{B}\times\vec{H}$  [J/m<sup>3</sup>].

Using  $\vec{B} = \vec{m}\vec{H}$ , one obtains two alternative formulas

$$W_m = \frac{1}{2} \dot{\mathbf{O}}_v \left| \vec{H} \right|^2 dv = \frac{1}{2} \dot{\mathbf{O}}_v \left| \frac{\vec{B} \right|^2}{\mathbf{m}} dv$$

To show how the energy concept studied is applied to electromechanical devices, we find the energy stored in inductors. To approach this problem, we substitute  $\vec{B} = \vec{N} \cdot \vec{A}$ , and using the following vector identity  $\vec{H} \times \vec{N} \cdot \vec{A} = \vec{N} \times (\vec{A} \cdot \vec{H}) + \vec{A} \times \vec{N} \cdot \vec{H}$ , one obtains

$$W_{m} = \frac{1}{2} \overleftrightarrow{B}^{\vec{\mu}} \times \vec{H} dv = \frac{1}{2} \overleftrightarrow{V}^{\vec{\mu}} \times (\vec{A} \cdot \vec{H}) dv + \frac{1}{2} \overleftrightarrow{V}^{\vec{\mu}} \times \vec{N} \cdot \vec{H} dv$$
$$= \frac{1}{2} \overleftrightarrow{A}^{\vec{\mu}} \cdot \vec{H} \times d\vec{s} + \frac{1}{2} \overleftrightarrow{V}^{\vec{\mu}} \times \vec{J} dv = \frac{1}{2} \overleftrightarrow{V}^{\vec{\mu}} \times \vec{J} dv.$$

Using the general expression for the vector magnetic potential  $\vec{A}(\vec{r})$  [Wb/m], as given by

$$\vec{A}(\vec{r}) = \frac{\boldsymbol{m}_0}{4\boldsymbol{p}} \overset{\mathcal{J}(\vec{r}_A)}{\underset{\boldsymbol{v}_A}{\overset{\mathcal{J}}{x}}} d\boldsymbol{v}_J , \ \vec{N} \times \vec{A} = 0,$$

we have

$$W_m = \frac{\boldsymbol{m}}{8\boldsymbol{p}} \bigotimes_{v \, v_J} \frac{\tilde{J}(\vec{r}_A) \times \tilde{J}(\vec{r})}{x} dv_J dv.$$

Here,  $v_J$  is the volume of the medium where  $\vec{J}$  exists.

The general formula for the self-inductance i = j and the mutual inductance  $i^{1} j$  of loops *i* and *j* is

$$L_{ij} = \frac{N_i \mathsf{F}_{ij}}{i_j} = \frac{\mathbf{y}_{ij}}{i_j},$$

where  $\mathbf{y}_{ij}$  is the flux linkage through *i*th coil due to the current in *j*th coil;  $i_j$  is the current in *j*th coil.

The Neumann formula is applied to find the mutual inductance. We have,

$$L_{ij} = L_{ji} = \frac{\boldsymbol{m}}{4\boldsymbol{p}} \bigotimes_{l_i \ l_j} \frac{dl_j \times dl_i}{x_{ij}}, i \ 1 \ j$$

Then, using 
$$W_m = \frac{\mathbf{m}}{8\mathbf{p}} \bigotimes_{v v_J} \frac{\hat{J}(\vec{r}_A) \times \hat{J}(\vec{r})}{x} dv_J dv$$
, one obtains

$$W_m = \frac{\boldsymbol{m}}{8\boldsymbol{p}} \bigotimes_{l_i \ l_j}^{i_j d \vec{l}_j \times i_i d \vec{l}_i} x_{ij}$$

Hence, the energy stored in the magnetic field is found to be

$$W_m = \frac{1}{2}i_i L_{ij}i_j.$$

As an example, the energy, stored in the inductor is  $W_m = \frac{1}{2}Li^2$ .

The differential change in the stored magnetic energy should be found. Using

$$\frac{dW_m}{dt} = \frac{1}{2} \underbrace{\overset{\infty}{\xi}}_{\xi} L_{ij} i_j \frac{di_i}{dt} + L_{ij} i_i \frac{di_j}{dt} + i_i i_j \frac{dL_{ij} \overset{\circ}{}}{dt} + \underbrace{\overset{\circ}{}}_{\sharp} \frac{dL_{ij}}{dt} + \underbrace{\overset{\circ}{}}_{ij} \frac{dL_{ij}}{dt} + \underbrace{\overset{\circ}{}}_{ij} \frac{dL_{ij}}{dt} + \underbrace{\overset{\ast}{}}_{ij} \frac{dL$$

we have  $dW_m = \frac{1}{2} g^2 L_{ij} i_j di_i + L_{ij} i_i di_j + i_i i_j dL_{ij} \frac{\ddot{o}}{o}$ .

For translational motion, the differential change in the mechanical energy is expressed by

 $dW_{mec} = \vec{F}_m \times d\vec{l}$  .

Assuming that the system is conservative (for lossless systems  $dW_{mec} = dW_m$ ), in the rectangular coordinate system we obtain the following equation

$$dW_m = \frac{\P W_m}{\P x} dx + \frac{\P W_m}{\P y} dy + \frac{\P W_m}{\P z} dz = \vec{\mathsf{N}} W_m \times d\vec{l} \ .$$

Hence, the force is the gradient of the stored magnetic energy, and  $\vec{F}_m = \vec{N} W_m$ .

In the XYZ coordinate system for the translational motion, we have

$$F_{mx} = \frac{\P W_m}{\P x}, F_{my} = \frac{\P W_m}{\P y} \text{ and } F_{mz} = \frac{\P W_m}{\P z}.$$

For the rotational motion, the torque should be used. Using the differential change in the mechanical energy as a function of the angular displacement  $\boldsymbol{q}$ , the following formula results if the rigid body (nano- or microactuator) is constrained to rotate about the *z*-axis

$$dW_{mec} = T_e d\boldsymbol{q} \; ,$$

where  $T_e$  is the z-component of the electromagnetic torque.

Assuming that the system is lossless, one obtains the following expression for the electromagnetic torque

$$T_e = \frac{\P W_m}{\P q}$$

*Example 2.2.4.* 

Calculate the magnetic energy of the torroidal microsolenoid if the self-inductance is  $1' 10^{-10}$  H ( $L=2' 10^{-10}$  H) when the current is 0.001 A (i=0.001 A).

Solution. The stored field energy is  $W_m = \frac{1}{2}Li^2$ , therefore  $W_m = \frac{1}{2}2'10^{-10}'0.001 = 1'10^{-13}$  J.

Example 2.2.5.

Calculate the force developed by the microelectromagnet with the crosssectional area A if the current  $i_a(t)$  in and N coils produces the constant flux  $F_m$ , see Figure 2.2.1.



Figure 2.2.1. Microelectromagnet *Solution*.

From  $W_m = \frac{1}{2} \bigotimes_{v} \left| \vec{H} \right|^2 dv = \frac{1}{2} \bigotimes_{v} \left| \frac{\vec{B} \right|^2}{m} dv$ , for the virtual displacement dy,

assuming that the flux is constant and taking into the account the fact that the displacement changes only the magnetic energy stored in the air gaps, we have

$$dW_m = dW_{m \ air \ gap} = 2\frac{B^2}{2m_0}Ady = \frac{\mathsf{F}_m^2}{m_0A}dy.$$

Thus, if  $F_m$  =const, one concludes that the increase of the air gap (dy) leads to increase of the stored magnetic energy, and from  $F_{mx} = \frac{\P W_m}{\P x}$  one finds the expression for the force

$$\vec{F}_{mx} = -\vec{a}_y \frac{\mathbf{F}_m^2}{\mathbf{m}_0 A}.$$

The result indicates that the force tends to reduce the air-gap length, and the movable member is attached to the spring which develops the force which opposite to the electromagnetic force.

In nano- and microscale electromechanical motion devices, the coupling (magnetic interaction) between windings that are carrying currents is represented by their mutual inductances. In fact, the current in each winding causes the magnetic field in other windings. The mutually induced *emf* is characterized by the mutual inductance which is a function of the position x or the angular displacement  $\boldsymbol{q}$ . By applying the expression for the coenergy  $W_c[i, L(x)]$  or  $W_c[i, L(\boldsymbol{q})]$ , the developed electromagnetic torque can be easily found. In particular,

$$T_e(i,x) = \frac{\P W_c[i,L(x)]}{\P x} \text{ and } T_e(i,x) = \frac{\P W_c[i,L(\boldsymbol{q})]}{\P \boldsymbol{q}}$$

#### Example 2.2.6.

Consider the microelectromagnet which has N turns, see Figure 2.2.2. The distance between the stationary and movable members is denoted as x(t). The mean lengths of the stationary and movable members are  $l_1$  and  $l_2$ , and the cross-sectional area is A. Neglecting the leakage flux, find the force exerted on the movable member if the time-varying current  $i_a(t)$  is supplied. The permeabilities of stationary and movable members are  $\mathbf{m}_1$  and  $\mathbf{m}_2$ .



Figure 2.2.2. Schematic of an electromagnet

Solution.

The magnetostatic force is

$$F_{mx} = \frac{\P W_m}{\P x},$$

where  $W_m = \frac{1}{2} L i_a^2(t)$ .

The magnetizing inductance should be calculated, and we have

$$L = \frac{N\mathsf{F}}{i_a(t)} = \frac{\mathbf{y}}{i_a(t)},$$

where the magnetic flux is  $\mathbf{F} = \frac{Ni_a(t)}{\hat{\mathbf{A}}_1 + \hat{\mathbf{A}}_x + \hat{\mathbf{A}}_x + \hat{\mathbf{A}}_2}$ .

The reluctances of the ferromagnetic materials of stationary and movable members  $\hat{A}_1$  and  $\hat{A}_2$ , as well as the reluctance of the air gap  $\hat{A}_x$ , are found as

$$\hat{\mathsf{A}}_1 = \frac{l_1}{\mathbf{m}_0 \mathbf{m}_1 A}, \ \hat{\mathsf{A}}_2 = \frac{l_2}{\mathbf{m}_0 \mathbf{m}_2 A} \text{ and } \hat{\mathsf{A}}_x = \frac{x(t)}{\mathbf{m}_0 A}$$

and the circuit analog with the reluctances of the various paths is illustrated in Figure 2.2.3.



Figure 2.2.3. Circuit analog

By making use the reluctances in the movable and stationary members and air gap, one obtains the following formula for the flux linkages

$$\mathbf{y} = N\mathbf{F} = \frac{N^2 i_a(t)}{\frac{l_1}{\mathbf{m}_0 \mathbf{m}_1 A} + \frac{2x(t)}{\mathbf{m}_0 A} + \frac{l_2}{\mathbf{m}_0 \mathbf{m}_2 A}}$$

and the magnetizing inductance is a nonlinear function of the displacement. We have

$$L(x) = \frac{N^2}{\frac{l_1}{m_0 m_1 A} + \frac{2x(t)}{m_0 A} + \frac{l_2}{m_0 m_2 A}} = \frac{N^2 m_0 m_1 m_2 A}{m_2 l_1 + m_1 m_2 2x(t) + m_1 l_2}.$$
  
Using  $F_{mx} = \frac{\#W_m}{\#x} = \frac{1}{2} \frac{\#(L(x(t))i_a^2(t))}{\#x}$ , the force in the x direction is and to be

found to be

$$F_{mx} = -\frac{N^2 \mathbf{m}_0 \mathbf{m}_1^2 \mathbf{m}_2^2 A i_a^2}{\mathbf{m}_2 l_1 + \mathbf{m}_1 \mathbf{m}_2 2 x(t) + \mathbf{m}_1 l_2}$$

It should be emphasized that as differential equations must be developed to model the microelectromagnet studied. Using Newton's second law of motion, one obtains

$$\frac{dx}{dt} = v,$$

$$\frac{dv}{dt} = \frac{1}{m} \mathop{\mathfrak{S}}\limits^{\mathfrak{S}} - \frac{N^2 \mathbf{m}_0 \mathbf{m}_1^2 \mathbf{m}_2^2 A i_a^2}{\mathbf{m}_2 l_1 + \mathbf{m}_2 2 x(t) + \mathbf{m}_1 l_2} - k_s x^2 \mathop{\dot{\mathfrak{O}}}\limits^{\ddot{\mathfrak{O}}}_{\phi}$$

#### Example 2.2.7.

Two micro-coils have mutual inductance 0.00005 H ( $L_{12}$ =0.00005 H). The current in the first coil is  $i_1 = \sqrt{\sin 4t}$ . Find the induced *emf* in the second coil.

Solution.

The induced *emf* is given as  $J_2 = L_{12} \frac{di_1}{dt}$ .

By using the power rule for the time-varying current in the first coil  $i_1 = \sqrt{\sin 4t}$ , we have

$$\frac{di_1}{dt} = \frac{2\cos 4t}{\sqrt{\sin 4t}}.$$
  
Hence,  $\int_2 = \frac{0.0001\cos 4t}{\sqrt{\sin 4t}}.$ 

# Basic Foundations in Model Developments of Nano- and Microactuators in Electromagnetic Fields

Electromagnetic theory and mechanics form the basis for the development of NEMS and MEMS models.

The electrostatic and magnetostatic equations in linear isotropic media are found using the vectors of the electric field intensity  $\vec{E}$ , electric flux density  $\vec{D}$ , magnetic field intensity  $\vec{H}$ , and magnetic flux density  $\vec{B}$ . In addition, one uses the constitutive equations

 $\vec{D} = \mathbf{e}\vec{E}$  and  $\vec{B} = \mathbf{m}\vec{H}$ 

where  $\boldsymbol{e}$  is the permittivity;  $\boldsymbol{m}$  is the permiability.

The basic equations are given in the Table 1.

Table 2.2.1.

Fundamental Equations of Electrostatic and Magnetostatic Fields

	Electrostatic Model	Magnetostatic Model
Governing	$\tilde{N} \stackrel{\prime}{=} \vec{E}(x, y, z, t) = 0$	$\tilde{N}' \vec{H}(x, y, z, t) = 0$
equations	$\tilde{\mathbf{N}} \times \vec{E}(x, y, z, t) = \frac{\mathbf{r}_{v}(x, y, z, t)}{\mathbf{e}}$	$\tilde{N} \times \vec{H}(x, y, z, t) = 0$
Constitutive	$\vec{D} = e\vec{E}$	$\vec{B} = \mathbf{m}\vec{H}$
equations		

In the static (time-invariant) fields, electric and magnetic field vectors form separate and independent pairs. That is,  $\vec{E}$  and  $\vec{D}$  are not related to  $\vec{H}$  and  $\vec{B}$ , and vice versa. However, in reality, the electric and magnetic fields are time-varying, and the changes of magnetic field influence the electric field, and vice versa.

The partial differential equations are found by using Maxwell's equations. In particular, four Maxwell's equations in the differential form for time-varying fields are

$$\begin{split} \tilde{\mathsf{N}} &\check{\vec{E}}(x,y,z,t) = -\mathbf{m} \frac{\P \vec{H}(x,y,z,t)}{\P t}, \\ \tilde{\mathsf{N}} &\check{\vec{H}}(x,y,z,t) = \mathbf{s} \vec{E}(x,y,z,t) + \mathbf{e} \frac{\P \vec{E}(x,y,z,t)}{\P t} + \vec{J}(x,y,z,t), \\ \tilde{\mathsf{N}} \times \vec{E}(x,y,z,t) = \frac{\mathbf{r}_{v}(x,y,z,t)}{\mathbf{e}}, \\ \tilde{\mathsf{N}} \times \vec{H}(x,y,z,t) = 0, \end{split}$$

where  $\vec{E}$  is the electric field intensity, and using the permittivity  $\boldsymbol{e}$ , the electric flux density is  $\vec{D} = \boldsymbol{e}\vec{E}$ ;  $\vec{H}$  is the magnetic field intensity, and using the permeability  $\boldsymbol{m}$ , the magnetic flux density is  $\vec{B} = \boldsymbol{m}\vec{H}$ ;  $\vec{J}$  is the current density, and using the conductivity  $\boldsymbol{s}$ , we have  $\vec{J} = \boldsymbol{s}\vec{E}$ ;  $\boldsymbol{r}_v$  is the volume charge density, and the total electric flux through a closed surface is  $\mathbf{F} = \bigotimes_{v}^{p} \times d\vec{s} = \bigotimes_{v}^{p} dv = Q$  (Gauss's law), while the magnetic flux crossing

surface is  $\mathbf{F} = \partial \vec{B} \times d\vec{s}$ .

The electromotive and magnetomotive forces are found as

$$emf = \bigotimes_{l} \vec{E} \times d\vec{l} = \bigotimes_{l} \vec{v} \cdot \vec{B} \times d\vec{l} - \bigotimes_{s} \frac{\P B}{\P t} d\vec{s} \text{ and}$$
  
motional induction (generation) transformer induction  
$$mmf = \bigotimes_{l} \vec{H} \times d\vec{l} = \bigotimes_{s} \vec{J} \times d\vec{s} + \bigotimes_{s} \frac{\P \vec{D}}{\P t} d\vec{s} .$$

The motional *emf* is a function of the velocity and the magnetic flux density, while the electromotive force induced in a stationary closed circuit is equal to the negative rate of increase of the magnetic flux (transformer induction).

We introduce the vector magnetic potential which is denoted as  $\vec{A}$ . Using the equation  $\vec{B} = \tilde{N}' \vec{A}$ , one finds the following nonhomogeneous vector wave equation

$$\tilde{\mathbf{N}}^2 \cdot \vec{A} - \boldsymbol{m} \mathbf{e} \, \frac{\P^2 \vec{A}}{\P t^2} = - \, \boldsymbol{m} \vec{J}$$

and the solution gives the waves traveling with the velocity  $\frac{1}{\sqrt{me}}$ .

To develop mathematical models, consider the rotational motion of the bar magnet, current loop, and solenoid in a uniform magnetic field as illustrated in Figure 2.2.4.



Figure 2.2.4. Clockwise rotation of a magnetic bar, current loop, and solenoid

The torque tends to align the magnetic moment  $\vec{m}$  with  $\vec{B}$ , and  $\vec{T} = \vec{m} \cdot \vec{B}$ .

For a magnetic bar with the length *l*, the pole strength is *Q*.

The magnetic moment is m = Ql, and the force is found as F = QB. The electromagnetic torque is found to be

$$T = 2F \frac{1}{2}l\sin a = QlB\sin a = mB\sin a$$

Using the vectors, one obtains

$$\vec{T} = \vec{m} \cdot \vec{B} = \vec{a}_m m \cdot \vec{B} = Q l \vec{a}_m \cdot \vec{B}, \qquad (2.2.1)$$

where  $\vec{a}_m$  is the unit vector in the magnetic moment direction.

For a current loop with the area A, the torque is found as

$$\vec{T} = \vec{m} \cdot \vec{B} = \vec{a}_m m \cdot \vec{B} = iA\vec{a}_m \cdot \vec{B} .$$
(2.2.2)

For a solenoid with N turns, one obtains

$$\vec{T} = \vec{m} \, \vec{B} = \vec{a}_m m \, \vec{B} = iAN\vec{a}_m \, \vec{B} \,. \tag{2.2.3}$$

The straightforward application of Newton's second law for the rotational motion gives

$$\mathbf{\mathring{a}}\ \vec{T}_{s} = J\frac{d\mathbf{w}_{r}}{dt},\tag{2.2.4}$$

where  $\mathbf{\mathring{a}} \vec{T}_{s}$  is the net torque;  $\mathbf{w}_{r}$  is the angular velocity; *J* is the equivalent moment of inertia\.

The transient evolution of the angular displacement  $q_r$  is modeled as

$$\frac{d\boldsymbol{q}_r}{dt} = \boldsymbol{w}_r \,. \tag{2.2.5}$$

Augmenting equations (2.2.1), (2.2.2) or (2.2.3) with (2.2.4) and (2.2.5), the mathematical model of nano and micro rotational actuators results.

The energy is stored in the magnetic field, and media are classified as diamagnetic, paramagnetic, ferromagnetic, antiferromagnetic, and superparamagnetic. Using the magnetic susceptibility  $\boldsymbol{c}_m$ , the magnetization is expressed as

$$\vec{M} = \boldsymbol{c}_m \vec{H}$$
 .

Magnetization curves should be studied, and the permeability is  $\mathbf{m} = \frac{B}{H}$ .

The magnetic field density B lags behind the magnetic flux intensity H, and this phenomenon is called hysterisis. Thus, the B-H magnetization curves must be studied.

The per-unit volume magnetic energy stored is  $\partial HdB$ . The density of the *B* 

energy stored in the magnetic field is  $\frac{1}{2}\vec{B}\times\vec{H}$ . If *B* is linearly related to *H*, we have the expression for the total energy stored in the magnetic field as  $\frac{1}{2}\vec{O}\vec{B}\times\vec{H}dv$ .

For translational motion, Newton's second law states that the net force acting on the object is related to its acceleration as  $\mathbf{a} \quad \vec{F} = m\vec{a}$ . In the XYZ coordinate system, one obtains

**å** 
$$F_x = ma_x$$
, **å**  $F_y = ma_y$  and **å**  $F_z = ma_z$ .

The force is the gradient of the stored magnetic energy; that is,

$$\vec{F}_m = \mathbf{\tilde{N}} W_m$$

Hence, in the xyz directions, we have

$$F_{mx} = \frac{\P W_m}{\P x}, F_{my} = \frac{\P W_m}{\P y} \text{ and } F_{mz} = \frac{\P W_m}{\P z},$$

where the stored magnetic energy is found using the volume current density  $\vec{J}$ 

$$W_m = \frac{\boldsymbol{m}}{8\boldsymbol{p}} \bigotimes_{\boldsymbol{v} \, \boldsymbol{v}_A}^{\boldsymbol{J}(\boldsymbol{\vec{r}}_A) \times \boldsymbol{\vec{J}}(\boldsymbol{\vec{r}})} R d\boldsymbol{v}_A d\boldsymbol{v}.$$

Applying the field quantities, we have

$$W_m = \frac{1}{2} \bigotimes_{v} \vec{A} \times \vec{J} dv = \frac{1}{2} \bigotimes_{v} \vec{B} \times \vec{H} dv$$

The magnetic energy density is

$$w_m = \frac{1}{2}\vec{A}\times\vec{J} = \frac{1}{2}\vec{B}\times\vec{H}.$$

Using Newton's second law and the stored magnetic energy, we have nine highly coupled nonlinear differential equations for the *xyz* translational motion of microactuator. In particular,

$$\frac{dF_{xyz}}{dt} = f_F \left( F_{xyz}, v_{xyz}, x_{xyz}, H \right), 
\frac{dv_{xyz}}{dt} = f_v \left( F_{xyz}, v_{xyz}, x_{xyz}, F_{Lxyz} \right), 
\frac{dx_{xyz}}{dt} = f_x \left( v_{xyz}, x_{xyz} \right),$$
(2.2.6)

where  $F_{xyz}$  are the forces developed;  $v_{xyz}$  and  $x_{xyz}$  are the linear velocities and positions;  $F_{Lxyz}$  are the load forces.

The expressions for energies stored in electrostatic and magnetic fields in terms of field quantities should be derived. The total potential energy stored in the electrostatic field is obtained using the potential difference V as  $W_e = \frac{1}{2} \partial \mathbf{r}_v V dv$ , where the volume charge density is found as  $\mathbf{r}_v = \mathbf{\vec{N}} \times \mathbf{\vec{D}}$ ,

 $\tilde{N}$  is the curl operator.

In the Gauss form, using  $\mathbf{r}_{v} = \mathbf{\vec{N}} \times \mathbf{\vec{D}}$  and making use of  $\mathbf{\vec{E}} = -\mathbf{\vec{N}}V$ , one obtains the following expression for the energy stored in the electrostatic field  $W_{e} = \frac{1}{2} \overleftarrow{\mathbf{O}} \vec{\mathcal{P}} \times \mathbf{\vec{E}} dv$ , and the electrostatic volume energy density is  $\frac{1}{2} \vec{D} \times \mathbf{\vec{E}}$ . For a linear isotropic medium, one finds  $W_{e} = \frac{1}{2} \overleftarrow{\mathbf{O}} |\mathbf{\vec{E}}|^{2} dv = \frac{1}{2} \overleftarrow{\mathbf{O}}_{e}^{1} |\mathbf{\vec{D}}|^{2} dv$ .

The electric field  $\vec{E}(x,y,z)$  is found using the scalar electrostatic potential function V(x,y,z) as

 $\vec{E}(x,y,z) = -\vec{N}V(x,y,z) .$ 

In the cylindrical and spherical coordinate systems, we have

$$\vec{E}(r, f, z) = -\tilde{N}V(r, f, z)$$
 and  $\vec{E}(r, q, f) = -\tilde{N}V(r, q, f)$ 

Using the principle of virtual work, for the lossless conservative nanoand microelectromechanical systems, the differential change of the electrostatic energy  $dW_e$  is equal to the differential change of mechanical energy  $dW_{mec}$ ,  $dW_e = dW_{mec}$ . For translational motion  $dW_{mec} = \vec{F}_e \times d\vec{l}$ , where  $d\vec{l}$  is the differential displacement.

One obtains  $dW_e = \vec{N}W_e \times d\vec{l}$ .

Hence, the force is the gradient of the stored electrostatic energy,  $\vec{r} = \vec{S}_{1117}$ 

 $\vec{F}_e = \vec{N} W_e \,.$ 

In the Cartesian coordinates, we have

$$F_{ex} = \frac{\pi W_e}{\pi x}, F_{ey} = \frac{\pi W_e}{\pi y}$$
 and  $F_{ez} = \frac{\pi W_e}{\pi z}$ .

Energy conversion takes place in nanoand microscale electromechanical motion devices (actuators and sensors, smart structures), antennas and ICs. We study electromechanical motion devices that convert electrical energy (more precisely electromagnetic energy) to mechanical energy and vise versa (conversion of mechanical energy to electromagnetic energy). Fundamental principles of energy conversion, applicable to nano and micro electromechanical motion devices were studied to provide basic foundations. Using the principle of conservation of energy we can formulate: for a lossless nano- and microelectromechanical motion devices (in the conservative system no energy is lost through friction, heat, or other irreversible energy conversion) the sum of the instantaneous kinetic and potential energies of the system remains constant.

The energy conversion is represented in Figure 2.2.5.



Figure 2.2.5. Energy transfer in nano and micro electromechanical systems

The total energy stored in the magnetic field is found as

$$W_m = \frac{1}{2} \overleftrightarrow{B} \times \vec{H} dv$$

where  $\vec{B}$  and  $\vec{H}$  are related using the permeability  $\boldsymbol{m}$ ,  $\vec{B} = \boldsymbol{m}\vec{H}$ .

The material becomes magnetized in response to the external field  $\tilde{H}$ , and the dimensionless magnetic susceptibility  $c_m$  or relative permeability m are used. We have,

$$\vec{B} = \boldsymbol{m}\vec{H} = \boldsymbol{m}_0(1 + \boldsymbol{c}_m)\vec{H} = \boldsymbol{m}_0\boldsymbol{m}_{\vec{H}}\vec{H} = \boldsymbol{m}\vec{H}.$$

Based upon the value of the magnetic susceptibility  $c_m$ , the materials are classified as

- · diamagnetic,  $\boldsymbol{c}_m \gg -1^{\prime} 10^{-5}$  ( $\boldsymbol{c}_m = -9.5^{\prime} 10^{-6}$  for copper,  $\boldsymbol{c}_m = -3.2^{\prime} 10^{-5}$  for gold, and  $\boldsymbol{c}_m = -2.6^{\prime} 10^{-5}$  for silver);
- paramagnetic,  $c_m \gg 1 \cdot 10^{-4}$  ( $c_m = 1.4 \cdot 10^{-3}$  for Fe<sub>2</sub>O<sub>3</sub>, and  $c_m = 1.7 \cdot 10^{-3}$  for Cr<sub>2</sub>O<sub>3</sub>);
- ferromagnetic,  $|c_m| >> 1$  (iron, nickel and cobalt, Neodymium Iron Boron and Samarium Cobalt permanent magnets).

The magnetization behavior of the ferromagnetic materials is mapped by the magnetization curve, where H is the externally applied magnetic field, and B is total magnetic flux density in the medium. Typical B-H curves for hard and soft ferromagnetic materials are given in Figure 2.2.6, respectively.



Figure 2.2.6. B-H curves for hard and soft ferromagnetic materials

The *B* versus *H* curve allows one to establish the energy analysis. Assume that initially  $B_0 = 0$  and  $H_0 = 0$ . Let *H* increases form  $H_0 = 0$  to  $H_{\text{max}}$ . Then, *B* increases from  $B_0 = 0$  until the maximum value of *B*, denoted as  $B_{\text{max}}$ , is reached. If then *H* decreases to  $H_{\text{min}}$ , *B* decreases to  $B_{\text{min}}$  through the remanent value  $B_r$  (the so-called the residual magnetic flux density) along the different curve, see Figure 2.18. For variations of *H*,  $H\hat{1} [H_{\text{min}} H_{\text{max}}]$ , *B* changes within the *hysteresis loop*, and  $B\hat{1} [B_{\text{min}} B_{\text{max}}]$ . In the per-unit volume, the applied field energy is  $W_F = \mathop{}_{B}HdB$ , while

the stored energy is expressed as  $W_c = \partial B dH$ .

In the volume v, we have the following expressions for the field and stored energy

$$W_F = v \partial H dB$$
 and  $W_c = v \partial B dH$ 

A complete B versus H loop should be considered, and the equations for field and stored energy represent the areas enclosed by the corresponding curve. It should be emphasized that each point of the B versus H curve represent the total energy.

In ferromagnetic materials, time-varying magnetic flux produces core losses which consist of hysteresis losses (due to the hysteresis loop of the B-H curve) and the eddy-current losses, which are proportional to the current frequency and lamination thickness. The area of the hysteresis loop is related to the hysteresis losses. Soft ferromagnetic materials have narrow hysteresis loop and they are easily magnetized and demagnetized. Therefore, the lower hysteresis losses, compared with hard ferromagnetic materials, result.

For electromechanical motion devices, the flux linkages are plotted versus the current because the current and flux linkages are used rather than the flux intensity and flux density. In nano- and microectromechanical motion devices almost all energy is stored in the air gap. Using the fact that the air is a conservative medium, one concludes that the coupling filed is lossless.

Figure 2.2.7 illustrates the nonlinear magnetizing characteristic (normal magnetization curve), and the energy stored in the magnetic field is  $W_F = \oint_{\mathbf{y}} d\mathbf{y}$ , while the coenergy is found as  $W_c = \oint_{i} d\mathbf{y}$ . The total energy is  $W_F + W_c = \oint_{\mathbf{y}} d\mathbf{y} + \oint_{\mathbf{y}} d\mathbf{i} = \mathbf{y}\mathbf{i}$ .



Figure 2.2.7. Magnetization curve and energies

The flux linkages is the function of the current *i* and position *x* (for translational motion) or angular displacement  $\boldsymbol{q}$  (for rotational motion). That is,  $\boldsymbol{y} = f(i, \boldsymbol{x})$  or  $\boldsymbol{y} = f(i, \boldsymbol{q})$ . The current can be found as the nonlinear function of the flux linkages and position or angular displacement. Hence,

$$d\mathbf{y} = \frac{\P \mathbf{y}(i,x)}{\P i} di + \frac{\P \mathbf{y}(i,x)}{\P x} dx, \ d\mathbf{y} = \frac{\P \mathbf{y}(i,q)}{\P i} di + \frac{\P \mathbf{y}(i,q)}{\P q} dq,$$
  
and 
$$di = \frac{\P i(\mathbf{y},x)}{\P \mathbf{y}} d\mathbf{y} + \frac{\P i(\mathbf{y},x)}{\P x} dx, \ di = \frac{\P i(\mathbf{y},q)}{\P \mathbf{y}} d\mathbf{y} + \frac{\P i(\mathbf{y},q)}{\P q} dq.$$

Therefore,

$$W_F = \bigotimes_{\mathbf{y}} i d\mathbf{y} = \bigotimes_{i} \frac{\mathbf{\Pi} \mathbf{y}(i, x)}{\mathbf{\Pi} i} di + \bigotimes_{x} \frac{\mathbf{\Pi} \mathbf{y}(i, x)}{\mathbf{\Pi} x} dx ,$$
$$W_F = \bigotimes_{\mathbf{y}} i d\mathbf{y} = \bigotimes_{i} \frac{\mathbf{\Pi} \mathbf{y}(i, q)}{\mathbf{\Pi} i} di + \bigotimes_{q} \frac{\mathbf{\Pi} \mathbf{y}(i, q)}{\mathbf{\Pi} q} dq ,$$

and 
$$W_c = \bigotimes_{i} V di = \bigotimes_{\mathbf{y}} \frac{\P i(\mathbf{y}, x)}{\P \mathbf{y}} d\mathbf{y} + \bigotimes_{\mathbf{x}} \frac{\P i(\mathbf{y}, x)}{\P \mathbf{x}} dx$$
,  
 $W_c = \bigotimes_{i} V di = \bigotimes_{\mathbf{y}} \frac{\P i(\mathbf{y}, q)}{\P \mathbf{y}} d\mathbf{y} + \bigotimes_{\mathbf{q}} \frac{\P i(\mathbf{y}, q)}{\P q} d\mathbf{q}$ .

Assuming that the coupling field is lossless, the differential change in the mechanical energy (which is found using the differential displacement  $d\vec{l}$  as  $dW_{mec} = \vec{F}_m \times d\vec{l}$ ) is related to the differential change of the coenergy. For displacement dx at constant current, one obtains  $dW_{mec} = dW_c$ , and hence, the electromagnetic force is  $F_e(i,x) = \frac{\P W_c(i,x)}{\P x}$ .

For rotational motion, the electromagnetic torque is

$$T_e(i,\boldsymbol{q}) = \frac{\P W_c(i,\boldsymbol{q})}{\P \boldsymbol{q}}.$$

Micro- and meso-scale structures, as well as thin magnetic films, exhibit anisotropy. Consider the anisotropic ferromagnetic element in the Cartesian (rectangular) coordinate systems as shown in Figure 2.2.8.



Figure 2.2.8. Material in the xyz coordinate system

The permeability is  $\mathbf{m}(x, y, z) = \begin{pmatrix} \mathbf{\acute{e}m}_{xx} & \mathbf{m}_{xy} & \mathbf{m}_{xz} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{yx} & \mathbf{m}_{yy} & \mathbf{m}_{yz} \mathbf{\acute{u}}, \text{ and therefore,} \\ \mathbf{\acute{e}m}_{xx} & \mathbf{m}_{zy} & \mathbf{m}_{zz} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{zx} & \mathbf{m}_{zy} & \mathbf{m}_{zz} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{zx} & \mathbf{\acute{e}m}_{zx} & \mathbf{m}_{yy} & \mathbf{m}_{yz} \mathbf{\acute{u}}, \mathbf{\acute{e}m}_{zx} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{yy} \mathbf{\acute{u}} = \mathbf{\acute{e}m}_{yx} & \mathbf{m}_{yy} & \mathbf{m}_{yz} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{zx} & \mathbf{\acute{e}m}_{zx} & \mathbf{m}_{zy} & \mathbf{m}_{zz} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{zx} & \mathbf{\acute{e}m}_{yy} & \mathbf{m}_{yz} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{zx} & \mathbf{\acute{e}m}_{zx} & \mathbf{m}_{zy} & \mathbf{m}_{zz} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{z} \mathbf{\acute{e}m}_{zx} & \mathbf{m}_{zy} & \mathbf{m}_{zz} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{z} \mathbf{\acute{u}} \mathbf{\acute{e}m}_{z} & \mathbf{m}_{zy} & \mathbf{m}_{zz} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{z} \mathbf{\acute{u}} \mathbf{\acute{e}m}_{z} & \mathbf{m}_{zy} & \mathbf{m}_{zz} \mathbf{\acute{u}} \\ \mathbf{\acute{e}m}_{z} \mathbf{\acute{u}} \mathbf{\acute{u}} \mathbf{\acute{u}} \mathbf{\acute{u}} \mathbf{\acute{e}m}_{z} \mathbf{\acute{u}} \mathbf{$ 

The analysis of anisotropic nano- and microscale actuators and sensors can be performed. Some actuators and sensors can be studied assuming that the media is linear, homogeneous, and isotropic. Unfortunately, this assumption is not valid in general.

Control of microactuators position and linear velocity, angular displacement and angular velocity, is established by changing H. In (2.2.6), the magnetic field intensity can be considered as a control. However, the electromagnetic field is developed by ICs or antennas. Hence, the microICs or microantenna dynamics have to be integrated in (2.2.6). Thus, microscale antennas and ICs must be thoroughly considered.

Consider the microactuator controlled by the microantenna. Assume that the linear isotropic media has permittivity  $\mathbf{e}_0 \mathbf{e}_m$  and permeability  $\mathbf{m}_0 \mathbf{m}_m$ .

The force is calculated using the stress energy tensor  $T_{ab}$  which is given in terms of the electromagnetic field as

$$\vec{T}_{ab} = \boldsymbol{e}_0 \boldsymbol{e}_m \boldsymbol{E}_a \boldsymbol{E}_b + \boldsymbol{m}_0 \boldsymbol{m}_m \boldsymbol{H}_a \boldsymbol{H}_b - \frac{1}{2} \boldsymbol{d}_{ab} \left( \boldsymbol{e}_0 \boldsymbol{e}_m \boldsymbol{E}_g \boldsymbol{E}_g + \boldsymbol{m}_0 \boldsymbol{m}_m \boldsymbol{H}_g \boldsymbol{H}_g \right),$$
  
where  $\boldsymbol{d}_{ab}$  is the Kronecker delta-function, defined as  $\boldsymbol{d}_{ab} = \begin{bmatrix} 1 & \text{if } \boldsymbol{a} = \boldsymbol{b} \\ 1 & 0 & \text{if } \boldsymbol{a}^{-1} & \boldsymbol{b} \end{bmatrix}$ .

The electromagnetic field tensor is expressed as

$$\vec{F}_{ab} = \begin{pmatrix} \acute{\mathbf{e}} & 0 & \vec{E}_x & \vec{E}_y & \vec{E}_z & \dot{\mathbf{u}} \\ \acute{\mathbf{e}} & \vec{E}_x & 0 & \vec{B}_z & - \vec{B}_y & \dot{\mathbf{u}} \\ \acute{\mathbf{e}} & \vec{E}_y & - \vec{B}_z & 0 & \vec{B}_x & \dot{\mathbf{u}} \\ \acute{\mathbf{e}} & \vec{E}_z & \vec{B}_y & - \vec{B}_x & 0 & \acute{\mathbf{g}} \end{pmatrix}$$

and Maxwell's equation can be expressed in the tensor form.

Then, the electromagnetic force is found as

$$\vec{F} = \overleftarrow{O}_{ab} d\vec{s}$$

The results derived can be viewed using the energy analysis, and one has

$$\mathring{\mathbf{B}} \vec{F}(\vec{\mathbf{r}}) = - \tilde{\mathbf{N}} \mathsf{P}(\vec{\mathbf{r}}), \ \mathsf{P}(\vec{\mathbf{r}}) = \frac{\boldsymbol{e}_0 \boldsymbol{e}_m}{2} \underbrace{\mathbf{c}}_s \vec{\mathcal{E}} \times \vec{\mathcal{E}} dv + \frac{1}{2\boldsymbol{m}_0 \boldsymbol{m}_m} \underbrace{\mathbf{c}}_s \vec{\mathcal{H}} \times \vec{\mathcal{H}} dv.$$

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# 2.3. CLASSICAL MECHANICS AND ITS APPLICATION

With advanced molecular computer-aided-design tools, one can design, analyze, and evaluate three-dimensional (3-D) nanostructures in the steadystate. However, the comprehensive analysis in the time domain needs to be performed. That is, the designer must study the dynamic evolution of NEMS and MEMS. Conventional methods of molecular mechanics do not allow one to perform numerical analysis of complex NEMS and MEMS in timedomain, and even 3-D modeling is restricted to simple structures. Our goal is to develop a fundamental understanding of electromechanical and electromagnetic processes in nano- and microscale structures. An addition, the basic theoretical foundations will be developed and used in analysis of NEMS and MEMS from systems standpoints. That is, we depart from the subsystem analysis and study NEMS and MEMS as dynamics systems.

From modeling, simulation, analysis, and visualization standpoints, NEMS and MEMS are very complex. In fact, NEMS and MEMS are modeled using advanced concepts of quantum mechanics, electromagnetic theory, structural dynamics, thermodynamics, thermochemistry, etc. It was illustrated that NEMS and MEMS integrate a great number of components (subsystems), and mathematical model development is an extremely challenging problem because the commonly used conventional methods, assumptions, and simplifications may not be applied to NEMS and MEMS (for example, the Newtonian mechanics are not applicable to the molecularscale analysis, and Maxwell's equations must be used to study the electromagnetic phenomena). As the result, partial differential equations describe large-scale multivariable mathematical models of MEMS and NEMS. The visualization issues must be addressed to study the complex tensor data (tensor field). Techniques and software for visualizing scalar and vector field data are available to visualize the data in three dimensions. In contrast, techniques to visualize tensor fields are not available due to the complex, multivariate nature of the data, and the fact that no commonly used experimental analogy exists for visualizing tensor data. The second-order tensor fields consist of 3'3 matrices defined at each node in a computational grid. Tensor field variables can include stress, viscous stress, rate of strain, and momentum (tensor variables in conventional structural dynamics include stress and strain). The tensor field can be simplified and visualized as a scalar field. Alternatively, the individual vectors that comprise the tensor field can be analyzed. However, these simplifications result in the loss of valuable information needed to analyze complex tensor fields. Vector fields can be visualized using streamlines that depict a subset of the data. Hyperstreamlines, as an extension of the streamlines to the second-order tensor fields, provide one with a continuous representation of the tensor field along a three-dimensional path. Due to obvious limitations and scope, this book does not cover the tensor field topologies, and through this brief discussion of the resultant visualization, the author emphasizes the multidisciplinary nature and complexity of the phenomena in NEMS and MEMS.

While some results have been thoroughly studied, many important aspects have not been approached and researched, primarily due to the multidisciplinary nature and complexity of NEMS and MEMS. The major objectives of this book are to study the fundamental theoretical foundations, develop innovative concepts in structural design and optimization, perform modeling and simulation, as well as solve the motion control problem and validate the results. To develop mathematical models, we augment nano- or microactuator/sensor and circuitry dynamics (the dynamics can be studied at the nano and micro scales). Newtonian and quantum mechanics, Lagrange's and Hamilton's concepts, and other cornerstone theories are used to model NEMS and MEMS dynamics in the time domain. Taking note of these basic principles and laws, nonlinear mathematical models are found to perform comprehensive analysis and design. The control mechanisms and decision making are discussed, and control algorithms must be synthesized to attain the desired specifications and requirements imposed on the performance. It is evident that nano- and microsystem features must be thoroughly considered when approaching modeling, simulation, analysis, and design. The ability to find mathematical models is a key problem in NEMS and MEMS analysis and optimization, synthesis and control, manufacturing, and commercialization. For MEMS, using electromagnetic theory and electromechanics, we develop adequate mathematical models to attain the design objectives. The proposed approach, which augments electromagnetics and electromechanics, allows the designer to solve a much broader spectrum of problems compared with finite-element analysis because an interactive electromagnetic-mechanical-ICs analysis is performed. The developed theoretical results are verified to demonstrate.

In this book the author studies large-scale NEMS and MEMS (actuators and sensors have been primarily studied and analyzed from the fabrication standpoints) and thorough fundamental theory is developed. Applying the theoretical foundations to analyze and regulate in the desired manner the energy or information flows in NEMS and MEMS, the designer is confronted with the need to find adequate mathematical models of the phenomena, and design NEMS and MEMS configurations. Mathematical models can be found using basic physical concepts. In particular, in electrical, mechanical, fluid, or thermal systems, the mechanism of storing, dissipating, transforming, and transferring energies is analyzed. We will use the Lagrange equations of motion, Kirchhoff's and Newton's laws, Maxwell's equations, and quantum theory to illustrate the model developments. It was emphasized that NEMS and MEMS integrate many components and subsystems. One can reduce interconnected systems to simple, idealized subsystems (components). However, this idealization is impractical. For example, one cannot study nano- and microscale actuators and sensors without studying subsystems (devices) to actuate and control these transducers. That is, NEMS and MEMS integrate mechanical and electromechanical motion devices (actuators and sensors), power converters and antennas, processors and IO devices, etc. One of the primary objectives of this book is to illustrate how one can develop comprehensive mathematical models of NEMS and MEMS using basic principles and laws. Through illustrative examples, differential equations will be found to model dynamic systems.

Based upon the synthesized NEMS and MEMS architectures, to analyze and regulate in the desired manner the energy or information flows, the designer needs to find adequate mathematical models and optimize the performance characteristics through the design of control algorithms. Some mathematical models can be found using basic foundations and mathematical theory to map the dynamics of some processes, and system evolution is not developed yet. In this section we study electrical, mechanical, fluid, and thermal systems, the mechanism of storing, dissipating, transforming, and transferring energies in actuators and sensors which can be manufactured using a large variety of different nano-, micro-, and miniscale technologies. In this section we will use the Lagrange equations of motion, as well as Kirchhoff's and Newton's laws to illustrate the model developments applicable to a large class of nano-, micro-, and miniscale transducers. It has been illustrated that one cannot reduce interconnected systems (NEMS and MEMS) to simple, idealized sub-systems (components). For example, one cannot study actuators and smart structures without studying the mechanism to regulate these actuators, and ICs and antennas must be integrated as well. These ICs and antennas are controlled by the processor, which receives the information from sensors. The primary objective of this chapter is to illustrate how one can develop mathematical models of dynamic systems using basic principles and laws. Through illustrative examples, differential equations will be found and simulated.

Nano- and microelectromechanical systems must be studied using the fundamental laws and basic principles of mechanics and electromagnetics. Let us identify and study these key concepts to illustrate the use of cornerstone principles. The study of the motion of systems with the corresponding analysis of forces that cause motion is our interest.

# 2.3.1. Newtonian Mechanics

# Newtonian Mechanics: Translational Motion

The equations of motion for mechanical systems can be found using Newton's second law of motion. Using the position (displacement) vector  $\vec{r}$ , the Newton equation in the vector form is given as

$$\mathbf{\mathring{a}}\ \vec{F}(t,\vec{\mathbf{r}}) = m\vec{a}\ , \tag{2.3.1}$$

where  $\mathbf{a} \ \vec{F}(t, \vec{r})$  is the vector sum of all forces applied to the body ( $\vec{F}$  is called the *net* force);  $\vec{a}$  is the vector of acceleration of the body with respect to an inertial reference frame; *m* is the mass of the body.

From (2.3.1), in the Cartesian system (xyz coordinates) we have

$$\mathbf{\mathring{a}} \ \vec{F}(t,\vec{\mathbf{r}}) = m\vec{a} = m\frac{d\vec{\mathbf{r}}^2}{dt^2} = m\frac{\mathbf{\mathring{e}}d\vec{x}^2 \dot{\mathbf{u}}}{\mathbf{\mathring{e}}dt^2 \dot{\mathbf{u}}} \mathbf{\mathring{e}}d\vec{x} \mathbf{\mathring{u}} \mathbf{\mathring{e}}d\vec{x}^2 \dot{\mathbf{u}}}{\mathbf{\mathring{e}}dt^2 \dot{\mathbf{u}}} \mathbf{\mathring{e}}d\vec{x} \mathbf{\mathring{u}} \mathbf{\mathring{e}}d\vec{x}^2 \dot{\mathbf{u}} \mathbf{\mathring{e}}d\vec{x}^2 \dot{\mathbf{u}}}{\mathbf{\mathring{e}}dt^2 \dot{\mathbf{u}}} \mathbf{\mathring{e}}d\vec{x} \mathbf{\mathring{u}} \mathbf{\mathring{e}}d\vec{x}^2 \dot{\mathbf{u}}}{\mathbf{\mathring{e}}dt^2 \dot{\mathbf{u}}} \mathbf{\mathring{e}}d\vec{x}^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}d\vec{x}^2 \mathbf{\mathring{u}}}{\mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}}} \mathbf{\mathring{e}}d\vec{x}^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}d\vec{x}^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}d\vec{x}^2 \mathbf{\mathring{u}}}{\mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}}} \mathbf{\mathring{e}}d\vec{x}^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}d\vec{x}^2 \mathbf{\mathring{u}}}{\mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}}}{\mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}} \mathbf{\mathring{e}}dt^2 \mathbf{\mathring{u}}}$$

In the Cartesian coordinate system, Newton's second law is expressed as  $\mathbf{\mathring{a}} \ F_x = ma_x$ ,  $\mathbf{\mathring{a}} \ F_y = ma_y$ , and  $\mathbf{\mathring{a}} \ F_z = ma_z$ .

It is worth noting that  $m\vec{a}$  represents the magnitude and direction of the applied net force acting on the object. Hence,  $m\vec{a}$  is not a force.

A body is at equilibrium (the object is at rest or is moving with constant speed) if  $\mathbf{a}$   $\vec{F} = 0$ .

Newton's second law in terms of the linear momentum, which is found as  $\vec{p} = m\vec{v}$ , is given by

$$\mathbf{\mathring{a}} \ \vec{F} = \frac{d\vec{p}}{dt} = \frac{d(m\vec{v})}{dt},$$

where  $\vec{v}$  is the vector of the object velocity.

Thus, the force is equal to the rate of change of the momentum. The object or particle moves uniformly if  $\frac{d\vec{p}}{dt} = 0$  (thus,  $\vec{p} = const$ ).

Newton's laws are extended to multi-body systems, and the momentum of a system of N particles is the vector sum of the individual momenta. That is,

$$\vec{P} = \mathop{\mathsf{a}}_{i=1}^{N} \vec{p}_i$$

Consider the multi-body system of N particles. The position (displacement) is represented by the vector **r** which in the Cartesian coordinate system has the components *x*, *y* and *z*. Taking note of the expression for the potential energy  $P(\vec{\mathbf{r}})$ , one has for the conservative mechanical system

$$\mathbf{\mathring{a}} \ \vec{F}(\vec{\mathbf{r}}) = - \ \widetilde{\mathsf{NP}}(\vec{\mathbf{r}}).$$

Therefore, the work done per unit time is

$$\frac{dW}{dt} = \mathbf{\mathring{a}} \ \vec{F}(\vec{\mathbf{r}}) \frac{d\vec{\mathbf{r}}}{dt} = - \ \tilde{\mathsf{NP}}(\vec{\mathbf{r}}) \frac{d\vec{\mathbf{r}}}{dt} = - \frac{d\mathsf{P}(\vec{\mathbf{r}})}{dt}$$

From Newton's second law one obtains

$$m\vec{a} \cdot \mathbf{a} \vec{F}(\vec{\mathbf{r}}) = m \frac{d^2 \vec{\mathbf{r}}}{dt^2} \cdot \mathbf{a} \vec{F}(\vec{\mathbf{r}}) = 0,$$

hence, for a conservative system we have

$$m\frac{d^2\vec{\mathbf{r}}}{dt^2} + \tilde{\mathbf{NP}}(\vec{\mathbf{r}}) = 0.$$

For the system of N particles, the equations of motion are

$$m_{N} \frac{d^{2} \vec{\mathbf{r}}_{N}}{dt^{2}} + \tilde{\mathbf{NP}}(\vec{\mathbf{r}}_{N}) = 0,$$
  
r 
$$m_{i} \frac{d^{2}(\vec{x}_{i}, \vec{y}_{i}, \vec{z}_{i})}{dt^{2}} + \frac{\P \mathbf{P}(\vec{x}_{i}, \vec{y}_{i}, \vec{z}_{i})}{\P(\vec{x}_{i}, \vec{y}_{i}, \vec{z}_{i})} = 0, i = 1, ..., N.$$

or

The total kinetic energy of the particle is  $G = \frac{1}{2}mv^2$ , and for N particles, one has

$$\mathbf{G}_{\mathbf{v}}^{\mathbf{z}} \frac{d\vec{x}_{i}}{dt}, \frac{d\vec{y}_{i}}{dt}, \frac{d\vec{z}_{i}}{dt} \overset{\mathbf{O}}{=} \frac{1}{2} \overset{N}{\mathbf{a}} m_{i} \overset{\mathbf{z}}{\mathbf{v}} \frac{d\vec{x}_{i}}{dt}, \frac{d\vec{y}_{i}}{dt}, \frac{d\vec{z}_{i}}{dt} \overset{\mathbf{O}}{=} \frac{\mathbf{v}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf{O}}{=} \frac{\mathbf{v}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf{O}}{=} \frac{\mathbf{v}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf{O}}{=} \frac{\mathbf{v}}{\mathbf{a}} \overset{\mathbf{O}}{\mathbf{a}} \overset{\mathbf$$

Using the generilized coordinates  $(q_1,...,q_n)$  and generalized velocities  $\begin{array}{c} \overbrace{\mathbf{c}}^{\mathbf{z}} dq_1\\ \overbrace{\mathbf{c}}^{\mathbf{z}} dt\\ \hline{\mathbf{d}} t\\ \hline{\mathbf{d}} t\\ \hline{\mathbf{d}} t\\ \hline{\mathbf{c}} \end{array}$ , one finds the total kinetic  $\begin{array}{c} \overbrace{\mathbf{c}}^{\mathbf{z}} \mathbf{c}\\ \overbrace{\mathbf{c}}^{\mathbf{z}} q_1,...,q_n, \frac{dq_1}{dt},...,\frac{dq_n}{dt} \overset{\mathbf{o}}{\overset{\mathbf{o}}{\mathbf{o}}} \end{array}$  and potential  $P(q_1,...,q_n)$  energies. Hence, using the expressions for the total kinetic and potential energies, Newton's second law of motion can be given as

$$\frac{d}{dt} \underbrace{\underbrace{\mathbf{g}}_{\mathbf{g}_{i}}^{\mathbf{g}} \underbrace{\mathbf{G}}_{i}^{\mathbf{g}}}_{\mathbf{g}_{i}} \underbrace{\mathbf{g}}_{\mathbf{g}_{i}}^{\mathbf{g}} + \underbrace{\mathbf{g}}_{\mathbf{g}_{i}}^{\mathbf{g}} = 0$$

That is, the generalized coordinates  $q_i$  are used to model multibody systems, and  $(q_1,...,q_n) = (\vec{x}_1, \vec{y}_1, \vec{z}_1, ..., \vec{x}_N, \vec{y}_N, \vec{z}_N)$ .

The obtained results are connected to the Lagrange equations of motion, which will be studied later.

Newtonian Mechanics: Rotational Motion
For rotational motion, the net torque and angular acceleration must are used. The rotational analog of Newton's second law for a rigid bogy is

$$\mathbf{\mathring{a}} \ \vec{T} = J \vec{a}$$
 ,

where  $\mathbf{\hat{a}} \ \vec{T}$  is the *net* torque; *J* is the moment of inertia (*rotational inertia*);

 $\vec{a}$  is the angular acceleration vector,  $\vec{a} = \frac{d}{dt}\frac{d\vec{q}}{dt} = \frac{d^2\vec{q}}{dt^2} = \frac{d\vec{w}}{dt}$ ;  $\vec{q}$  is the

angular displacement; w denotes the angular velocity.

The angular momentum of the system  $L_M$  is expressed as

$$\vec{L}_M = \vec{r} \quad \vec{p} = \vec{r} \quad m\vec{v} ,$$

and  $\mathbf{\mathring{a}} \quad \vec{T} = \frac{dL_M}{dt} = \vec{r} \quad \vec{F}$ ,

where  $\vec{r}$  is the position vector with respect to the origin.

For the rigid body, rotating around the axis of symmetry, we have

$$\vec{L}_M = J\vec{w}$$

*Example 2.3.1.* 

A micro-motor has the equivalent moment of inertia  $J = 5 \cdot 10^{-20} \text{ kg-m}^2$ . Let the angular velocity of the rotor is  $\mathbf{w}_r = 10t^{1/5}$ . Find the angular momentum and the developed electromagnetic torque as functions of time. The load and friction torques are zero.

Solution.

The angular momentum is found as 
$$L_M = J \mathbf{w}_r = 5 \cdot 10^{-19} t^{1/5}$$
.  
The developed electromagnetic torque is  $T_e = \frac{dL_M}{dt} = 1 \cdot 10^{-19} t^{-4/5}$ .

From Newtonian mechanics one concludes that the applied net force plays a central role in quantitatively describing the motion. An alternative analysis of motion can be performed in terms of the energy or momentum quantities, which are conserved. The principle of conservation of energy states that energy can only be converted from one form to another. Kinetic energy is associated with motion, while potential energy is associated with position. The sum of the kinetic (G), potential (P), and dissipated (D) energies is called the total energy of the system ( $S_T$ ), which is conserved, and the total amount of energy remains constant; that is,

$$S_T = G + P + D = const$$
.

For example, consider the translational motion of a body which is attached to an ideal spring that obeys Hooke's law. Neglecting friction, one obtains the following expression for the total energy

$$S_T = G + P = \frac{1}{2}(mv^2 + k_s x^2) = const$$
.

Here, the translational kinetic energy is  $G = \frac{1}{2}mv^2$ ; the elastic potential energy is  $P = \frac{1}{2}k_sx^2$ ;  $k_s$  is the force constant of the spring; x is the displacement.

For rotating spring, we have

$$\mathbf{S}_T = \mathbf{G} + \mathbf{P} = \frac{1}{2} (J \mathbf{w}^2 + k_s \mathbf{q}^2) = const ,$$

where the rotational kinetic energy is  $\mathbf{G} = \frac{1}{2}J\mathbf{w}^2$  and the elastic potential energy is obtained as  $\mathbf{P} = \frac{1}{2}k_s q^2$ .

The kinetic energy of a rigid body having translational and rotational components of motion is found to be

$$\mathbf{G} = \frac{1}{2}(mv^2 + J\mathbf{w}^2)$$

That is, motion of the rigid body is represented as a combination of translational motion of the center of mass and rotational motion about the axis through the center of mass. The moment of inertia depends upon how the mass is distributed with respect to the axis, and J is different for different axes of rotation. If the body is uniform in density, J can be easily calculated for regularly shaped bodies in terms of their dimensions. For example, a rigid cylinder with mass m (which is uniformly distributed), radius R, and length l, has the following horizontal and vertical moments of inertia  $J_{horizontal} = \frac{1}{2}mR^2$  and  $J_{vertical} = \frac{1}{4}mR^2 + \frac{1}{12}ml^2$ . The radius of gyration can be found for irregularly shaped objects, and the moment of inertia can be easily obtained.

In electromechanical motion devices, the force and torque are thoroughly studied. Assuming that the body is rigid and the moment of inertia is constant, one has

$$\vec{T}d\vec{q} = J\vec{a}d\vec{q} = J\frac{d\vec{w}}{dt}d\vec{q} = J\frac{d\vec{q}}{dt}d\vec{w} = J\vec{w}d\vec{w}$$
.

The total work, as given by

$$W = \bigotimes_{\boldsymbol{q}_0}^{\boldsymbol{q}_f} \vec{d} \, \vec{\boldsymbol{q}} = \bigotimes_{\boldsymbol{w}_0}^{\boldsymbol{w}_f} J \, \vec{\boldsymbol{w}} d \, \vec{\boldsymbol{w}} = \frac{1}{2} (J \, \boldsymbol{w}_f^2 - J \, \boldsymbol{w}_0^2) \,,$$

represents the change of the kinetic energy.

Furthermore,

$$\frac{dW}{dt} = \vec{T} \frac{d\vec{q}}{dt} = \vec{T} \cdot \vec{w} ,$$

and the power is defined by

 $P = \vec{T} \cdot \vec{w}$ .

This equation is an analog of  $P = \vec{F} \cdot \vec{v}$ , which is applied for translational motion.

Example 2.3.2.

Consider a micro-positioning table actuated by a micromotor. How much work is required to accelerate a 2 mg payload (m = 2 mg) from  $v_0 = 0$  m/sec to  $v_f = 1$  m/sec?

Solution.

The work needed is calculated as

$$W = \frac{1}{2}(mv_f^2 - mv_0^2) = \frac{1}{2}2' 10^{-6}' 1^2 = 1' 10^{-6} \text{ J.}$$

*Example 2.3.3.* 

The rated power and angular velocity of a micromotor are 0.001 W and 100 rad/sec. Calculate the rated electromagnetic torque.

Solution.

The electromagnetic torque is

$$T_e = \frac{P}{W_r} = \frac{0.001}{100} = 1' \ 10^{-5} \text{ N-m.}$$

#### Example 2.3.4.

Consider a body of mass *m* in the *XY* coordinate system. The force  $\vec{F}_a$  is applied in the *x* direction. Neglecting *Coulomb* and static friction, and assuming that the viscous friction force is  $F_{fr} = B_v \frac{dx}{dt}$ , find the equations of

motion. Here  $B_{\nu}$  is the viscous friction coefficient.

### Solution.

The free-body diagram developed is illustrated in Figure 2.3.1.



Figure 2.3.1. Free-body diagram

The sum of the forces, acting in the y direction, is expressed as

$$\mathbf{\mathring{a}} \ \vec{F}_{Y} = \vec{F}_{N} - \vec{F}_{g},$$

where  $\vec{F}_g = mg$  is the gravitational force acting on the mass m;  $\vec{F}_N$  is the normal force which is equal and opposite to the gravitational force.

From (2.3.1), the equation of motion in the y direction is expressed as

$$\vec{F}_N - \vec{F}_g = ma_y = m\frac{d^2y}{dt^2},$$

where  $a_y$  is the acceleration in the y direction,  $a_y = \frac{d^2 y}{dt^2}$ .

Making use  $\vec{F}_N = \vec{F}_g$ , we have  $\frac{d^2 y}{dt^2} = 0.$ 

The sum of the forces acting in the x direction is found using the applied force  $\vec{F}_a$  and the friction force  $\vec{F}_{fr}$ ; in particular, we have

**å** 
$$\vec{F}_X = \vec{F}_a \cdot \vec{F}_{fr}$$

The applied force can be time-invariant  $\vec{F}_a = const$  or time-varying  $\vec{F}_a(t) = f(t, x, y, z)$ . For example,

$$\vec{F}_a(t) = x\sin(6t - 4)e^{-0.5t} + \frac{dy}{dt}t^2 + z^3\cos\frac{\partial a}{\partial t}t - y^2t^4\frac{\ddot{o}}{\dot{\phi}}$$

Using (2.1), the equation motion in the x direction is found to be

$$\vec{F}_a - \vec{F}_{fr} = ma_x = m\frac{d^2x}{dt^2},$$

where  $a_x$  is the acceleration in the X direction,  $a_x = \frac{d^2x}{dt^2}$ , and the

velocity in the X direction is  $v = \frac{dx}{dt}$ .

Assuming that the *Coulomb* and static friction can be neglected, the friction force, as a function of the viscous friction coefficient  $B_v$  and

velocity 
$$v = \frac{dx}{dt}$$
, is given by  $F_{fr} = B_v \frac{dx}{dt}$ 

Hence, one obtains the second-order nonlinear differential equation to map the body dynamics in the x direction

$$\frac{d^2x}{dt^2} = \frac{1}{m} \overleftarrow{\mathbf{e}} F_a - B_v \frac{dx \ddot{\mathbf{o}}}{dt \dot{\mathbf{o}}},$$

A set of two first-order linear differential equations results, and

$$\frac{dx}{dt} = v,$$
$$\frac{dv}{dt} = \frac{1}{m} (F_a - B_v v).$$

The application of Newton's law leads to the partial differential equations. To illustrate this, we consider two examples.

## Example 2.3.5.

The elastic membrane is illustrated in Figure 2.3.2. Derive the mathematical model to model the rectangular membrane vibration. That is, the goal is to study the time varying membrane deflection d(t,x,y) in the *xy* plane. The mass of the undeflected membrane per unit area  $\mathbf{r}$  is constant (homogeneous membrane).



Figure 2.3.2. Vibrating rectangular membrane

### Solution.

Assume that the membrane is perfectly flexible. For small deflections, the tension T (the force per unit length) is the same at all points in all directions, and suppose that T is constant during the motion. It should be emphasized that because the deflection of the membrane is small compared with the membrane size ab, the inclination angles are small.

Taking note of these assumptions, the forces acting on the sides are approximated as  $F_x = T\mathbf{D}x$  and  $F_y = T\mathbf{D}y$ . The membrane is assumed to be perfectly flexible, therefore, forces  $F_x$  and  $F_y$  are tangential to the membrane.

The horizontal components of the forces are found as the cosine functions of the inclination angles. The horizontal components at the opposite sides (right and left) are equal because angles  $\boldsymbol{a}$  and  $\boldsymbol{b}$  are small. Thus, the membrane motion in the horizontal direction can be neglected.

The vertical components of the forces are  $TDy \sin b$  and  $-TDy \sin a$ .

Using Newton's second law of motion, the net force must be found. We have the following expression

$$\overset{\circ}{\mathbf{a}} F = T \mathsf{D} y \Big( d_x (x + \mathsf{D} x, y_1) - d_x (x, y_2) \Big) + T \mathsf{D} x \Big( d_y (x_1, y + \mathsf{D} y) - d_y (x_2, y) \Big)$$
Thus, two dimensional partial (news) differential equation is

Thus, two-dimensional partial (wave) differential equation is

$$\frac{\P^2 d(t,x,y)}{\P t^2} = \frac{T}{r} \underbrace{\overset{\overset{\overset{\overset{}}}{\mathsf{g}}}{\mathsf{g}}}_{\P x^2} + \frac{\P^2 d(t,x,y)}{\P y^2} \underbrace{\overset{\overset{\overset{}}{\mathsf{g}}}{\overset{\overset{}}{\mathsf{g}}}}_{\overset{\overset{}}{\mathsf{g}}} = \frac{T}{r} \tilde{\mathsf{N}}^2 d(t,x,y).$$

Using initial and boundary conditions, the solution can be found.

Let the initial conditions are  $d(t_0, x, y) = d_0(x, y)$  and  $\frac{\P d(t_0, x, y)}{\P t} = d_1(x, y)$ . Thus, the initial displacement  $d_0(x, y)$  and initial

velocity  $d_1(x, y)$  are given.

Assume that the boundary conditions are

$$d(t, x_0, y_0) = 0$$
 and  $d(t, x_f, y_f) = 0$ .

Then, the solution is found to be

$$d(t, x, y) = \overset{*}{\overset{*}{a}} \overset{*}{\overset{*}{a}} d_{ij}(t, x, y)$$
$$= \overset{*}{\overset{*}{a}} \overset{*}{\overset{*}{a}} (A_{ij} \cos I_{ij}t + B_{ij} \sin I_{ij}t) \sin \frac{ipx}{a} \sin \frac{jpx}{b},$$

where the eigenvalues (characteristic values) are found as

$$\boldsymbol{l}_{ij} = \sqrt{\frac{T}{r}} \boldsymbol{p} \sqrt{\frac{i^2}{a^2} + \frac{j^2}{b^2}} \,.$$

Using initial conditions, the Fourier coefficients are obtained in the form of the double Fourier series. In particular, we have

$$A_{ij} = \frac{4}{ab} \bigotimes_{0}^{b} {a}_{0} (x, y) \sin \frac{i\mathbf{p}x}{a} \sin \frac{j\mathbf{p}y}{b} dx dy,$$
  
and 
$$B_{ij} = \frac{4}{ab\mathbf{l}_{ij}} \bigotimes_{0}^{b} {a}_{0} (x, y) \sin \frac{i\mathbf{p}x}{a} \sin \frac{j\mathbf{p}y}{b} dx dy.$$

## Example 2.3.6.

Derive the mathematical model of the infinitely long beam on the elastic foundation as shown in Figure 2.3.3. The load force is the square function. The modulus (the spring stiffness per unit length) of the elastic foundation is  $k_s$ .



Figure 2.3.3. Beam on elastic foundation under the load force f(x)

#### Solution.

Using the Euler beam theory, the deflection y(x) due to the net load force F(x) is modeled by the fourth-order differential equation

$$k_r \frac{d^4 y}{dt^4} = F(x) \,,$$

where  $k_r$  is the flexural rigidity constant.

Therefore, we have the following differential equation to model the infinite beam under the consideration

$$k_r \frac{d^4 y}{dt^4} + k_s y = f(x) \,.$$

The general homogeneous solution is given by

$$y(x) = e^{\frac{1}{2}\sqrt[4]{k_r}xx} \left[ k_1 \sin\left(\frac{1}{2}\sqrt[4]{k_r}x\right) + k_2 \sin\left(\frac{1}{2}\sqrt[4]{k_r}x\right) \right]$$
$$+ e^{-\frac{1}{2}\sqrt[4]{k_r}x} \left[ k_3 \sin\left(\frac{1}{2}\sqrt[4]{k_r}x\right) + k_4 \sin\left(\frac{1}{2}\sqrt[4]{k_r}x\right) \right],$$

where the unknown coefficients  $k_I$  can be determined using the initial and boundary conditions. The boundary-value problem can be relaxed, and the solution can be found in the series form.

The load force is the periodic function, and using the Fourier series we have

$$f(x) = \frac{f_0}{2} + \frac{2f_0}{p} \overset{\texttt{x}}{\underset{i=1}{\overset{\texttt{x}}{a}}} \frac{\sin\left(\frac{1}{2}ip\right)}{i} \cos\frac{ipx}{2a}$$

The solution of the differential equation  $k_r \frac{d^4 y}{dt^4} + k_s y = f(x)$  can be

found in the following form

$$y(x) = a_0 + \mathop{\mathbf{a}}_{i=1}^{\underbrace{*}} a_i \cos \frac{i \mathbf{p} x}{2a}.$$

Differentiating this equation four times gives

$$k_{s}a_{0} = \frac{f_{0}}{2}$$
  
and  $\overset{\text{e}}{\mathbf{g}}k_{r} \frac{i^{4}\mathbf{p}^{4}}{16a^{4}} + k_{s} \frac{\ddot{\mathbf{o}}}{\dot{\mathbf{g}}}a_{i} = \frac{2f_{0}}{\mathbf{p}} \frac{\sin(\frac{1}{2}i\mathbf{p})}{i}$ 

Thus, the Fourier series coefficients are found as

$$a_0 = \frac{f_0}{2k_s} \text{ and } a_i = \frac{2f_0}{\mathbf{p}} \frac{\sin(\frac{1}{2}i\mathbf{p})}{\stackrel{\acute{e}}{i \partial k_r} \stackrel{\acute{e}}{c} \frac{a_i \mathbf{p}}{2a} \stackrel{\acute{o}}{\varphi}^4 + k_s \stackrel{\acute{u}}{\acute{u}}}_{\acute{\mathbf{q}}}^{i} 1.$$

Therefore, the solution is given by

$$y(x) = \frac{f_0}{2k_s} + \frac{32f_0a^4}{p} \overset{\texttt{x}}{\overset{\texttt{a}}{=}} \frac{\sin(\frac{1}{2}ip)}{i(k_ri^4p^4 + 16a^4k_s)} \cos\frac{ipx}{2a}$$

The first-order approximation is

$$y(x) \gg \frac{f_0}{2k} + \frac{32f_0a^4}{p(k_rp^4 + 16a^4k_s)}\cos\frac{px}{2a}.$$

Friction Models in Electromechanical Systems

A thorough consideration of friction is essential for understanding the operation of electromechanical systems. Friction is a very complex nonlinear phenomenon that is difficult to model. The classical *Coulomb* friction is a retarding frictional force (for translational motion) or torque (for rotational motion) that changes its sign with the reversal of the direction of motion, and the amplitude of the frictional force or torque are constant. For translational and rotational motions, the *Coulomb* friction force and torque are

$$F_{Coulomb} = k_{Fc} \operatorname{sgn}(v) = k_{Fc} \operatorname{sgn} \overset{\widetilde{\mathbf{e}}dx}{\underbrace{\mathbf{o}}}_{dt} \overset{\widetilde{\mathbf{o}}}{,}$$
$$T_{Coulomb} = k_{Tc} \operatorname{sgn}(\mathbf{w}) = k_{Tc} \operatorname{sgn} \overset{\widetilde{\mathbf{e}}dx}{\underbrace{\mathbf{o}}}_{dt} \overset{\widetilde{\mathbf{o}}}{,}$$

where  $k_{Fc}$  and  $k_{Tc}$  are the Coulomb friction coefficients.

Figure 2.3.4.a illustrates the *Coulomb* friction.



Figure 2.3.4. Functional representations of: a) *Coulomb* friction; b) viscous friction; c) static friction

Viscous friction is a retarding force or torque that is a linear function of linear or angular velocity. The viscous friction force and torque versus linear and angular velocities are shown in Figure 2.3.4.b. The following expressions are commonly used to model the viscous friction

$$F_{viscous} = B_v v = B_v \frac{dx}{dt}$$
 for translational motion,  
 $d\mathbf{a}$ 

and  $T_{viscous} = B_m \mathbf{w} = B_m \frac{d\mathbf{q}}{dt}$  for rotational motion,

where  $B_{v}$  and  $B_{m}$  are the viscous friction coefficients.

The static friction exists only when the body is stationary, and vanishes as motion begins. The static friction is a force  $F_{static}$  or torque  $T_{static}$ , and we have the following expressions

$$F_{static} = \pm F_{st} \Big|_{v = \frac{dx}{dt} = 0},$$

and  $T_{static} = \pm T_{st} \Big|_{\mathbf{w} = \frac{d\mathbf{q}}{dt} = 0}$ .

One concludes that the static friction is a retarding force or torque that tends to prevent the initial translational or rotational motion at the beginning (see Figure 2.3.4.c).

In general, the friction force and torque are nonlinear functions that must be modeled using frictional memory, presliding conditions, etc. The empirical formulas, commonly used to express  $F_{static}$  and  $T_{static}$ , are

$$F_{fr} = \left(k_{fr1} - k_{fr2}e^{-k|v|} + k_{fr3}|v|\right)\operatorname{sgn}(v_t) = \operatorname{c}_{k}^{\mathfrak{S}} k_{fr1} - k_{fr2}e^{-k\left|\frac{dx}{dt}\right|} + k_{fr3}\left|\frac{dx}{dt}\right|_{\dot{\mathfrak{S}}}^{\ddot{\mathsf{O}}} \operatorname{sgn}_{\mathfrak{S}}^{\mathfrak{S}} dx \overset{\ddot{\mathsf{O}}}{\mathfrak{S}} dx \dot{\tilde{\mathsf{O}}} dx \dot{\tilde{\mathsf{O}$$

and

$$T_{fr} = \left(k_{fr1} - k_{fr2}e^{-k|\mathbf{w}|} + k_{fr3}|\mathbf{w}|\right)\operatorname{sgn}(\mathbf{w}) = \overset{\mathfrak{W}}{\underset{\mathbf{g}}{\operatorname{ch}}} k_{fr2}e^{-k\left|\frac{d\mathbf{q}}{dt}\right|} + k_{fr3}\left|\frac{d\mathbf{q}}{dt}\right|_{\dot{\underline{v}}}^{\ddot{\mathrm{o}}}\operatorname{sgn}_{\mathbf{g}}^{\mathfrak{W}}\frac{d\mathbf{q}}{dt}_{\dot{\underline{v}}}^{\ddot{\mathrm{o}}}$$

These  $F_{static}$  and  $T_{static}$  are shown in Figure 2.3.5.



Figure 2.3.5. Friction force and torque are functions of linear and angular velocities

# Example 2.3.7. Transducer model

Figure 2.3.6 shows a simple electromechanical device (actuator) with a stationary member and movable plunger. Using Newton's second law, find the differential equations.



Figure 2.3.6. Schematic of a transducer

### Solution.

Let us apply Newton's second law of motion to find the equations of motion and study the dynamics. Newton's law states that the acceleration of an object is proportional to the net force. The vector sum of all forces acting on the object can be found by using a free-body diagram. In particular, for the studied translational mechanical system, one obtains

$$F(t) = m\frac{d^2x}{dt^2} + B_v \frac{dx}{dt} + (k_{s1}x + k_{s2}x^2) + F_e(t) ,$$

where x denotes the displacement of a plunger; m is the mass of a movable member;  $B_v$  is the viscous friction coefficient;  $k_{s1}$  and  $k_{s2}$  are the spring constants;  $F_e(t)$  is the magnetic force,

$$F_e(i,x) = \frac{\P W_c(i,x)}{\P x}.$$

It should be emphasized that Hooke's law is valid only for sufficiently small displacements. The stretch and restoring forces are not directly proportional to the displacement, and these forces are different on either side of the equilibrium position. The restoring/stretching force exerted by the spring is expressed by  $(k_{s1}x + k_{s2}x^2)$ .

Assuming that the magnetic system is linear, the coenergy is expressed as

$$W_c(i,x) = \frac{1}{2}L(x)i^2,$$

then  $F_e(i,x) = \frac{1}{2}i^2 \frac{dL(x)}{dx}$ .

The inductance is found by using the following formula

$$L(x) = \frac{N^2}{\hat{A}_f + \hat{A}_g} = \frac{N^2 m_f m_0 A_f A_g}{A_g l_f + 2A_f m_f (x + 2d)},$$

where  $\hat{A}_f$  and  $\hat{A}_g$  are the reluctances of the ferromagnetic material and air gap;  $A_f$  and  $A_g$  are the associated cross section areas;  $l_f$  and (x + 2d) are the lengths of the magnetic material and the air gap.

Hence, 
$$\frac{dL}{dx} = -\frac{2N^2 \mathbf{m}_f^2 \mathbf{m}_0 A_f^2 A_g}{[A_g l_f + 2A_f \mathbf{m}_f (x + 2d)]^2}$$
.

Using Kirchhoff's law, the voltage equation for the electric circuit is given as

$$u_a = ri + \frac{d\mathbf{y}}{dt},$$

where the flux linkage  $\mathbf{y}$  is expressed as  $\mathbf{y} = L(x)i$ .

One obtains

$$u_a = ri + L(x)\frac{di}{dt} + i\frac{dL(x)}{dx}\frac{dx}{dt},$$

and thus

$$\frac{di}{dt} = -\frac{r}{L(x)}i + \frac{2N^2\mathbf{m}_f^2\mathbf{m}_bA_f^2A_g}{L(x)[A_gl_f + 2A_f\mathbf{m}_f(x+2d)]^2}iv + \frac{1}{L(x)}u_a.$$

Augmenting this equation with differential equation for the mechanical systems

$$F(t) = m \frac{d^2 x}{dt^2} + B_v \frac{dx}{dt} + (k_{s1}x + k_{s2}x^2) + F_e(t) ,$$

three nonlinear differential equations for the considered transducer are found as

$$\begin{aligned} \frac{di}{dt} &= -\frac{r[A_g l_f + 2A_f \mathbf{m}_f (x+2d)]}{N^2 \mathbf{m}_f \mathbf{m}_0 A_f A_g} i + \frac{2\mathbf{m}_f A_f}{A_g l_f + 2A_f \mathbf{m}_f (x+2d)} iv + \frac{A_g l_f + 2A_f \mathbf{m}_f (x+2d)}{N^2 \mathbf{m}_f \mathbf{m}_0 A_f A_g} u_a, \\ \frac{dx}{dt} &= v, \\ \frac{dv}{dt} &= -\frac{N^2 \mathbf{m}_f^2 \mathbf{m}_0 A_f^2 A_g}{m[A_g l_f + 2A_f \mathbf{m}_f (x+2d)]} i^2 - \frac{1}{m} (k_{s1}x + k_{s2}x^2) - \frac{B_v}{m} v. \end{aligned}$$

Newtonian Mechanics: Rotational Motion

For one-dimensional rotational systems, Newton's second law of motion is expressed as

 $M = J\mathbf{a}$ , (2.3.2) where *M* is the sum of all moments about the center of mass of a body, (N-m); *J* is the moment of inertia about its center of mass, (kg-m<sup>2</sup>); **a** is the angular acceleration of the body, (rad/sec<sup>2</sup>).

### *Example 2.3.8.*

Given a point mass m suspended by a massless, unstretchable string of length l, (see Figure 2.3.7). Derive the equations of motion for a simple pendulum with negligible friction.



Figure 2.3.7. A simple pendulum

#### Solution.

The restoring force, which is proportional to  $\sin q$  and given by -  $mg\sin q$ , is the tangential component of the net force. Therefore, the sum of the moments about the pivot point O is found as

$$\mathbf{\mathring{a}} M = - mgl\sin q + T_a$$

where  $T_a$  is the applied torque; l is the length of the pendulum measured from the point of rotation.

Using (2.3.2), one obtains the equation of motion

$$J\boldsymbol{a} = J\frac{d^2\boldsymbol{q}}{dt^2} = -mgl\sin\boldsymbol{q} + T_a,$$

where J is the moment of inertial of the mass about the point O.

Hence, the second-order differential equation is found to be

$$\frac{d^2 \boldsymbol{q}}{dt^2} = \frac{1}{J} \left( - mgl\sin \boldsymbol{q} + T_a \right).$$

Using the following differential equation for the angular displacement

$$\frac{d\boldsymbol{q}}{dt} = \boldsymbol{w} \,,$$

one obtains the following set of two first-order differential equations

$$\frac{d\boldsymbol{w}}{dt} = \frac{1}{J} \left( - mgl\sin\boldsymbol{q} + T_a \right),$$
$$\frac{d\boldsymbol{q}}{dt} = \boldsymbol{w}.$$

The moment of inertia is expressed by  $J = ml^2$ . Hence, we have the following differential equations to be used in modeling of a simple pendulum

$$\frac{d\boldsymbol{w}}{dt} = -\frac{g}{l}\sin\boldsymbol{q} + \frac{1}{ml^2}T_a,$$
$$\frac{d\boldsymbol{q}}{dt} = \boldsymbol{w}.$$

### 2.3.2. Lagrange Equations of Motion

Electromechanical systems augment mechanical and electronic components. Therefore, one studies mechanical, electromagnetic, and circuitry transients. It was illustrated that the designer can integrate the *torsional-mechanical* dynamics and circuitry equations of motion. However, there exist general concepts to model systems. The Lagrange and Hamilton concepts are based on the energy analysis. Using the system variables, one finds the total kinetic, dissipation, and potential energies (which are denoted as G,

*D* and **P**). Taking note of the total kinetic 
$$\overrightarrow{\operatorname{Qet}}_{e}^{e}, q_1, \dots, q_n, \frac{dq_1}{dt}, \dots, \frac{dq_n}{dt} \overset{\circ}{\varphi}$$

dissipation  $D_{\mathbf{c}t}^{\mathbf{a}}, q_1, ..., q_n, \frac{dq_1}{dt}, ..., \frac{dq_n}{dt} \stackrel{\mathbf{o}}{\div}, \text{ and potential } \mathsf{P}(t, q_1, ..., q_n)$ 

energies, the Lagrange equations of motion are

$$\frac{d}{dt} \bigotimes_{\mathbf{C}} \frac{\mathfrak{g}}{\mathbf{Q}_{i}} \bigotimes_{\mathbf{C}} \frac{\mathfrak{g}}{\mathbf{Q}_{i}} + \frac{\mathfrak{g}}{\mathfrak{g}_{i}} + \frac{\mathfrak{g}}{\mathfrak{g}_{i}} + \frac{\mathfrak{g}}{\mathfrak{g}_{i}} = Q_{i}.$$
(2.3.3)

Here,  $q_i$  and  $Q_i$  are the generalized coordinates and the generalized forces (applied forces and disturbances). The generalized coordinates  $q_i$  are used to derive expressions for energies  $\mathbf{G}_{e}^{\mathbf{e}t}, q_1, \dots, q_n, \frac{dq_1}{dt}, \dots, \frac{dq_n}{dt} \overset{\mathbf{o}}{\mathbf{\varphi}}, D_{\mathbf{e}t}^{\mathbf{e}t}, q_1, \dots, q_n, \frac{dq_1}{dt}, \dots, \frac{dq_n}{dt} \overset{\mathbf{o}}{\mathbf{\varphi}}, \mathbf{Q}_i, \dots, \mathbf{Q}_n, \mathbf{$ 

Taking into account that for conservative (losseless) systems D = 0, we have the following Lagrange's equations of motion

$$\frac{d}{dt} \underbrace{\overset{\mathfrak{gm}}{\mathsf{G}} \overset{\mathfrak{g}}{\mathsf{G}}}_{\mathsf{G}} \overset{\mathfrak{g}}{\div} - \frac{\mathfrak{g}}{\mathfrak{g}}_{i} + \frac{\mathfrak{g}}{\mathfrak{g}}_{i} = Q_{i}.$$

Example 2.3.9. Mathematical model of a simple pendulum

Derive the mathematical model for a simple pendulum using the Lagrange equations of motion.

Solution.

Derivation of the mathematical model for the simple pendulum, shown in Figure 2.3.7, was performed in Example 2.3.8 using the Newtonian mechanics. For the studied conservative (losseless) system we have D = 0. Thus, the Lagrange equations of motion are

$$\frac{d}{dt} \bigotimes_{\mathbf{C}} \frac{\mathfrak{M}\mathbf{G}\ddot{\mathbf{O}}}{\mathfrak{I}\dot{q}_i \, \mathbf{\emptyset}} \stackrel{\cdot}{\to} - \frac{\mathfrak{M}\mathbf{G}}{\mathfrak{M}q_i} + \frac{\mathfrak{M}\mathbf{P}}{\mathfrak{M}q_i} = Q_i$$

The kinetic energy of the pendulum bob is  $\mathbf{G} = \frac{1}{2} m \left( l \dot{\boldsymbol{q}} \right)^2$ .

The potential energy is found as  $P = mgl(1 - \cos q)$ .

As the generalized coordinate, the angular displacement is used,  $q_i = q$ .

The generalized force is the torque applied,  $Q_i = T_a$ . One obtains

$$\frac{\P \mathbf{G}}{\P \dot{q}_i} = \frac{\P \mathbf{G}}{\P \dot{q}} = m l^2 \dot{q} , \quad \frac{\P \mathbf{G}}{\P q_i} = \frac{\P \mathbf{G}}{\P q} = 0 , \quad \frac{\P \mathbf{P}}{\P q_i} = \frac{\P \mathbf{P}}{\P q} = mg l \sin q .$$

Thus, the first term of the Lagrange equation is found to be

$$\frac{d}{dt} \underbrace{\mathfrak{E}}_{\mathbf{q},\mathbf{q},\mathbf{\phi}}^{\mathbf{g},\mathbf{G},\mathbf{\phi}} = ml^2 \frac{d^2 \mathbf{q}}{dt^2} + 2ml \frac{dl}{dt} \frac{d\mathbf{q}}{dt}.$$

Assuming that the string is unstretchable, we have  $\frac{dl}{dt} = 0$ .

Hence,

$$ml^2 \frac{d^2 \boldsymbol{q}}{dt^2} + mgl\sin \boldsymbol{q} = T_a \,.$$

Thus, one obtains

$$\frac{d^2 \boldsymbol{q}}{dt^2} = \frac{1}{ml^2} (-mgl\sin \boldsymbol{q} + T_a).$$

Recall that the equation of motion, derived by using Newtonian mechanics, is

$$\frac{d^2 \boldsymbol{q}}{dt^2} = \frac{1}{J} \left( - mgl \sin \boldsymbol{q} + T_a \right), \text{ where } \boldsymbol{J} = ml^2.$$

One concludes that the results are the same, and the equations are

$$\frac{d\mathbf{w}}{dt} = -\frac{g}{l}\sin\mathbf{q} + \frac{1}{ml^2}T_a,$$
$$\frac{d\mathbf{q}}{dt} = \mathbf{w}.$$

## Example 2.3.10. Mathematical Model of a Pendulum

Consider a double pendulum of two degrees of freedom with no external forces applied to the system (see Figure 2.3.8). Using the Lagrange equations of motion, derive the differential equations.



Figure 2.3.8. Double pendulum

#### Solution.

The angular displacement  $q_1$  and  $q_2$  are chosen as the independent generalized coordinates. In the XY plane studied, let  $(x_1, y_1)$  and  $(x_2, y_2)$ be the rectangular coordinates of  $m_1$  and  $m_2$ . Then, we obtain

$$x_{1} = l_{1} \cos \boldsymbol{q}_{1}, \ x_{2} = l_{1} \cos \boldsymbol{q}_{1} + l_{2} \cos \boldsymbol{q}_{2},$$
  

$$y_{1} = l_{1} \sin \boldsymbol{q}_{1}, \ y_{2} = l_{1} \sin \boldsymbol{q}_{1} + l_{2} \sin \boldsymbol{q}_{2}.$$
  
The total kinetic energy **G** is found to be  

$$\mathbf{G} = \frac{1}{2}m_{1}(\dot{x}_{1}^{2} + \dot{y}_{1}^{2}) + \frac{1}{2}m_{2}(\dot{x}_{2}^{2} + \dot{y}_{2}^{2})$$
  

$$= \frac{1}{2}(m_{1} + m_{2})l_{1}^{2}\dot{\boldsymbol{q}}_{1}^{2} + m_{2}l_{1}l_{2}\dot{\boldsymbol{q}}_{1}\dot{\boldsymbol{q}}_{2} \cos(\boldsymbol{q}_{2} - \boldsymbol{q}_{1}) + \frac{1}{2}m_{2}l_{2}^{2}\dot{\boldsymbol{q}}_{2}^{2}.$$
  
Then one obtains

Then, one obtains

$$\frac{\#G}{\#q_{1}} = m_{2}l_{1}l_{2}\sin(q_{2} - q_{1})\dot{q}_{1}\dot{q}_{2},$$

$$\frac{\#G}{\#q_{1}} = (m_{1} + m_{2})l_{1}^{2}\dot{q}_{1} + m_{2}l_{1}l_{2}\cos(q_{2} - q_{1})\dot{q}_{2},$$

$$\frac{\#G}{\#q_{2}} = -m_{2}l_{1}l_{2}\sin(q_{1} - q_{2})\dot{q}_{1}\dot{q}_{2},$$

$$\frac{\#G}{\#q_{2}} = m_{2}l_{1}l_{2}\cos(q_{2} - q_{1})\dot{q}_{1} + m_{2}l_{1}^{2}\dot{q}_{2}.$$
The total potential energy is given by
$$P = m_{1}gy_{1} + m_{2}gy_{2} = -(m_{1} + m_{2})gl_{1}\cos q_{1} - m_{2}gl_{2}\cos q_{2}.$$
Hence, 
$$\frac{\#P}{\#q_{1}} = (m_{1} + m_{2})gl_{1}\sin q_{1} \text{ and } \frac{\#P}{\#q_{2}} = m_{2}gl_{2}\sin q_{2}.$$
The Lagrange equations of motion are
$$\frac{d}{dt}\frac{\#GGGG}{\#q_{1}}\dot{g}_{2} = \frac{\#G}{\#q_{2}} + \frac{\#P}{\#q_{2}} = 0.$$
Hence, the dynamic equations of the system are
$$(m_{1} + m_{2})l_{1}\ddot{q}_{1} + m_{2}l_{2}\cos(q_{2} - q_{1})\ddot{q}_{2} - m_{2}l_{2}\sin(q_{2} - q_{1})\dot{q}_{2}^{2} + (m_{1} + m_{2})g\sin q_{1} = 0,$$

$$l_{2}\ddot{q}_{2} + l_{1}}\cos(q_{2} - q_{1})\ddot{q}_{1} + l_{1}\sin(q_{2} - q_{1})\dot{q}_{1}^{2} + g\sin q_{2} = 0.$$

It should be emphasized that if the torques  $T_1$  and  $T_2$  are applied to the first and second joints, the following equations of motions results

$$(m_1 + m_2)l_1\ddot{q}_1 + m_2l_2\cos(q_2 - q_1)\ddot{q}_2 - m_2l_2\sin(q_2 - q_1)\dot{q}_2^2 + (m_1 + m_2)g\sin q_1 = T_1,$$
  

$$l_2\ddot{q}_2 + l_1\cos(q_2 - q_1)\ddot{q}_1 + l_1\sin(q_2 - q_1)\dot{q}_1^2 + g\sin q_2 = T_2.$$

Example 2.3.11. Mathematical Model of a Circuit Network

Consider a two-mesh electric circuit, as shown in Figure 2.3.9. Find the circuitry dynamics.



Figure 2.3.9. Two-mesh circuit network

## Solution.

We use  $q_1$  and  $q_2$  as the independent generalized coordinates, where  $q_1$  is the electric charge in the first loop,  $q_2$  represents the electric charge in the second loop. The generalized force, which is applied to the system, is denoted as  $Q_1$ . These generalized coordinates are related to the circuitry variables. In particular, the currents  $i_1$  and  $i_2$  are found in terms of charges,

 $i_1 = \dot{q}_1$  and  $i_2 = \dot{q}_2$ . That is,  $q_1 = \frac{\dot{i}_1}{s}$  and  $q_2 = \frac{\dot{i}_2}{s}$ . The generalized force is the applied voltage,  $u_1(t) = Q$ .

the applied voltage,  $u_a(t) = Q_1$ .

The total magnetic energy (kinetic energy) is expressed by

$$\mathsf{G} = \frac{1}{2} L_1 \dot{q}_1^2 + \frac{1}{2} L_{12} (\dot{q}_1 - \dot{q}_2)^2 + \frac{1}{2} L_2 \dot{q}_2^2.$$

By using this equation for G, we have

$$\frac{\P G}{\P q_1} = 0, \quad \frac{\P G}{\P \dot{q}_1} = (L_1 + L_{12}) \dot{q}_1 - L_{12} \dot{q}_2,$$
$$\frac{\P G}{\P q_2} = 0, \quad \frac{\P G}{\P \dot{q}_2} = -L_{12} \dot{q}_1 + (L_2 + L_{12}) \dot{q}_2.$$

Using the equation for the total electric energy (potential energy)

$$\mathsf{P} = \frac{1}{2} \frac{q_1^2}{C_1} + \frac{1}{2} \frac{q_2^2}{C_2},$$

one finds

$$\frac{\P P}{\P q_1} = \frac{q_1}{C_1}$$
 and  $\frac{\P P}{\P q_2} = \frac{q_2}{C_2}$ .

The total heat energy dissipated is

$$D = \frac{1}{2} R_1 \dot{q}_1^2 + \frac{1}{2} R_2 \dot{q}_2^2.$$
  
Hence,  
$$\frac{\P D}{\P \dot{q}_1} = R_1 \dot{q}_1 \text{ and } \frac{\P D}{\P \dot{q}_2} = R_2 \dot{q}_2$$

The Lagrange equations of motion are expressed using the independent coordinates used. We obtain

$$\frac{d}{dt} \underbrace{\overset{\mathfrak{S}}{\mathbf{c}} \overset{\mathfrak{I}}{\mathbf{G}} \overset{\mathfrak{O}}{\mathbf{o}}}_{\mathbf{d}_{1}} \cdot \frac{\boldsymbol{\P} \mathbf{G}}{\boldsymbol{\P}_{1}} + \frac{\boldsymbol{\P} \mathbf{D}}{\boldsymbol{\P}_{1}} + \frac{\boldsymbol{\P} \mathbf{P}}{\boldsymbol{\P}_{1}} = Q_{1} ,$$
  
$$\frac{d}{dt} \underbrace{\overset{\mathfrak{S}}{\mathbf{c}} \overset{\mathfrak{I}}{\mathbf{\eta}_{2}} \overset{\mathfrak{O}}{\mathbf{o}}}_{\mathbf{d}_{2}} \cdot \frac{\boldsymbol{\P} \mathbf{G}}{\boldsymbol{\P}_{2}} + \frac{\boldsymbol{\P} \mathbf{D}}{\boldsymbol{\P}_{2}} + \frac{\boldsymbol{\P} \mathbf{P}}{\boldsymbol{\P}_{2}} = 0 .$$

Hence, the differential equations for the circuit studied are found to be

$$(L_1 + L_{12})\ddot{q}_1 - L_{12}\ddot{q}_2 + R_1\dot{q}_1 + \frac{q_1}{C_1} = u_a ,$$
  
-  $L_{12}\ddot{q}_1 + (L_2 + L_{12})\ddot{q}_2 + R_2\dot{q}_2 + \frac{q_2}{C_2} = 0 .$ 

The SIMULINK model can be built using these derived nonlinear differential equations. In particular, we have

$$\ddot{q}_{1} = \frac{1}{\left(L_{1} + L_{12}\right)} \overset{\mathfrak{g}}{\overset{\bullet}{\mathbf{e}}} \cdot \frac{q_{1}}{C_{1}} - R_{1}\dot{q}_{1} + L_{12}\ddot{q}_{2} + u_{a} \overset{\mathbf{\ddot{o}}}{\div}$$
  
and  $\ddot{q}_{2} = \frac{1}{\left(L_{2} + L_{12}\right)} \overset{\mathfrak{g}}{\overset{\bullet}{\mathbf{e}}} L_{12}\ddot{q}_{1} - \frac{q_{2}}{C_{2}} - R_{2}\dot{q}_{2} \overset{\mathbf{\ddot{o}}}{\overset{\bullet}{\Rightarrow}}.$ 

.

The corresponding SIMULINK diagram is shown in Figure 2.3.10.

It should be emphasized that the currents  $i_1$  and  $i_2$  are expressed in terms of charges as

$$i_1 = \dot{q}_1$$
 and  $i_2 = \dot{q}_2$ .  
That is, we have

$$q_1 = \frac{i_1}{s}$$
 and  $q_2 = \frac{i_2}{s}$ 



Figure 2.3.10. SIMULINK diagram

To perform simulations (numerical analysis), one must use the parameter values. The circuitry parameters are assigned to be:  $L_1 = 0.01$  H,  $L_2 = 0.005$  H,  $L_{12} = 0.0025$  H,  $C_1 = 0.02$  F,  $C_2 = 0.1$  F,  $R_1 = 10$  ohm,  $R_2 = 5$  ohm and  $u_a = 100 \sin(200t)$  V.

Simulation results, which give the time history of  $q_1(t)$ ,  $q_2(t)$ ,  $i_1(t)$  and  $i_2(t)$ , are documented in Figure 2.3.11.



Figure 2.3.11. Circuit dynamics: evolution of the generalized coordinates and currents

# Example 2.3.12. Mathematical Model of an Electric Circuit

Using the Lagrange equations of motion, develop the mathematical models for the circuit shown in Figure 2.3.12. Prove that the model derived using the Lagrange equations of motion are equivalent to the model developed using Kirchhoff's law.



Figure 2.3.12. Electric circuit

Solution.

Using  $q_1$  and  $q_2$  as the independent generalized coordinates, the Lagrange equations of motion can be found. Here,  $q_1$  is the electric charge in the first loop and  $i_a = \dot{q}_1$ , and  $q_2$  is the electric charge in the second loop,  $i_L = \dot{q}_2$ . The generalized force, applied to the system, is denoted as  $Q_1$ , and  $u_a(t) = Q_1$ .

The total kinetic energy is  $G = \frac{1}{2}L\dot{q}_2^2$ .

Therefore, we have,

$$\frac{\P \mathbf{G}}{\P q_1} = 0, \quad \frac{\P \mathbf{G}}{\P \dot{q}_1} = 0, \text{ and } \quad \frac{d}{dt} \underbrace{\mathfrak{S}}_{\mathbf{G}} \overset{\mathfrak{G}}{\P \dot{q}_1} \overset{\mathfrak{G}}{=} 0, \\ \frac{\P \mathbf{G}}{\P q_2} = 0, \quad \frac{\P \mathbf{G}}{\P \dot{q}_2} = L \dot{q}_2, \text{ and } \quad \frac{d}{dt} \underbrace{\mathfrak{S}}_{\mathbf{G}} \overset{\mathfrak{G}}{\P \dot{q}_2} \overset{\mathfrak{G}}{=} L \ddot{q}_2$$

The total potential energy is expressed as

$$\mathsf{P} = \frac{1}{2} \frac{(q_1 - q_2)^2}{C}.$$

Hence

$$\frac{\P \mathbf{P}}{\P q_1} = \frac{q_1 \cdot q_2}{C} \text{ and } \frac{\P \mathbf{P}}{\P q_2} = \frac{-q_1 + q_2}{C}$$

The total dissipated energy is

$$D = \frac{1}{2} R \dot{q}_1^2 + \frac{1}{2} R_L \dot{q}_2^2.$$

Therefore

$$\frac{\P D}{\P \dot{q}_1} = R \dot{q}_1 \text{ and } \frac{\P D}{\P \dot{q}_2} = R_L \dot{q}_2.$$
  
The Lagrange equations of motion
$$\frac{d}{dt} \bigotimes_{\P \eta \dot{q}_1}^{\otimes \P \mathbb{G}} \bigotimes_{\P \eta \dot{q}_1}^{\otimes \P \mathbb{G}} - \frac{\P \mathbb{G}}{\P q_1} + \frac{\P D}{\P \dot{q}_1} + \frac{\P P}{\P q_1} = Q_1,$$
$$\frac{d}{dt} \bigotimes_{\P \eta \dot{q}_2}^{\otimes \P \mathbb{G}} \bigotimes_{\P \eta \dot{q}_2}^{\otimes \Theta} - \frac{\P \mathbb{G}}{\P q_2} + \frac{\P D}{\P \dot{q}_2} + \frac{\P P}{\P q_2} = 0$$

lead one to the following two differential equations

$$\begin{aligned} R\dot{q}_1 + \frac{q_1 - q_2}{C} &= u_a, \\ L\ddot{q}_2 + R_L \dot{q}_2 + \frac{-q_1 + q_2}{C} &= 0. \end{aligned}$$

Hence, we have found a set of two differential equations. In particular,

$$\dot{q}_1 = \frac{1}{R} \underbrace{\underbrace{\mathfrak{E}}_{\mathbf{c}} \quad q_1 + q_2}_{C} + u_a \overset{\mathbf{O}}{\div},$$
$$\ddot{q}_2 = \frac{1}{L} \underbrace{\underbrace{\mathfrak{E}}_{\mathbf{c}} \quad R_L \dot{q}_2}_{C} + \frac{q_1 - q_2}{C} \overset{\mathbf{O}}{\ddagger}$$

By using Kirchhoff's law, two differential equations result

$$\frac{du_C}{dt} = \frac{1}{C} \underbrace{\overset{\mathbf{e}}{\mathbf{e}}}_{R} \frac{u_C}{R} \cdot i_L + \frac{u_a(t)}{R} \underbrace{\overset{\mathbf{o}}{\mathbf{e}}}_{R},$$
$$\frac{di_L}{dt} = \frac{1}{L} (u_C \cdot R_L i_L).$$

Taking note of  $i_a = \dot{q}_1$  and  $i_L = \dot{q}_2$ , and making use  $C \frac{du_C}{dt} = i_a - i_L$ ,

we obtain

$$u_C = \frac{q_1 - q_2}{C} \, .$$

The equivalence of the differential equations derived using the Lagrange equations of motion and Kirchhoff's law is proven.

## Example 2.3.13. Mathematical model of a boost converter

A high-frequency, one-quadrant *boost* (*step-up*) dc-dc switching converter is documented in Figure 2.3.13. Find the mathematical model in the form of differential equations.



Figure 2.3.13. Boost converter

#### Solution.

To solve the model development problem, we will derive the differential equations if the duty ratio  $d_D$  is 1 and 0. Then, we will augment two mathematical models found to model the *boost* converter.

When the switch is closed, the diode *D* is reverse biased. For  $d_D = 1$  ( $t_{off} = 0$ ), one obtains the following set of linear differential equations

$$\begin{aligned} \frac{du_C}{dt} &= -\frac{1}{C}i_a, \\ \frac{di_L}{dt} &= \frac{1}{L}\left(-\left(r_L + r_s\right)i_L + V_d\right), \\ \frac{di_a}{dt} &= \frac{1}{L_a}\left(u_C - \left(r_a + r_c\right)i_a - E_a\right) \end{aligned}$$

If the switch is open  $(d_D = 0)$ , the diode *D* is forward biased because the direction of the inductor current  $i_L$  does not change instantly. Therefore, one has three linear differential equations

$$\begin{aligned} \frac{du_C}{dt} &= \frac{1}{C} (i_L - i_a), \\ \frac{di_L}{dt} &= \frac{1}{L} (-u_C - (r_L + r_c)i_L + r_c i_a + V_d), \\ \frac{di_a}{dt} &= \frac{1}{L_a} (u_C + r_c i_L - (r_a + r_c)i_a - E_a). \end{aligned}$$

Assuming the switching frequency id high, the *averaging* concept is applied, and we have

$$\begin{aligned} \frac{du_C}{dt} &= \frac{1}{C} (i_L - i_a - i_L d_D), \\ \frac{di_L}{dt} &= \frac{1}{L} (- u_C - (r_L + r_c)i_L + r_c i_a + u_C d_D + (r_c - r_s)i_L d_D - r_c i_a d_D + V_d), \\ \frac{di_a}{dt} &= \frac{1}{L_a} (u_C + r_c i_L - (r_a + r_c)i_a - r_c i_L d_D - E_a). \end{aligned}$$

Considering the duty ratio as the control input, one concludes that a set of nonlinear differential equations result. In fact, the state variables are multiplied by the control.

Let us illustrate that Lagrange's concept gives the same differential equations. We denote the electric charges in the first and the second loops as  $q_1$  and  $q_2$ , and the generalized forces are  $Q_1$  and  $Q_2$ . Then,

$$\frac{d}{dt} \bigotimes_{\mathbf{e}} \mathbb{I}[\mathbf{G}] \overset{\mathbf{o}}{\mathbf{o}} \cdot \frac{\mathbf{I}\mathbf{G}}{\mathbf{f}q_1} + \frac{\mathbf{I}\mathbf{D}}{\mathbf{f}q_1} + \frac{\mathbf{I}\mathbf{P}}{\mathbf{f}q_1} = Q_1 ,$$
  
$$\frac{d}{dt} \bigotimes_{\mathbf{e}} \mathbb{I}[\mathbf{G}] \overset{\mathbf{o}}{\mathbf{o}} \cdot \frac{\mathbf{I}\mathbf{G}}{\mathbf{f}q_2} + \frac{\mathbf{f}\mathbf{D}}{\mathbf{f}q_2} + \frac{\mathbf{f}\mathbf{P}}{\mathbf{f}q_2} = Q_2 .$$

For the closed switch, the total kinetic, potential, and dissipated energies are

$$\mathsf{G} = \frac{1}{2} \left( L \dot{q}_1^2 + L_a \dot{q}_2^2 \right), \mathsf{P} = \frac{1}{2} \frac{q_2^2}{C}, D = \frac{1}{2} \left( \left( r_L + r_s \right) \dot{q}_1^2 + \left( r_c + r_a \right) \dot{q}_2^2 \right).$$

Assuming that the resistances, inductances, and capacitance are time-invariant (constant), one obtains

$$\begin{split} \frac{\P \mathbf{G}}{\P q_1} &= 0 \;, \; \frac{\P \mathbf{G}}{\P q_2} = 0 \;, \; \frac{\P \mathbf{G}}{\P \dot{q}_1} = L \dot{q}_1 \;, \; \frac{\P \mathbf{G}}{\P \dot{q}_2} = L_a \dot{q}_2 \;, \\ \frac{d}{dt} \underbrace{\mathfrak{C}}_{\boldsymbol{q}} \underbrace{\mathfrak{R}}_{\boldsymbol{q}_1} \dot{\boldsymbol{\sigma}} \dot{\boldsymbol{\sigma}} = L \ddot{q}_1 \;, \; \frac{d}{dt} \underbrace{\mathfrak{C}}_{\boldsymbol{q}} \underbrace{\mathfrak{R}}_{\boldsymbol{q}_2} \dot{\boldsymbol{\sigma}} \dot{\boldsymbol{\sigma}} = L_a \ddot{q}_2 \;, \\ \frac{\Pi \mathbf{P}}{\P q_1} &= 0 \;, \; \frac{\Pi \mathbf{P}}{\P q_2} = \frac{q_2}{C} \;, \\ \frac{\Pi \mathbf{D}}{\P \dot{q}_1} &= \left(r_L + r_s\right) \dot{q}_1 \;, \; \frac{\Pi \mathbf{D}}{\P \dot{q}_2} = \left(r_c + r_a\right) \dot{q}_2 \;. \end{split}$$
Therefore,
$$L \ddot{q}_1 + \left(r_L + r_s\right) \dot{q}_1 = Q_1, \\ L_a \ddot{q}_2 + \left(r_c + r_a\right) \dot{q}_2 + \frac{1}{C} q_2 = Q_2 \;, \end{split}$$

and thus,

$$\begin{split} \ddot{q}_{1} &= \frac{1}{L} \Big( - \left( r_{L} + r_{s} \right) \dot{q}_{1} + Q_{1} \Big), \\ \ddot{q}_{2} &= \frac{1}{L_{a}} \bigotimes_{\mathbf{e}}^{\mathbf{e}} \left( r_{c} + r_{a} \right) \dot{q}_{2} - \frac{1}{C} q_{2} + Q_{2} \overset{\mathbf{O}}{\rightleftharpoons}, \end{split}$$

The total kinetic, potential, and dissipated energies if the switch is open are found to be

$$\begin{aligned} \mathbf{G} &= \frac{1}{2} \Big( L \dot{q}_{1}^{2} + L_{a} \dot{q}_{2}^{2} \Big), \mathbf{P} = \frac{1}{2} \frac{\left( q_{1} - q_{2} \right)^{2}}{C}, D = \frac{1}{2} \Big( r_{L} \dot{q}_{1}^{2} + r_{c} \big( \dot{q}_{1} - \dot{q}_{2} \big)^{2} + r_{a} \dot{q}_{2}^{2} \Big). \end{aligned}$$
Thus,  

$$\begin{aligned} \frac{\eta \mathbf{G}}{\eta q_{1}} &= 0, \quad \frac{\eta \mathbf{G}}{\eta q_{2}} = 0, \quad \frac{\eta \mathbf{G}}{\eta \dot{q}_{1}} = L \dot{q}_{1}, \quad \frac{\eta \mathbf{G}}{\eta \dot{q}_{2}} = L_{a} \dot{q}_{2}, \end{aligned}$$

$$\begin{aligned} \frac{d}{dt} \bigotimes_{\mathbf{G}} \frac{\bigotimes_{\mathbf{G}} \mathbf{G}}{\eta \dot{q}_{1}} \stackrel{=}{=} L \ddot{q}_{1}, \quad \frac{d}{dt} \bigotimes_{\mathbf{G}} \frac{\bigotimes_{\mathbf{G}} \mathbf{G}}{\eta \dot{q}_{2}} \stackrel{=}{=} L_{a} \ddot{q}_{2}, \end{aligned}$$

$$\begin{aligned} \frac{\eta \mathbf{P}}{\eta q_{1}} &= \frac{q_{1} - q_{2}}{C}, \quad \frac{\eta \mathbf{P}}{\eta q_{2}} = -\frac{q_{1} - q_{2}}{C}, \end{aligned}$$

$$\begin{aligned} \frac{\eta \mathbf{D}}{\eta \dot{q}_{1}} &= (r_{L} + r_{c}) \dot{q}_{1} - r_{c} \dot{q}_{2}, \quad \frac{\eta \mathbf{D}}{\eta \dot{q}_{2}} = -r_{c} \dot{q}_{1} + (r_{c} + r_{a}) \dot{q}_{2}. \end{aligned}$$
Using  

$$\begin{aligned} L \ddot{q}_{1} + (r_{L} + r_{c}) \dot{q}_{1} - r_{c} \dot{q}_{2} + \frac{q_{1} - q_{2}}{C} = Q_{1}, \end{aligned}$$

$$\begin{aligned} L_{a} \ddot{q}_{2} - r_{c} \dot{q}_{1} + (r_{c} + r_{a}) \dot{q}_{2} - \frac{q_{1} - q_{2}}{C} = Q_{2}, \end{aligned}$$

one has

$$\begin{split} \ddot{q}_{1} &= \frac{1}{L} \underbrace{\overset{\mathbf{e}}{\mathbf{c}}}_{C} \left( r_{L} + r_{c} \right) \dot{q}_{1} + r_{c} \dot{q}_{2} - \frac{q_{1} - q_{2}}{C} + Q_{1} \overset{\mathbf{O}}{\overset{\mathbf{O}}{\mathbf{b}}}, \\ \ddot{q}_{2} &= \frac{1}{L_{a}} \underbrace{\overset{\mathbf{e}}{\mathbf{c}}}_{C} \dot{q}_{1} - (r_{c} + r_{a}) \dot{q}_{2} + \frac{q_{1} - q_{2}}{C} + Q_{2} \overset{\mathbf{O}}{\overset{\mathbf{O}}{\mathbf{b}}}. \end{split}$$

It must be emphasized that  $i_L = \dot{q}_1$ ,  $i_a = \dot{q}_2$ , and  $Q_1 = V_d$ ,  $Q_2 = -E_a$ . Taking note of the differential equations when the switch is closed and open, the differential equations in Cauchy's form are found using  $\frac{dq_1}{dt} = i_L$  and  $\frac{dq_2}{dt} = i_a$ . The voltage across the capacitor  $u_C$  is expressed using the charges  $q_1$  and  $q_2$ . When the switch is closed  $u_C = -\frac{q_2}{C}$ . If the switch is open  $u_C = \frac{q_1 - q_2}{C}$ . The analysis of the differential equations derived using Kirchhoff's voltage law and the Lagrange equations of motion illustrates that the mathematical models are found using different state variables. In particular,  $u_C$ ,  $i_L$ ,  $i_a$  and  $q_1$ ,  $i_L$ ,  $q_2$ ,  $i_a$  are used. However, the resulting differential equations are the same as one applies the corresponding variable transformations as given by

$$\frac{dq_1}{dt} = i_L, \ \frac{dq_2}{dt} = i_a, \ Q_1 = V_d \text{ and } Q_2 = -E_a$$

Example 2.3.14. Mathematical model of an electric motor

Consider a motor with two independently excited stator and rotor windings, see Figure 2.3.14. Derive the differential equations.



Figure 2.3.14. Motor with stator and rotor windings *Solution*.

The following notations are used:  $i_s$  and  $i_r$  are the currents in the stator and rotor windings;  $u_s$  and  $u_r$  are the applied voltages to the stator and rotor windings;  $w_r$  and  $q_r$  are the rotor angular velocity and displacement;  $T_e$ and  $T_L$  are the electromagnetic and load torques;  $r_s$  and  $r_r$  are the resistances of the stator and rotor windings;  $L_s$  and  $L_r$  are the selfinductances of the stator and rotor windings;  $L_{sr}$  is the mutual inductance of the stator and rotor windings;  $\hat{A}_m$  is the reluctance of the magnetizing path;  $N_s$  and  $N_r$  are the number of turns in the stator and rotor windings; J is the moment of inertia of the rotor and attached load;  $B_m$  is the viscous friction coefficient;  $k_s$  is the spring constant.

The magnetic fluxes that cross an air gap produce a force of attraction, and the developed electromagnetic torque  $T_e$  is countered by the tortional spring which causes a *counterclockwise* rotation. The load torque  $T_L$  should be considered.

Our goal is to find a nonlinear mathematical model. In fact, the ability to formulate the modeling problem and find the resulting equations that describe a motion device constitute the most important issues. By using the Lagrange concept, the independent generalized coordinates must be chosen. Let us use  $q_1$ ,  $q_2$  and  $q_3$ , where  $q_1$  and  $q_2$  denote the electric charges in the stator and rotor windings;  $q_3$  represents the rotor angular displacement.

We denote the generalized forces, applied to an electromechanical system, as  $Q_1$ ,  $Q_2$  and  $Q_3$ , where  $Q_1$  and  $Q_2$  are the applied voltages to the stator and rotor windings;  $Q_3$  is the load torque.

The first derivative of the generalized coordinates  $\dot{q}_1$  and  $\dot{q}_2$  represent the stator and rotor currents  $i_s$  and  $\dot{i}_r$ , while  $\dot{q}_3$  is the angular velocity of the rotor  $\mathbf{w}_r$ . We have,

$$q_{1} = \frac{i_{s}}{s}, \ q_{2} = \frac{i_{r}}{s}, \ q_{3} = \mathbf{q}_{r}, \ \dot{q}_{1} = i_{s}, \ \dot{q}_{2} = i_{r}, \ \dot{q}_{3} = \mathbf{w}_{r}, Q_{1} = u_{s}, \ Q_{2} = u_{r} \text{ and } Q_{3} = -T_{L}.$$

The Lagrange equations are expressed in terms of each independent coordinates, and we have

$$\frac{d}{dt} \bigotimes_{\mathbf{C}} \frac{\mathbf{\mathcal{B}} \| \mathbf{G} \, \ddot{\mathbf{o}}}{\mathbf{C} \mathbf{q}_{1} \, \dot{\mathbf{o}}} - \frac{\mathbf{\Pi} \mathbf{G}}{\mathbf{\Pi} q_{1}} + \frac{\mathbf{\Pi} D}{\mathbf{\Pi} \dot{q}_{1}} + \frac{\mathbf{\Pi} \mathbf{P}}{\mathbf{\Pi} q_{1}} = Q_{1},$$

$$\frac{d}{dt} \bigotimes_{\mathbf{C}} \frac{\mathbf{\mathcal{B}} \| \mathbf{G} \, \ddot{\mathbf{o}}}{\mathbf{Q}_{2} \, \dot{\mathbf{o}}} - \frac{\mathbf{\Pi} \mathbf{G}}{\mathbf{\Pi} q_{2}} + \frac{\mathbf{\Pi} D}{\mathbf{\Pi} \dot{q}_{2}} + \frac{\mathbf{\Pi} \mathbf{P}}{\mathbf{\Pi} q_{2}} = Q_{2},$$

$$\frac{d}{dt} \bigotimes_{\mathbf{C}} \frac{\mathbf{\mathcal{B}} \| \mathbf{G} \, \ddot{\mathbf{o}}}{\mathbf{Q}_{3} \, \dot{\mathbf{o}}} - \frac{\mathbf{\Pi} \mathbf{G}}{\mathbf{\Pi} q_{3}} + \frac{\mathbf{\Pi} D}{\mathbf{\Pi} \dot{q}_{3}} + \frac{\mathbf{\Pi} \mathbf{P}}{\mathbf{\Pi} q_{3}} = Q_{3}.$$

The total kinetic energy of electrical and mechanical systems is found as a sum of the total magnetic (electrical)  $\mathbf{G}_{E}$  and mechanical  $\mathbf{G}_{M}$  energies. The total kinetic energy of the stator and rotor circuitry is given as

$$\mathbf{G}_{E} = \frac{1}{2} L_{s} \dot{q}_{1}^{2} + L_{sr} \dot{q}_{1} \dot{q}_{2} + \frac{1}{2} L_{r} \dot{q}_{2}^{2}$$

The total kinetic energy of the mechanical system, which is a function of the equivalent moment of inertia of the rotor and the payload attached, is expressed by

$$\begin{split} \mathbf{G}_{M} &= \frac{1}{2} J \dot{q}_{3}^{2} \,. \end{split}$$
  
Then, we have  
$$\mathbf{G} &= \mathbf{G}_{E} + \mathbf{G}_{M} = \frac{1}{2} L_{s} \dot{q}_{1}^{2} + L_{sr} \dot{q}_{1} \dot{q}_{2} + \frac{1}{2} L_{r} \dot{q}_{2}^{2} + \frac{1}{2} J \dot{q}_{3}^{2} \end{split}$$
  
The mutual inductance is a periodic function of

The mutual inductance is a periodic function of the angular rotor displacement, and  $L_{sr}(q_r) = \frac{N_s N_r}{\hat{A}_m(q_r)}$ .

The magnetizing reluctance is maximum if the stator and rotor windings are not displaced, and  $\hat{A}_m(\boldsymbol{q}_r)$  is minimum if the coils are displaced by 90

degrees. Then, 
$$L_{sr\min} \not\in L_{sr}(\boldsymbol{q}_r) \not\in L_{sr\max}$$
, where  $L_{sr\max} = \frac{N_s N_r}{\hat{A}_m(90^\circ)}$  and

$$L_{sr\min} = \frac{N_s N_r}{\hat{\mathsf{A}}_m(0^\circ)} \,.$$

The mutual inductance can be approximated as a cosine function of the rotor angular displacement. The amplitude of the mutual inductance between

the stator and rotor windings is found as  $L_M = L_{sr \max} = \frac{N_s N_r}{\hat{A}_m (90^\circ)}$ .

Then,

$$L_{sr}(\boldsymbol{q}_r) = L_M \cos \boldsymbol{q}_r = L_M \cos \boldsymbol{q}_3$$

One obtains an explicit expression for the total kinetic energy as

$$\mathbf{G} = \frac{1}{2} L_s \dot{q}_1^2 + L_M \dot{q}_1 \dot{q}_2 \cos q_3 + \frac{1}{2} L_r \dot{q}_2^2 + \frac{1}{2} J \dot{q}_3^2.$$

The following partial derivatives result

$$\begin{aligned} \frac{\#\mathbf{G}}{\#q_1} &= 0 , \ \frac{\#\mathbf{G}}{\#\dot{q}_1} = L_s \dot{q}_1 + L_M \dot{q}_2 \cos q_3, \\ \frac{\#\mathbf{G}}{\#q_2} &= 0 , \ \frac{\#\mathbf{G}}{\#\dot{q}_2} = L_M \dot{q}_1 \cos q_3 + L_r \dot{q}_2, \\ \frac{\#\mathbf{G}}{\#q_3} &= -L_M \dot{q}_1 \dot{q}_2 \sin q_3, \ \frac{\#\mathbf{G}}{\#\dot{q}_3} = J \dot{q}_3. \end{aligned}$$

The potential energy of the spring with constant  $k_s$  is  $P = \frac{1}{2}k_s q_3^2$ .

Therefore,

$$\frac{\P \mathsf{P}}{\P q_1} = 0, \quad \frac{\P \mathsf{P}}{\P q_2} = 0, \text{ and } \quad \frac{\P \mathsf{P}}{\P q_3} = k_s q_3.$$

The total heat energy dissipated is expressed as

 $D = D_E + D_M,$ 

where  $D_E$  is the heat energy dissipated in the stator and rotor windings,  $D_E = \frac{1}{2}r_s\dot{q}_1^2 + \frac{1}{2}r_r\dot{q}_2^2$ ;  $D_M$  is the heat energy dissipated by mechanical system,  $D_M = \frac{1}{2}B_m\dot{q}_3^2$ .

Hence,

$$D = \frac{1}{2}r_s\dot{q}_1^2 + \frac{1}{2}r_r\dot{q}_2^2 + \frac{1}{2}B_m\dot{q}_3^2.$$

One obtains

$$\frac{\P D}{\P \dot{q}_1} = r_s \dot{q}_1, \quad \frac{\P D}{\P \dot{q}_2} = r_r \dot{q}_2 \text{ and } \quad \frac{\P D}{\P \dot{q}_3} = B_m \dot{q}_3.$$

Using

$$q_{1} = \frac{i_{s}}{s}, \ q_{2} = \frac{i_{r}}{s}, \ q_{3} = \boldsymbol{q}_{r}, \ \dot{q}_{1} = i_{s}, \ \dot{q}_{2} = i_{r}, \ \dot{q}_{3} = \boldsymbol{w}_{r}, Q_{1} = u_{s}, \ Q_{2} = u_{r} \text{ and } Q_{3} = -T_{L},$$

we have three differential equations for a servo-system. In particular,

$$L_s \frac{di_s}{dt} + L_M \cos \mathbf{q}_r \frac{di_r}{dt} - L_M i_r \sin \mathbf{q}_r \frac{d\mathbf{q}_r}{dt} + r_s i_s = u_s,$$
  

$$L_r \frac{di_r}{dt} + L_M \cos \mathbf{q}_r \frac{di_s}{dt} - L_M i_s \sin \mathbf{q}_r \frac{d\mathbf{q}_r}{dt} + r_r i_r = u_r,$$
  

$$J \frac{d^2 \mathbf{q}_r}{dt^2} + L_M i_s i_r \sin \mathbf{q}_r + B_m \frac{d\mathbf{q}_r}{dt} + k_s \mathbf{q}_r = -T_L.$$

The last equation should be rewritten by making use the rotor angular velocity; that is,

$$\frac{d\boldsymbol{q}_r}{dt} = \boldsymbol{w}_r$$

Finally, using the stator and rotor currents, angular velocity and position as the state variables, the nonlinear differential equations in Cauchy's form are found as

$$\begin{aligned} \frac{di_s}{dt} &= \frac{-r_s L_r i_s - \frac{1}{2} L_M^2 i_s \mathbf{w}_r \sin 2\mathbf{q}_r + r_r L_M i_r \cos \mathbf{q}_r + L_r L_M i_r \mathbf{w}_r \sin \mathbf{q}_r + L_r u_s - L_M \cos \mathbf{q}_r u_r}{L_s L_r - L_M^2 \cos^2 \mathbf{q}_r}, \\ \frac{di_r}{dt} &= \frac{r_s L_M i_s \cos \mathbf{q}_r + L_s L_M i_s \mathbf{w}_r \sin \mathbf{q}_r - r_r L_s i_r - \frac{1}{2} L_M^2 i_r \mathbf{w}_r \sin 2\mathbf{q}_r - L_M \cos \mathbf{q}_r u_s + L_s u_r}{L_s L_r - L_M^2 \cos^2 \mathbf{q}_r}, \\ \frac{d\mathbf{w}_r}{dt} &= \frac{1}{J} \Big( - L_M i_s i_r \sin \mathbf{q}_r - B_m \mathbf{w}_r - k_s \mathbf{q}_r - T_L \Big), \\ \frac{d\mathbf{q}_r}{dt} &= \mathbf{w}_r. \end{aligned}$$

The developed nonlinear mathematical model in the form of highly coupled nonlinear differential equations cannot be linearized, and one must model the doubly exited transducer studied using the nonlinear differential equations derived.

### 2.3.3. Hamilton Equations of Motion

The Hamilton concept allows one to model the system dynamics, and the differential equations are found using the generalized momenta  $p_i$ ,  $p_i = \frac{\P L}{\P \dot{q}_i}$ 

(the generalized coordinates were used in the Lagrange equations of motion).

The Lagrangian function 
$$L_{\mathbf{c}t}^{\mathbf{a}}, q_1, ..., q_n, \frac{dq_1}{dt}, ..., \frac{dq_n}{dt} \overset{\mathbf{o}}{\overset{\mathbf{o}}{\overset{\mathbf{o}}{\overset{\mathbf{o}}{\overset{\mathbf{o}}}}}$$
 for the

conservative systems is the difference between the total kinetic and potential energies. In particular,

$$L_{\mathbf{e}}^{\mathbf{a}}, q_1, \dots, q_n, \frac{dq_1}{dt}, \dots, \frac{dq_n}{dt} \overset{\mathbf{o}}{\underset{\boldsymbol{\varphi}}{\overset{\mathbf{o}}}} = \mathbf{G}_{\mathbf{e}}^{\mathbf{a}}, q_1, \dots, q_n, \frac{dq_1}{dt}, \dots, \frac{dq_n}{dt} \overset{\mathbf{o}}{\underset{\boldsymbol{\varphi}}{\overset{\mathbf{o}}}} \mathsf{P}(t, q_1, \dots, q_n) \ .$$

Thus,  $L\overset{\mathfrak{g}}{\underset{e}{\mathsf{e}}}, q_1, \dots, q_n, \frac{dq_1}{dt}, \dots, \frac{dq_n}{dt} \overset{\bullet}{\underset{\varphi}{\mathsf{o}}}$  is the function of 2n independent

variables. One has

$$dL = \overset{n}{\overset{n}{\mathbf{a}}} \underbrace{\overset{\mathfrak{ge}}{\overset{\mathfrak{ge}}{\mathbf{f}}}}_{i=1} \frac{L}{\overset{\mathfrak{ge}}{\mathbf{f}}} dq_i + \frac{\mathbb{f}L}{\overset{\mathfrak{ge}}{\mathbf{f}}_i} d\dot{q}_i \overset{\mathfrak{ge}}{\overset{\mathfrak{ge}}{\mathbf{f}}} = \overset{n}{\overset{\mathfrak{ge}}{\mathbf{a}}} (\dot{p}_i dq_i + p_i d\dot{q}_i).$$

We define the Hamiltonian function as

$$H(t, q_{1}, ..., q_{n}, p_{1}, ..., p_{n}) = -L_{e}^{\bigotimes}, q_{1}, ..., q_{n}, \frac{dq_{1}}{dt}, ..., \frac{dq_{n}}{dt} \overset{\circ}{\underset{\varphi}{\mapsto}} + \overset{a}{\overset{n}{a}} p_{i}\dot{q}_{i},$$
  

$$dH = \overset{n}{\overset{n}{a}} (-\dot{p}_{i}dq_{i} + \dot{q}_{i}dp_{i}),$$
  
where  $\overset{n}{\overset{n}{a}} p_{i}\dot{q}_{i} = \overset{n}{\overset{n}{a}} \frac{\P L}{\P \dot{q}_{i}} \dot{q}_{i} = \overset{n}{\overset{n}{a}} \frac{\P G}{\P \dot{q}_{i}} = 2G.$   
Thus, we have  

$$H_{e}^{\bigotimes}, q_{1}, ..., q_{n}, \frac{dq_{1}}{dt}, ..., \frac{dq_{n}}{dt} \overset{\circ}{\underset{\varphi}{\to}} = G_{e}^{\bigotimes}, q_{1}, ..., q_{n}, \frac{dq_{1}}{dt}, ..., \frac{dq_{n}}{dt} \overset{\circ}{\underset{\varphi}{\to}} + P(t, q_{1}, ..., q_{n})$$

$$\begin{array}{c} H(t, q_1, ..., q_n, \frac{dt}{dt}, ..., \frac{dt}{dt}) = \mathbf{G}(t, q_1, ..., q_n, \frac{dt}{dt}, ..., \frac{dt}{dt}) + \mathbf{P}(t, q_1, ..., q_n) \\ \text{or} \quad H(t, q_1, ..., q_n, p_1, ..., p_n) = \mathbf{G}(t, q_1, ..., q_n, p_1, ..., p_n) + \mathbf{P}(t, q_1, ..., q_n). \end{array}$$

One concludes that the Hamiltonian, which is equal to the total energy, is expressed as a function of the generalized coordinates and generalized momenta. The equations of motion are governed by the following equations

$$\dot{p}_i = -\frac{\P H}{\P q_i}, \ \dot{q}_i = \frac{\P H}{\P p_i},$$
(2.3.4)

which are called the Hamiltonian equations of motion.

It is evident that using the Hamiltonian mechanics, one obtains the system of 2n first-order partial differential equations to model the system dynamics. In contrast, using the Lagrange equations of motion, the system of n second-order differential equations results. However, the derived differential equations are equivalent.

#### Example 2.3.15.

Consider the harmonic oscillator. The total energy is given as the sum of the kinetic and potential energies,  $S_T = G + P = \frac{1}{2}(mv^2 + k_s x^2)$ . Find the equations of motion using the Lagrange and Hamilton concepts.

Solution.

The Lagrangian function is

$$L_{\mathsf{e}x}^{\mathfrak{a}}, \frac{dx \, \ddot{\mathsf{o}}}{dt \, \varphi} = \mathsf{G} - \mathsf{P} = \frac{1}{2}(mv^2 - k_s x^2) = \frac{1}{2}(m\dot{x}^2 - k_s x^2).$$

Making use of the Lagrange equations of motion

$$\frac{d}{dt}\frac{\P L}{\P \dot{x}} - \frac{\P L}{\P x} = 0$$

we have

$$m\frac{d^2x}{dt^2} + k_s x = 0$$

From Newton's second law, the second-order differential equation motion

is

$$m\frac{d^2x}{dt^2} + k_s x = 0.$$

The Hamiltonian function is expressed as

$$H(x, p) = \mathbf{G} + \mathbf{P} = \frac{1}{2}(mv^2 - k_s x^2) = \frac{1}{2} \frac{\mathbf{\mathfrak{E}}}{\mathbf{\mathfrak{E}}} p^2 - k_s x^2 \frac{\mathbf{\ddot{o}}}{\mathbf{\mathfrak{E}}}.$$

From the Hamiltonian equations of motion  $\dot{p}_i = -\frac{\P H}{\P q_i}$  and  $\dot{q}_i = \frac{\P H}{\P p_i}$ ,

as given by (2.3.4), one obtains

$$\dot{p} = -\frac{\P H}{\P x} = -k_s x ,$$
  
$$\dot{x} = \dot{q} = \frac{\P H}{\P p} = \frac{p}{m} .$$

The equivalence the results and equations of motion are obvious.

## 2.4. ATOMIC STRUCTURES AND QUANTUM MECHANICS

The fundamental and applied research as well as engineering developments in NEMS and MEMS have undergone major developments in last years. High-performance nanostructures and nanodevices, as well as MEMS have been manufactured and implemented (accelerometers and microphones, actuators and sensors, molecular wires and transistors, et cetera). Smart structures and MEMS have been mainly designed and built using conventional electromechanical and CMOS technologies. The next critical step to be made is to research nanoelectromechanical structures and systems, and these developments will have a tremendous positive impact on economy and society. Nanoengineering studies NEMS and MEMS, as well as their structures and subsystems, which are made from atoms and molecules, and the electron is considered as a fundamental particle. The students and engineers have obtained the necessary background in physics classes. The properties and performance of materials (media) is understood through the analysis of the atomic structure.

The atomic structures were studied by Rutherford and Einstein (in the 1900's), Heisenberg and Dirac (in the 1920's), Schrödinger, Bohr, Feynman, and many other scientists. For example, the theory of quantum electrodynamics studies the interaction of electrons and photons. In the 1940's, the major breakthrough appears in augmentation of the electron dynamics with electromagnetic field. One can control molecules and group of molecules (nanostructures) applying the electromagnetic field, and microand nanoscale devices (e.g., actuators and sensors) have been fabricated, and some problems in structural design and optimization have been approached and solved. However, these nano- and micro-scale devices (which have dimensions nano- and micrometers) must be controlled, and one faces an extremely challenging problem to design NEMS and MEMS integrating control and optimization, self-organization and decision making, diagnostics and self-repairing, signal processing and communication, as well as other features. In 1959, Richard Feynman gave a talk to the American Physical Society in which he emphasized the important role of nanotechnology and nanoscale organic and inorganic systems on the society and progress.

All media are made from atoms, and the medium properties depend on the atomic structure. Recalling the Rutherford's structure of the atomic nuclei, we can view here very simple atomic model and omit detailed composition, because only three subatomic particles (proton, neutron and electron) have bearing on chemical behavior.

The nucleus of the atom bears the major mass. It is an extremely dense region, which contains positively charged protons and neutral neutrons. It occupies small amount of the atomic volume compared with the virtually indistinct cloud of negatively charged electrons attracted to the positively charged nucleus by the force that exists between the particles of opposite electric charge. For the atom of the element the number of protons is always the same but the number of neutrons may vary. Atoms of a given element, which differ in number of neutrons (and consequently in mass), are called isotopes. For example, carbon always has 6 protons, but it may have 6 neutrons as well. In this case it is called "carbon-12" (<sup>12</sup>C). The representation of the carbon atom is given in Figure 2.4.1.



Figure 2.4.1.Simplified two-dimensional representation of carbon atom (C). Six protons (p+, dashed color) and six neutrons (n, white) are in centrally located nucleus. Six electrons (*e*<sup>-</sup>, black), orbiting the nucleus, occupy two shells

Atom has no net charge due to the equal number of positively charged protons in the nucleus and negatively charged electrons around it. For example, all atoms of carbon have 6 protons and 6 electrons. If electrons are lost or gained by the neutral atom due to the chemical reaction, a charged particle called ion is formed.

When one deals with such subatomic particles as electron, the dual nature of matter places a fundamental limitation on how accurate we can describe both location and momentum of the object. Austrian physicist Erwin Schrödinger in 1926 derived an equation that describes wave and particle natures of the electron. This fundamental equation led to the new area in physics, called quantum mechanics, which enables us to deal with subatomic particles. The complete solution to Schrödinger's equation gives a set of wave functions and set of corresponding energies. These wave functions are called orbitals. A collection of orbitals with the same principal quantum number, which describes the orbit, called electron shell. Each shell is divided into the number of subshells with the equal principal quantum

number. Each subshell consists of number of orbitals. Each shell may contain only two electrons of the opposite spin (Pouli exclusion principle). When the electron in the lowest energy orbital, the atom is in its ground state. When the electron enters the orbital, the atom is in an excited state. To promote the electron to the excited-state orbital, the photon of the appropriate energy should be absorbed as the energy supplement.

When the size of the orbital increases, and the electron spends more time farther from the nucleus. It possesses more energy and less tightly bound to the nucleus. The most outer shell is called the valence shell. The electrons, which occupy it, are referred as valence electrons. Inner shells electrons are called the core electrons. There are valence electrons, which participate in the bond formation between atoms when molecules are formed, and in ion formation when the electrons are removed from the electrically neutral atom and the positively charged cation is formed. They possess the highest ionization energies (the energy which measure the easy of the removing the electron from the atom), and occupy energetically weakest orbital since it is the most remote orbital from the nucleus. The valence electrons removed from the valence shell become free electrons transferring the energy from one atom to another. We will describe the influence of the electromagnetic field on the atom later in the text, and it is relevant to include more detailed description of the Pauli exclusion principal.

The electric conductivity of a media is predetermined by the density of free electrons, and good conductors have the free electron density in the range of  $10^{23}$  free electrons per cm<sup>3</sup>. In contrast, the free electron density of good insulators is in the range of 10 free electrons per cm<sup>3</sup>. The free electron density of semiconductors in the range from  $10^7/\text{cm}^3$  to  $10^{15}/\text{cm}^3$  (for example, the free electron concentration in silicon at  $25^{\circ}$ C and  $100^{\circ}$ C are 2  $\cdot 10^{10}/\text{cm}^3$  and 2  $\cdot 10^{12}/\text{cm}^3$ , respectively). The free electron density is determined by the energy gap between valence and conduction (free) electrons. That is, the properties of the media (conductors, semiconductors, and insulators) are determined by the atomic structure.

Using the atoms as building blocks, one can manufacture different structures using the molecular nanotechnology. There are many challenging problems needed to be solve such as mathematical modeling and analysis, simulation and design, optimization and testing, implementation and deployment, technology transfer and mass production. In addition, to build NEMS, advanced manufacturing technologies must be developed and applied. To fabricate nanoscale systems at the molecular level, the problems in atomic-scale positional assembly ("maneuvering things atom by atom" as Richard Feynman predicted) and artificial self-replication (systems are able to build copies of themselves, e.g., like the crystals growth process, complex DNA strands which copy tens of millions atoms with perfect accuracy, or self replicating tomato which has millions of genes, proteins, and other molecular components) must be solved. The author does not encourage the blind copying, and the submarine and whale are very different even though both sail. Using the Scanning or Atomic Probe Microscopes, it is possible to

achieve positional accuracy in the angstrom-range. However, the atomicscale "manipulator" (which will have a wide range of motion guaranteeing the flexible assembly of molecular components), controlled by the external source (electromagnetic field, pressure, or temperature) must be designed and used. The position control will be achieved by the molecular computer and which will be based on molecular computational devices.

The quantitative explanation, analysis and simulation of natural phenomena can be approached using comprehensive mathematical models which map essential features. The Newton laws and Lagrange equations of motion, Hamilton concept and d'Alambert concept allow one to model conventional mechanical systems, and the Maxwell equations applied to model electromagnetic phenomena. In the 1920's, new theoretical developments, concepts and formulations (*quantum mechanics*) have been made to develop the atomic scale theory because atomic-scale systems do not obey the classical laws of physics and mechanics. In 1900 Max Plank discovered the effect of quantization of energy, and he found that the radiated (emitted) energy is given as

E = nhv,

where *n* is the nonnegative integer, n = 0, 1, 2, ...; h is the Plank constant,

 $h = 6.626' 10^{-34} \text{ J-sec}$ ; v is the frequency of radiation,  $v = \frac{c}{l}$ , c is the

speed of light,  $c = 3 \cdot 10^8 \frac{\text{m}}{\text{sec}}$ ; *I* is the wavelength which is measured in angstroms ( $\stackrel{o}{A} = 1 \cdot 10^{-10} \text{ m}$ ),  $I = \frac{c}{2}$ .

angstroms (
$$A = 1$$
 10 <sup>10</sup> m),  $I = -$ .

The following discrete energy values result:

 $E_0 = 0, E_1 = hv, E_2 = 2hv, E_3 = 3hv$ , etc.

The observation of discrete energy spectra suggests that each particle has the energy hv (the radiation results due to N particles), and the particle with the energy hv is called *photon*.

The *photon* has the momentum as expressed as

$$p = \frac{hv}{c} = \frac{h}{l}.$$

Soon, Einstein demonstrated the discrete nature of light, and Niels Bohr develop the model of the hydrogen atom using the planetary system analog, see Figure 2.4.2. It is clear that if the electron has planetary-type orbits, it can be excited to an outer orbit and can "fall" to the inner orbits. Therefore, to develop the model, Bohr postulated that the electron has the certain stable circular orbit (that is, the orbiting electron does not produces the radiation because otherwise the electron would lost the energy and change the path); the electron changes the orbit of higher or lower energy by receiving or radiating discrete amount of energy; the angular momentum of the electron is p = nh.


Figure 2.4.2. Hydrogen atom: uniform circular motion

To attain the uniform circular motion, using Newton's law, the electrostatic (Coulomb) force must be equal to the radial force, and for radii  $R_1$  and  $R_2$  we have

$$\frac{q^2}{4pe_0R_1^2} = \frac{mv^2}{R_1} \text{ and } \frac{q^2}{4pe_0R_2^2} = \frac{mv^2}{R_2}.$$
  
That is, in general  
$$\frac{q^2}{4pe_0R_n^2} = \frac{mv^2}{R_n},$$

where  $R_n$  is the radius of the *n* orbit, and  $R_n = \frac{4\mathbf{p}\mathbf{e}_0 n^2 h^2}{mq^2}$ .

Applying the expression for the angular momentum  $p = nh = mvR_n$ ,

we have

$$\frac{q^2}{4\boldsymbol{p}\boldsymbol{e}_0 R_n^2} = \frac{m}{R_n} \underbrace{\overset{\boldsymbol{e}}{\boldsymbol{\delta}} nh}_{\boldsymbol{\delta} \boldsymbol{m} \boldsymbol{m}_n} \underbrace{\overset{\boldsymbol{o}^2}{\boldsymbol{\delta}}}_{\boldsymbol{\sigma} \boldsymbol{\sigma}} = \frac{1}{mR_n} \frac{n^2 h^2}{R_n^2}$$

The kinetic and potential energies are

$$\mathbf{G} = \frac{1}{2}mv^2 = \frac{mq^4}{32\boldsymbol{p}^2\boldsymbol{e}_0^2n^2h^2} \text{ and } \mathbf{P} = -\frac{q^2}{4\boldsymbol{p}\boldsymbol{e}_0R_n} = -\frac{mq^4}{16\boldsymbol{p}^2\boldsymbol{e}_0^2n^2h^2}.$$

The total energy of the electron in the *n*th orbit is found to be

$$E_n = \mathbf{G} + \mathbf{P} = -\frac{mq^4}{32\mathbf{p}^2 \mathbf{e}_0^2 n^2 h^2}$$

One finds the energy difference between the orbits as

$$DE = E_{n2} - E_{n1} = \frac{mq^4}{32\boldsymbol{p}^2 \boldsymbol{e}_0^2 h^2} \boldsymbol{\bigotimes}_{n_1}^{2-1} - \frac{1}{n_2^2 \boldsymbol{\bigotimes}}^{\mathbf{ö}}.$$

Bohr's model was expanded and generalized by Heisenberg and Schrödinger using the *matrix* and *wave mechanics*. The characteristics of particles and waves are augmented replacing the trajectory consideration by the waves using continuous, finite, and single-valued wave function

- Y(x, y, z, t) in the Cartesian coordinate system,
- Y(r, f, z, t) in the cylindrical coordinate system,
- Y(r,q,f,t) in the spherical coordinate system.

The wavefunction gives the dependence of the wave amplitude on space coordinates and time.

Using the classical mechanics, for a particle of mass m with energy E moving in the Cartesian coordinate system one has

$$E(x, y, z, t) = \mathbf{G}(x, y, z, t) + \mathbf{P}(x, y, z, t)$$
  
total energy kinetic energy potential energy  

$$= \frac{p^2(x, y, z, t)}{2m} + \mathbf{P}(x, y, z, t) = H(x, y, z, t).$$
Hamiltonian

Thus, we have

$$p^{2}(x, y, z, t) = 2m[E(x, y, z, t) - P(x, y, z, t)].$$

Using the formula for the wavelength (Broglie's equation)

$$I = \frac{h}{p} = \frac{h}{mv}$$

one finds

$$\frac{1}{l^2} = \overset{\text{gp}}{\overset{\text{o}}{\mathsf{c}}}_{\overset{\text{o}}{\mathsf{b}}}^{\overset{\text{o}}{\mathsf{o}}} = \frac{2m}{h^2} [E(x, y, z, t) - \mathsf{P}(x, y, z, t)].$$

This expression is substituted in the *Helmholtz* equation

$$\tilde{\mathsf{N}}^2\mathsf{Y} + \frac{4\boldsymbol{p}^2}{\boldsymbol{l}^2}\mathsf{Y} = 0$$

which gives the evolution of the wavefunction.

We obtain the Schrödinger equation as

$$E(x, y, z, t) \mathbf{Y}(x, y, z, t) = -\frac{\hbar^2}{2m} \tilde{\mathbf{N}}^2 \mathbf{Y}(x, y, z, t) + \mathbf{P}(x, y, z, t) \mathbf{Y}(x, y, z, t)$$

or

$$E(x, y, z, t) \mathbf{Y} (x, y, z, t)$$
  
=  $-\frac{\hbar^2}{2m} \underbrace{\overset{\otimes}{\mathbf{g}} \overset{\otimes}{\mathbf{q}} \overset{\otimes}{\mathbf{q}} (x, y, z, t)}_{\mathbf{q}x^2} + \frac{\overset{\otimes}{\mathbf{q}} \overset{\otimes}{\mathbf{q}} (x, y, z, t)}{\overset{\otimes}{\mathbf{q}} y^2} + \frac{\overset{\otimes}{\mathbf{q}} \overset{\otimes}{\mathbf{q}} (x, y, z, t)}{\overset{\otimes}{\mathbf{q}} z^2} \underbrace{\overset{\otimes}{\overset{\otimes}{\mathbf{q}}}_{\overset{\otimes}{\mathbf{q}}}$   
+  $\mathbf{P} (x, y, z, t) \mathbf{Y} (x, y, z, t).$ 

Here, the modified Plank constant is

$$\hbar = \frac{h}{2p} = 1.055 \,\text{'}\,10^{-34} \,\text{J-sec.}$$

In 1926, Erwine Schrödinger derive the following equation

$$-\frac{\hbar^2}{2m}\tilde{N}^2Y + PY = EY$$

which can be related to the Hamiltonian

$$H = -\frac{\hbar^2}{2m}\tilde{N} + P ,$$

and thus

•

$$HY = EY$$

For different coordinate systems we have

Cartesian system •

$$\tilde{\mathsf{N}}^{2}\mathsf{Y}(x, y, z, t) = \frac{\P^{2}\mathsf{Y}(x, y, z, t)}{\P x^{2}} + \frac{\P^{2}\mathsf{Y}(x, y, z, t)}{\P y^{2}} + \frac{\P^{2}\mathsf{Y}(x, y, z, t)}{\P z^{2}};$$

cylindrical system

$$\tilde{\mathsf{N}}^{2}\mathsf{Y}(r, \boldsymbol{f}, z, t) = \frac{1}{r} \frac{\P}{\P r} \underbrace{\bigotimes_{\boldsymbol{e}}^{\boldsymbol{e}} \frac{\P\mathsf{Y}(r, \boldsymbol{f}, z, t)}{\P r} \mathop{\overset{\boldsymbol{\Theta}}{\Rightarrow}}_{\boldsymbol{\varphi}} + \frac{1}{r^{2}} \frac{\P^{2}\mathsf{Y}(r, \boldsymbol{f}, z, t)}{\P r^{2}} + \frac{\P^{2}\mathsf{Y}(r, \boldsymbol{f}, z, t)}{\P z^{2}};$$

$$\cdot \text{ spherical system}$$

$$\tilde{\mathsf{N}}^{2}\mathsf{Y}(r, \boldsymbol{q}, \boldsymbol{f}, t) =$$

$$\frac{1}{r^{2}} \frac{\P}{\P r} \overset{\text{(}r,q,f,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{(}r,q,r,t)}{\stackrel{\text{(}r,q,r,t)}{\stackrel{(}r,q,r,r,t)}{\stackrel{(}r,q,r,t)}{\stackrel{(}r,q,r,t)}{\stackrel{(}r,q,r,t)}{\stackrel{(}r,$$

The Schrödinger partial differential equation must be solved, and the wavefunction is normalized using the probability density

$$\mathbf{\dot{O}}^{\mathsf{Y}} |^2 d\mathbf{V} = 1.$$

Let us illustrate the application of the Schrödinger equation.

# Example 2.4.1.

Assume that the particle moves in the *x* direction (translational motion). We have,

$$-\frac{\hbar^2}{2m}\frac{d^2 Y(x)}{dx^2} + P(x)Y(x) = E(x)Y(x).$$

The Hamiltonian function is given as

$$H(x,p) = \frac{p^{2}(x)}{2m} + P(x) = -\frac{\hbar^{2}}{2m}\frac{d^{2}}{dx^{2}} + P(x).$$

Let the particle moves from x = 0 to  $x = x_f$ , and the potential energy is

$$\mathsf{P}(x) = \begin{bmatrix} 0, & 0 \pounds x \pounds x_f \\ 1 & \forall, x < 0 \text{ and } x > x_f \end{bmatrix}.$$

Thus, the motion of the particle is bounded in the "potential wall", and

•

$$Y(x) = \int_{1}^{1} continuous if 0 \notin x \notin x_{f}$$
  
$$0 \text{ if } x < 0 \text{ and } x > x_{f}$$

If  $0 \pounds x \pounds x_f$ , the potential energy is zero, and we have

$$-\frac{\hbar^2}{2m}\frac{d^2\mathbf{Y}(x)}{dx^2} = E\mathbf{Y}(x), \ \mathbf{0} \,\mathbf{\pounds} \, \mathbf{x} \,\mathbf{\pounds} \, \mathbf{x}_f.$$

The solution of the resulting second-order differential equation

$$\frac{d^{2}\mathbf{Y}(x)}{dx^{2}} + k^{2}\mathbf{Y}(x) = 0, \ k = \sqrt{\frac{2mE}{\hbar^{2}}}$$

is

$$Y(x) = ae^{ikx} + be^{-ikx} = a(\cos kx + i\sin kx) + b(\cos kx - i\sin kx)$$

 $= c \sin kx + d \cos kx.$ 

The solution can be easily verified by plugging the solution in the leftside of the differential equation

$$-\frac{\hbar^2}{2m}\frac{d^2\mathbf{Y}(x)}{dx^2} = E\mathbf{Y}(x),$$

and we have

$$E\mathbf{Y}\left(x\right) = E\mathbf{Y}\left(x\right).$$

It should be emphasized that the kinetic energy of the particle is given as  $\frac{p^2}{2}$ , where p = kh.

$$\frac{P}{2m}$$
, where  $p = kh$ 

It is obvious that one must use the boundary conditions.

We have  $|\mathbf{Y}(x)|_{x=0} = \mathbf{Y}(0) = 0$ , and therefore d = 0.

From  $Y(x)|_{x=x_f} = Y(x_f) = 0$  using  $c \sin kx_f = 0$  one must find the constant *c* and the expression for  $kx_f$ .

Assuming that  $c^{1} 0$  from  $c \sin kx_{f} = 0$ , we have

$$kx_f = n\boldsymbol{p}$$
,

where *n* is the positive or negative integer (if n = 0, the wavefunction vanishes everywhere, and thus,  $n^{1} 0$ ).

From  $k = \sqrt{\frac{2mE}{\hbar^2}}$  and making use of  $kx_f = n\mathbf{p}$  we have the

expression for the energy (discrete values of the energy which allow of solution of the Schrödinger equation) as

$$E_n = \frac{\hbar^2 \mathbf{p}^2}{2mx_f^2} n^2, n = 1, 2, 3, \dots,$$

where the integer n designates the allowed energy level (n is called the quantum number).

For example, if n = 1 and n = 2, we have  $E_1 = \frac{\hbar^2 \mathbf{p}^2}{2mc^2}$  (the lowest possible energy which is called the ground state) and  $E_2 = \frac{2\hbar^2 \mathbf{p}^2}{mc^2}$ .

Thus, we have illustrated that the energy of the particle is quantized. The expression for the wavefunction is found to be

$$\mathbf{Y}_n(x) = c\sin kx + d\cos kx = c\sin \frac{n\mathbf{p}}{x_f}x.$$

Using the probability density, we normalize the wavefunction, and the following results

$$\bigvee_{0}^{x_{f}} (x) dx = c^{2} \bigvee_{0}^{x_{f}} n^{2} \frac{np}{x_{f}} x dx = c^{2} \frac{x_{f}}{np} \bigvee_{0}^{np} n^{2} g dg$$

$$c^{2} \frac{x_{f}}{np} \frac{np}{2} = c^{2} \frac{x_{f}}{2} = 1, g = \frac{np}{x_{f}} x.$$
Hence,  $c = \sqrt{\frac{2}{x_{f}}}$ , and one finally obtains
$$Y_{n}(x) = \sqrt{\frac{2}{x_{f}}} \sin \frac{np}{x_{f}} x, 0 \pounds x \pounds x_{f}.$$
For  $n = 1$  and  $n = 2$ , we have
$$Y_{n}(x) = \sqrt{\frac{2}{x_{f}}} \sin \frac{p}{x_{f}} x \text{ and } Y_{n}(x) = \sqrt{\frac{2}{x_{f}}} \sin \frac{p}{x_{f}} x$$

$$\mathbf{Y}_1(x) = \sqrt{\frac{2}{x_f}} \sin \frac{\mathbf{p}}{x_f} x \text{ and } \mathbf{Y}_2(x) = \sqrt{\frac{2}{x_f}} \sin \frac{2\mathbf{p}}{x_f} x.$$

Using the formula for the probability density, as given by  $\mathbf{r} = \mathbf{Y}^T \mathbf{Y}$ , one has

$$\boldsymbol{r}_n(x) = \frac{2}{x_f} \sin^2 \frac{n\boldsymbol{p}}{x_f} x \,.$$

It was shown that

$$H\mathbf{Y} = E\mathbf{Y}$$
,  $H = -\frac{\hbar^2}{2m}\mathbf{\tilde{N}} + \mathbf{P}$ .

Using the CGS (centimeter/gram/second) units, when the electromagnetic field is quantized, the potential can be used instead of wavefunction. In particular, using the momentum operator due to electron orbital angular momentum L, the classical Hamiltonian for electrons in electromagnetic field is

$$H = \frac{1}{2m} \mathop{\rm e}\limits^{\oplus}_{e} + \frac{e}{c} \mathbf{A}_{\neq}^{\mathbf{\ddot{O}}^2} - e\mathbf{f}.$$

From the Hamilton equations

$$\dot{q} = \frac{\P H}{\P p}$$
 and  $\dot{p} = -\frac{\P H}{\P q}$ ,

by making use of

$$\frac{d\mathbf{r}}{dt} = \frac{1}{m} \stackrel{\mathcal{E}}{\mathbf{c}} \mathbf{p} + \frac{e}{c} \mathbf{A} \stackrel{\mathbf{\ddot{o}}}{\div}, \mathbf{p} = m\mathbf{v} - \frac{e}{c} \mathbf{A}, \ \dot{\mathbf{p}} = -\frac{e}{mc} \stackrel{\mathcal{E}}{\mathbf{c}} \mathbf{p} + \frac{e}{c} \mathbf{A} \stackrel{\mathbf{\ddot{o}}}{\div} \stackrel{\mathbf{\P}}{\mathbf{M}} + e \stackrel{\mathbf{\P}f}{\mathbf{\P}},$$

one finds the Lorentz force equation

$$\mathbf{F} = -\frac{e}{c}\mathbf{v}' \mathbf{B} - e\mathbf{E}$$

This equation gives the force due to motion in a magnetic field and the force due to electric field.

It is important to emphasize that the following equation results

$$-\frac{\hbar^2}{2m}\tilde{\mathbf{N}}^2\mathbf{Y} + \frac{e}{2mc}\mathbf{B} \times \mathbf{L}\mathbf{Y} + \frac{e^2}{8mc^2}(r^2B^2 - (\mathbf{r}\times\mathbf{B})^2)\mathbf{Y} = (E + e\mathbf{f})\mathbf{Y}$$

to study the quantized Hamilton equation, where the dominant term due to magnetic field is

$$\frac{e}{2mc}\mathbf{B} \times \mathbf{L} = -\mathbf{i} \times \mathbf{B},$$

where ì the magnetic momentum due to the electron orbital angular

momentum (the so-called Zeeman effect) is 
$$\mathbf{i} = -\frac{e}{2mc}\mathbf{L}$$
.

# 2.5. MOLECULAR AND NANOSTRUCTURE DYNAMICS

Conventional, mini- and microscale electromechanical systems can be modeled using electromagnetic and circuitry theories, classical mechanics and thermodynamic, as well as other fundamental concepts. The complexity of mathematical models of mini- and microelectromechanical systems (nonlinear ordinary and partial differential equations explicitly describe the spectrum of electromagnetics and electromechanics phenomena and processes) is not ambiguous, and numerical algorithms to solve the equations derived are available. Illustrated examples have been studied in sections 2.2 and 2.3. Nano-scale structures, in general, cannot be studied using the conventional concepts, and the basis of quantum mechanics was covered in chapter 2.4.

The fundamental and applied research in molecular nanotechnology and nanostructures, nanodevices and nanosystems, NEMS and MEMS, is concentrated on design, modeling, simulation, and fabrication of molecular scale structures and devices. The design, modeling, and simulation of NEMS, MEMS, and their components can be attacked using advanced theoretical developments and simulation concepts. Comprehensive analysis must be performed before the designer embarks in costly fabrication (a wide range of nano-scale structures and devices, molecular machines and subsystems, can be fabricated with atomic precision) because through modeling and simulation the rapid evaluation and prototyping can be performed facilitating significant advantages and manageable perspectives to attain the desired objectives. With advanced computer-aided-design tools, complex large-scale nanostructures, nanodevices, and nanosystems can be designed, analyzed, and evaluated.

Classical quantum mechanics does not allow the designer to perform analytical and numerical analysis even for simple nanostructures which consist of a couple of molecules. Steady-state three-dimensional modeling and simulation are also restricted to simple nanostructures. Our goal is to develop a fundamental understanding of phenomena and processes in nanostructures with emphasis on their further applications in nanodevices, nanosubsystems, NEMS, and MEMS. The objective is the development of theoretical fundamentals (theory of nanoelectromechanics) to perform 3D+ (three-dimensional geometry dynamics in time domain) modeling and simulation.

The atomic level electomechanics can be studied using the wave function solving the Schrödinger equation for N-electron systems (multibody problem). However, this problem cannot be solved even for simple nanostrustures. In papers [2 - 4], the density functional theory was developed, and the charge density is used rather than the electron wavefunctions. In particular, the N-electron problem is formulated as N oneelectron equations where each electron interacts with all other electrons via an effective exchange-correlation potential. These interactions are augmented using the charge density. Plane wave sets and total energy pseudo-potential methods can be used to solve the Kohn-Sham one electron equations [2 - 4]. The Hellmann-Feynman theory can be applied to calculate the forces solving the molecular dynamics problem [1 - 5].

## 2.5.1. Schrödinger Equation and Wavefunction Theory

For two point charges, Coulomb's law is given as

$$\mathbf{F} = \frac{q_1 q_2}{4\pi\varepsilon d^2} \mathbf{a}_r = \frac{q_1 q_2}{4\pi\varepsilon} \frac{(\mathbf{r} - \mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|^3},$$

and in the Cartesian coordinate systems one has

$$\mathbf{F} = \frac{q_1 q_2}{4\pi \varepsilon d^2} \mathbf{a}_r = \frac{q_1 q_2}{4\pi \varepsilon d^2} \frac{(x - x') \mathbf{a}_x + (y - y') \mathbf{a}_y + (z - z') \mathbf{a}_z}{\sqrt{(x - x')^2 + (y - y')^2 + (z - z')^2}}.$$

In the case of charge distribution, using the volume charge density  $\rho_v$ , the net force exerted on  $q_1$  by the entire volume charge distribution is the vector sum of the contribution from all differential elements of charge within this distribution. In particular,

$$\mathbf{F} = \frac{q_1}{4\pi\varepsilon} \int_{v} \rho_v \frac{(\mathbf{r} - \mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|^3} dv,$$

see Figure 2.5.1.



Figure 2.5.1. Coulomb's law

In the electrostatic field, the potential energy stored in a region of continuous charge distribution is found as

$$\Pi_V = \frac{1}{2} \int_{v} \mathbf{D} \cdot \mathbf{E} dv = \frac{1}{2} \int_{v} \varepsilon \mathbf{E}^2 dv = \frac{1}{2} \int_{v} \rho_v(\mathbf{r}) V(\mathbf{r}) dv,$$

where  $V(\mathbf{r})$  is the potential; v is the volume containing  $\rho_v$ .

The charge distribution can be given in terms of volume, surface, and line charges. In particular, we have

$$V(\mathbf{r}) = \int_{v} \frac{\rho_{v}(\mathbf{r}')}{4\pi\varepsilon |\mathbf{r} - \mathbf{r}'|} dv',$$
$$V(\mathbf{r}) = \int_{s} \frac{\rho_{s}(\mathbf{r}')}{4\pi\varepsilon |\mathbf{r} - \mathbf{r}'|} ds',$$

and  $V(\mathbf{r}) = \int_{l} \frac{\rho_{l}(\mathbf{r}')}{4\pi\varepsilon |\mathbf{r}-\mathbf{r}'|} dl'$ .

It should be emphasized that that the electric field intensity is found as

$$\mathbf{E}(\mathbf{r}) = \int_{v} \frac{\rho_{v}(\mathbf{r}')}{4\pi\varepsilon} \frac{(\mathbf{r} - \mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|^{3}} dv'$$

Thus, the energy of an electric field or a charge distribution is stored in the field.

The energy, stored in the steady magnetic field is

$$\Pi_M = \frac{1}{2} \int_{v} \mathbf{B} \cdot \mathbf{H} dv$$

The Hamiltonian function, which in section 2.4 was given as

$$H = -\frac{\hbar^2}{2m}\nabla^2 + \Pi,$$
  
one-electron kinetic energy potential energy,

was used to derive the one-electron Schrödinger equation.

To describe the behavior of electrons in a media, one must use Ndimensional Schrödinger equation to obtain the N-electron wavefunction  $\Psi(t, \mathbf{r}_1, \mathbf{r}_2, ..., \mathbf{r}_{N-1}, \mathbf{r}_N)$ .

The Hamiltonian for an isolated N-electron atomic system is

$$H = -\frac{\hbar^{2}}{2m} \sum_{i=1}^{N} \nabla_{i}^{2} - \frac{\hbar^{2}}{2M} \nabla^{2} - \sum_{i=1}^{N} \frac{1}{4\pi\varepsilon} \frac{e_{i}q}{|\mathbf{r}_{i} - \mathbf{r}_{n}|} + \sum_{i\neq j}^{N} \frac{1}{4\pi\varepsilon} \frac{e^{2}}{|\mathbf{r}_{i} - \mathbf{r}_{j}|},$$

where q is the potential due to nucleus;  $e = 1.6 \times 10^{-19}$  C.

For an isolated *N*-electron, *Z*-nucleus molecular system, the Hamiltonian function (Hamiltonian operator) is found to be

$$\begin{split} H &= -\frac{\hbar^2}{2m} \sum_{i=1}^N \nabla_i^2 - \sum_{k=1}^Z \frac{\hbar^2}{2m_k} \nabla_k^2 \\ &- \sum_{i=1}^N \sum_{k=1}^Z \frac{1}{4\pi\varepsilon} \frac{e_i q_k}{\left|\mathbf{r}_i - \mathbf{r}_k\right|} + \sum_{i\neq j}^N \frac{1}{4\pi\varepsilon} \frac{e^2}{\left|\mathbf{r}_i - \mathbf{r}_j\right|} + \sum_{k\neq m}^Z \frac{1}{4\pi\varepsilon} \frac{q_k q_m}{\left|\mathbf{r}_k - \mathbf{r}_m\right|}, \end{split}$$

where  $q_k$  are the potentials due to nuclei.

Terms of the Hamiltonian function 
$$-\frac{\hbar^2}{2m}\sum_{i=1}^N \nabla_i^2$$
 and  $-\sum_{k=1}^Z \frac{\hbar^2}{2m_k} \nabla_k^2$ 

are the multi-body kinetic energy operators.

Term 
$$-\sum_{i=1}^{N}\sum_{k=1}^{Z}\frac{1}{4\pi\varepsilon}\frac{e_{i}q_{k}}{\left|\mathbf{r}_{i}-\mathbf{r}_{k}\right|}$$
 maps the interaction of the electrons with

the nuclei at **R** (the electron-nucleus attraction energy operator).

In the Hamiltonian, the fourth term  $\sum_{i\neq j}^{N} \frac{1}{4\pi\varepsilon} \frac{e^2}{|\mathbf{r}_i - \mathbf{r}_j|}$  gives the

interactions of electrons with each other (the electron-electron repulsion energy operator).

Term 
$$\sum_{k \neq m}^{Z} \frac{1}{4\pi\varepsilon} \frac{q_k q_m}{|\mathbf{r}_k - \mathbf{r}_m'|}$$
 describes the interaction of the Z nuclei at **R**

(the nucleus-nucleus repulsion energy operator).

For an isolated *N*-electron *Z*-nucleus atomic or molecular systems in the Born-Oppenheimer nonrelativistic approximation, we have

 $H\Psi = E\Psi$ .

Thus, the Schrödinger equation is

$$\begin{bmatrix} -\frac{\hbar^2}{2m} \sum_{i=1}^N \nabla_i^2 - \sum_{k=1}^Z \frac{\hbar^2}{2m_k} \nabla_k^2 \\ -\sum_{i=1}^N \sum_{k=1}^Z \frac{1}{4\pi\varepsilon} \frac{e_i q_k}{\left|\mathbf{r}_i - \mathbf{r}_k\right|} + \sum_{i\neq j}^N \frac{1}{4\pi\varepsilon} \frac{e^2}{\left|\mathbf{r}_i - \mathbf{r}_j\right|} + \sum_{k\neq m}^Z \frac{1}{4\pi\varepsilon} \frac{q_k q_m}{\left|\mathbf{r}_k - \mathbf{r}_m\right|} \end{bmatrix} \\ \times \Psi(t, \mathbf{r}_1, \mathbf{r}_2, ..., \mathbf{r}_{N-1}, \mathbf{r}_N) = E(t, \mathbf{r}_1, \mathbf{r}_2, ..., \mathbf{r}_{N-1}, \mathbf{r}_N) \Psi(t, \mathbf{r}_1, \mathbf{r}_2, ..., \mathbf{r}_{N-1}, \mathbf{r}_N).$$

(2.5.1) The total energy  $E(t, \mathbf{r}_1, \mathbf{r}_2, ..., \mathbf{r}_{N-1}, \mathbf{r}_N)$  must be found using the

nucleus-nucleus Coulomb repulsion energy as well as the electron energy. It is very difficult or impossible to solve analytically or numerically the

It is very difficult, or impossible, to solve analytically or numerically the nonlinear partial differential equation (2.5.1). Taking into account only the Coulomb force (electrons and nuclei are assumed to interact due to the Coulomb force only), the Hartree approximation is applied. In particular, the

N-electron wavefunction  $\Psi(t, \mathbf{r}_1, \mathbf{r}_2, ..., \mathbf{r}_{N-1}, \mathbf{r}_N)$  is expressed as a product of N one-electron wavefunctions as

 $\Psi(t, \mathbf{r}_1, \mathbf{r}_2, ..., \mathbf{r}_{N-1}, \mathbf{r}_N) = \psi_1(t, \mathbf{r}_1)\psi_2(t, \mathbf{r}_2)...\psi_{N-1}(t, \mathbf{r}_{N-1})\psi_N(t, \mathbf{r}_N).$ The one-electron Schrödinger equation for *i*th electron is

$$\left(-\frac{\hbar^2}{2m}\nabla_j^2 + \Pi(t,\mathbf{r})\right)\psi_j(t,\mathbf{r}) = E_j(t,\mathbf{r})\psi_j(t,\mathbf{r}).$$
(2.5.2)

In equation (2.5.2), the first term  $-\frac{\hbar^2}{2m}\nabla_j^2$  is the one-electron kinetic energy, and  $\Pi(t, \mathbf{r}_j)$  is the total potential energy. The potential energy includes the potential that *j*th electron feels from the nucleus (considering the ion, the repulsive potential in the case of anion, or attractive in the case of cation). It is obvious that *j*th electron feels the repulsion (repulsive forces) from other electrons. Assumed that the negative electrons charge density  $\rho(\mathbf{r})$  is smoothly distributed in **R**. Hence, the potential energy due interaction (repulsion) of an electron in **R** is

$$\Pi_{Ej}(t,\mathbf{r}) = \int_{\mathbf{R}} \frac{e\rho(\mathbf{r}')}{4\pi\varepsilon |\mathbf{r}-\mathbf{r}'|} d\mathbf{r}'$$

We made some assumptions, and the results derived contradict with some fundamental principles. The Pauli exclusion principle requires that the multi-system wavefunction is an antisymmetric under the interchange of electrons. For two electrons, we have,

$$\Psi(t,\mathbf{r}_{1},\mathbf{r}_{2},...,\mathbf{r}_{j},...,\mathbf{r}_{j+i},...,\mathbf{r}_{N-1},\mathbf{r}_{N}) = -\Psi(t,\mathbf{r}_{1},\mathbf{r}_{2},...,\mathbf{r}_{j+i},...,\mathbf{r}_{j},...,\mathbf{r}_{N-1},\mathbf{r}_{N}).$$

This principle is not satisfied, and the generalizations is needed to integrate the asymmetry phenomenon using the asymmetric coefficient  $\pm 1$ . The Hartree-Fock equation is

$$\begin{bmatrix} -\frac{\hbar^2}{2m} \nabla_j^2 + \Pi(t, \mathbf{r}) \end{bmatrix} \psi_j(t, \mathbf{r}) -\sum_i \int_{\mathbf{R}} \frac{\psi_i^*(t, \mathbf{r}') \psi_j(t, \mathbf{r}') \psi_i(t, \mathbf{r}) \psi_j^*(t, \mathbf{r})}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r}' = E_j(t, \mathbf{r}) \psi_j(t, \mathbf{r}).$$
(2.5.3)

The so-called Hartree-Fock nonlinear partial differential equation (2.5.3), which is difficult to solve, is the approximation because the multibody electron interactions should be considered in general. Thus, the explicit equation for the total energy must be used. This phenomenon can be integrated using the charge density function.

## **2.5.2. Density Functional Theory**

There is a critical need to develop computationally efficient and accurate procedures to perform quantum modeling of nano-scale structures. This section reports the related results and gives the formulation of the modeling problem to avoid the complexity associated with many-electron wavefunctions which result if the classical quantum mechanics formulation is used. The complexity of the Schrödinger equation is enormous even for very simple molecules. For example, the carbon atom has 6 electrons. Can one visualize six-dimensional space? Furthermore, the simplest carbon nanotube molecule has 6 carbon atoms. That is, one has 36 electrons, and 36-dimensional problem results. The difficulties associated with the solution of the Schrödinger equation drastically limit the applicability of the conventional quantum mechanics. The analysis of properties, processes, phenomena, and effects in even simplest nanostructures cannot be studied and comprehended. The problems can be solved applying the Hohenberg-Kohn density functional theory.

The statistical consideration, proposed by Thomas and Fermi in 1927, gives the distribution of electrons in atoms. The following assumptions were used: electrons are distributed uniformly, and there is an effective potential field that is determined by the nuclei charge and the distribution of electrons. Considering electrons distributed in a three-dimensional box, the energy analysis can be performed. Summing all energy levels, one finds the energy. Thus, one can relate the total kinetic energy and the electron charge density. The statistical consideration can be used in order to approximate the distribution of electrons E, and the electron density was derived using the local density approximation concept. The Thomas-Fermi kinetic energy functional is

$$\Gamma_F(\rho_e(\mathbf{r})) = 2.87 \int_{\mathbf{R}} \rho_e^{5/3}(\mathbf{r}) d\mathbf{r} \,,$$

and the exchange energy is found to be

$$E_F(\rho_e(\mathbf{r})) = 0.739 \int_{\mathbf{R}} \rho_e^{4/3}(\mathbf{r}) d\mathbf{r} \, .$$

For homogeneous atomic systems, the application of the electron charge density  $\rho_e(\mathbf{r})$ , considering electrostatic electron-nucleus attraction and electron-electron repulsion, Thomas and Fermi derived the following energy functional

$$E_F(\rho_e(\mathbf{r})) = 2.87 \int_{\mathbf{R}} \rho_e^{5/3}(\mathbf{r}) d\mathbf{r} - q \int_{\mathbf{R}} \frac{\rho_e(\mathbf{r})}{r} d\mathbf{r} + \int_{\mathbf{R}} \int_{\mathbf{R}} \frac{1}{4\pi\varepsilon} \frac{\rho_e(\mathbf{r})\rho_e(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r} d\mathbf{r}' .$$

Following this idea, instead of the many-electron wavefunctions, Kohn proposed to use the charge density for N-electron systems [2, 4]. Only the knowledge of the charge density is needed to perform analysis of molecular dynamics. The charge density is the function that describes the number of

electrons per unit volume (function of three spatial variables x, y and z in the Cartesian coordinate system). The quantum mechanics and quantum modeling must be applied to understand and analyze nanostructures and nanodevices because they operate under the quantum effects.

The total energy of *N*-electron system under the external field is defined in the term of the three-dimensional charge density  $\rho(\mathbf{r})$  [1 - 5]. The complexity is significantly decreased because the problem of modeling of *N*electron *Z*-nucleus systems become equivalent to the solution of equation for one electron. The total energy is given as

$$E(t,\rho(\mathbf{r})) = \Gamma_1(t,\rho(\mathbf{r})) + \Gamma_2(t,\rho(\mathbf{r})) + \int_{\mathbf{R}} \frac{e\rho(\mathbf{r}')}{4\pi\varepsilon|\mathbf{r}-\mathbf{r}'|} d\mathbf{r}' , \qquad (2.5.4)$$

where  $\Gamma_1(t, \rho(\mathbf{r}))$  and  $\Gamma_2(t, \rho(\mathbf{r}))$  are the interacting (exchange) and noninteracting kinetic energies of a single electron in *N*-electron *Z*-nucleus system,

$$\Gamma_{1}(t,\rho(\mathbf{r})) = \int_{\mathbf{R}} \gamma(t,\rho(\mathbf{r}))\rho(\mathbf{r})d\mathbf{r}, \Gamma_{2}(t,\rho(\mathbf{r})) = -\frac{\hbar^{2}}{2m} \sum_{j=1}^{N} \int_{\mathbf{R}} \psi_{j}^{*}(t,\mathbf{r})\nabla_{j}^{2}\psi_{j}(t,\mathbf{r})d\mathbf{r};$$

 $\gamma(t, \rho(\mathbf{r}))$  is the parameterization function.

It should be emphasized that the Kohn-Sham electronic orbitals are subject to the following orthogonal condition

$$\int_{\mathbf{R}} \boldsymbol{\psi}_i^*(t,\mathbf{r}) \boldsymbol{\psi}_j(t,\mathbf{r}) d\mathbf{r} = \boldsymbol{\delta}_{ij} \,.$$

The state of substance (media) depends largely on the balance between the kinetic energies of the particles and the interparticle energies of attraction.

The expression for the total potential energy is easily justified.

Term  $\int_{\mathbf{R}} \frac{e\rho(\mathbf{r}')}{4\pi\varepsilon |\mathbf{r}-\mathbf{r}'|} d\mathbf{r}'$  represents the Coulomb interaction in **R**, and the

total potential energy is a functions of the charge density  $\rho(\mathbf{r})$ .

The total kinetic energy (interactions of electrons and nuclei, and electrons) is integrated into the equation for the total energy. The total energy, as given by (2.5.4), is stationary with respect to variations in the charge density. The charge density is found taking note of the Schrödinger equation. The first-order Fock-Dirac electron charge density matrix is

$$\rho_e(\mathbf{r}) = \sum_{j=1}^N \boldsymbol{\psi}_j^*(t, \mathbf{r}) \boldsymbol{\psi}_j(t, \mathbf{r}) \,. \tag{2.5.5}$$

The three-dimensional electron charge density is a function in three variables (x, y and z in the Cartesian coordinate system). Integrating the electron charge density  $\rho_e(\mathbf{r})$ , one obtains the charge of the total number of electrons N. Thus,

$$\int_{\mathbf{R}} \rho_e(\mathbf{r}) d\mathbf{r} = Ne \; .$$

Hence,  $\rho_e(\mathbf{r})$  satisfies the following properties

$$\begin{split} \rho_{e}(\mathbf{r}) &> 0, \int_{\mathbf{R}} \rho_{e}(\mathbf{r}) d\mathbf{r} = Ne, \\ &\int_{\mathbf{R}} \left| \sqrt{\nabla \rho_{e}(\mathbf{r})} \right|^{2} d\mathbf{r} < \infty, \\ &\int_{\mathbf{R}} \nabla^{2} \rho_{e}(\mathbf{r}) d\mathbf{r} = \infty. \end{split}$$

For the nuclei charge density, we have

$$\rho_n(\mathbf{r}) > 0$$
 and  $\int_{\mathbf{R}} \rho_n(\mathbf{r}) d\mathbf{r} = \sum_{k=1}^{Z} q_k$ .

There exist an infinite number of antisymmetric wavefunctions that give the same  $\rho(\mathbf{r})$ . The minimum-energy concept (energy-functional minimum principle) is applied. The total energy is a function of  $\rho(\mathbf{r})$ , and the socalled ground state  $\Psi$  must minimize the expectation value  $\langle E(\rho) \rangle$ .

The searching density functional  $F(\rho)$ , which searches all  $\Psi$  in the N-electron Hilbert space *H* to find  $\rho(\mathbf{r})$  and guarantee the minimum to the energy expectation value, is expressed as

$$F(\rho) \leq \min_{\substack{\Psi \to \rho \\ \Psi \in H_{\Psi}}} \left\langle \Psi \right| E(\rho) \left| \Psi \right\rangle,$$

where  $H_{\psi}$  is any subset of the N-electron Hilbert space.

Using the variational principle, we have

$$\frac{\Delta E(\rho)}{\Delta f(\rho)} = \int_{\mathbf{R}} \frac{\Delta E(\rho)}{\Delta \rho(\mathbf{r}')} \frac{\Delta \rho(\mathbf{r}')}{\Delta f(\mathbf{r})} d\mathbf{r}' = 0,$$

where  $f(\rho)$  is the nonnegative function.

Thus, 
$$\frac{\Delta E(\rho)}{\Delta f(\rho)}\Big|_{N} = \text{const}$$
.

The solutions to the system of equations (2.5.2) is found using the charge density (2.5.5).

To perform the analysis of nanostructure dynamics, one studies the molecular dynamics. The force and displacement must be found. Substituting the expression for the total kinetic and potential energies in (2.5.4), where the charge density is given by (2.5.5), the total energy  $E(t, \rho(\mathbf{r}))$  results.

The external energy is supplied to control nanoscale actuators, and one has

$$E_{\Sigma}(t,\mathbf{r}) = E_{external}(t,\mathbf{r}) + E(t,\rho(\mathbf{r})).$$
  
Then, the force at position  $\mathbf{r}_{r}$  is  
$$\mathbf{F}_{r}(t,\mathbf{r}) = -\frac{dE_{\Sigma}(t,\mathbf{r})}{d\mathbf{r}_{r}}$$
$$= -\frac{\partial E_{\Sigma}(t,\mathbf{r})}{\partial \mathbf{r}_{r}} - \sum_{j} \frac{\partial E(t,\mathbf{r})}{\partial \psi_{j}(t,\mathbf{r})} \frac{\partial \psi_{j}(t,\mathbf{r})}{\partial \mathbf{r}_{r}} - \sum_{j} \frac{\partial E(t,\mathbf{r})}{\partial \psi_{j}^{*}(t,\mathbf{r})} \frac{\partial \psi_{j}^{*}(t,\mathbf{r})}{\partial \mathbf{r}_{r}}.$$
(2.5.6)

Taking note of

$$\sum_{j} \frac{\partial E(t,\mathbf{r})}{\partial \psi_{j}(t,\mathbf{r})} \frac{\partial \psi_{j}(t,\mathbf{r})}{\partial \mathbf{r}_{r}} + \sum_{j} \frac{\partial E(t,\mathbf{r})}{\partial \psi_{j}^{*}(t,\mathbf{r})} \frac{\partial \psi_{j}^{*}(t,\mathbf{r})}{\partial \mathbf{r}_{r}} = 0,$$

the expression for the force is found from (2.5.6). In particular, one finds

$$\mathbf{F}_{r}(t,\mathbf{r}) = -\frac{\partial E_{external}(t,\mathbf{r})}{\partial \mathbf{r}_{r}} - \int_{\mathbf{R}} \rho(t,\mathbf{r}) \frac{\partial [\Pi_{r}(t,\mathbf{r}) + \Gamma_{r}(t,\mathbf{r})]}{\partial \mathbf{r}_{r}} d\mathbf{r} - \int_{\mathbf{R}} \frac{\partial E_{\Sigma}(t,\mathbf{r})}{\partial \rho(t,\mathbf{r})} \frac{\partial \rho(t,\mathbf{r})}{\partial \mathbf{r}_{r}} d\mathbf{r}.$$

As the wavefunctions converge (the conditions of the Hellmann-Feynman theorem are satisfied), we have

$$\int_{\mathbf{R}} \frac{\partial E(t,\mathbf{r})}{\partial \rho(t,\mathbf{r})} \frac{\partial \rho(t,\mathbf{r})}{\partial \mathbf{r}_{r}} d\mathbf{r} = 0.$$

One can deduce the expression for the wavefunctions, find the charge density, calculate the forces, and study processes and phenomena in nanoscale. The displacement is found using the following equation of motion

$$m\frac{d^2\mathbf{r}}{dt^2} = \mathbf{F}_r(t,\mathbf{r}) ,$$

or

$$m\frac{d^2(\vec{x},\vec{y},\vec{z})}{dt^2} = \mathbf{F}_r(\vec{x},\vec{y},\vec{z}).$$

## 2.5.3. Nanostructures and Molecular Dynamics

Atomistic modeling can be performed using the force field method. The effective interatomic potential for a system of N particles is found as the sum of the second-, third-, fourth-, and higher-order terms as

$$\Pi(\mathbf{r}_{1},...,\mathbf{r}_{N}) = \sum_{i,j=1}^{N} \Pi^{(2)}(\mathbf{r}_{ij}) + \sum_{i,j,k=1}^{N} \Pi^{(3)}(\mathbf{r}_{i},\mathbf{r}_{j},\mathbf{r}_{k}) + \sum_{i,j,k,l=1}^{N} \Pi^{(4)}(\mathbf{r}_{i},\mathbf{r}_{j},\mathbf{r}_{k},\mathbf{r}_{l}) + \dots$$
  
Usually, the interatomic effective pair potential  $\sum_{i,j=1}^{N} \Pi^{(2)}(\mathbf{r}_{ij})$ , which

depends on the interatomic distance  $r_{ij}$  between the nuclei *i* and *j*, dominates. For example, the three-body interconnection terms cannot be omitted only if the angle-dependent potentials are considered. Using the effective ionic charges  $Q_i$  and  $Q_j$ , we have

$$\Pi^{(2)} = \frac{Q_i Q_j}{4\pi \varepsilon r_{ij}} + \phi(\mathbf{r}_{ij})$$

where  $\phi(\mathbf{r}_{ij})$  is the short-range interaction energy due to the repulsion between electron charge clouds, Van der Waals attraction, bond bending and stretching phenomena.

For ionic and partially ionic media we have

$$\phi(r_{ij}) = k_{1ij}e^{-k_{2ij}r_{ij}} - k_{3ij}r_{ij}^{-6} + k_{4ij}r_{ij}^{-12},$$
  
where  $k_{1ij} = \sqrt{k_{1i}k_{1j}}, k_{2ij} = \sqrt{k_{2i}k_{2j}}, k_{3ij} = \sqrt{k_{3i}k_{3j}}$  and  $k_{4ij} = \sqrt{k_{4i}k_{4j}}$ ;  $k_i$   
are the bond energy constants (for example, for *Si* we have  $Q = 2.4, k_3 =$   
0.00069 and  $k_4 = 104$ , for *Al* one has  $Q = 1.4, k_3 = 1690$  and  $k_4 = 278$ , and for  
*Na*<sup>+</sup> we have  $Q = 1, k_3 = 0.00046$  and  $k_4 = 67423$ ).

Another, commonly used approximation is  $\phi(r_{ij}) = k_{5ij}(r_{ij} - r_{Eij})$ , where

 $r_{ij}$  is the bond length,  $r_{ij} = |\mathbf{r}_j - \mathbf{r}_i|$ ;  $r_{Eij}$  is the equilibrium bond distance

Performing the summations in the studied **R**, one finds the potential energy, and the force results. The position (displacement) is represented by the vector **r** which in the Cartesian coordinate system has the components *x*, *y* and *z*. Taking note of the expression for the potential energy  $\Pi(\vec{\mathbf{r}}) = \Pi(\mathbf{r}_1,...,\mathbf{r}_N)$ , one has

$$\sum \vec{F}(\vec{\mathbf{r}}) = -\nabla \Pi(\vec{\mathbf{r}}).$$

From Newton's second law for the system of N particles, we have the following equation of motion

$$m_N \frac{d^2 \vec{\mathbf{r}}_N}{dt^2} + \nabla \Pi(\vec{\mathbf{r}}_N) = 0,$$

$$m_{i} \frac{d^{2}(\vec{x}_{i}, \vec{y}_{i}, \vec{z}_{i})}{dt^{2}} + \frac{\partial \Pi(\vec{x}_{i}, \vec{y}_{i}, \vec{z}_{i})}{\partial(\vec{x}_{i}, \vec{y}_{i}, \vec{z}_{i})} = 0, i = 1, ..., N.$$

To perform molecular modeling one applies the energy-based methods. It was shown that electrons can be considered explicitly. However, it can be assumed that electrons will obey the optimum distribution once the positions of the nuclei in **R** are known. This assumption is based on the Born-Oppenheimer approximation of the Schrödinger equation. This approximation is satisfied because nuclei mass is much greater then electron mass, and thus, nuclei motions (vibrations and rotations) are slow compared with the electrons' motions. Therefore, nuclei motions can be studied separately from electrons dynamics. Molecules can be studied as Z-body systems of elementary masses (nuclei) with springs (bonds between nuclei). The molecule potential energy (potential energy equation) is found using the number of nuclei and bond types (bending, stretching, lengths, geometry, angles, and other parameters), van der Waals radius, parameters of media, etc. The molecule potential energy surface is

 $E_T = E_{bs} + E_b + E_{sb} + E_{ts} + E_W + E_{dd}$ .

Here, the energy due to bond stretching is found using the equation similar to Hook's law. In particular,

 $E_{bs} = k_{bs1}(l - l_0) + k_{bs3}(l - l_0)^3,$ 

where  $k_{bsl}$  and  $k_{bs3}$  are the constants; l and  $l_0$  are the actual and natural bond length (displacement).

The equations for energies due to bond angle bending  $E_b$ , stretch-bend interactions  $E_{sb}$ , torsion strain  $E_{ts}$ , van der Waals interactions  $E_W$ , and dipoledipole interactions  $E_{dd}$  are well known and can be readily applied.

#### 2.6. MOLECULAR WIRES AND MOLECULAR CIRCUITS

The molecular wire consists of the single molecule chain with its end adsorbed to the surface of the gold lead that can cover monolayers of other molecules. Molecular wires connect the nanoscale structures and devices. The current density of carbon nanotubes, 1,4-dithiol benzene (molecular wire) and copper are  $10^{11}$ ,  $10^{12}$  and  $10^6$  electroncs/sec-nm<sup>2</sup>, respectively. The current technology allows one to fill carbon nanotubes with other media (metals, organic and inorganic materials). That is, to connect nanostructures, as shown in Figure 2.6.1, it is feasible to use molecular wires which can be synthesized through the organic synthesis.



Figure 2.6.1. Nanoswitch with carbon nanotube, molecular wire (1,4-dithiol benzene) and nanoantenna

Consider covalent bonds. These bonds occur from sharing the electrons between two atoms. Covalent bonds represent the interactions of two nonmetallic elements, or metallic and nonmetallic elements. Let us study the electron density around the nuclei of two atoms. If electron clouds overlap region passes through on the line joining two nuclei, the bond is called  $\sigma$  bond, see Figure 2.6.2. The overlap may occur between orbitals perpendicularly oriented to the internuclear axis. The resulting covalent bond produces overlap above and below the internuclear axis. Such bond is called  $\pi$  bond. There is no probability of finding the electron on the internuclear axis in a  $\pi$  bond, and the overlap in it is lesser than in the  $\sigma$  bond. Therefore,  $\pi$  bonds are generally weaker than  $\sigma$  bonds.



Figure 2.6.2.  $\sigma$  and  $\pi$  covalent bonds

Single bonds are usually  $\sigma$  bonds. Double bonds, which are much stronger, consist of one  $\sigma$  bond and one  $\pi$  bond, and the triple bond (the strongest one) consists of one  $\sigma$  bond and two  $\pi$  bonds. In the case of carbon nanotubes, the strong interaction among the carbon atoms is guaranteed by the strength of the C-C single bond which holds carbon atoms together in the honeycomb-like hexagon unit (open-ended nanotube).

In molecular wires, the current  $i_m$  is a function of the applied voltage  $u_m$ , and Landauer's formula is

$$i_{m} = \frac{2e}{h} \int_{-\infty}^{+\infty} T(E_{m}, u_{m}) \left( \frac{1}{e^{\frac{E_{m} - \mu_{p1}}{k_{B}T}} + 1} - \frac{1}{e^{\frac{E_{m} - \mu_{p2}}{k_{B}T}} + 1} \right) dE_{m}$$

where  $\mu_{p1}$  and  $\mu_{p2}$  are the electrochemical potentials,  $\mu_{p1} = E_F + \frac{1}{2}eu_m$ and  $\mu_{p2} = E_F - \frac{1}{2}eu_m$ ;  $E_F$  is the equilibrium Fermi energy of the source;  $T(E_m, u_m)$  is the transmission function obtained using the molecular energy levels and coupling.

We have [7]

$$i_m = \frac{2e}{h} \int_{\mu_{p1}}^{\mu_{p2}} T(E_m, u_m) \frac{1}{4k_B T} \operatorname{sech}^2\left(\frac{E_m}{2k_B T}\right) dE_m, k_B T = 26 \operatorname{meV}.$$

Thus, the molecular wire conductance is found as

$$c_m = \frac{\partial i_m}{\partial u_m} \approx \frac{e^2}{h} [T(\mu_{p1}) + T(\mu_{p2})].$$

Using molecular wires and molecular circuits (which form molecular electronic switches and devices), the designer can synthesize polyphenylenebased rectifying diodes, switching logics, as well as other devices. It must be emphasized that the results given above are based upon the thorough and comprehensive overview of molecular circuits reported in [2]. Figure 2.6.3 illustrates the molecular circuitry for a polyphenylene-based molecular rectifying diode. This diode can be fabricated using the chemically doped polyphenylene-based molecular wire as the constructive medium. The electron donating substituent group X (n-dopant) and the electron withdrawing substituent group Y (p-dopant) form two intermolecular dopant groups. These groups are separated by the semi-insulating group R (potential energy barrier) from an electron acceptor subcomplex. Thus, the R group serves as an insulation (barrier) between the donor X and acceptor Y. The semi-insulating group R can be synthesized using the aliphatic (sigmabounded methylene) or dimethylene groups. To guarantee electrical isolation between the molecular circuitry and gold substrate, additional barrier is used as shown in Figure 2.6.3.



Figure 2.6.3. Molecular circuit and schematics of electron orbital energylevels levels for a polyphenylene-based molecular rectifying diode [2]

In computers, DSPs, microcontrollers, and microprocessors, simple arithmetic functions, e.g. addition and subtraction, are implemented using combinational register-level components. Adders and subtracters (which have carry-in and carry-out lines) of fixed-point binary numbers are basic register-level components from which other arithmetic circuits are formed. Other arithmetic components are widely used, and comparators compare the magnitude of two binary numbers. These arithmetic elements can be fabricated using molecular circuit technology. In fact, to perform logic operations (AND, OR, XOR, and NOT gates) and arithmetic, diode-based molecular electronic digital circuits and nanologic gates can be synthesized using single nanoscale molecule structures. It should be emphasized that the size of these molecular logic gates is within 5 nm (thousand times less then the logic gates used in current computers which are fabricated using most advanced CMOS technologies). Using diode-diode logic, AND and OR logic gates are designed using molecular circuits, and the schematics are illustrated in Figures 2.6.4 and 2.6.5. The molecular AND logic gate is designed by connecting in parallel two diodes. The doped polyphenylenebased diodes are connected through polyphenylene-based wire. The semiinsulating group R (potential energy barrier) reduces power dissipation and maintains a distinct output voltage signal at the terminal C when the A and Binputs (carry-in lines) cause the molecular diodes to be forward biased (current flows through diodes). The difference between the AND and OR gates is that the diode orientations, see Figures 2.6.4 and 2.6.5. The diodebased molecular electronic digital circuit (XOR gate) is illustrated in Figure 2.6.6, and the truth table is also documented. The total voltage applied across the XOR gate is the sum of the voltage drop across the input resistances plus the voltage drop across the resonant tunneling diode (RTD). The effective resistance of the logic gate, containing two rectifying diodes, differs whether one or both parallel signals (A and B can be 1 or 0) are on. If A and B are on (1), the effective resistance is half. Thus, according to Ohm's law, there are two possible cases: full voltage drop and half voltage drop which distinct the XOR gate operating points. Figure 2.6.7 documents the molecular half adder which is synthesized using the AND and XOR molecular gates. Here, A and B denote the one-bit binary signals (inputs) to the adder, while S (sum bit) and C (carry bit) are one-bit binary signals (outputs). The XOR gate gives the sum of two bits, and the resulting output is at lead S. The AND gate forms the sum of two bits, and the resulting output is at lead C. The molecular full adder is given in Figure 2.6.8.





(b)





Figure 2.6.4. Molecular circuit and schematics of AND molecular gate [2]





Figure 2.6.5. Molecular circuit and schematics of OR molecular gate [2]



Figure 2.6.6. Molecular circuit and schematics of XOR molecular gate [2]



Figure 2.6.7. Molecular circuit and schematics of molecular half adder [2]





Figure 2.6.8. Molecular circuit and schematics of molecular full adder [2]

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#### 2.7. THERMOANALYSIS AND HEAT EQUATION

It is known that the heat propagates (flows) in the direction of decreasing temperature, and the rate of propagation is proportional to the gradient of the temperature. Using the thermal conductivity of the media  $k_t$  and the temperature T(t, x, y, z), one has the following equation to calculate the velocity of the heat flow

$$\vec{\mathbf{v}}_h = -k_t \nabla T(t, x, y, z). \tag{2.7.1}$$

Consider the region **R** and let *s* is the boundary surface. Using the divergence theorem, from (2.7.1) one obtains the partial differential equation (heat equation) which is expressed as

$$\frac{\partial T(t, x, y, z)}{\partial t} = k^2 \nabla^2 T(t, x, y, z), \qquad (2.7.2)$$

where k is the thermal diffusivity of the media.

We have

$$k = \frac{k_t}{k_h k_d},$$

where  $k_h$  and  $k_d$  are the specific heat and density constants.

Solving partial differential equation (2.7.2), which is subject to the initial and boundary conditions, one finds the temperature of the homogeneous media. In the Cartesian coordinate system, one has

$$\nabla^2 T(t, x, y, z) = \frac{\partial^2 T(t, x, y, z)}{\partial x^2} + \frac{\partial^2 T(t, x, y, z)}{\partial y^2} + \frac{\partial^2 T(t, x, y, z)}{\partial z^2}.$$

Using the Laplacian of T in the cylindrical and spherical coordinate systems, one can reformulate the thermoanalysis problem using different coordinates in order to straightforwardly solve the problem.

It the heat flow is steady (time-invariant), then

$$\frac{\partial T(t, x, y, z)}{\partial t} = 0.$$

Hence, three-dimensional heat equation (2.7.2) becomes Laplace's equation as given by

$$0 = k^2 \nabla^2 T(t, x, y, z).$$

The two-dimensional heat equation is

$$\frac{\partial T(t, x, y)}{\partial t} = k^2 \nabla^2 T(t, x, y) = k^2 \left( \frac{\partial^2 T(t, x, y)}{\partial x^2} + \frac{\partial^2 T(t, x, y)}{\partial y^2} \right).$$
  
If  
$$\frac{\partial T(t, x, y)}{\partial t} = 0,$$

one has

$$0 = k^{2} \nabla^{2} T(t, x, y) = k^{2} \left( \frac{\partial^{2} T(t, x, y)}{\partial x^{2}} + \frac{\partial^{2} T(t, x, y)}{\partial y^{2}} \right)$$

Using initial and boundary conditions, this partial differential equation can be solved using Fourier series, Fourier integrals, Fourier transforms.

The so-called one-dimensional heat equation is

$$\frac{\partial T(t,x)}{\partial t} = k^2 \frac{\partial^2 T(t,x)}{\partial x^2}$$

with initial and boundary conditions

$$T(t_0, x) = T_t(x), T(t, x_0) = T_0 \text{ and } T(t, x_f) = T_f.$$

A large number of analytical and numerical methods are available to solve the heat equation.

The analytic solution if

$$T(t, x_0) = 0$$
 and  $T(t, x_f) = 0$ 

is given as

$$T(t,x) = \sum_{i=1}^{\infty} B_i \sin \frac{i\pi x}{x_f} e^{-i^2 \frac{k^2 \pi^2}{x_f^2} t}$$
$$B_i = \frac{2}{x_f} \int_{x_0}^{x_f} T_t(x) \sin \frac{i\pi x}{x_f} dx.$$

Assuming that  $T_t(x)$  is piecewise continuous in  $x \in [x_0 \ x_f]$  and has one-sided derivatives at all interior points, one finds the coefficients of the Fourier sine series  $B_i$ .

#### Example 2.7.1.

Consider the copper bar with length 0.1 mm. The thermal conductivity, specific heat and density constants are  $k_t = 1$ ,  $k_h = 0.09$  and  $k_d = 9$ . The initial and boundary conditions are

$$T(0,x) = T_t(x) = 0.2 \sin \frac{\pi x}{0.001}, \ T(t,0) = 0 \text{ and } T(t,0.001) = 0.$$

Find the temperature in the bar as a function of the position and time.

Solution.

From the general solution

$$T(t,x) = \sum_{i=1}^{\infty} B_i \sin \frac{i\pi x}{x_f} e^{-i^2 \frac{k^2 \pi^2}{x_f^2} t}$$

using the initial condition, we have

$$T(0,x) = \sum_{i=1}^{\infty} B_i \sin \frac{i\pi x}{x_f} = 0.2 \sin \frac{\pi x}{0.001}$$

Thus,  $B_1 = 0.2$  and all other  $B_i$  coefficients are zero.n

Hence, the solution (temperature as the function of the position and time) is found to be

$$T(t,x) = \sum_{i=1}^{\infty} B_i \sin \frac{i\pi x}{x_f} e^{-i^2 \frac{k^2 \pi^2}{x_f^2} t} = B_1 \sin \frac{\pi x}{x_f} e^{-\frac{k^2 \pi^2}{x_f^2} t}$$
$$= 0.2 \sin \frac{\pi x}{0.001} e^{-1.5 \times 10^7 t}.$$

# **CHAPTER 3**

## STRUCTURAL DESIGN, MODELING, AND SIMULATION

### **3.1. NANO- AND MICROELECTROMECHANICAL SYSTEMS**

#### **3.1.1.** Carbon Nanotubes and Nanodevices

Carbon nanotubes, discovered in 1991, are molecular structures which consist of graphene cylinders closed at either end with caps containing pentagonal rings. Carbon nanotubes are produced by vaporizing carbon graphite with an electric arc under an inert atmosphere. The carbon molecules organize a perfect network of hexagonal graphite rolled up onto itself to form a hollow tube. Buckytubes are extremely strong and flexible and can be single- or multi-walled. The standard arc-evaporation method produces only multilayered tubes, and the single-layer uniform nanotubes (constant diameter) were synthesis only a couple years ago. One can fill nanotubes with any media, including biological molecules. The carbon nanotubes can be conducting or insulating medium depending upon their structure.

A single-walled carbon nanotube (one atom thick), which consists of carbon molecules, is illustrated in Figure 3.1.1. The application of these nanotubes, formed with a few carbon atoms in diameter, provides the possibility to fabricate devices on an atomic and molecular scale. The diameter of nanotube is 100000 times less that the diameter of the sawing needle. The carbon nanotubes, which are much stronger than steel wire, are the perfect conductor (better than silver), and have thermal conductivity better than diamond. The carbon nanotubes, manufactured using the carbon vapor technology, and carbon atoms bond together forming the pattern. Single-wall carbon nanotubes are manufactured using laser vaporization, arc technology, vapor growth, as well as other methods. Figure 3.1.2. illustrates the carbon ring with six atoms. When such a sheet rolls itself into a tube so that its edges join seamlessly together, a nanotube is formed.



Figure 3.1.1. Single-walled carbon nanotube



Figure 3.1.2. Single carbon nanotube ring with six atoms

Carbon nanotubes, which allow one to implement the molecular wire technology in nanoscale ICs, are used in NEMS and MEMS. Two slightly displaced (twisted) nanotube molecules, joined end to end, act as the diode. Molecular-scale transistors can be manufactured using different alignments. There are strong relationships between the nanotube electromagnetic properties and its diameter and degree of the molecule twist. In fact, the electromagnetic properties of the carbon nanotubes depend on the molecule's twist, and Figures 3.1.3 illustrate possible configurations. If the graphite sheet forming the single-wall carbon nanotube is rolled up perfectly (all its hexagons line up along the molecules axis), the nanotube is a perfect conductor. If the graphite sheet rolls up at a twisted angle, the nanotube exhibits the semiconductor properties. The carbon nanotubes, which are much stronger than steel wire, can be added to the plastic to make the conductive composite materials.



Figure 3.1.3. Carbon nanotubes

The vapor grown carbon nanotubes with N layers are illustrated in Figure 3.1.4, and the industrially manufactured nanotubes have  $\Delta$ ngstroms diameter and length.



Figure 3.1.4. N-layer carbon nanotube

The carbon nanotubes can be organized as large-scale complex neural networks to perform computing and data storage, sensing and actuation, etc. The density of ICs designed and manufactured using the carbon nanotube technology thousands time exceed the density of ICs developed using convention silicon and silicon-carbide technologies. Metallic solids (conductor, for example copper, silver, and iron) consist of metal atoms. These metallic solids usually have hexagonal, cubic, or bodycentered cubic close-packed structures (see Figure 3.1.5). Each atom has 8 or 12 adjacent atoms. The bonding is due to valence electrons that are delocalized thought the entire solid. The mobility of electrons is examined to study the conductivity properties.



b) hexagonal packing; c) body-centered cubic

More than two electrons can fit in an orbital. Furthermore, these two electrons must have two opposite spin states (spin-up and spin-down). Therefore, the spins are said to be paired. Two opposite directions in which the electron spins (up  $+\frac{1}{2}$  and down  $-\frac{1}{2}$ ) produce oppositely directed magnetic fields. For an atom with two electrons, the spin may be either parallel (S = 1) or opposed and thus cancel (S = 0). Because of spin pairing, most molecules have no net magnetic field, and these molecules are called diamagnetic (in the absence of the external magnetic field, the net magnetic field produced by the magnetic fields of the orbiting electrons and the magnetic fields produced by the electron spins is zero). The external magnetic field will produce no torque on the *diamagnetic* atom as well as no realignment of the dipole fields. Accurate quantitative analysis can be performed using the quantum theory. Using the simplest atomic model, we assume that a positive nucleus is surrounded by electrons which orbit in various circular orbits (an electron on the orbit can be studied as a current loop, and the direction of current is opposite to the direction of the electron rotation). The torque tends to align the magnetic field, produced by the orbiting electron, with the external magnetic field. The electron can have a spin magnetic moment of  $\pm 9' 10^{-24}$  A-m<sup>2</sup>. The plus and minus signs that there are two possible electron alignments; in particular, aiding or opposing to the external magnetic field. The atom has many electrons, and only the spins of those electrons in shells which are not completely filed contribute to the atom magnetic moment. The nuclear spin negligible contributes to the atom moment. The magnetic properties of the media (diamagnetic, superparamagnetic. ferromagnetic, antiferromagnetic. paramagnetic. ferrimagnetic) result due to the combination of the listed atom moments Let us discuss the *paramagnetic* materials. The atom can have small magnetic moment, however, the random orientation of the atoms results that the net torque is zero. Thus, the media do not show the magnetic effect in the absence the external magnetic field. As the external magnetic field is applied, due to the atom moments, the atoms will align with the external field. If the atom has large dipole moment (due to electron spin moments), the material is called ferromagnetic. In antiferromagnetic materials, the net magnetic moment is zero, and thus the ferromagnetic media are only slightly affected by the external magnetic field.

Using carbon nanotubes, one can design electromechanical and electromagnetic nanoswitches, which are illustrated in Figure 3.1.6.



Figure 3.1.6. Application of carbon nanotubes in nanoswitches

# 3.1.2. Microelectromechanical Systems and Microdevices

Different MEMS have been discussed, and it was emphasized that MEMS can be used as actuators, sensors, and actuators-sensors. Due to the limited torque and force densities, MEMS usually cannot develop high torque and force, and large-scale cooperative MEMS are used, e.g. multilayer configurations. In contrast, these characteristics (power, torque, and force densities) are not critical in sensor applications. Therefore, MEMS are widely used as sensors. Signal-level signals, measured by sensors, are fed to analog or digital controllers, and sensor design, signal processing, and interfacing are extremely important in engineering practice. Smart integrated sensors are the sensors in which in addition to sensing the physical variable, data acquisition, filtering, data storage, communication, interfacing, and networking are embedded. Thus, while the primary component is the sensing element (microstructure), multifunctional integration of sensors and ICs is the current demand. High-performance accelerometers, manufactured by Analog Devices using integrated microelectromechanical system technology (*i*MEMS), are studied in this section. In addition, the application of smart integrated sensors is discussed.

We study the dual-axis, surface-micromachined ADXL202 accelerometer (manufactured on a single monolithic silicon chip) which combines highly accurate acceleration sensing motion microstructure (proof mass) and signal processing electronics (signal conditioning ICs). As documented in the Analog Device Catalog data (which is attached), this accelerometer, which is manufactured using the *i*MEMS technology, can measure dynamic positive and negative acceleration (vibration) as well as static acceleration (force of gravity). The functional block diagram of the ADXL202 accelerometer with two digital outputs (ratio of pulse width to period is proportional to the acceleration) is illustrated in Figure 3.1.7.



Figure 3.1.7. Functional block diagram of the ADXL202 accelerometer

Polysilicon surface-micromachined sensor motion microstructure is fabricated on the silicon wafer by depositing polysilicon on the sacrificial oxide layer which is then etched away leaving the suspended proof mass (beam). Polysilicon springs suspend this proof mass over the surface of the wafer. The deflection of the proof mass is measured using the capacitance difference, see Figure 3.1.8.



Figure 3.1.8. Accelerometer structure: proof mass, polysilicon springs, and sensing elements (fixed outer plates and central movable plates attached to the proof mass)

The proof mass (1.3 mm, 2 mm thick) has movable plates which are shown in Figure 3.1.8. The air capacitances  $C_1$  and  $C_2$  (capacitances between the movable plate and two stationary outer plates) are functions of the corresponding displacements  $x_1$  and  $x_2$ .

The parallel-plate capacitance is proportional to the overlapping area between the plates (125 mm 2 mm) and the displacement (up to 1.3 mm). In particular, neglecting the fringing effects (nonuniform distribution near the edges), the parallel-plate capacitance is

$$C = \boldsymbol{e} \frac{A}{d} = \boldsymbol{e}_A \frac{1}{d} \,,$$

where e is the permittivity; A is the overlapping area; d is the displacement between plates;  $e_A = eA$ 

If the acceleration is zero, the capacitances  $C_1$  and  $C_2$  are equal because  $x_1 = x_2$  (in ADXL202 accelerometer,  $x_1 = x_2 = 1.3$  **m** m).

Thus, one has
$$C_1 = C_2$$
,  
where  $C_1 = \boldsymbol{e}_A \frac{1}{x_1}$  and  $C_2 = \boldsymbol{e}_A \frac{1}{x_2}$ 

The proof mass (movable microstructure) displacement x results due to acceleration. If  $x^1 = 0$ , we have the following expressions for capacitances

$$C_1 = \mathbf{e}_A \frac{1}{x_1 + x}$$
 and  $C_2 = \mathbf{e}_A \frac{1}{x_2 - x} = \mathbf{e}_A \frac{1}{x_1 - x}$ .

The capacitance difference is found to be

$$\mathsf{D}C = C_1 - C_2 = 2\mathbf{e}_A \frac{x}{x^2 - x_1^2}$$

Measuring DC, one finds the displacement x by solving the following nonlinear algebraic equation

$$\mathsf{D}Cx^2 - 2\mathbf{e}_A x - \mathsf{D}Cx_1^2 = 0.$$

For small displacements, neglecting the term  $DCx^2$ , one has

$$x \gg -\frac{x_1^2}{2\boldsymbol{e}_A} \mathsf{D}C.$$

Hence, the displacement is proportional to the capacitance difference DC.

For an ideal spring, Hook's law states that the spring exhibits a restoring force  $F_s$  which is proportional to the displacement x. Hence, we have the following formula

 $F_s = k_s x$ ,

where  $k_{\rm s}$  is the spring constant.

From Newton's second law of motion, neglecting friction, one writes

$$ma = m \frac{d^2 x}{dt^2} = k_s x \, .$$

Thus, the displacement due to the acceleration is

$$x = \frac{m}{k_s} a$$
,

while the acceleration, as a function of the displacement, is given as

$$a = \frac{k_s}{m} x$$

Then, making use of the measured (calculated)  $\mathsf{D} C$  , the acceleration is found to be

$$a = -\frac{k_s x_1^2}{2m\boldsymbol{e}_A} \mathsf{D} C \,.$$

Making use of Newton's second law of motion, we have

$$ma = m \frac{d^2 x}{dt^2} = \int_{\text{spring force}} f_s(x) ,$$

where  $f_s(x)$  is the spring restoring force which is a nonlinear function of the displacement, and  $f_s(x) = k_{s1}x + k_{s2}x^2 + k_{s3}x^3$ ;  $k_{s1}$ ,  $k_{s2}$  and  $k_{s3}$  are the spring constants.

Therefore, the following nonlinear equation results

$$ma = k_{s1}x + k_{s2}x^{2} + k_{s3}x^{3}.$$
  
Thus,  
$$a = \frac{1}{m} \left( k_{s1}x + k_{s2}x^{2} + k_{s3}x^{3} \right)$$
$$x^{2}.$$

where  $x \gg -\frac{x_1^2}{2\boldsymbol{e}_A} DC$ .

This equation can be used to calculate the acceleration a using the capacitance difference DC.

Two beams (proof masses which are motion microstructures) can be placed orthogonally to measure the accelerations in the X and Y axis (ADXL250), as well as the movable plates can be mounted along the sides of the square beam (ADXL202). Figures 3.1.9 and 3.1.10 document the ADXL202 and ADXL250 accelerometers.



Figure 3.1.9. ADXL202 accelerometer: proof mass with fingers and ICs (courtesy of Analog Devices)



Figure 3.1.10.ADXL250 accelerometer: proof masses with fingers and ICs (courtesy of Analog Devices)

Responding to acceleration, the proof mass moves due to the mass of the movable microstructure (m) along X and Y axes relative to the stationary member (accelerometer). The motion of the proof mass is constrained, and the polysilicon springs hold the movable microstructure (beam). Assuming that the polysilicon springs and the proof mass obey Hook's and Newton's laws, it was shown that the acceleration is found using the following formula

$$a = \frac{k_s}{m} x \, .$$

The fixed outer plates are excited by two square wave 1 MHz signals of equal magnitude that are 180 degrees out of phase from each other. When the movable plates are centered between the fixed outer plates we have  $x_1 = x_2$ . Thus, the capacitance difference DC and the output signal is zero. If the proof mass (movable microstructure) is displaced due to the acceleration, we have DC<sup>1</sup> 0. Thus, the capacitance imbalance, and the amplitude of the output voltage is a function (proportional) to the displacement of the proof mass *x*. Phase demodulation is used to determine the sign (positive or negative) of acceleration. The ac signal is amplified by buffer amplifier and demodulated by a synchronous synchronized demodulator. In particular, the filtered signal is converted to a PWM signal by the 14-bit duty cycle modulator. The zero acceleration produces 50% duty cycle. The PWM output fundamental period can be set from 0.5 to 10ms.

There is a wide range of industrial systems where smart integrated sensors are used. For example, accelerometers can be used for

- 1. active vibration control and diagnostics,
- 2. health and structural integrity monitoring,
- 3. internal navigation systems,
- 4. earthquake-actuated safety systems,
- 5. seismic instrumentation: monitoring and detection,
- 6. etc.

Current research activities in analysis, design, and optimization of flexible structures (aircraft, missiles, manipulators and robots, spacecraft, surface and underwater vehicles) are driven by requirements and standards which must be guaranteed. The vibration, structural integrity, and structural behavior are addressed and studied. For example, fundamental, applied, and experimental research in aeroelasticity and structural dynamics are conducted to obtain fundamental understanding of the basic phenomena involved in flutter, force and control responses, vibration, and control. Through optimization of aeroelastic characteristics as well as applying passive and active vibration control, the designer minimizes vibration and noise, and current research integrates development of aeroelastic models and diagnostics to predict stalled/whirl flutter, force and control responses, unsteady flight, aerodynamic flow, etc. Vibration control is a very challenging problem because the designer must account complex interactive physical phenomena (elastic theory, structural and continuum mechanics, radiation and transduction, wave propagation, chaos, et cetera). Thus, it is necessary to accurately measure the vibration, and the accelerometers, which allow one to measure the acceleration in the micro-g range, are used. The application of the MEMS-based accelerometers ensures small size, low cost, ruggedness, hermeticity, reliability, and flexible interfacing with microcontrollers, microprocessors, and DSPs.

High-accuracy low-noise accelerometers can be used to measure the velocity and position. This provides the back-up in the case of the GPS system failures or in the dead reckoning applications (the initial coordinates and speed are assumed to be known). Measuring the acceleration, the velocity and position in the *xy* plane are found using integration. In particular,

$$v_x(t) = \mathop{\bigotimes}\limits_{t_0}^{t_f} a_x(t)dt , v_y(t) = \mathop{\bigotimes}\limits_{t_0}^{t_f} a_y(t)dt ,$$
  
$$x_x(t) = \mathop{\bigotimes}\limits_{t_0}^{t_f} v_x(t)dt , x_y(t) = \mathop{\bigotimes}\limits_{t_0}^{t_f} v_y(t)dt .$$

The Analog Devices data for *i*MEMS accelerometers ADXL202/ADXL210 and ADXL150/ADXL250 are given below (courtesy of Analog Devices).

It is important to emphasize that microgyroscope have been designed, fabricated, and deployed using the similar technology as *i*MEMS accelerometers. In particular, using the difference capacitance (between the movable rotor and stationary stator plates), the angular acceleration is measured. The butterfly-shaped polysilicon rotor suspended above the substrate, and Figure 3.1.11 illustrates the microgyroscope.



Figure 3.1.11. Angular microgyroscope structure

Using the experimental data (input-output dynamic behavior and Bode plots), the mathematical model of microaccelerometers is obtained in the form of ordinary differential equations, and the coefficients (accelerometer parameters) are identified. The dominant microaccelerometer dynamics is described by a system of six linear differential equations

$$\frac{dx}{dt} = Ax + Bu, \ y = Cx,$$

where the matrices of coefficients are

$$\begin{aligned} & \begin{pmatrix} \acute{\mathbf{e}} & 2.6^{\prime} 10^{4} & -2.7^{\prime} 10^{10} & -4.2^{\prime} 10^{14} & -1.5^{\prime} 10^{20} & -9^{\prime} 10^{23} & -3.7^{\prime} 10^{27} \grave{\mathbf{U}} \\ & \acute{\mathbf{e}} & 1 & 0 & 0 & 0 & 0 & \acute{\mathbf{U}} \\ & \acute{\mathbf{e}} & 0 & 1 & 0 & 0 & 0 & \acute{\mathbf{U}} \\ & \acute{\mathbf{e}} & 0 & 0 & 1 & 0 & 0 & \acute{\mathbf{U}} \\ & \acute{\mathbf{e}} & 0 & 0 & 0 & 1 & 0 & 0 & \acute{\mathbf{U}} \\ & \acute{\mathbf{e}} & 0 & 0 & 0 & 1 & 0 & \acute{\mathbf{U}} \\ & \acute{\mathbf{e}} & 0 & 0 & 0 & 1 & 0 & \acute{\mathbf{U}} \\ & \acute{\mathbf{e}} & \acute{\mathbf{U}} & \acute{\mathbf{U}} & \acute{\mathbf{U}} \\ & \acute{\mathbf{E}} & \acute{\mathbf{U}} & \acute{\mathbf{U}} \\ & \acute{\mathbf{E}} & \acute{\mathbf{U}} & \acute{\mathbf{U}} \\ & \acute{\mathbf{U} & \acute{\mathbf{U}} \\ & \acute{\mathbf{U}} & \acute{\mathbf{U}} \\ & \acute{\mathbf{U}} & \acute{\mathbf{U} & \acute{\mathbf{U}} \\$$

The accelerometer output, which is the measured acceleration *a*, was denoted as y, y = a. It is evident that the acceleration is a function of the state variable  $x_6$ . All other five states model the proof mass (motion microstructure) and microICs (oscillator, demodulator, modulator, filter, et cetera) dynamics.

The eigenvalues are found to be

- 5.9  $\cdot$  10<sup>3</sup> ±*i*1.4  $\cdot$  10<sup>5</sup>, - 4.2  $\cdot$  10<sup>3</sup> ±*i*8.8  $\cdot$  10<sup>4</sup>, - 3  $\cdot$  10<sup>3</sup> ±*i*4  $\cdot$  10<sup>3</sup>.

This mathematical model of the microaccelerometer can be used in systems analysis, diagnostics, and design of a wide variety of systems where iMEMS are used.



## Low Cost ±2 g/±10 g Dual Axis *i*MEMS<sup>®</sup> Accelerometers with Digital Output

## ADXL202/ADXL210

#### FEATURES

2-Axis Acceleration Sensor on a Single IC Chip Measures Static Acceleration as Well as Dynamic Acceleration

Duty Cycle Output with User Adjustable Period Low Power <0.6 mA

Faster Response than Electrolytic, Mercury or Thermal Tilt Sensors

Bandwidth Adjustment with a Single Capacitor Per Axis 5 mg Resolution at 60 Hz Bandwidth

+3 V to +5.25 V Single Supply Operation 1000 g Shock Survival

#### APPLICATIONS

2-Axis Till Sensing Computer Peripherals Inertial Navigation Seismic Monitoring Vehicle Security Systems Battery Powered Motion Sensing

#### GENERAL DESCRIPTION

The ADXL202/ADXL210 are low cost, low power, complete 2-axis accelerometers with a measurement range of either  $\pm 2 g/\pm 10 g$ . The ADXL202/ADXL210 can measure both dynamic acceleration (e.g., vibration) and static acceleration (e.g., gravity).

The outputs are digital signals whose duty cycles (ratio of pulsewidth to period) are proportional to the acceleration in each of the 2 sensitive axes. These outputs may be measured directly with a microprocessor counter, requiring no A/D converter or glue logic. The output period is adjustable from 0.5 ms to 10 ms via a single resistor ( $R_{\rm SFD}$ ). If a voltage output is desired, a voltage output proportional to acceleration is available from the X<sub>FBT</sub> and Y<sub>FBT</sub> pins, or may be reconstructed by filtering the duty cycle outputs.

The bandwidth of the ADXL202/ADXL210 may be set from 0.01 Hz to 5 kHz via capacitors  $C_x$  and  $C_y$ . The typical noise floor is  $500 \, \mu g/\sqrt{Hz}$  allowing signals below 5 mg to be resolved for bandwidths below 60 Hz.

The ADXL202/ADXL210 is available in a hermetic 14-lead Surface Mount CERPAK, specified over the 0°C to +70°C commercial or -40°C to +85°C industrial temperature range.

#### FUNCTIONAL BLOCK DIAGRAM



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ADXL202/ADXL210-SPECIFICATIONS	$ \begin{array}{l} (T_{\text{A}}=T_{\text{MIN}} \text{ to } T_{\text{MAX}}, \ T_{\text{A}}=+25^{\circ}\text{C} \ \text{for J Grade only, } V_{\text{DD}}=+5 \ \text{V}, \\ R_{\text{SET}}=125 \ \text{k}\Omega, \ \text{Acceleration}=0 \ \text{g}, \ \text{unless otherwise noted}) \end{array} $
--------------------------------	--

		AD	ADXL202/JQC/AQC			ADXL210/JQC/AQC		
Parameter	Conditions	Min	Тур	Max	Min	Тур	Max	Units
SENSOR INPUT Measurement Range <sup>1</sup> Nonlinearity Alignment Error <sup>2</sup> Alignment Error Transverse Sensitivity <sup>3</sup>	Each Axis Best Fit Straight Line X Sensor to Y Sensor	±1.5			±8			g % of FS Degrees Degrees %
SENSITIVITY Duty Cycle per g Sensitivity, Analog Output Temperature Drift <sup>4</sup>	Each Axis T1/T2 @ +25°C At Pins $X_{FILT}$ , $Y_{FILT}$ $\Delta$ from +25°C	10	12.5 312 ±0.5	15	3.2	4.0 100 ±0.5	4.8	%/g mV/g % Rdg
ZERO g BIAS LEVEL 0 g Duty Cycle Initial Offset 0 g Duty Cycle vs. Supply 0 g Offset vs. Temperature <sup>4</sup>	Each Axis T1/T2 Δ from +25°C	25	50 ±2 1.0 2.0	75 4.0	42	50 ±2 1.0 2.0	58 4.0	% g %/V mg/°C
NOISE PERFORMANCE Noise Density <sup>5</sup>	@ +25°C		500	1000		500	1000	µg/√Hz
FREQUENCY RESPONSE 3 dB Bandwidth 3 dB Bandwidth Sensor Resonant Frequency	Duty Cycle Output At Pins $X_{FILT}$ , $Y_{FILT}$		500 5 10			500 5 14		Hz kHz kHz
FILTER R <sub>FILT</sub> Tolerance Minimum Capacitance	32 k $\Omega$ Nominal At X <sub>FILT</sub> , Y <sub>FILT</sub>	1000	±15		1000	±15		% pF
SELF TEST Duty Cycle Change	Self-Test "0" to "1"		10			10		%
DUTY CYCLE OUTPUT STAGE F <sub>SET</sub> F <sub>SET</sub> Tolerance Output High Voltage Output Low Voltage T2 Drift vs. Temperature Rise/Fall Time	$\begin{split} R_{SET} &= 125 \text{ k}\Omega\\ I &= 25 \mu\text{A}\\ I &= 25 \mu\text{A} \end{split}$	0.7 V <sub>s</sub> – 2	125 MΩ/ 200 mV 35 200	R <sub>SET</sub> 1.3 200	0.7 V <sub>s</sub> – 2	125 MΩ/ 200 mV 35 200	R <sub>SET</sub> 1.3 200	kHz mV mV ppm/°C ns
POWER SUPPLY Operating Voltage Range Specified Performance Quiescent Supply Current Turn-On Time <sup>6</sup>	То 99%	3.0 4.75	0.6 160 С <sub>гит</sub>	5.25 5.25 1.0 + 0.3	2.7 4.75	0.6 160 С <sub>ғил</sub>	5.25 5.25 1.0 + 0.3	V V mA ms
TEMPERATURE RANGE Operating Range Specified Performance	JQC AQC	0 -40		+70 +85	0 -40		+70 +85	°C °C

NOTES

INOTES
 IFor all combination of offset no sensitivity variation.
 <sup>2</sup>Alignment error is specified as the angle between the true and indicated axis of sensitivity.
 <sup>3</sup>Transverse sensitivity is the algebraic non of the alignment and the indicated axis sensitivity errors.

<sup>4</sup>Specification refers to the maximum change in parameter from its initial at +25°C to its worst case value at T<sub>MIN</sub> T<sub>MAX</sub>.

<sup>5</sup>Noose density ( $\mu g/\sqrt{Hz}$ ) is the average noise at any frequency in the bandwith of the part.

Note each of (1984) (1) is the average noise at any nequency in the balawin on the part.  ${}^{6}C_{\text{PHI}}$  in µF. Addition of filter capacitor will increase turn on time. Please see the Application section on power cycling. All min and max specifications are guaranteed. Typical specifications are not tested or guaranteed. Specifications subject to change without notice.

#### ABSOLUTE MAXIMUM RATINGS\*

Acceleration (Any Axis, Unpowered for 0.5 ms) 1000 g
Acceleration (Any Axis, Powered for 0.5 ms) 500 g
+V <sub>8</sub> 0.3 V to +7.0 V
Output Short Circuit Duration
(Any Pin to Common) Indefinite
Operating Temperature
Storage Temperature65°C to +I 50°C

\*Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; the functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Drops onto hard surfaces can cause shocks of greater than 1000 g and exceed the absolute maximum rating of the device. Care should be exercised in handling to avoid damage.

#### PIN FUNCTION DESCRIPTIONS

Pin	Name	Description
1	NC	Not Connect
2	V <sub>TP</sub>	Test Point, Do Not Connect
3	ST	Self Test
4	COM	Common
5	T2	Connect R <sub>SET</sub> to Set T2 Period
6	NC	No Connect
7	COM	Common
8	NC	No Connect
9	Yout	Y Axis Duty Cycle Output
10	X <sub>OUT</sub>	X Axis Duty Cycle Output
11	Y <sub>FILT</sub>	Connect Capacitor for Y Filter
12	X <sub>FILT</sub>	Connect Capacitor for X Filter
13	V <sub>DD</sub>	+3 V to +5.25 V, Connect to 14
14	V <sub>DD</sub>	+3 V to +5.25 V, Connect to 13

#### PACKAGE CHARACTERISTICS

Package	$\theta_{JA}$	$\theta_{JC}$	Device Weight
14-Lead CERPAK	110°C/W	30°C/W	5 Grams

#### PIN CONFIGURATION



Figure 1 shows the response of the ADXL202 to the Earth's gravitational field. The output values shown are nominal. They are presented to show the user what type of response to expect from each of the output pins due to changes in orientation with respect to the Earth. The ADXL210 reacts similarly with output changes appropriate to its scale.



Figure 1. ADXL202/ADXL210 Nominal Response Due to Gravity

	ORDERING GUIDE					
Model	g Range	Temperature Range	Package Description	Package Option		
ADXL202JQC	±2	0°C to +70°C	14-Lead CERPAK	QC-14		
ADXL202AQC	±2	-40°C to +85°C	14-Lead CERPAK	QC-14		
ADXL210JQC	±10	0°C to +70°C	14-Lead CERPAK	QC-14		
ADXL210AQC	±10	-40°C to +85°C	14-Lead CERPAK	QC-14		

#### ORDERING GUIDE

#### CAUTION.

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the ADXL202/ADXL210 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



## TYPICAL CHARACTERISTICS (@ +25°C $R_{SET}$ = 125 kΩ, $V_{DD}$ = +5 V, unless otherwise noted)



Figure 2. Normalized DCM Period (T2) vs. Temperature



Figure 3. Typical Zero g Offset vs. Temperature



Figure 4. Typical Supply Current vs. Temperature



Figure 5. Typical X Axis Sensitivity Drift Due to Temperature



Figure 6. Typical Turn-On Time



Figure 7. Typical Zero g Distribution at +25°C



Figure 8. Typical Sensitivity per g at +25°C



Figure 9. Typical Noise at X<sub>FILT</sub> Output



Figure 10. Typical Noise at Digital Outputs



Figure 11. Rotational Die Alignment

#### DEFINITIONS

T1	Length of the "on" portion of the cycle.
T2	Length of the total cycle.
Duty Cycle	Ratio of the "on" time (T1) of the cycle to the total cycle (T2). Defined as TIM for the ADXL202/ADXL210.
Pulsewidth	Time period of the "on" pulse. Defined as T1 for the ADXL202/ADXL210.

#### THEORY OF OPERATION

The ADXL202/ADXL210 are complete dual axis acceleration measurement systems on a single monolithic IC. They contain a polysilicon surface-micromachined sensor and signal conditioning circuitry to implement an open loop acceleration measurement architecture. For each axis, an output circuit converts the analog signal to a duty cycle modulated (DCM) digital signal that can be decoded with a counter/timer port on a microprocessor cessor. The ADXL202/ADXL210 are capable of measuring both positive and negative accelerations to a maximum level of  $\pm 2 g$ or  $\pm 10 g$ . The accelerometer measures static acceleration forces such as gravity, allowing it to be used as a tilt sensor.

The sensor is a surface micromachined polysilicon structure built on top of the silicon wafer. Polysilicon springs suspend the structure over the surface of the wafer and provide a resistance against acceleration forces. Deflection of the structure is measured using a differential capacitor that consists of independent fixed plates and central plates attached to the moving mass. The fixed plates are driven by 180° out of phase square waves. An acceleration will deflect the beam and unbalance the differential capacitor, resulting in an output square wave whose amplitude is proportional to acceleration. Phase sensitive demodulation techniques are then used to rectify the signal and determine the direction of the acceleration.

The output of the demodulator drives a duty cycle modulator (DCM) stage through a 32 kΩ resistor. At this point a pin is available on each channel to allow the user to set the signal bandwidth of the device by adding a capacitor. This filtering improves measurement resolution and helps prevent aliasing.

After being low-pass filtered, the analog signal is converted to a duty cycle modulated signal by the DCM stage. A single resistor sets the period for a complete cycle (T2), which can be set between 0.5 ms and 10 ms (see Figure 12). A 0 g acceleration produces a nominally 50% duty cycle. The acceleration signal can be determined by measuring the length of the T1 and T2 pulses with a counter/timer or with a polling loop using a low cost microcontroller

An analog output voltage can be obtained either by buffering the signal from the  $X_{\rm FILT}$  and  $Y_{\rm FILT}$  pin, or by passing the duty cycle signal through an RC filter to reconstruct the dc value.

The ADXL202/ADXL210 will operate with supply voltages as low as 3.0 V or as high as 5.25 V.



Figure 12. Typical Output Duty Cycle

### APPLICATIONS

#### POWER SUPPLY DECOUPLING

For most applications a single 0. 1 µF capacitor,  $C_{DC}$ , will adequately decouple the accelerometer from signal and noise on the power supply. However, in some cases, especially where digital devices such as microcontrollers share the same power supply, digital noise on the supply may cause interference on the ADXL.202/ADXL210 output. This is often observed as a slowly undulating fluctuation of voltage at  $X_{FLT}$  and  $Y_{FLT}$ . If additional decoupling is needed, a 100  $\Omega$  (or smaller) resistor or ferrite beads, may be inserted in the ADXL202/ADXL210's supply line.

#### DESIGN PROCEDURE FOR THE ADXL202/ADXL210

The design procedure for using the ADXL202/ADXL210 with a duty cycle output involves selecting a duty cycle period and a filter capacitor. A proper design will take into account the Application requirements for bandwidth, signal resolution and acquisition time, as discussed in the following sections.

#### $\mathbf{V}_{\mathrm{DD}}$

The ADXL202/ADXL210 have two power supply ( $V_{DD}$ ) Pins: 13 and 14. These two pins should be connected directly together.

#### сом

The ADXL202/ADXL210 have two commons, Pins 4 and 7. These two pins should be connected directly together and Pin 7 grounded.

#### $\mathbf{V}_{\mathrm{TP}}$

This pin is to be left open; make no connections of any kind to this pin.

#### Decoupling Capacitor C<sub>DC</sub>

A 0.1  $\mu$ F Capacitor is recommended from Von to COM for power supply decoupling.

#### ST

The ST pin controls the self-test feature. When this pin is set to  $V_{DD}$ , an electrostatic force is exerted on the beam of the accelerometer. The resulting movement of the beam allows the user to test if the accelerometer is functional. The typical change in output will be 10% at the duty cycle outputs (corresponding to 800 mg). This pin may be left open circuit or connected to common in normal use.

#### **Duty Cycle Decoding**

The ADXL202/ADXL210's digital output is a duty cycle modulator. Acceleration is proportional to the ratio T1/T2. The nominal output of the ADXL202 is:

0 g = 50% Duty Cycle

Scale factor is 12.5% Duty Cycle Change per g

The nominal output of the ADXL210 is:

#### 0 g = 50% Duty Cycle

#### Scale factor is 4% Duty Cycle Change per g

These nominal values are affected by the initial tolerance of the device including zero g offset error and sensitivity error.

T2 does not have to be measured for every measurement cycle. It need only be updated to account for changes due to temperature, (a relatively slow process). Since the T2 time period is shared by both X and Y channels, it is necessary only to measure it on one channel of the ADXL202/ADXL210. Decoding algorithms for various microcontrollers have been developed. Consult the appropriate Application Note.



Figure 13. Block Diagram

#### Setting the Bandwidth Using $C_X$ and $C_Y$

The ADXL202/ADXL210 have provisions for bandlimiting the X<sub>FHT</sub> and Y<sub>FHT</sub> pins. Capacitors must be added at these pins to implement low-pass filtering for antialiasing and noise reduction. The equation for the 3 dB bandwidth is:

$$F_{-3\,dB} = \frac{1}{\left(2\pi(32\,k\Omega) \times C(x,y)\right)}$$

or, more simply,  $F_{-3\,dB} = \frac{5\,\mu F}{C_{(X,Y)}}$ 

The tolerance of the internal resistor ( $R_{\rm FILT}$ ) can vary as much as  $\pm 25\%$  of its nominal value of 32 kΩ; so the bandwidth will vary accordingly. A minimum capacitance of 1000 pF for  $C_{(X,Y)}$  is required in all cases.

Tabla	r –	Filtor	Ca	nacitor	Salact	ion	C	and	C
Table :		rnter	U a	pacitor	Sciecci	JUII,	UX.	anu	S

Bandwidth	Capacitor Value
10 Hz	0.47 µF
50 Hz	0.10 µF
100 Hz	0.05 µF
200 Hz	0.027 µF
500 Hz	0.01 µF
5 kHz	0.001 µF

#### Setting the DCM Period with $\ensuremath{R_{\text{SET}}}$

The period of the DCM output is set for both channels by a single resistor from  $R_{SET}$  to ground. The equation for the period is:

$$T2 = \frac{R_{SET}(\Omega)}{125 \ M\Omega}$$

A 125 k $\Omega$  resistor will set the duty cycle repetition rate to approximately 1 kHz, or 1 ms. The device is designed to operate at duty cycle periods between 0.5 ins and 10 ms.

Table II. Resistor Values to Set T2

T2	R <sub>SET</sub>
1 ms	125 kΩ
2 ins	250 kΩ
5 ms	625 kΩ
10 ms	1.25 MΩ

Note that the  $R_{\text{SET}}$  should always be included, even if only an analog output is desired. Use an  $R_{\text{SET}}$  value between 500 kΩ and 2 MΩ when taking the output from  $X_{\text{FILT}}$  or  $Y_{\text{FILT}}$ . The  $R_{\text{SET}}$  resistor should be place close to the T2 Pin to minimize parasitic capacitance at this node.

#### Selecting the Right accelerometer

For most till sensing applications the ADXL202 is the most appropriate accelerometer. Its higher sensitivity (12.5%/gallows the user to use a lower speed counter for PWM decoding while maintaining high resolution. The ADXL210 should be used in applications where accelerations of greater than  $\pm 2 g$ are expected.

#### MICROCOMPUTER INTERFACES

The ADXL202/ADXL210 were specifically designed to work with low cost microcontrollers. Specific code sets, reference designs, and application notes are available from the factory. This section will outline a general design procedure and discuss the various trade-offs that need to be considered.

The designer should have some idea of the required performance of the system in terms of:

Resolution: the smallest signal change that needs to be detected.

Bandwidth: the highest frequency that needs to be detected.

Acquisition Time: the time that will be available to acquire the signal on each axis.

These requirements will help to determine the accelerometer bandwidth, the speed of the microcontroller clock and the length of the T2 period.

When selecting a microcontroller it is helpful to have a counter timer port available. The microcontroller should have provisions for software calibration. While the ADXL202/ADXL210 are highly accurate accelerometers, they have a wide tolerance for

initial offset. The easiest way to null this offset is with a calibration factor saved on the mictrocontroller or by a user calibration for zero g. In the case where the offset is calibrated during manufacture, there are several options, including external EEPROM and microcontrollers with "one-time programmable" features.

#### DESIGN TRADE-OFFS FOR SELECTING FILTER CHARACTERISTICS: THE NOISE/BW TRADE-OFF

The accelerometer bandwidth selected will determine the measurement resolution (smallest detectable acceleration). Filtering can be used to lower the noise floor and improve the resolution of the accelerometer. Resolution is dependent on both the analog filter bandwidth at X<sub>FILT</sub> and Y<sub>FILT</sub> and on the speed of the microcontroller counter.

The analog output of the ADXL202/ADXL210 has a typical bandwidth of 5 kHz, much higher than the duty cycle stage is capable of converting. The user must filter the signal at this point to limit aliasing errors. To minimize DCM errors the analog bandwidth should be less than 1/10 the DCM frequency. Analog bandwidth may be increased to up to 1/2 the DCM frequency in many applications. This will result in greater dynamic error generated at the DCM.

The analog bandwidth may be further decreased to reduce noise and improve resolution. The ADXL202/ADXL210 noise has the characteristics of white Gaussian noise that contributes equally at all frequencies and is described in terms of  $\mu g$  per root Hz; i.e., the noise is proportional to the square root of the handwidth of the accelerometer. It is recommended that the user limit bandwidth to the lowest frequency needed by the application, to maximize the resolution and dynamic range of the accelerometer.

With the single pole roll-off characteristic, the typical noise of the ADXL202/ADXL210 is determined by the following equation:

$$Noise(rms) = (500 \, \mu g / \sqrt{Hz}) \times (\sqrt{BW \times 1.5})$$

At 100 Hz the noise will be:

Noise(rms) = 
$$\left(500 \mu g / \sqrt{Hz}\right) \times \left(\sqrt{100 \times (1.5)}\right) = 6.12 \text{ mg}$$

Often the peak value of the noise is desired. Peak-to-peak noise can only be estimated by statistical methods. Table III is useful for estimating the probabilities of exceeding various peak values, given the rms value.

Table III. Estimation of Peak-to-Peak Noise

Nominal Peak-to-Peak Value	% of Time that Noise Will Exceed Nominal Peak-to-Peak Value
$2.0 \times \text{rms}$	32%
$4.0 \times \text{rms}$	4.6%
$6.0 \times \text{rms}$	0.27%
$8.0 \times rms$	0.006%

The peak-to-peak noise value will give the best estimate of the uncertainty in a single measurement.

Table IV gives typical noise output of the ADXL202/ADXL210 for various  $C_x$  and  $C_y$  values.

Table IV.	Filter	Capacitor	Selection,	C <sub>v</sub> and	C <sub>v</sub>
				~ ~ ~ ~ ~ ~ ~ ~	~ Y

Bandwidth	C <sub>x</sub> , C <sub>y</sub>	rms Noise	Peak-to-Peak Noise Estimate 95% Probability (rms × 4)
10 Hz	0.47 μF	1.9 mg	7.6 mg
50 Hz	0.10 µF	4.3 mg	17.2 mg
100 Hz	0.05 µF	6.1 mg	24.4 mg
200 Hz	0.027 µF	8.7 mg	35.8 mg
500 Hz	0.01 µF	13.7 mg	54.8 mg

## CHOOSING T2 AND COUNTER FREQUENCY: DESIGN TRADE-OFFS

The noise level is one determinant of accelerometer resolution. The second relates to the measurement resolution of the counter when decoding the duty cycle output.

The ADXL202/ADXL210's duty cycle converter has a resolution of approximately 14 bits; better resolution than the accelerometer itself. The actual resolution of the acceleration signal is, however, limited by the time resolution of the counting devices used to decode the duty cycle. The faster the counter clock, the higher the resolution of the duty cycle and the shorter the T2 period can be for a given resolution. The following table shows some of the trade-offs. It is important to note that this is the resolution due to the microprocessors's counter. It is probable that the accelerometer's noise floor may set the lower limit on the resolution as discussed in the previous section.

Table V. Trade-offs Between Microcontroller Counter Rate, T2 Period and Resolution of Duty Cycle Modulator

T2(ms)	R <sub>SET</sub> (kΩ)	ADXL202/ ADXL210 Sample Rate	Counter- Clock Rate (MHz)	Counts per T2 Cycle	Counts per g	Resolution (mg)
1.0	124	1000	2.0	2000	250	4.0
1.0	124	1000	1.0	1000	125	8.0
1.0	124	1000	0.5	500	62.5	16.0
5.0	625	200	2.0	10000	1250	0.8
5.0	625	200	1.0	5000	625	1.6
5.0	625	200	0.5	2500	312.5	3.2
10.0	1250	100	2.0	20000	2500	0.4
10.0	1250	100	1.0	10000	1250	0.8
10.0	1250	100	0.5	5000	625	1.6

## STRATEGIES FOR USING THE DUTY CYCLE OUTPUT WITH MICROCONTROLLERS

Application notes outlining various strategies for using the duty cycle output with low cost microcontrollers are available from the factory.

## USING THE ADXL202/ADXL210 AS A DUAL AXIS TILT SENSOR

One of the most popular applications of the ADXL202/ADXL210 is tilt measurement. An accelerometer uses the force of gravity as an input vector to determine orientation of an object in space.

An accelerometer is most sensitive to tilt when its sensitive axis is perpendicular to the force of gravity, i.e., parallel to the earth's surface. At this orientation its sensitivity to changes in tilt is highest. When the accelerometer is oriented on axis to gravity, i. e., near its +1 g or -1 g reading, the change in output acceleration per degree of tilt is negligible. When the accelerometer is perpendicular to gravity, its output will change nearly 17.5 mg per degree of tilt, but at 45° degrees it is changing only at 12.2 mg per degree and resolution declines. The following table illustrates the changes in the X and Y axes as the device is tilted  $\pm 90^{\circ}$  through gravity.



	X OUTPUT		Y OUTPUT (g)	
X AXIS ORIENTATION TO HORIZON (°)	X OUTPUT (g)	D PER DEGREE OF TILT (mg)	Y OUTPUT (g)	∆ PER DEGREE OF TILT (mg)
-90	-1.000	-0.2	0.000	17.5
-75	-0.966	4.4	0.259	16.9
-60	-0.866	8.6	0.500	15.2
-45	-0.707	12.2	0.707	12.4
-30	-0.500	15.0	0.866	8.9
-15	-0.259	16.8	0.966	4.7
0	0.000	17.5	1.000	0.2
15	0.259	16.9	0.966	-4.4
30	0.500	15.2	0.866	-8.6
45	0.707	12.4	0.707	-12.2
60	0.866	8.9	0.500	-15.0
75	0.966	4.7	0.259	-16.8
90	1.000	0.2	0.000	-17.5

Figure 14. How the X and Y Axes Respond to Changes in Tilt

#### A DUAL AXIS TILT SENSOR: CONVERTING ACCELERATION TO TILT

When the accelerometer is oriented so both its X and Y axes are parallel to the earth's surface it can be used as a two axis tilt sensor with a roll and a pitch axis. Once the output signal from the accelerometer has been converted to an acceleration that varies between -1 g and +1 g, the output tilt in degrees is calculated as follows:

$$Pitch = ASIN (Ax/1 g)$$

$$Roll = ASIN (Ay/1 g)$$

Be sure to account for overranges. It is possible for the accelerometers to output a signal greater than  $\pm 1 g$  due to vibration, shock or other accelerations.

#### MEASURING 360° OF TILT

It is possible to measure a full 360° of orientation through gravity by using two accelerometers oriented perpendicular to one another (see Figure 15). When one sensor is reading a maximum change in output per degree, the other is at its minimum.



Figure 15. Using a Two-Axis Accelerometer to Measure 360° of Tilt

#### USING THE ANALOG OUTPUT

The ADXL202/ADXL210 was specifically designed for use with its digital outputs, but has provisions to provide analog outputs as well.

#### **Duty Cycle Filtering**

An analog output can be reconstructed by filtering the duty cycle output. This technique requires only passive components. The duty cycle period (T2) should be set to 1 ms. An RC filter with a 3 dB point at least a factor of 10 less than the duty cycle frequency is connected to the duty cycle output. The filter resistor should be no less than 100 kΩ to prevent loading of the output stage. The analog output signal will be ratiometric to the supply voltage. The advantage of this method is an output scale factor of approximately double the analog output. Its disadvantage is that the frequency response will be lower than when using the  $X_{\rm FIIT}$ ,  $Y_{\rm FIIT}$  output.

#### X<sub>FILT</sub>, Y<sub>FILT</sub> Output

The second method is to use the analog output present at the  $X_{\rm FIT}$  and  $Y_{\rm FIT}$  pin. Unfortunately, these pins have a 32 k $\Omega$  output impedance and are not designed to drive a load directly. An op amp follower may be required to buffer this pin. The advantage of this method is that the full 5 kHz bandwidth of the accelerometer is available to the user. A capacitor still must be added at this point for filtering. The duty cycle converter should be kept running by using  $R_{\rm SET}$  <a href="https://www.setuplus.com">https://www.setuplus.com</a> (M  $\Omega$ ). Note that the accelerometer offset and sensitivity are nominally:

$0 g \text{ Offset} = V_{DD}/2$	2.5 V at +5 V
ADXL202 Sensitivity = $(60 \text{ mV} \times \text{V}_{\text{S}})/\text{g}$	300 mV/g at +5 V, $V_{DD}$
ADXL210 Sensitivity = $(20 \text{ mV} \times \text{V}_{o})/\sigma$	100 mV/g at +5 V V

## USING THE ADXL202/ADXL210 IN VERY LOW POWER APPLICATIONS

An application note outlining low power strategies for the ADXL202/ADXL210 is available. Some key points are presented here. It is possible to reduce the ADXL202/ADXL210's average current from 0.6 mA to less than 20 µA by using the following techniques:

1. Power Cycle the accelerometer.

2. Run the accelerometer at a Lower Voltage, (Down to 3 V).

#### Power Cycling with an External A/D

Depending on the value of the X<sub>FILT</sub> capacitor, the ADXL202/ ADXL210 is capable of turning on and giving a good reading in 1.6 ms. Most microcontroller based A/Ds can acquire a reading in another 25 µs. Thus it is possible to turn on the ADXL202/ ADXL210 and take a reading in <2 ms. If we assume that a 20 Hz sample rate is sufficient, the total current required to take 20 samples is 2 ms × 20 samples/s × 0.6 mA = 24 µA average current. Running the part at 3 V will reduce the supply current from 0.6 mA to 0.4 mA, bringing the average current down to 16 µA.

The A/D should read the analog output of the ADXL202/ ADXL210 at the  $X_{FILT}$  and  $Y_{FILT}$  pins. A buffer amplifier is recommended, and may be required in any case to amplify the analog Output to give enough resolution with an 8-bit to 10-bit converter.

#### Power Cycling When Using the Digital Output

An alternative is to run the microcontroller at a higher clock rate and put it into shutdown between readings, allowing the use of the digital output. In this approach the

ADXL202/ADXL210 should be set at its fastest sample rate (T2 = 0.5 ms), with a 500 Hz filter at  $X_{FILT}$  and  $Y_{FILT}$ . The concept is to acquire a reading as quickly as possible and then shut down the ADXL202/ADXL210 and the microcontroller until the next sample is needed.

In either of the above approaches, the ADXL202/ADXL210 can be turned on and off directly using a digital port pin on the microcontroller to power the accelerometer without additional components. The port should be used to switch the common pin of the accelerometer so the port pin is "pulling down."

#### CALIBRATING THE ADXL202/ADXL210

The initial value of the offset and scale factor for the ADXL202/ ADXL210 will require calibration for applications such as tilt measurement. The ADXL202/ADXL210 architecture has been designed so that these calibrations take place in the software of the microcontroller used to decode the duty cycle signal. Calibration factors can be stored in EEPROM or determined at turnon and saved in dynamic memory.

For low g applications, the force of gravity is the most stable, accurate and convenient acceleration reference available. A reading of the 0 g point can be determined by orientating the device parallel to the earth's surface and then reading the output.

A more accurate calibration method is to make a measurements at +1 g and -1 g. The sensitivity can be determined by the two measurements.

To calibrate, the accelerometer's measurement axis is pointed directly at the earth. The 1 g reading is saved and the sensor is turned  $180^{\circ}$  to measure -1 g. Using the two readings, the sensitivity is:

Let A = Accelerometer output with axis oriented to +1 g

Let B = Accelerometer output with axis oriented to -1 g then: Sensitivity = [A - B]/2 g

For example, if the +1 g reading (A) is 55% duty cycle and the -1 g reading (B) is 32% duty cycle, then:

Sensitivity = 
$$[55\% - 32\%]/2 g = 11.5\%/g$$

These equations apply whether the output is analog, or duty cycle.

Application notes outlining algorithms for calculating acceleration from duty cycle and automated calibration routines are available from the factory.

#### OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).





## ANALOG $\pm 5 g$ to $\pm 50 g$ , Low Noise, Low Power, DEVICES Single/Dual Axis $i M EMS^{\textcircled{B}}$ Accelerometers

#### FEATURES

Complete Acceleration Measurement System on a Single Monolithic IC 80 dB Dynamic Range Pin Programmable  $\pm 50$  g or  $\pm 25$  g Full Scale Low Noise: 1 mg./Hz Typical Low Power: <2 mA per Axis Supply Voltages as Low as 4 V 2-Pole Filter On-Chip Ratiometric Operation Complete Mechanical & Electrical Self-Test Dual & Single Axis Versions Available Surface Mount Package

#### GENERAL DESCRIPTION

The ADXL150 and ADXL250 are third generation  $\pm$ 50 g surface micromachined accelerometers. These improved replacements for the ADXL50 offer lower noise, wider dynamic range, reduced power consumption and improved zero g bias drift.

The ADXL150 is a single axis product; the ADXL250 is a fully integrated dual axis accelerometer with signal conditioning on a single monolithic IC, the first of its kind available on the commercial market. The two sensitive axes of the ADXL250 are orthogonal (90°) to each other. Both devices have their sensitive axes in the same plane as the silicon chip.

The ADXL150/ADXL250 offer lower noise and improved signal-to-noise ratio over the ADXL50. Typical S/N is 80 dB, allowing resolution of signals as low as 10 mg, yet still providing a  $\pm$ 50 g full-scale range. Device scale factor can be increased from 38 mV/g to 76 mV/g by connecting a jumper between V<sub>01T</sub> and the offset null pin. Zero g drift has been reduced to 0.4 g over the industrial temperature range, a 10x improvement over the ADXL50. Power consumption is a modest 1.8 mA per axis. The scale factor and zero g output level are both ratiometric to the power supply, eliminating the need for a voltage reference

## ADXL150/ADXL250

FUNCTIONAL BLOCK DIAGRAMS



when driving ratiometric A/D converters such as those found in most microprocessors. A power supply bypass capacitor is the only external component needed for normal operation.

The ADXL150/ADXL250 are available in a hermetic 14-lead surface mount cerpac package specified over the  $0^{\circ}$ C to  $+70^{\circ}$ C commercial and  $-40^{\circ}$ C to  $+85^{\circ}$ C industrial temperature ranges. Contact factory for availability of devices specified over automotive and military temperature ranges.

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## $\label{eq:ADXL150/ADXL250-SPECIFICATIONS} (T_{A} = +25^{\circ}C \mbox{ for J Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ to } +85^{\circ}C \mbox{ for A Grade}, T_{A} = 40^{\circ}C \mbox{ for$

		ADXL150JQC/AQC		ADXL250JQC/AQC				
Parameter	Condition	Min	Тур	Max	Min	Тур	Max	Units
SENSOR Guaranteed Full-Scale Range Nonlinearity Package Alignment Error <sup>1</sup> Sensor-to-Sensor Alignment Error Transverse Sensitivity <sup>2</sup>		±40	±50 0.2 ±1 ±2		±40	±50 0.2 ±1 ±0.1 ±2		g % of FS Degrees Degrees %
SENSITIVITY Sensitivity (Ratiometric) <sup>3</sup> Sensitivity Drift Due to Temperature	Y Channel X Channel Delta from 25°C to T <sub>MIN</sub> or T <sub>MAX</sub>	33.0	38.0 ±0.5	43.0	33.0 33.0	38.0 38.0 ±0.5	43.0 43.0	mV/g mV/g %
ZERO g BIAS LEVEL Output Bias voltage <sup>4</sup> Zero g Drift Due to Temperature	Delta from 25°C to T <sub>MIN</sub> or T <sub>MAX</sub>	V <sub>s</sub> /2–0.35	V <sub>s</sub> /2 0.2	V <sub>s</sub> /2+0.35	V <sub>s</sub> /2–0.35	V <sub>s</sub> /2 0.3	V <sub>s</sub> /2+0.35	V g
ZERO-g OFFSET ADJUSTMENT Voltage Gain Input Impedence	Delta V <sub>OUT</sub> /Delta V <sub>OS PIN</sub>	0.45 20	0.50 30	0.55	0.45 20	0.50 30	0.55	V/V kΩ
NOISE PERFORMANCE Noise Density <sup>5</sup> Clock Noise			1 5	2.5		1 5	2.5	mg/√Hz mV p-p
FREQUENCY RESPONSE -3 dB Bandwidth Bandwidth Temperature Drift Sensor Resonant Frequency	$T_{MIN}$ to $T_{MAX}$ Q = 5	900	1000 50 24		900	1000 50 24		Hz kHz kHz
SELF-TEST Output Change	ST Pin from Logic "0" to '1"	0.25	0.40	0.60	0.25	0.40	0.60	v
Logic "1" Voltage Logic "0" Voltage Input Resistance	To Common	V <sub>s</sub> -1 30	50	1.0	V <sub>s</sub> -1 30	50	1.0	V V kΩ
OUTPUT AMPLIFIER Output Voltage Swing Capacitive Load Drive	$I_{OUT} = \pm 100 \ \mu A$	0.25 1000		V <sub>s</sub> -0.25	0.25 1000		V <sub>s</sub> -0.25	V pF
POWER SUPPLY (V <sub>s</sub> ) <sup>7</sup> Functional Voltage Range Quiescent Supply Current	ADXL150 ADXL250 (Total 2 Channels)	4.0	1.8	6.0 3.0	4.0	3.5	6.0 5.0	V mA mA
TEMPERATURE RANGE Operating Range J Specified Performance A		0 -40		+70 +85	0 -40		+70 +85	°C °C

NOTES

Alignment error is specified as the scale between the ture axis of sensitivity and the edge of the package.

<sup>2</sup>Transverse sensitivity is measured with an applied acceleration that is 90 degrees from the indicated axis of sensitivity. <sup>3</sup>Ratiometric:  $V_{OUT} = V_y 2 +$  (Sensitivity ×  $V_y 5$  V × a) where a = applied acceleration in gs, and  $V_s$  = supply voltage. See Figure 21. Output scale factor can be doubled by connecting V<sub>OUT</sub> to the offset null pin.

<sup>4</sup>Ratiometric, proportional to V<sub>s</sub>/2. See Figure 21.

<sup>5</sup>See Figure 11 and Device Bandwidth vs. Resolution section.

6Sclf-test output varies with supply voltage.

7When wing ADXL250, both Pins 13 and 14 must be connected to the supply for the device to function.

Specifications subject to change without notice.

#### ABSOLUTE MAXIMUM RATINGS\*

Acceleration (Any Axis, Unpowered for 0.5 ms) 2000 g
Acceleration (Any Axis, Powered for 0.5 ms) 500 g
+V <sub>8</sub> 0.3 V to -7.0 V
Output Short Circuit Duration
(V <sub>OUT</sub> , V <sub>REF</sub> Terminals to Common) Indefinite
Operating Temperature55°C to +125°C
Storage Temperature65°C to +150°C

"Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; the functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Drops onto hard surfaces can cause shocks of greater than 2000 g and exceed the absolute maximum rating of the device. Care should be exercised in handling to avoid damage.



Figure 1. ADXL150 and ADXL250 Sensitive Axis Orientation

#### Package Characteristics

Package	$\theta_{JA}$	$\theta_{JC}$	Device Weight
14-Lead CERPAK	110°C/W	30°C/W	5 Grams

#### ORDERING GUIDE

Model	Temperature Range
ADXL150JQC	0°C to +70°C
ADXL150AQC	-40°C to +85°C
ADXL250JQC	0°C to +70°C
ADXL250AQC	-40°C to +85°C

#### PIN CONNECTIONS



NOTE: WHEN USING ADXL250, BOTH PINS 13 AND 14 NEED TO BE CONNECTED TO SUPPLY FOR DEVICE TO FUNCTION

#### CAUTION.

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the ADXL150/ADXL250 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



#### GLOSSARY OF TERMS

Acceleration: Change in velocity per unit time.

Acceleration Vector: Vector describing the net acceleration acting upon the ADXL150/ADXL250.

**g**: A unit of acceleration equal to the average force of gravity occurring at the earth's surface. A g is approximately equal to 32.17 feet/s<sup>2</sup> or 9.807 meters/s<sup>2</sup>.

Nonlinearity: The maximum deviation of the ADXL150/ ADXL250 output voltage from a best fit straight line fitted to a plot of acceleration vs. output voltage, calculated as a % of the full-scale output voltage (at 50 g).

Resonant Frequency: The natural frequency of vibration of the ADXL150/ADXL250 sensor's central plate (or "beam"). At its resonant frequency of 24 kHz, the ADXL150/ADXL250's moving center plate has a slight peak in its frequency response.

**Sensitivity:** The output voltage change per g unit of acceleration applied, specified at the  $V_{OUT}$  pin in mV/g.

Total Alignment Error: Net misalignment of the ADXL150/ ADXL250's on-chip sensor and the measurement axis of the application. This error includes error due to sensor die alignment to the package, and any misalignment due to installation of the sensor package in a circuit board or module.

Transverse Acceleration: Any acceleration applied  $90^{\circ}$  to the axis of sensitivity.

Transverse Sensitivity Error: Ile percent of a transverse acceleration that appears at V<sub>OUT</sub>.

Transverse Axis: The axis perpendicular (90°) to the axis of sensitivity.

Zero g Bias Level: The output voltage of the ADXL150/ ADXL250 when there is no acceleration (or gravity) acting upon the axis of sensitivity. The output offset is the difference between the actual zero g bias level and  $(V_s/2)$ .

#### Polarity of the Acceleration Output

The polarity of the ADXL150/ADXL250 output is shown in Figure 1. When its sensitive axis is oriented to the earth's gravity (and held in place), it will experience in acceleration of +1 g. This corresponds to a change of approximately +38 mV at the output pin. Note that the polarity will be reversed if the package is rotated 180°. The figure shows the ADXL250 oriented so that its "X" axis measures +1 g. If the package is rotated 90° clockwise (Pin 14 up, Pin 1 down), the ADXL250's "Y" axis will now measure +1 g.



Figure 2. Output Polarity

#### Acceleration Vectors

The ADXL150/ADXL250 is a sensor designed to measure accelerations that result from an applied force. It responds to the component of acceleration on its sensitive X axis (ADXL150) or on both the "X" and "Y" axis (ADXL250).

## Typical Characteristics (@+5 V dc, +25°C with a 38 mV/g Scale Factor unless otherwise noted)



Figure 3. Typical Sensitivity Error from Ideal Ratiometric Response for a Number of Units



Figure 4. Offset Error of Zero g Level from Ideal  $V_S/2$  Response as a Percent of Full-Scale for a Number of Units



Figure 5. Typical Supply Current vs. Supply Voltage



Figure 6. Typical Output Response vs. Frequency of ADXL150/ADXL250 on a PC Board that Has Been Conformally Coated



Figure 7. Typical Zero g Drift for a Number of Units



Figure 8. Typical 500 g Step Recovery at the Output



Figure 9. Typical Output Noise Voltage with Spikes Generated by Internal Clock



Figure 10. Typical Self-Test Response



Figure 12. Noise vs. Supply Voltage



Figure 13. Baseband Error Graph





Figure 11. Noise Spectral Density

#### THEORY OF OPERATION

The ADXL150 and ADXL250 are fabricated using a proprietary surface micromachining process that has been in high volume production since 1993. The fabrication technique uses standard integrated circuit manufacturing methods enabling all the signal processing circuitry to be combined on the same chip with the sensor.

The surface micromachined sensor element is made by depositing polysilicon on a sacrificial oxide layer that is then etched away leaving the suspended sensor element. Figure 14 is a simplified view of the sensor structure. The actual sensor has 42 unit cells for sensing acceleration. The differential capacitor sensor is composed of fixed plates and moving plates attached to the beam that moves in response to acceleration. Movement of the beam changes the differential capacitance, which is measured by the on chip circuitry.

The sensor has 12-unit capacitance cells for electrostatically forcing the beam during a self-test. Self-test is activated by the user with a logic high on the self-test input pin. During a logic high, an electrostatic force acts on the beam equivalent to approximately 20% of full-scale acceleration input, and thus a proportional voltage change appears on the output pin. When activated, the self-test feature exercises both the entire mechanical structure and the electrical circuitry.



Figure 14. Simplified View of Sensor Under Acceleration

All the circuitry needed to drive the sensor and convert the capacitance change to voltage is incorporated on the chip requiring no external components except for standard power supply decoupling. Both sensitivity and the zero-g value are ratiometric to the supply voltage, so that ratiometeric devices following the accelerometer (such as an ADC, etc.) will track the accelerometer if the supply voltage changes. The output voltage ( $V_{OUT}$ ) is a function of both the acceleration input (a) and the power supply voltage ( $V_{s}$ ) as follows:

$$V_{OUT} = V_s/2 - (Sensitivity \times \frac{V_s}{5V} \times a)$$

Both the ADXL150 and ADYCL250 have a 2-pole Bessel switched-capacitor filter. Bessel filters, sometimes called linear phase filters, have a step response with minimal overshoot and a maximally flat group delay. The -3 dB frequency of the poles is preset at the factory to 1 kHz. These filters are also completely self-contained and buffered, requiring no external components.

#### MEASURING ACCELERATIONS LESS THAN 50 g

The ADXL150/ADXL250 require only a power supply bypass capacitor to measure  $\pm 50$  g accelerations. For measuring  $\pm 50$  g accelerations, the accelerometer may be directly connected to an ADC (see Figure 25). The device may also be easily modified to measure lower g signals by increasing its output wale factor.

The scale factor of an accelerometer specifies the voltage change of the output per g of applied acceleration. This should not be confused with its resolution. The resolution of the device is the lowest g level the accelerometer is capable of measuring. Resolution is principally determined by the device noise and the measurement bandwidth.

The zero g bias level is simply the dc output Level of the accelerometer when it is not in motion or being acted upon by the earth's gravity.

#### Pin Programmable Scale Factor Option

In its normal state, the ADXL150/ADXL250's buffer amplifier provides in output scale factor of 38 mV/g, which is set by an internal voltage divider. This gives a full-scale range of +50 gand a nominal bandwidth of 1 kHz.

A factor-of-two increase in sensitivity can be obtained by connecting the V<sub>OUT</sub> pin to the offset null pin, assuming that it is not needed for offset adjustment. This connection has the effect of reducing the internal feedback by a factor of two, doubling the buffer's gain. This increases the output scale factor to 76 mV/g and provides a  $\pm 25$  g full-scale range.

Simultaneously, connecting these two pins also increases the amount of internal post filtering, reducing the noise floor and changing the nominal 3 dB bandwidth of the ADXL150/ ADXL250 to 500 Hz. Note that the post filter's "Q" will also be reduced by a factor of  $\sqrt{2}$  from 0.58 (Bessel response) to a much gentler "Q" value of 0.41. The primary effect of this change in "Q" is only at frequencies within two octaves of the corner frequency; above this the two filter slopes am essentially the same. In applications where a flat response up to 500 Hz is needed, it is better to operate the device at 38 mV/g and use an external post filter. Note also that connecting  $V_{OUT}$  to the offset pin adds a 30 k $\Omega$  load from  $V_{OUT}$  to  $V_2/2$ . When swinging ±2 V at  $V_{OUT}$  to 30  $\mu$ A (typical) output current drive.

## Increasing the *i*MEMS Accelerometer's Output Scale Factor

Figure 15 shows the basic connections for using an external buffer amplifier to increase die output scale factor.

The output multiplied by the gain of the buffer, which is simply the value of resistor R3 divided by RI. Choose a convenient scale factor, keeping in mind that the buffer pin not only amplifies the signal, but my noise or drift as well. Too much pin can also cause the buffer to saturate and clip the output waveform.

Note that the "+" input of the external op amp uses the offset null pin of the ADXL150/ADXL250 as a reference, biasing the op amp at midsupply, saving two resistors and reducing power consumption. The offset null pin connects to the  $V_s/2$  reference point inside the accelerometer via 30 kΩ, so it is important not to load this pin with more dim a few microamps.

It is important to use a single-supply or "rail-to-rail" op amp for the external buffer as it needs to be able to swing close to the supply and ground.

The circuit of Figure 15 is entirely adequate for many applications, but its accuracy is dependent on the pretrimmed accuracy of the accelerometer and this will vary by product type and grade. For the highest possible accuracy, an external trim is mended. As shown by Figure 20, this consists of a potentiometer Rla, in series with a fixed resistor, Rlb. Another to select resistor values after measuring the device's scale (see Figure 17).

#### AC Coupling

If a dc (gravity) response is not required—for example \*\* tion measurement applications—ac coupling can be \*\* between the accelerometer's output and the external op\*\* input as shown in Figure 16. The use of ac coupling \*\* eliminates my zero g drift and allows the maximum \*\* amp gain without clipping.

Resistor R2 and capacitor C3 together form a high \*\* whose corner frequency is  $1/(2 \times R2 C3)$ . This filter \*\* the signal from the accelerometer by 3 dB at the \*\*, and it will continue to reduce it at a rate of 6 \*\* (20 dB per decade) for signals below the corner frequ \*\* Capacitor CBS should be a nonpolarized, low leakage type \*\*

If ac coupling is used, the self-test feature must be \*\* the accelerometer's output rather than at the external \*\* output (since the self-test output is a dc voltage).



Figure 15. Using an External Op Amp to Increase Output Scale Factor



Figure 16. AC Coupled Connection Using an External Op Amp



Figure 17. "Quick Zero g Calibration" Connection

#### Adjusting the Zero g Bias Level

When a true dc (gravity) response is needed, the output from the accelerometer must be dc coupled to the external amplifier's input. For high gain applications, a zero g offset trim will also be needed. The external offset trim permits the user to set the zew g offset voltage to exactly +2.5 volts (allowing the maximum output swing from the external amplifier without clipping with a +5 supply).

With a dc coupled connection, any difference between the zero g output and +2.5 V will be amplified along with the signal. To obtain the exact zero g output desired or to allow the maximum output voltage swing from the external amplifier, the zero g offset will need to be externally trimmed using the circuit of Figure 20.

The external amplifier's maximum output swing should be limited to  $\pm 2$  volts, which provides a safety margin of  $\pm 0.25$ volts before clipping. With a  $\pm 2.5$  volt zero g level, the maximum gain will equal:

> 2 Volts 38 mV/g Times the Max Applied Acceleration in g

The device scale factor and zero g offset levels can be calibrated using the earth's gravity, as explained in the section "calibrating the ADXL150/ADXL250."

#### Using the Zero g "Quick-Cal" Method

In Figure 18 (accelerometer alone, no external op amp), a trim potentiometer connects directly to the accelerometer's zero g null pin. The "quick offset calibration" scheme shown in Figure 17 is preferred over using a potentiometer, which could change its setting over time due to vibration. The "quick offset calibration" method requires measuring only the output voltage of the ADXL150/ADXL250 while it is oriented normal to the earth's gravity. Then, by using the simple equations shown in the figures, the correct resistance value for R2 can be calculated. In Figure 17, an external op amp is used to amplify the signal. A resistor, R2, is connected to the op amp's summing junction. The other side of R2 connects to either ground or +V<sub>8</sub> depending on which direction the offset needs to be shifted.



Figure 18. Offset Nulling the ADXL150/ADXL250 Using a Trim Potentiometer

#### DEVICE BANDWIDTH VS. MEASUREMENT RESOLUTION

Although an accelerometer is usually specified according to its full-scale g level, the limiting resolution of the device, i.e., its minimum discernible input level, is extremely important when measuring low g accelerations.



Figure 19. ADXL150/ADXL250 Noise Level vs. 3 dB Bandwidth (Using a "Brickwall" Filter)

The limiting resolution is predominantly set by the measurement noise "floor," which includes the ambient background noise and the noise of the ADXL150/ADXL250 itself. The level of the noise floor varies directly with the bandwidth of the measurement. As the measurement bandwidth is reduced, the noise floor drops, improving the signal-to-noise ratio of the measurement and increasing its resolution.

The bandwidth of the accelerometer can be easily reduced by adding low-pass or bandpass filtering. Figure 19 shows the typical noise vs. bandwidth characteristic of the ADXL150/ ADXL250.

The output noise of the ADXL150/ADXL250 scales with the square root of the measurement bandwidth. With a single pole roll-off, the equivalent rms noise bandwidth is  $\pi$  divided by 2 or approximately 1.6 times the 3 dB bandwidth. For example, the typical rms noise of the ADXL150 using a 100 Hz one pole post filter is:

$$Noise(rms) = 1 mg/\sqrt{Hz} \times \sqrt{100(1.6)} = 12.25 mg$$

Because the ADXL150/ADXL250's noise is, for all practical purposes, Gaussian in amplitude distribution, the highest noise amplitudes have die smallest (yet nonzero) probability. Peakto-peak noise is therefore difficult to measure and can only be estimated due to its statistical nature. Table I is useful for estimating the probabilities of exceeding various peak values, given the rms value.

TABLE I.					
Nominal Peak-to- Peak Value	% of Time that Noise Will Exceed Nominal Peak-to-Peak Value				
$2.0 \times rms$	32%				
$4.0 \times rms$	4.6%				
$6.0 \times rms$	0.27%				
$6.6 \times rms$	0.1%				
$8.0 \times rms$	0.006%				

RMS and peak-to-peak noise (for 0. 1% uncertainty) for various bandwidths are estimated in Figure 19. As shown by the figure, device noise drops dramatically as the operating bandwidth is reduced. For example, when operated in a 1 kHz bandwidth, the ADXL150/ADXL250 typically have an rms noise level of 32 mg. When the device bandwidth is rolled off to 100 Hz, the noise level is reduced to approximately 10 mg.

Alternatively, the signal-to-noise ratio may be improved considerably by using a microprocessor to perform multiple measurements and then to compute the average signal level.

#### Low-Pass Filtering

The bandwidth of the accelerometer can easily be reduced by using post filtering. Figure 20 shows how the buffer amplifier can be connected to provide 1-pole post filtering, zero g offset trimming, and output scaling. The table provides practical component values



Figure 20. One-Pole Post Filter Circuit with SF and Zero g Offset Trims

for various full-scale *g* levels and approximate circuit bandwidths. For bandwidths other than those listed, use the formula:

$$Cf = \frac{1}{(2\pi R^3) \text{ Desired 3dB Bandwidth in } Hz}$$

or simply scale the value of capacitor Cf accordingly; i.e., for an application with a 50 Hz bandwidth, the value of Cf will need to be twice as large as its 100 Hz value. If further noise reduction is needed while maintaining the maximum possible bandwidth, a 2- or 3-pole post filter is recommended. These provide a much steeper roll-off of noise above the pole frequency. Figure 21 shows a circuit that provides 2-pole post filtering. Component values for the 2-pole filter were selected to operate the first op amp at unity gain. Capacitors C3 and C4 were chosen to provide 3 dB bandwidths of 10 Hz, 30 Hz, 100 Hz and 300 Hz.

The second op amp offsets and scales the output to provide a  $\pm 2.5 \text{ V} \pm 2 \text{ V}$  output over a wide range of full-scale g levels.

#### APPLICATION HINTS

#### ADXL250 Power Supply Pins

When wiring the ADXL250, be sure to connect BOTH power supply terminals, Pins 14 and 13.

#### **Ratiometric Operation**

Ratiometric operation means that the circuit uses the power supply as its voltage reference. If the supply voltage varies, the accelerometer and the other circuit components (such as an ADC, etc.) track each other and compensate for the change. Figure 22 shows how both the zero g offset and output sensitivity of the ADXL150/ADXL250 vary with changes in supply voltage. If they are to be used with nonratiometric devices, such as an ADC with a built-in 5 V reference, then both components should be referenced to the same source, in this case the ADC reference. Alternatively, the circuit can be powered from an external +5 volt reference.



Figure 22. Typical Ratiornetric Operation

Since any voltage variation is transferred to the accelerometer's output, it is important to reduce any power supply noise. Simply following good engineering practice of bypassing the power supply right at Pin 14 of the ADXL150/ADXL250 with a 0.1  $\mu F$  capacitor should be sufficient.



Figure 21. Two-Pole Post Filter Circuit

#### Additional Noise Reduction Techniques

Shielded wire should be used for connecting the accelerometer to any circuitry that is more than a few inches away—to avoid 60 Hz pickup from ac line voltage. Ground the cable's shield at only one end and connect a separate common lead between the circuits; this will help to prevent ground loops. Also, if the accelerometer is inside a metal enclosure, this should be grounded as well.

#### Mounting Fixture Resonances

A common source of error in acceleration sensing is resonance of the mounting fixture. For example, the circuit board that the ADXL150/ADXL250 mounts to may have resonant frequencies in the same range as the signals of interest. This could cause the signals measured to be larger than they really are. A common solution to this problem is to damp these resonances by mounting the ADXL150/ADXL250 near a mounting post or by adding extra screws to hold the board more securely in place.

When testing the accelerometer in your end application, it is recommended that you test the application at a variety of frequencies to ensure that no major resonance problems exist.

#### REDUCING POWER CONSUMPTION

The use of a simple power cycling circuit provides a dramatic reduction in the accelerometer's average current consumption. In low bandwidth applications such as shipping recorders, a simple, low cost circuit can provide substantial power reduction.

If a microprocessor is available, it can supply a TTL clock pulse to toggle the accelerometer's power on and off.

A 10% duty cycle, 1 ms on, 9 ms off, reduces the average current consumption of the accelerometer from 1.8 mA to 180  $\mu$ A, providing a power reduction of 90%.

Figure 23 shows the typical power-on settling time of the ADXL150/ADXL250.



Figure 23. Typical Power-On Settling with Full-Scale Input. Time Constant of Post Filter Dominates the Response When a Signal Is Present.

#### CALIBRATING THE ADXL150/ADXL250

If a calibrated shaker is not available, both the zero g level and scale factor of the ADXL150/ADXL250 may be easily set to fair accuracy by using a self-calibration technique based on the 1 g acceleration of the earth's gravity. Figure 24 shows how gravity and package orientation affect the ADXL150/ADXL250's output. With its axis of sensitivity in the vertical plane, the ADXL150/ADXL250's output. ADXL250 should register a 1 g acceleration, either positive or negative, depending on orientation. With the axis of sensitivity in the horizontal plane, no acceleration (the zero g bias level) should be indicated. The use of an external buffer amplifier may invert the polarity of the signal.



Figure 24. Using the Earth's Gravity to Self-Calibrate the ADXL150/ADXL250

Figure 24 shows how to self-calibrate the ADXL150/ADXL250. Place the accelerometer on its side with its axis of sensitivity oriented as shown in "a." (For the ADXL250 this would be the "X" axis—its "Y" axis is calibrated in the same manner, but the part is rotated 90° clockwise.) The zero g offset potentiometer RT is then roughly adjusted for midscale: +2.5 V at the external amp output (see Figure 20).

Next, the package axis should be oriented as in "c" (pointing down) and the output reading noted. The package axis should then be rotated 180° to position "d" and the scale factor potentiometer, Rlb, adjusted so that the output voltage indicates a change of 2 gs in acceleration. For example, if the circuit scale factor at the external buffer's output is 100 mV per g, the scale factor trim should be adjusted so that an output change of 200 mV is indicated.

#### Self-Test Function

A Logic "1" applied to the self-test (ST) input will cause an electrostatic force to be applied to the sensor that will cause it to deflect. If the accelerometer is experiencing an acceleration when the self-test is initiated, the output will equal the algebraic sum of the two inputs. The output will stay at the self-test level as long as the ST input remains high, and will return to the actual acceleration level when the ST voltage is removed.

Using an external amplifier to increase output scale factor may cause the self-test output to overdrive the buffer into saturation. The self-test may still be used in this case, but the change in the output must then be monitored at the accelerometer's output instead of the external amplifier's output.

Note that the value of the self-test delta is not an exact indication of the sensitivity (mV/g) and therefore may not be used to calibrate the device for sensitivity error.

#### MINIMIZING EMI/RFI

The architecture of the ADXL150/ADXL250, and its use of synchronous demodulation, makes the device immune to most electromagnetic (EMI) and radio frequency (RFI) interference. The use of synchronous demodulation allows the circuit to reject all signals except those at the frequency of the oscillator driving the sensor element. However, the ADXL150/ADXL250 have a sensitivity to noise on the supply lines that is near its internal clock frequency (approximately 100 kHz) or its odd harmonics and can exhibit baseband errors at the output. These error signals are the beat frequency signals between the clock and the supply noise.

Such noise can be generated by digital switching elsewhere in the system and must be attenuated by proper bypassing. By inserting a small value resistor between the accelerometer and its power supply, an RC filter is created. This consists of the resistor and the accelerometer's normal 0.1  $\mu F$  bypass capacitor. For example if R = 20  $\Omega$  and C = 0.1  $\mu F$ , a filter with a pole at 80 kHz is created, which is adequate to attenuate noise on the supply from most digital circuits, with proper ground and supply layout.

Power supply decoupling, short component leads, physically small (surface mount, etc.) components and attention to good grounding practices all help to prevent RFI and EMI problems. Good grounding practices include having separate analog and digital grounds (as well as separate power supplies or very good decoupling) on the printed circuit boards.

#### INTERFACING THE ADXL150/ADXL250 SERIES iMEMS ACCELEROMETERS WITH POPULAR ANALOG-TO-DIGITAL CONVERTERS.

#### **Basic Issues**

The ADXL150/ADXL250 Series accelerometers were designed to drive popular analog-to-digital converters (ADCs) directly. In applications where both a  $\pm 50$  g full-scale measurement range and a 1 kHz bandwidth are needed, the V<sub>0UT</sub> terminal of the accelerometer is simply connected to the V<sub>IN</sub> terminal of the ADC as shown in Figure 25a. The accelerometer provides its (nominal) factory preset scale factor of +2.5 V  $\pm 38$  mV/g which drives the ADC input with +2.5 V  $\pm 1.9$  V when measuring a 50 g full-scale signal (38 mV/g  $\times 50$  g = 1.9 V).

As stated earlier, the use of post filtering will dramatically improve the accelerometer's low g resolution. Figure 25b shows a simple post filter connected between the accelerometer and the ADC. This connection, although easy to implement, will require fairly large values of Cf, and the accelerometer's signal will be loaded down (causing a scale factor error) unless the ADC's input impedance is much greater than the value of Rf. ADC input impedance's range from less than 1.5 k\Omega up to greater than 1.5 kΩ with S kΩ values being typical. Figure 25c is the preferred connection for implementing low-pass filtering with the added advantage of providing an increase in scale factor, if desired.

#### Calculating ADC Requirements

The resolution of commercial ADCs is specified in bits. In an ADC, the available resolution equals  $2^n$ , where *n* is the number of bits. For example, an 8-bit converter provides a resolution of  $2^8$  which equals 256. So the full-scale input range of the converter divided by 256 will equal the smallest signal it can resolve.

In selecting an appropriate ADC to use with our accelerometer we need to find a device that has a resolution better than the measurement resolution but, for economy's sake, not a great deal better.

For most applications, an 8- or 10-bit converter is appropriate. The decision to use a 10-bit converter alone, or to use a gain stage together with an 8-bit converter, depends on which is more important: component cost or parts count and ease of assembly, Table II shows some of the tradeoffs involved.

Table II.						
	8-Bit Converter and Op Amp Preamp	10-bit (or 12-Bit) Converter				
Advantages:	Low Cost Converter	No Zero g Trim Required				
Disadvantages:	Needs Op Amp Needs Zero g Trim	Higher Cost Converter				

Adding amplification between the accelerometer and the ADC will reduce the circuit's full-scale input range but will greatly reduce the resolution requirements (and therefore the cost) of the ADC. For example, using an op amp with a gain of 5.3 following the accelerometer will increase the input drive to the ADC from 38 mV/g to 200 mV/g. Since the signal has been gained up, but the maximum full-scale (clipping) level is still the same, the dynamic range of the measurement has also been reduced by 5.3.

 Table III. Typical System Resolution Using Some Popular

 ADCs Being Driven with and without an Op Amp Preamp

Converter Type	2 <sup>n</sup>	Converter mV/Bit (5 V/2 <sup>n</sup> )	Preamp Gain	SF in mV/g	FS Range in g's	System Resolution in g's (p-p)
8 Bit	256	19.5 mV	None	38	±50	0.51
	256	19.5 mV	2	76	±25	0.26
	256	19.5 mV	2.63	100	±20	0.20
	256	19.5 mV	5.26	200	±10	0.10
10 Bit	1,024	4.9 mV	None	38	±50	0.13
	1,024	4.9 mV	2	76	±25	0.06
	1,024	4.9 mV	2.63	100	±20	0.05
	1,024	4.9 mV	5.26	200	±10	0.02
12 Bit	4,096	1.2 mV	None	38	±50	0.03
	4,096	1.2 mV	2	76	±25	0.02
	4,096	1.2 mV	2.63	100	±20	0.01
	4,096	1.2 mV	5.26	200	±10	0.006

Table III is a chart showing the required ADC resolution vs. the scale factor of the accelerometer with or without a gain amplifier. Note that the system resolution specified in the table refers

to that provided by the converter and preamp (if used). It is necessary to use sufficient post filtering with the accelerometer to reduce its noise floor to allow full use of the converter's resolution (see post filtering section).

The use of a pin stage following the accelerometer will normally require the user to adjust the zero g offset level (either by trimming or by resistor selection—see previous sections).

For many applications, a modern "economy priced" 10-bit converter, such as the AD7810 allows you to have high resolution without using a preamp or adding much to the overall circuit cost. In addition to simplicity and cost, it also meets two other necessary requirements: it operates from a single +5 V supply and is very low power.







a. Direct Connection, No Signal Amplification or Post Filtering



b. Single-Pole Post Filtering, No Signal Amplification



c. Single-Pole Post Filtering and Signal Amplification

Figure 25. Interfacing the ADXL150/ADXL250 Series Accelerometers to an ADC

# 3.2. STRUCTURAL SYNTHESIS OF NANO- AND MICROELECTROMECHANICAL ACTUATORS AND SENSORS

New advances in micromachining and microstructures, nano- and microscale electromechanical devices, analog and digital ICs, provide enabling benefits and capabilities to design and manufacture NEMS and MEMS. Critical issues are to improve power and thermal management, circuitry and actuator/sensor integration, as well as embedded electronically controlled actuator/sensor assemblies. Very large scale integrated circuit and micromachining silicon, germanium, and gallium arsenic technologies have been developed and used to manufacture ICs and motion microstructures (microscale actuators and sensors). While enabling technologies have been developed to manufacture NEMS and MEMS, a spectrum of challenging quantum problems remains. Electromagnetics and fluid dynamic, electro-thermo-mechanics phenomena, and optics, biophysics and biochemistry, mechanical and structural synthesis, analysis and optimization, simulation and virtual prototyping, among other important problems, must be thoroughly studied in nano- and microscale. There are several key focus areas to be studied. In particular, structural synthesis and optimization, fabrication, nonlinear model development and analysis, system design and simulations.

An important problem addressed and studied in this section is the structural synthesis of motion nano- and microstructures (shape/geometry synthesis, optimization, and database developments). The proposed concept allows the designer to generate optimal structures of actuators and sensors. Using the proposed concept one can generate and optimize different nano- and microdevices, perform modeling and simulations, etc. These directly leverage high-fidelity model development and structural synthesis, allowing the designer to attain physical and behavioral (steady-state and transient) analysis, optimization, performance assessment, outcome prediction, etc.

### 3.2.1. Configurations and Structural Synthesis of Motion Nano- and Microstructures (Actuators and Sensors)

Using the structural synthesis concept, nano-, micro-, and miniscale actuators and sensors can be synthesized, analyzed, and optimized. In particular, electromechanical/electromagnetic-based motion nano- and microstructures (actuators and sensors) are classified using the specific classifiers, and the structural synthesis can be performed based upon different possible configurations, operating principles, phenomena, and physical laws.

We use the following electromagnetic systems

- endless (E),
- open-ended (O),
- integrated (I),

and actuator/sensor geometry

- plate (P),
- spherical (S),
- torroidal (T),
- conical (N),
- cylindrical (C) and
- asymmetrical (A).

Using the possible electromagnetic systems and geometry, actuators and sensors (motion nano- and microstructures as well as nano- and microdevices) can be classified. From optimal structural and performance optimization viewpoints, a great number of factors influence the synthesis. For example, the designer must decide either rotational or translational devices (actuators and sensors) should be used. From electromagnetic standpoints, it is obvious that rotational-type actuators have higher power, torque and force densities, superior efficiency and performance compared with translational actuators. However, in many applications the translational actuators and sensors should be used due to specific kinematics, requirements, volume available, or size (for example, to measure the loads in the aircraft structures, the application of the translational-type sensor obviously is the preferable solution). Different rotational and translational actuators, as applied to displace the control surfaces and to change the geometry of flight surfaces, were illustrated in Figure 1.4.3 and 2.1.5.

The structural synthesis (geometrical design) and performance optimization of actuators and sensors is based on the consideration of the electromotive and magnetomotive forces, electromagnetic fields and magnetic structure, excitation, air gap and winding configurations, cooling and other important quantities. All possible actuator and sensor configurations can be classified using endless (closed) and open-ended (open) electromagnetic systems. This idea is extremely useful in studying existing and synthesizing novel motion structures and devices because an infinite number of innovative actuators and sensors can be synthesized. The application of a classifier is a starting point in structural synthesis and performance optimization. Advanced configurations can be synthesized and straightforwardly interpreted even without comprehensive analytical and numerical analysis (thorough analysis is needed as different actuator and sensor configurations are synthesized, and nonlinear electromagneticmechanical-thermal analysis must be performed and validated). It is evident that actuator/sensor geometry and electromagnetic systems play a central role in efficiency and performance. In fact, a motion structure (actuator/sensor) classifier, which is documented in Table 2.5.1, in addition to being qualitative, leads to quantitative analysis. Applying the cornerstone laws, the differential equations to model the actuator/sensor dynamics are straightforwardly derived, and analysis and simulations can be performed.

The actuators/sensors geometry and electromagnetic systems, as documented in Table 3.2.1, are partitioned into 3 horizontal and 6 vertical

strips, and contains 18 sections, each identified by ordered pairs of characters, such as (E, P) or (O, C). In each ordered pair, the first entry is a letter chosen from the bounded electromagnetic system set

 $M = \{E, O, I\}.$ The second entry is a letter chosen from the geometric set  $G = \{P, S, T, N, C, A\}.$ That is, the actuator/sensor set is give as  $M' G = \{(E, P), (E, S), (E, T), \dots, (I, N), (I, C), (I, A)\}.$ In general, we have  $M' G = \{(m, g): m\hat{I} \ M \text{ and } g\hat{I} \ G\}.$ 

However, the geometry-electromagnetic system classifier must be extended to guarantee completeness in the synthesis of motion structures and devices. It is well-known that using the basic electromagnetic features, the following basic types of nano-, micro-, and miniscale actuators and sensors can be synthesized:

- 1. direct current;
- 2. alternating current:
  - induction;
  - synchronous.

That is, the actuators and sensors are classified using a type classifier  $T = \{t : t \mid T\}$ .

It was emphasized that translational, rotational, and hybrid actuators and sensors can be synthesized, and a motion classifier is

$$\dot{\mathbf{A}} = \{ n : n \hat{\mathbf{I}} \ \dot{\mathbf{A}} \}.$$

Therefore, we have

$$M \stackrel{\prime}{} G \stackrel{\prime}{} T \stackrel{\prime}{} \stackrel{\mathsf{A}}{=} \{ (m, g, t, n) : m \hat{1} M, g \hat{1} G, t \hat{1} T \text{ and } n \hat{1} \hat{\mathsf{A}} \}.$$

Winding and cooling, power and size, torque-speed characteristics, excitation and bearing, as well as other actuators/sensors distinct features can be easily distinct and classified using classifiers in order to be integrated into the synthesis, structural and performance optimization. One concludes that electromechanical actuators/sensors can be mapped by a *Z*-tuple as {electromagnetic system, geometry, type, winding, excitation, cooling, etc}.

### Structural Classification Problem Solver

The algorithmic concept in the structural synthesis and performance optimization starts by selecting an initial set of competing configurations and solutions (electromagnetic system, geometry, type, et cetera) for a particular problem using specifications and requirements imposed. The solutions can be generated randomly from the entire domain, however, as was emphasized earlier, available information and accessible knowledge can be readily used in order to formulate the partial domain (classifier subset). The solutions are evaluated for their efficiency and fitness. Performance (regret) functionals can be designed to integrate weighted cost integrands (terms), and linear and nonlinear optimization (linear and nonlinear programming) allows one to find optimal solutions. The maxima or minima can be found using the gradientbased search. Alternatively, the evolutionary algorithms can be used, and the performance functional is used to compare and rank the competing solutions. The analysis and evaluation of candidate solutions are very complex problems due to infinite number of possible solutions (it is very difficult or impossible to find solutions). Thus, the solutions must be examined in the partial domain (subset) of most efficient and suitable solutions. This will allow one to define the partial classifier domain of solutions generation. Hence, the following should be performed to simplify the search and optimize the algorithm to solve a wide variety of structural synthesis and optimization problems:

- formulate and apply rules and criteria for solution sustaining based upon performance analysis, assessments, and outcomes;
- develop and generate the partial classifier domain (subset), select solution representations;
- initialize solutions;
- analyze and compare solutions, find the optimal solution.

Using the classifier developed, the designer can synthesize nano-, microand miniscale actuators and sensors (motion structures and devices which in terminology conventional electromechanical systems are called electromechanical motion devices or transducers). As an example, the synthesis of a two-phase permanent-magnet synchronous structural sensor with microscale actuator (motor) (generator) endless \_ electromagnetic system is performed using the *endless* magnetic system. The spherical, spherical-conical, conical, cylindrical, and asymmetrical geometries of the synthesized actuator/sensor are documented in Figure 3.2.1.

Table 3.2.1. Classification of nano-, micro-, and mini-scale actuators and sensors (motion structures)

$\setminus$	G	Geometry								
Μ	$\geq$	Plate, P	Spherical, S	Torroidal, T	Conical, N	Cylindrical, C	Asymmetrical,A			
Svstem	Endless (Closed), E						S			
Electromagnetic S	1 Open-Ended(Open), O						S			
	Integrated,	S	S	S	S	S	S			



Figure 3.2.1. Synthesized microscale actuator/sensor geometry
To solve analysis, prediction, classification, modeling, and optimization problems, neural networks or genetic algorithms can be efficiently used. Neural networks and generic algorithms have evolved to the mature concepts which allow the designer to perform reliable analysis, design, and optimization. Qualitative reasoning in the structural synthesis and optimization of NEMS and MEMS is based upon artificial intelligence, and the ultimate goal is to analyze, model, and optimize qualitative models of NEMS and MEMS when knowledge, processes, and phenomena are not precisely known due to uncertainties (for example, micromachined motion microstructures properties and characteristics, e.g., charge density, thermal noise and geometry, are not precisely known and varying). It is well known that qualitative models are more reliable compared with traditional models if there is a need to perform qualitative analysis, modeling, design, optimization, and prediction. Quantitative analysis and design use a wide range of physical laws and mathematical methods to guarantee validity and robustness using partially available quantitative information.

Structural synthesis and performance optimization can be based on the Qualitative representations knowledge domain. and compositional (geometric) modeling are used to create control knowledge (existing knowledge, modeling and analysis assumptions, specific plans and requirements domains, task domain, and preferences) for solving a wide range of problems. The solving architectures are based upon qualitative reusable fundamental domains (physical laws). Qualitative reasoning must be applied to solve complex physics problems in NEMS and MEMS, as well as to perform engineering analysis and design. Emphasizing the heuristic concept for choosing the initial domain of solutions, the knowledge domain is available to efficiently and flexibly map all essential phenomena, effects, and performances. In fact, Structural Classification Table 3.2.1 ensures modeling, synthesis, and optimization in qualitative and quantitative knowledge domains carrying out numerical and analytical analysis of NEMS and MEMS. To avoid excessive computations, optimal structures can be found using qualitative analysis and design. That is, qualitative representations and compositional structural modeling can be used to create control knowledge in order to solve fundamental and engineering problems efficiently. The Structural Classification Problem Solver, which gives knowledge domain using compositional structural modeling, analysis, and synthesis can be developed applying qualitative representations. This Structural Classification Problem Solver must integrate modeling and analysis assumptions, expertise, structures, and preferences that are used in constraining search (initial structural domain). Structural optimization is given in terms of qualitative representations and compositional modeling, making fundamental concepts of the domain explicit. The Structural Classification Problem Solver can be verified solving problems analytically and numerically. Heuristic synthesis strategies and knowledge regarding physical principles must be augmented for designing nano- and microstructures as well as nano- and microdevices. Through qualitative analysis and design, one constrains the search domain, the solutions are automatically generated, and the major performance characteristics and endto-end behavior are predicted. Existing knowledge, specific plans and requirements domains, task domain, preferences and logical relations, make it possible to reason about the modeling and analysis assumptions explicitly, which is necessary to successfully solve fundamental and engineering problem.

The Venn diagram provides a way to represent information about NEMS and MEMS structures and configurations. Once can use regions labeled with capital letters to represent sets and use lowercase letters to represent elements. By constructing a diagram that represents some initial sets, the designer can deduce other important relations. The basic conventional form of the Venn diagram is three intersecting circles as shown in Figure 3.2.2. In this diagram, each of the circles represents a set of elements that have some common property or characteristic. Let A stands for actuators, B stands for sensors, and C stands for translational motion microstructure. Then, the region ABC represents actuators and sensors which are synthesized using translational motion microstructure (e.g., *i*MEMS accelerometer studied early).



Figure 3.2.2. Venn diagram, p = 3: The closed curves are circles, and eight regions are labeled with the interiors that are included in each intersection. The eighth region is the outside, corresponding to the empty set

Let  $A = \{a_1, a_2, ..., a_{p-1}, a_p\}$  is the collection of simple closed curves in the XY plane.

The collection A is said to be an independent family if the intersection of  $b_1, b_2, ..., b_{p-1}, b_p$  is nonempty, where each  $b_i$  is either  $int(a_i)$  (the interior of

 $a_i$ ) or is  $ext(a_i)$  (the exterior of  $a_i$ ). If, in addition, each such intersection is connected, then A is a p-Venn diagram, where p is the number of curves in the diagram.

## 3.2.2. Algebra of Sets

A set is a collection of objects (order is not significant and multiplicity is usually ignored) called the elements of the set. Symbols are used widely in the algebra of sets.

If a is an element of set A, we have  $a\hat{i} A$ , and if a is not an element of set A, we write  $a\hat{i} A$ .

If a set A contains only the single element a, it is denoted as  $\{a\}$ .

The null set (set does not contain any elements) is denoted as  $\mathcal{F}$ .

Two sets, A and B are equal (A = B) if  $a\hat{i} A$  iff  $a\hat{i} B$ .

If  $a\hat{i} A$  implies that  $a\hat{i} B$ , then A is a subset of B, and  $A\hat{i} B$ .

The symbols  $\hat{i}$  and  $\hat{i}$  are used to describe a proper and an improper subsets. For example, if  $A\hat{i} B$  and  $B\hat{i} A$ , then A is called an improper subset of B, A = B (if there exists element b in B which is not in A, then A is a proper subset of B).

If the set of all elements under consideration make up the universal set U, then  $A \stackrel{\circ}{l} U$ .

The set A' is the complement of set A, if it is made up of all the elements of U which are not elements of A. For each set A there exists a unique set A' such that  $A \bigcup A' = U$  and  $A \cap A' = \mathcal{F}$ . Furthermore, (A')' = A.

Two operations on sets are union  $\bigcup$  and intersection  $\bigcap$ . For example, an element  $a\hat{1} \ A \bigcup B$  iff  $a\hat{1} \ A \ or \ a\hat{1} \ B$ . In contrast, an element  $a\hat{1} \ A \cap B$  iff  $a\hat{1} \ A$  and  $a\hat{1} \ B$ .

Using  $\bigcup$  and  $\bigcap$  operators we have the following algebra of sets laws:

• closure: there is a unique set  $A \cup B$  which is a subset of U, and there is a unique set  $A \cap B$  which is a subset of U;

• commutative:  $A \cup B = B \cup A$  and  $A \cap B = B \cap A$ ;

associative:

 $(A \cup B) \cup C = A \cup (B \cup C)$  and  $(A \cap B) \cap C = A \cap (B \cap C)$ ;

• distributive:

 $A \cup (B \cap C) = (A \cup B) \cap (A \cup C) \text{ and } A \cap (B \cup C) = (A \cap B) \cup (A \cap C),$ and using the index set  $L, I\hat{I} L$ , one has

$$A \cup \stackrel{\circ}{\xi}_{I_1} \stackrel{\circ}{\sqcup} B_I \stackrel{\circ}{\underset{o}{\stackrel{\circ}{\to}}} = \bigcap_{I_1} (A \cup B_I) \text{ and } A \cap \stackrel{\circ}{\xi}_{I_1} \stackrel{\circ}{\sqcup} B_I \stackrel{\circ}{\underset{o}{\stackrel{\circ}{\to}}} = \bigcup_{I_1} (A \cap B_I);$$

idempotent:  $A \bigcup A = A$  and  $A \cap A = A$ ;

- identity:  $A \bigcup \mathcal{F} = A$  and  $A \cap U = A$ ;
- DeMorgan's:  $(A \cup B)' = A' \cap B'$  and  $(A \cap B)' = A' \cup B'$ ;
- U and Æ laws:  $U \bigcup A = U$ ,  $U \cap A = A$ , Æ $\bigcup A = A$  and Æ $\cap A = Æ$ . Additional rules and properties of the complement are:  $A \downarrow (A \cup B), (A \cap B) \downarrow A, A \downarrow U, Æ \downarrow A$ If  $A \downarrow B$  then  $A \cup B = B$ , and if  $B \downarrow A$  then  $A \cap B = B$ .

# Sets and Lattices

A set is simply a collection of elements. For example, a, b and c can be grouped together as a set which is expressed as  $\{a, b, c\}$  where the curly braces are used to enclose the elements that constitute a set. In addition to the set  $\{a, b, c\}$  we define the sets  $\{a, b\}$  and  $\{d, e, g\}$ . Using the union operation, we have

 $\{a,b,c\} \cup \{a,b\} = \{a,b,c\}$  and  $\{a,b,c\} \cup \{d,e,g\} = \{a,b,c,d,e,g\}$ , while the intersection operation leads us to

 $\{a,b,c\} \cap \{a,b\} = \{a,b\}$  and  $\{a,b,c\} \cap \{d,e,g\} = \mathcal{F} = \{\}$ , where  $\{\}$  is the empty (or null) set.

The subset relation can be used to partially order a set of sets. If some set A is a subset of a set B, then these sets are partially ordered with respect to each other. If a set A is not a subset of set B, and B is not a subset of A, then these sets are not ordered with respect to each other. This relation can be used to partially order a set of sets in order to classify NEMS and MEMS. Sets possess some additional structural, geometrical, as well as other properties. Additional definitions and properties can be formulated and used applying lattices.

Using a lattice, we have

- $A \stackrel{f}{i} A$  (reflexive law);
- if  $A \mid B$  and  $B \mid A$ , then A=B (antisymmetric law);
- if  $A \mid B$  and  $B \mid C$ , then  $A \mid C$  (transitive law);
- *A* and *B* have a unique greatest bound,  $A \cap B$ . Furthermore,  $G = A \cap B$ , or *G* is the greatest lower bound of *A* and *B* if:  $A \mid G$ ,  $B \mid G$ , and if *W* is any lower bound of *A* and *B*, then  $G \mid W$ ;
- A and B have a unique least upper bound,  $A \cup B$ . Furthermore,  $L = A \cup B$ , or L is the least upper bound of A and B if:  $L \upharpoonright A$ ,  $L \upharpoonright B$ , and if P is any upper bound of A and B, then  $P \upharpoonright L$ .

A lattice is a partially ordered set where for any pair of sets (hypotheses) there is a least upper bound and greatest lower bound. Let our current hypothesis is H1 and the current training example is H2. If H2 is a subset of

H1, then no change of H1 is required. If H2 is not a subset of H1, then H1 must be changed. The minimal generalization of H1 is the least upper bound of H2 and H1, and the minimal specialization of H1 is the greatest lower bound of H2 and H1. Thus, the lattice serves as a map that allows us to locate out current hypothesis H1 with reference to the new information H2. There exists the correspondence between the algebra of propositional logic and the algebra of sets. We refer to a hypotheses as logical expressions, as rules that define a concept, or as subsets of the possible instances constructible from some set of dimensions. Furthermore, union and intersection were the important operators used to define a lattice. In addition, the propositional logic expressions can also be organized into a corresponding lattice to implement the artificial learning.

A general structure S is an ordered pair formed by a set object O and a set of binary relations R such that

$$S = (O, R) = \bigcup_{i=1}^{n} S_i ,$$

where  $O = \{o_1, o_2, ..., o_{z-1}, o_z\}$ , " $o_i \hat{1} O$ ;  $R = \{r_1, r_2, ..., r_{p-1}, r_p\}$ , " $r_i \hat{1} R$ ;  $S_i$  is the simple structure.

In the set object *O* we define the input *n*, output *u*, and internal *a* variables. We have  $o_i = \{q_1^i, q_2^i, ..., q_{g-1}^i, q_g^i\}, q_j^i = (n_j^i, u_j^i, a_j^i), q_j^i \hat{1} O^3$ . Hence, the range of *q*, as a subset of *O*, is *R*(*q*). Using the input-output structural function, different NEMS and MEMS can be synthesized. The documented general theory of structural optimization, which is built using the algebra of sets, allows the designer to derive relationships, flexibly adapt, fit, and optimize the nano- and microscale structures within the sets of given possible solutions.

## **3.3. DIRECT-CURRENT MICROMACHINES**

It has been shown that the basic electromagnetic principles and fundamental physical laws are used to design motion nano- and microstructures. Nano- and microengineering leverages from conventional theory of electromechanical motion devices, electromagnetics, integrated circuits, and quantum mechanics. The fabrication of motion microstructures is based upon CMOS (VLSI) technology, and rotational and translational transducers (actuators and sensors) were manufactured and tested. The major challenge is the difficulties to fabricate windings for microdevices (micro electric machines), reliability and ruggedness (due to bearing problems), etc. It appears that novel fabrication technologies allow one to overcome many challenges. The most efficient class of micromachines to be used as MEMS motion microdevices are induction and synchronous. These micromachines do not have collector, and the stator windings (for induction micromachines) and permanent-magnet stator (for synchronous micromachines, e.g., permanent-magnet synchronous machine and stepper motors) have been manufactured and tested. Direct-current machines are not the preferable choice. However, these micromachines will be covered first because students and engineers are familiar with these electric machines. Furthermore, even using the conventional manufacturing technology, miniscale DC motors (less than 2 mm diameter) have been massively manufactured for pagers, phones, cameras, etc.

The list of basic variables and symbols used in this chapter is given below:

- $i_a$  is the currents in the armature winding;
- $u_a$  is the applied voltages to the armature windings;

 $\boldsymbol{w}_r$  and  $\boldsymbol{q}_r$  are the angular velocity and angular displacement of the rotor;

 $E_a$  is the *electromotive force*;

 $T_e$  and  $T_L$  are the electromagnetic and load torques;

- $r_a$  is the resistances of the armature windings;
- $L_a$  is the self-inductances of the armature windings;
- $B_m$  is the viscous friction coefficient;
- J is the equivalent moment of inertial of the rotor and attached load.

Micro- and miniscale permanent-magnet electric motors and generators are rotating energy-transfer electromechanical motion devices which convert energy by means of rotational motions. Electric machines (motion structures and motion devices) are the major part of MEMS, and therefore they must be thoroughly studied with the driving ICs. Electric motors convert electrical energy to mechanical energy, while generators convert mechanical energy to electrical energy. It is worth mentioning that permanent-magnet electric machines can be used as motors and generators. Hence, the energy conversion is reversible, and conventional generators can be operated as motors and vice versa. That is, micro permanent-magnet electric machines can be used as the actuators and sensors. Electric machines have stationary and rotating members, separated by an air gap. The armature winding is placed in the rotor slots and connected to a rotating commutator, which rectifies the induced voltage, see Figure 3.3.1. One supplies the armature and excitation voltages or feds the armature and excitation currents to the armature (rotor) and field (stator) windings. These stator and rotor windings are coupled magnetically.



Figure 3.3.1. Two-pole DC machine with commutator

The brushes, which are connected to the armature windings, ride on the commutator. The armature winding consists of identical coils carried in slots uniformly distributed around the periphery of the rotor. The stator has salient poles, and conventional DC machines are excited by direct current; in particular, if a voltage-fed converter is used, a dc voltage  $u_f$  is supplied to the stationary field windings. Hence, the excitation magnetic field is produced by the field coils. It should be emphasized that in the permanent-magnet machines, the magnetic field is established by permanent magnets. Due to the commutator (circular conducting segments), armature and field windings produce stationary *magnetomotive forces* which are displaced by 90 electrical degrees. The armature magnetic force is along the *quadrature* (rotor) magnetic torque is produced as a result of the interaction of these stationary *magnetomotive forces*.

From Kirchhoff's law, one obtains the following steady-state equation for the armature voltage for electric motors (the armature current opposes the induced *electromotive force*)

 $u_a - E_a = i_a r_a$ .

For generators, the armature current is in the same direction as the generated *electromotive force*, and we have

 $u_a - E_a = -i_a r_a$ .

The difference between the applied voltage and the induced *electromotive force* is the voltage drop across the internal armature resistance  $r_a$ . One concludes that electric machines rotate at an angular velocity at which the *electromotive force* generated in the armature winding balances the armature voltage. If an electric machine operates as a motor, the induced *electromotive force* is less than the voltage applied to the windings. If an electric machine operates as a generator, the generated (induced) *electromotive force* is greater than the terminal voltage.

The constant magnetic flux in AC and DC machines can be produced by permanent-magnet poles. Electric machines with permanent-magnet poles are called permanent-magnet machines. Permanent-magnet DC motor/generator is illustrated in Figure 3.3.2, and a schematic diagram of permanent-magnet DC machines is illustrated in Figure 3.3.3.



Figure 3.3.2. Permanent-magnet DC machines



Figure 3.3.3. Schematic diagram of permanent-magnet electric machines (current direction corresponds to the motor operation)

By using Kirchhoff's voltage law and Newton's second law of motion, the differential equations for permanent-magnet DC machines can be easily derived. Assuming that the *susceptibility* is constant (in reality, Curie's constant varies as a function of temperature), one supposes that the flux, established by the permanent magnet poles, is constant. Then, denoting the *back emf* and *torque* constants as  $k_a$ , we have the following differential equations describing the transient behavior of the armature winding and *torsional-mechanical* dynamics

$$\frac{di_a}{dt} = -\frac{r_a}{L_a}i_a - \frac{k_a}{L_a}\mathbf{w}_r + \frac{1}{L_a}u_a,$$

$$\frac{d\mathbf{w}_r}{dt} = \frac{k_a}{J}i_a - \frac{B_m}{J}\mathbf{w}_r - \frac{1}{J}T_L.$$
(3.3.1)

From (3.3.1) it is easy to find the model in matrix form. We have

An *s*-domain block diagram of permanent-magnet DC motors is illustrated in Figure 3.3.4.



Figure 3.3.4. Block diagram of permanent-magnet DC motors: *s*-domain block diagram

The angular velocity can be reversed if the polarity of the applied voltage is changed (the direction of the field flux cannot be changed). The steady-state torque-speed characteristic curves obey the following equation

$$\mathbf{W}_{r} = \frac{u_{a} - r_{a}i_{a}}{k_{a}} = \frac{u_{a}}{k_{a}} - \frac{r_{a}}{k_{a}^{2}}T_{e}, \qquad (3.3.2)$$

and a spectrum of the torque-speed characteristic curves is illustrated in Figure 3.3.5.



Figure 3.3.5.Torque-speed characteristics for permanent-magnet motors

If micro permanent-magnet DC machine is used as the generator (tachogenerator measure the angular velocity), the circuitry dynamics for the resistive load  $R_L$  is given as

$$\frac{di_a}{dt} = -\frac{r_a + R_L}{L_a}i_a + \frac{k_a}{L_a}\boldsymbol{W}_r$$

That is, in the steady-state, the armature current is proportional to the angular velocity, and we have

$$i_a = \frac{k_a}{r_a + R_L} \mathbf{w}_r$$

As was emphasized in section 1.5, flip-chip MEMS are found wide application due to low cost and application of well-developed fabrication processes. For example, monolithic dual power operational amplifiers (Motorola TCA0372 available in plastic packages 751G, 648, and 626) feeds DC minimotor to regulate the angular velocity, see Figure 3.3.6.



Figure 3.3.6. Application of a monolithic IC to control DC motor

Motion micro- and ministructures as well as micro- and minidevices (actuators and sensors) are mounted face down with bumps on the pads that form electrical and mechanical joints to the ICs substrate. Figure 3.3.7 illustrates a flip-chip MEMS with permanent-magnet micromotor driven by the MC33030 monolithic servo motor driver. Control algorithms are implemented to control the angular velocity of electric motors. The MC33030 integrates on-chip operational amplifier and comparator, driving and braking logic, PWM four-quadrant converter, etc. The MC33030 data and complete description are given. As in the conventional configurations, the difference between the reference (command) and actual angular velocity or displacement, linear velocity or position, is compared by the error amplifier, and two comparators are used. A pnp differential output power stage provides driving and braking capabilities, and the four-quadrant Hconfigured power stage guarantees high performance and efficiency. Using the error between the desired (command) and actual angular velocity or displacement, the bipolar voltage  $u_a$  is applied to the armature winding, the electromagnetic torque is developed due to the current  $i_a$ , and micro- or minimotor rotates. A complete description of the MC33030 monolithic servomotors driver is given below.



Figure 3.3.7. Flip-chip monolithic MEMS: MC33030 ICs and micromotor

## Monolithic ICs: Direct-Current Servo Motors Driver MC33030

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#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	VCC	36	V
Input Voltage Range Op Amp, Comparator, Current Limit (Pins 1, 2, 3, 6, 7, 8, 9, 15)	VIR	-0.3 to V <sub>CC</sub>	V
Input Differential Voltage Range Op Amp, Comparator (Pins 1, 2, 3, 6, 7, 8, 9)	VIDR	-0.3 to V <sub>CC</sub>	v
Delay Pin Sink Current (Pin 16)	IDLY (sink)	20	mA
Output Source Current (Op Amp)	Isource	10	mA
Drive Output Voltage Range (Note 1)	VDRV	-0.3 to (V <sub>CC</sub> + V <sub>F</sub> )	V
Drive Output Source Current (Note 2)	IDRV(source)	1.0	A
Drive Output Sink Current (Note 2)	IDRV(sink)	1.0	A
Brake Diode Forward Current (Note 2)	١F	1.0	Α
Power Dissipation and Thermal characteristics P Suffix, Dual In Line Case 648C Thermal Ressistance, Junction-to-Air Thermal Ressistance, Junction-to-Case (Pins 4, 5, 12, 13) DW Suffix, Dual In Line Case 751G Thermal Ressistance, Junction-to-Air Thermal Ressistance, Junction-to-Case (Pins 4, 5, 12, 13)	R <sub>0</sub> ja R <sub>0</sub> jc R <sub>0</sub> ja R <sub>0</sub> jc	80 15 94 18	°C/W
Operating Junction Temperature	ТJ	+150	°C
Operating Ambient Temperature Range	TA	-40 to +85	°C
Storage Temperature Range	Tsta	-65 to +150	°C

NOTES: 1. The upper vitale per lis clamped by the forward fory. Vort the the dide.
 2. These values are for continuous DC current. Maximum package power dissipation limits must be observed.

#### ELECTRICAL CHARACTERISTICS (V<sub>CC</sub> = 14 V, T<sub>A</sub> = 25°C, unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit		
ERROR AMP							
Input Offset Voltage ( $-40^{\circ}C \le T_A \le 85^{\circ}C$ ) VPin 6 = 7.0 V, R <sub>L</sub> = 100 k	VIO	-	1.5	10	mV		
Input Offset Current (VPin 6 = 1.0 V, RL = 100 k)	lio	-	0.7	-	nA		
Input Bias current (VPin 6 = 1.0 V, RL = 100 k)	IIB	-	7.0	-	nA		
Input Common–Mode Voltage Range $\Delta V_{IO} = 20 \text{ mV}, \text{ R}_{L} = 100 \text{ k}$	VICR	-	0 to (V <sub>CC</sub> - 1.2)	-	V		
Slew Rate, Open Loop (VID = 0.5 V, CL = 15 pF)	SR	-	0.40	-	V/µs		
Unity-Gain Crossover Frequency	fC	-	550	-	kHz		
Unity-Gain Phase Margin	φm	-	63	-	deg.		
Common-mode Rejection Ratio (VPin 6 = 7.0 V, RL = 100 k)	CMRR	50	82	-	dB		
Power Supply Rejection Ratio V <sub>CC</sub> = 9.0 to 16 V, V <sub>Pin 6</sub> = 7.0 V, RL = 100 k	PSRR	-	89	-	dB		
Output Source Current (VPin 6 = 12 V)	IO +	-	1.8	-	mA		
Output Sink Current (VPin 6 = 1.0 V)	IO -		250	-	μΑ		
Output Voltage Swing (R <sub>L</sub> = 17 k to Ground)	VOH VOL	12.5 -	13.1 0.02	-	V V		

NOTES: 3. The upper or lower hysteresis will be lost when operating the Input, Pin 3, close to the respective rail. Refer to Figure 4. 4. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient temperature as possible.

ELECTRICAL CHARACTERISTICS (continued)	(V <sub>CC</sub> = 14 V, I <sub>A</sub> = 25°C, unless otherwise noted.)

Characterstic	Symbol	Min	Тур	Max	Unit
WINDOW DETECTOR					
Input Hysteresis Voltage (V1 – V4, V2 – V, Figure 18)	VH	25	35	45	mV
Input Dead Zone Range (V2 - V4, Figure 18)	VIDZ	166	210	254	mV
Input Offset Voltage (I[V2 - VPin 2] - [VPin 2 - V4]I Figure 18)	VIO	-	25	-	mV
Input Functional Common-Mode Range (Note 3)					V
Upper Threshold	VIH	-	(V <sub>CC</sub> -1.05)	-	
Lower I nreshold	VIL	-	0.24	-	
Pins 1 and 2 Open	VRSC	-	(1/2 VCC)	-	v
Window Detactor Propagation Delay	tp(IN/DRV)	-	2.0	-	μs
Comparator Input, Pin 3, to Drive Outputs					
Over-Current References Resistor Voltage (pin 15)	Boc	3.9	4.3	47	V
Delay Pin Source Current		-	5.5	6.9	A
Delay Pin Sink Current (Boc = $27 \text{ k}$ (DD) = $0 \text{ mA}$ )	DLT (SOURCE)		0.0	0.0	mA
$V_{DLY} = 5.0 V$	·DLf (SITK)	-	0.1	-	
$V_{DLY} = 8.3 V$		-	0.7	-	
$V_{DLY} = 14 V$		-	16.5	-	
Delay Pin voltage, Low State (IDLY = 0 mA)	VOL(DLY)	-	0.3	0.4	V
Over-Current Shutdown Threshold	Vth(OC)				V
$V_{CC} = 14 V$		6.8	7.5	8.2	
$V_{CC} = 8.0 V$		5.5	0.0	0.5	-
Delay capacitor Input, Pin 16, to Outputs, VID = 0.5 V	<sup>t</sup> p(DLY/DRV)	_	1.8	-	μs
POWER H-SWITCH					
Drive–Output Saturation (–40°C $\leq$ TA $\leq$ +85°C, Note 4)					V
High-State (I <sub>source</sub> = 100 mA)	VOH(DRV)	(VCC - 2)	(V <sub>CC</sub> – 0.85)	-	
Low-State (Isink = 100 mA)	VOL(DRV)	-	0.12	1.0	-
Bise Time	tr	_	200	_	ns
Fall Time	tf	-	200	-	
Brake Diode Forward Voltage Drop (IF = 200 mA, Note 4)	VF	-	1.04	2.5	V
TOTAL DEVICE		1			
Standby Supply Current	ICC	-	14	25	mA
Over–Voltage Shutdown Threshold ( $-40^{\circ}C \le T_A \le +85^{\circ}C$ )	V <sub>th(OV)</sub>	16.5	18	20.5	V
Over-Voltage Shutdown Hysteresis (Device "off" to "on")	VH(OV)	0.3	0.6	1.0	V
Operating Voltage Lower Threshold (-40°C $\leq$ T <sub>A</sub> $\leq$ +85°C)	Vcc	-	7.5	8.0	V

NOTES: 3. The upper or lower hysteresis will be lost when operating the Input, Pin 3, close to the respective rail. Refer to Figure 4. 4. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient temperature as possible.













Figure 10. Normalized Delay Pin Source Current versus Temperature







Figure 15. P Suffix (DIP-16) Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length



Figure 16. DW Suffix (SOP--16L) Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length



#### **OPERATING DESCRIPTION**

The MC33030 was designed to drive tractional horsepower DC motors and sense actuator position by voltage feedback. A typical servo application and representative internal block diagram are shown in Figure 17. The system operates by setting a voltage on the reference input of the Window Detector (Pin 1) which appears on (Pin 2). A DC motor then drives a position sensor, usually a potentiometer driven by a gear box, in a corrective fashion so that a voltage proportional to position is present at Pin 3. The servo motor will continue to run until the voltage at Pin 3 falls within the dead zone, which is centered about the reference voltage.

The Window Detector is composed of two comparators, A and B, each containing hysteresis. The reference input, common to both comparators, is pre-biased at 1/2 V<sub>CC</sub> for simple two position servo systems and can easily be overriden by an external voltage divider. The feedback voltage present at Pin 3 is connected to the center of two resistors that are driven by an equal magnitude current source and sink. This generates an offset voltage at the input of each comparator which is centered about Pin 3 that can float virtually from V<sub>CC</sub> to ground. The sum of the upper and lower offset voltages is defined as the window detector input dead zone range.

To increase system flexibility, an on-chip Error Amp is provided. It can be used to buffer and/or gain-up the actuator position voltage which has the effect of narrowing the dead zone range. A PNP differential input stage is provided so that the input common-mode voltage range will include ground. The main design goal of the error amp output stage was to be able to drive the window detector input. It typically can source 1.8 mA and sink 250 µA. Special design considerations must be made if it is to be used for other applications.

The Power H–Switch provides a direct means for motor drive and braking with a maximum source, sink, and brake current of 1.0 A continuous. Maximum package power dissipation limits must be observed. Refer to Figure 15 for thermal information. For greater drive current requirements, a method for buffering that maintains all the system features is shown in Figure 30.

The Over-Current Monitor is designed to distinguish between motor start-up or locked rotor conditions that can occur when the actuator has reached its travel limit. A fraction of the Power H-Switch source current is internally fed into one of the two inverting inputs of the current comparator, while the non-inverfing input is driven by a programmable current reference. This reference level is controlled by the resistance value selected for ROC, and must be greater than the required motor run-current with its mechanical load over temperature; refer to Figure 8. During an over-current condition, the comparator will turn off and allow the current source to charge the delay capacitor, CDLY. When CDLY charges to a level of 7.5 V, the set input of the over-current latch will go high, disabling the drive and brake functions of the Power H-Switch. The programmable time delay is determined by the capacitance valueselected for CDLY.

$$t_{DLY} = \frac{v_{ref}C_{DLY}}{I_{DLY(source)}} = \frac{7.5 C_{DLY}}{5.5 \,\mu\text{A}} = 1.36 C_{DLY} \text{ in } \mu\text{F}$$

This system allows the Power H–Switch to supply motor start–up current for a predetermined amount of time. If the rotor is locked, the system will time-out and shut-down. This feature eliminates the need for servo end-of-travel or limit switches. Care must be taken so as not to select too large of a capacitance value for CpLy. An over-current condition for an excessively long time-out period can cause the integrated circuit to overheat and eventually fail. Again, the maximum package power dissipation limits must be observed. The over-current latch is reset upon power-up or by readjusting Vpin 2 as to cause Vpin 3 to enter or pass through the dead zone. This can be achieved by requesting the motor to reverse direction.

An Over–Voltage Monitor circuit provides protection for the integrated circuit and motor by disabling the Power H–Switch functions if V<sub>CC</sub> should exceed 18 V. Resumption of normal operation will commence when V<sub>CC</sub> falls below 17.4 V.

A timing diagram that depicts the operation of the Drive/Brake Logic section is shown in Figure 18. The waveforms grouped in [1] show a reference voltage that was preset, appearing on Pin 2, which corresponds to the desired actuator position. The true actuator position is represented by the voltage on Pin 3. The points V1 through V4 represent the input voltage thresholds of comparators A and B that cause a change in their respective output state. They are defined as follows:

 $V_1$  = Comparator B turn-off threshold  $V_2$  = Comparator A turn-on threshold  $V_3$  = Comparator A turn-off threshold  $V_4$  = Comparator B turn-on threshold

V1-V4 = Comparator B input hysteresis voltage

V2-V3 = Comparator A input hysteresis voltage

 $V_2 - V_4 =$  Window detector input dead zone range

I(V2-VPin2) - (VPin2 - V4)I = Window detector input voltage

It must be remembered that points V1 through V4 always try to follow and center about the reference voltage setting if it is within the input common-mode voltage range of Pin 3; Figures 4 and 5. Initially consider that the feedback input voltage level is somewhere on the dashed line between V2 and V4 in [1]. This is within the dead zone range as defined above and the motor will be off. Now if the reference voltage is raised so that VPin 3 is less than V4, comparator B will turn-on [3] enabling Q Drive, causing Drive Output A to sink and B to source motor current [8]. The actuator will move in Direction B until VPin 3 becomes greater than V1. Comparator B will turn-off, activating the brake enable [4] and Q Brake [6] causing Drive Output A to go high and B to go into a high impedance state. The inertia of the mechanical system will drive the motor as a generator creating a positive voltage on Pin 10 with respect to Pin 14. The servo system can be stopped quickly, so as not to over-shoot through the dead zone range, by braking. This is accomplished by shorting the motor/generator terminals together. Brake current will flow into the diode at Drive Output B, through the internal V<sub>CC</sub> rail, and out the emitter of the sourcing transistor at Drive Output A. The end of the solid line and beginning of the dashed for Vpin 3 [1] indicates the possible resting position of the actuator after braking



If Vpin 3 should continue to rise and become greater than V2, the actuator will have over shot the dead zone range and cause the motor to run in Direction A until Vpin 3 is equal to V3. The Drive/Brake behavior for Direction A is Identical to that of B. Overshooting the dead zone range in both directions can cause the servo system to continuously hunt or oscillate. Notice that the last motor run-direction is stored in the direction latch. This information is needed to determine whether Q or  $\overline{0}$  Brake is to be enabled when Vpin 3 enters the dead zone range. The dashed lines in [8,9] indicate the resulting waveforms of an over-current condition that has exceeded the programmed time delay. Notice that both Drive Outputs go into a high impedance state until Vpin 2 is readjusted so that Vpin 3 enters or crosses through the dead [7,4].

The inputs of the Error Amp and Window Detector can be susceptible to the noise created by the brushes of the DC motor and cause the servo to hunt. Therefore, each of these inputs are provided with an internal series resistor and are pinned out for an external bypass capacitor. It has been found that placing a capacitor with *short* leads directly across the brushes will significantly reduce noise problems. Good quality RF bypass capacitors in the range of 0.001 to 0.1  $\mu$ F may be required. Many of the more economical motors will generate significant levels of RF energy over a spectrum that extends from DC to beyond 200 MHz. The capacitance value and method of noise filtering must be determined on a system by system basis.

Thus far, the operating description has been limited to servo systems in which the motor mechanically drives a potentiometer for position sensing. Figures 19, 20, 27, and 31 show examples that use light, magnetic flux, temperature, and pressure as a means to drive the feedback element. Figures 21, 22 and 23 are examples of two position, open loop servo systems. In these systems, the motor runs the actuator to each end of its travel limit where the Over-Current Monitor detects a locked rotor condition and shuts down the drive. Figures 32 and 33 show two possible methods of using the MC33030 as a switching motor controller. In each example a fixed reference voltage is applied to Pin 2. This causes VPin 3 to be less than V4 and Drive Output A, Pin 14, to be in a low state saturating the TIP42 transistor. In Figure 32, the motor drives a tachometer that generates an ac voltage proportional to RPM. This voltage is rectified, filtered, divided down by the speed set potentiometer, and applied to Pin 8. The motor will accelerate until VPin 3 is equal to V1 at which time Pin 14 will go to a high state and terminate the motor drive. The motor will now coast until VPin 3 is less than V4 where upon drive is then reapplied. The system operation of Figure 31 is identical to that of 32 except the signal at Pin 3 is an amplified average of the motors drive and back EMF voltages. Both systems exhibit excellent control of RPM with variations of V<sub>CC</sub>; however, Figure 32 has somewhat better torque characteristics at low RPM.

Figure 18. Timing Diagram



### Figure 19. Solar Tracking Servo System



Figure 20. Magnetic Sensing Servo System



Typical sensitivity with gain set at 3.9 k is 1.5 mV/gauss. Servo motor controls magnetic field about sensor.

### Figure 22. Digital Two Position Servo System



Figure 21. Infrared Latched Two Position



Figure 24. Second Order Low-Pass Active Filter



Figure 23. 0.25 Hz Square-Wave

Servo Agitator





Figure 27. Temperature Sensing Servo System



In this application the servo motor drives the heat/air conditioner modulator door in a duct system.

Figure 29. Remote Latched Shutdown



A direction change signal is required at Pins 2 or 3 to reset the over-current latch.

Figure 26. Differential Input Amplifier



Figure 28. Bridge Amplifier



Figure 30. Power H-Switch Buffer



This circuit maintains the brake and over-current features of the MC33030. Set  $R_{OC}$  to 15 k for IDRV(max) ~ 0.5 Å.

### Figure 31. Adjustable Pressure Differential Regulator





Figure 33. Switching Motor Controller With Buffered Output and Back EMF Sensing



## **3.4. INDUCTION MOTORS**

In this section, the following variables and symbols are used:

 $u_{as}$ ,  $u_{bs}$  and  $u_{cs}$  are the phase voltages in the stator windings *as*, *bs* and *cs*;  $u_{qs}$ ,  $u_{ds}$  and  $u_{os}$  are the *quadrature-*, *direct-*, and *zero-*axis components of stator voltages;

 $i_{as}$ ,  $i_{bs}$  and  $i_{cs}$  are the phase currents in the stator windings *as*, *bs* and *cs*;  $i_{qs}$ ,  $i_{ds}$  and  $i_{os}$  are the *quadrature-*, *direct-*, and *zero-*axis components of stator currents;

 $\mathbf{y}_{as}, \mathbf{y}_{bs}$  and  $\mathbf{y}_{cs}$  are the stator flux linkages;

 $\mathbf{y}_{qs}$ ,  $\mathbf{y}_{ds}$  and  $\mathbf{y}_{os}$  are the *quadrature-*, *direct-*, and *zero-*axis components of stator flux linkages;

 $u_{ar}$ ,  $u_{br}$  and  $u_{cr}$  are the voltages in the rotor windings *ar*, *br* and *cr*;

 $u_{qr}$ ,  $u_{dr}$  and  $u_{or}$  are the *quadrature-*, *direct-*, and *zero-*axis components of rotor voltages;

 $i_{ar}$ ,  $i_{br}$  and  $i_{cr}$  are the currents in the rotor windings *ar*, *br* and *cr*;

 $i_{qr}$ ,  $i_{dr}$  and  $i_{or}$  are the *quadrature-*, *direct-*, and *zero-*axis components of rotor currents;

 $\mathbf{y}_{ar}, \mathbf{y}_{br}$  and  $\mathbf{y}_{cr}$  are the rotor flux linkages;

 $\mathbf{y}_{qr}$ ,  $\mathbf{y}_{dr}$  and  $\mathbf{y}_{or}$  are the *quadrature-*, *direct-*, and *zero-*axis components of rotor flux linkages;

 $\boldsymbol{W}_r$  and  $\boldsymbol{W}_{rm}$  are the electrical and mechanical angular velocities;

 $\boldsymbol{q}_r$  and  $\boldsymbol{q}_{rm}$  are the electrical and mechanical angular displacements;

 $T_e$  is the electromagnetic torque developed by the motor;

 $T_L$  is the load torque applied;

 $r_s$  and  $r_r$  are the resistances of the stator and rotor windings;

 $L_{ss}$  and  $L_{rr}$  are the self-inductances of the stator and rotor windings;

 $L_{ms}$  is the stator magnetizing inductance;

 $L_{ls}$  and  $L_{lr}$  are the stator and rotor leakage inductances;

 $N_s$  and  $N_r$  are the number of turns of the stator and rotor windings; P is the number of poles;

 $B_m$  is the viscous friction coefficient;

J is the equivalent moment of inertia;

w and q are the angular velocity and displacement of the reference frame.

# 3.4.1. Two-Phase Induction Motors

Two-phase induction motors, shown in Figure 3.4.1, have two stator and rotor windings.



Figure 3.4.1. Two-phase symmetrical induction motor

To develop a mathematical model of two-phase induction motors, we model the stator and rotor circuitry dynamics. As the control and state variables we use the voltages applied to the stator (as and bs) and rotor (ar and br) windings, as well as the stator and rotor currents and flux linkages.

Using Kirchhoff's voltage law, four differential equations are

$$u_{as} = r_s i_{as} + \frac{d\mathbf{y}_{as}}{dt}, \ u_{bs} = r_s i_{bs} + \frac{d\mathbf{y}_{bs}}{dt},$$
$$u_{ar} = r_r i_{ar} + \frac{d\mathbf{y}_{ar}}{dt}, \ u_{br} = r_r i_{br} + \frac{d\mathbf{y}_{br}}{dt}.$$

Hence, in matrix form we have

1\_--

$$\mathbf{u}_{abs} = \mathbf{r}_{s} \mathbf{i}_{abs} + \frac{d\mathbf{y}_{abs}}{dt},$$
  
$$\mathbf{u}_{abr} = \mathbf{r}_{r} \mathbf{i}_{abr} + \frac{d\mathbf{y}_{abr}}{dt},$$
(3.4.1)

where  $\mathbf{u}_{abs} = \stackrel{\acute{e}\mathcal{U}_{as}}{\stackrel{\acute{e}}{\underline{u}}}_{\stackrel{\acute{e}}{\underline{u}}}_{\stackrel{\acute{e}}{\underline{u}}}_{\stackrel{\acute{e}}{\underline{u}}}, \quad \mathbf{u}_{abr} = \stackrel{\acute{e}\mathcal{U}_{ar}}{\stackrel{\acute{e}}{\underline{u}}}_{\stackrel{\acute{e}}{\underline{u}}}, \quad \mathbf{i}_{abs} = \stackrel{\acute{e}\mathcal{U}_{as}}{\stackrel{\acute{e}}{\underline{u}}}_{\stackrel{\acute{e}}{\underline{u}}}, \quad \mathbf{i}_{abr} = \stackrel{\acute{e}\mathcal{U}_{ar}}{\stackrel{\acute{e}}{\underline{u}}}_{\stackrel{\acute{e}}{\underline{u}}}, \quad \mathbf{i}_{abr} = \stackrel{\acute{e}\mathcal{U}_{ar}}{\stackrel{\acute{e}\mathcal{U}}{\underline{u}}}, \quad \mathbf{i}_{abr} = \stackrel{\acute{e}\mathcal{U}_{ar}}{\stackrel{\acute{e}\mathcal{U}}{\underline{u}}}_{\stackrel{\acute{e}\mathcal{U}}{\underline{u}}}, \quad \mathbf{i}_{abr} = \stackrel{\acute{e}\mathcal{U}_{ar}}{\stackrel{\acute{e}\mathcal{U}}{\underline{u}}}, \quad \mathbf{i}_{abr} = \stackrel{\acute{e}\mathcal{U}_{abr}}{\stackrel{\acute{e}\mathcal{U}}{\underline{u}}}, \quad \mathbf{i}_{abr$ 

 $\mathbf{y}_{abs} = \stackrel{\acute{\mathbf{e}}}{\overset{\acute{\mathbf{e}}}{\mathbf{e}}}_{bs} \stackrel{\acute{\mathbf{u}}}{\overset{\acute{\mathbf{u}}}{\mathbf{u}}}, \text{ and } \mathbf{y}_{abr} = \stackrel{\acute{\mathbf{e}}}{\overset{\acute{\mathbf{e}}}{\mathbf{e}}}_{br} \stackrel{\acute{\mathbf{u}}}{\overset{\acute{\mathbf{u}}}{\mathbf{u}}} \text{ are the phase voltages, currents, and}$ 

flux linkages;  $\mathbf{r}_s = \stackrel{\acute{\Theta}r_s}{\stackrel{\acute{\Theta}}{e}_0} \quad \stackrel{\acute{O}}{r_s} \stackrel{\acute{U}}{\overset{\acute{U}}{u}}$  and  $\mathbf{r}_r = \stackrel{\acute{\Theta}r_r}{\stackrel{\acute{\Theta}}{e}_0} \quad \stackrel{\acute{O}}{r_r} \stackrel{\acute{U}}{\overset{\acute{U}}{u}}$  are the matrices of the

stator and rotor resistances.

Studying the magnetically coupled motor circuits, the following matrix equation for the flux linkages is found

where  $\mathbf{L}_{s}$  is the matrix of the stator inductances,  $\mathbf{L}_{s} = \stackrel{\acute{e}L_{ss}}{\stackrel{\acute{e}}{e}} \stackrel{0}{0} \stackrel{\acute{u}}{L_{ss}} \stackrel{\acute{u}}{\dot{u}}$ 

 $L_{ss} = L_{ls} + L_{ms}$ ,  $L_{ms} = \frac{N_s^2}{\hat{A}_m}$ ;  $\mathbf{L}_r$  is the matrix of the rotor inductances,

$$\mathbf{L}_{r} = \stackrel{\acute{e}L_{rr}}{\underset{e}{\mathbf{\acute{e}}}} \mathbf{0} \quad \stackrel{\acute{u}}{L_{rr}} \stackrel{\acute{u}}{\mathbf{\acute{u}}}, \ L_{rr} = L_{lr} + L_{mr}, \ L_{mr} = \frac{N_{r}^{2}}{\widehat{\mathbf{A}}_{m}}; \ \mathbf{L}_{sr} \text{ is the matrix of the}$$

stator-rotor mutual inductances,  $\mathbf{L}_{sr} = \begin{array}{c} \acute{\mathbf{e}}L_{sr}\cos\mathbf{q}_{r} & -L_{sr}\sin\mathbf{q}_{r} \grave{\mathbf{u}}_{s} \\ \acute{\mathbf{e}}L_{sr}\sin\mathbf{q}_{r} & L_{sr}\cos\mathbf{q}_{r} & \acute{\mathbf{u}}_{s} \end{array}$ 

$$L_{sr} = \frac{N_s N_r}{\hat{A}_m} \,.$$

Using the number of turns in the stator and rotor windings, we have

$$\mathbf{\dot{i}}_{abr} = \frac{N_r}{N_s} \mathbf{\dot{i}}_{abr}, \ \mathbf{\dot{u}}_{abr} = \frac{N_s}{N_r} \mathbf{u}_{abr}, \text{ and } \mathbf{y}_{abr} = \frac{N_s}{N_r} \mathbf{y}_{abr}$$

Then, taking note of the turn ratio, the flux linkages are written in matrix form as

$$\mathbf{L}'_{sr} = \bigotimes_{\mathbf{e}}^{\mathbf{e}N_s} \bigotimes_{sr}^{\mathbf{o}} \mathbf{L}_{sr} = L_{ms} \bigotimes_{\mathbf{e}sn}^{\mathbf{e}cos} \mathbf{q}_r \quad - \sin \mathbf{q}_r \overset{\mathbf{u}}{\mathbf{u}}, \ L_{ms} = \frac{N_s}{N_r} L_{sr} ,$$

$$\mathbf{L}'_{mr} = \bigotimes_{\mathbf{e}N_r}^{\mathbf{e}N_s} \bigotimes_{\mathbf{o}}^{\mathbf{o}^2} L_{mr} , \ \mathbf{L}'_{mr} = L_{ms} = \frac{N_s}{N_r} L_{sr} , \ \mathbf{L}'_{rr} = \mathbf{L}'_{lr} + L_{ms} .$$

Substituting the matrices for self- and mutual inductances  $\mathbf{L}_s$ ,  $\mathbf{L}_r$  and  $\mathbf{L}_{sr}$  in (3.4.2), one obtains

Therefore, the circuitry differential equations (3.4.1) are rewritten as

$$\mathbf{u}_{abs} = \mathbf{r}_{s}\mathbf{i}_{abs} + \frac{d\mathbf{y}_{abs}}{dt}, \ \mathbf{u}_{abr} = \mathbf{r}_{r}\mathbf{i}_{abr} + \frac{d\mathbf{y}_{abr}}{dt}.$$
  
where  $\mathbf{r}_{r} = \frac{N_{s}^{2}}{N_{r}^{2}}\mathbf{r}_{r} = \frac{N_{s}^{2}}{N_{r}^{2}}\frac{\mathbf{\acute{e}r}}{\mathbf{\acute{e}0}} \quad \stackrel{0}{r_{r}}\overset{0}{\mathbf{\acute{u}}}.$ 

Assuming that the self- and mutual inductances  $L_{ss}$ ,  $L_{rr}$ ,  $L_{ms}$  are timeinvariant and using the expressions for the flux linkages, one obtains a set of nonlinear differential equations to model the circuitry dynamics

$$L_{ss}\frac{di_{as}}{dt} + L_{ms}\frac{d(\dot{i}_{ar}\cos\boldsymbol{q}_{r})}{dt} - L_{ms}\frac{d(\dot{i}_{br}\sin\boldsymbol{q}_{r})}{dt} = -r_{s}\dot{i}_{as} + u_{as},$$

$$L_{ss}\frac{di_{bs}}{dt} + L_{ms}\frac{d(\dot{i}_{ar}\sin\boldsymbol{q}_{r})}{dt} + L_{ms}\frac{d(\dot{i}_{br}\cos\boldsymbol{q}_{r})}{dt} = -r_{s}\dot{i}_{bs} + u_{bs},$$

$$L_{ms}\frac{d(\dot{i}_{as}\cos\boldsymbol{q}_{r})}{dt} + L_{ms}\frac{d(\dot{i}_{bs}\sin\boldsymbol{q}_{r})}{dt} + L_{rr}\frac{d\dot{i}_{ar}}{dt} = -r_{r}\dot{i}_{ar} + u_{ar},$$

$$-L_{ms}\frac{d(\dot{i}_{as}\sin\boldsymbol{q}_{r})}{dt} + L_{ms}\frac{d(\dot{i}_{bs}\cos\boldsymbol{q}_{r})}{dt} + L_{rr}\frac{d\dot{i}_{ar}}{dt} = -r_{r}\dot{i}_{ar} + u_{ar},$$

Cauchy's form of these differential equations is found. In particular, we have the following nonlinear differential equations to model the stator-rotor circuitry dynamics for two-phase induction motors

$$\begin{aligned} \frac{di_{as}}{dt} &= -\frac{L_{rr}r_{s}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{as} + \frac{L_{ms}^{2}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{bs}\mathbf{W}_{r} + \frac{L_{ms}L_{rr}^{'}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{ar}^{*}\mathbf{\bigoplus}^{\mathbf{w}}\mathbf{W}_{r}\sin\mathbf{q}_{r} + \frac{r_{r}^{'}}{L_{rr}^{'}}\cos\mathbf{q}_{r}^{*}\mathbf{\bigoplus}^{\mathbf{v}}\mathbf{H}^{'} \\ &+ \frac{L_{ms}L_{rr}^{'}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{br}^{'}\mathbf{\bigoplus}^{\mathbf{w}}\mathbf{W}_{r}\cos\mathbf{q}_{r} - \frac{r_{r}^{'}}{L_{rr}^{'}}\sin\mathbf{q}_{r}^{*}\mathbf{\bigoplus}^{+} + \frac{L_{rr}^{'}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}u_{as} - \frac{L_{ms}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}\cos\mathbf{q}_{r}u_{ar} \\ &+ \frac{L_{ms}L_{rr}^{'}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}\sin\mathbf{q}_{r}u_{br}^{'}, \\ \\ \frac{di_{bs}}{dt} &= -\frac{L_{rr}r_{s}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{bs} - \frac{L_{ms}^{2}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{as}\mathbf{W}_{r} - \frac{L_{ms}L_{rr}^{'}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{ar}\mathbf{\bigoplus}^{'}\mathbf{\bigoplus}^{\mathbf{w}}_{r}\sin\mathbf{q}_{r} + \frac{r_{r}^{'}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{as}\mathbf{W}_{r}\cos\mathbf{q}_{r} - \frac{r_{ms}^{'}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{ar}\mathbf{\bigoplus}^{'}\mathbf{\bigoplus}^{\mathbf{w}}_{r}\sin\mathbf{q}_{r} \\ &+ \frac{L_{ms}L_{rr}^{'}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{br}\mathbf{\bigoplus}^{'}\mathbf{\bigoplus}^{\mathbf{w}}_{r}\sin\mathbf{q}_{r} + \frac{r_{r}^{'}}{L_{rr}^{'}\cos\mathbf{q}_{r}\mathbf{\bigoplus}^{'}\mathbf{\bigoplus}^{+}\frac{L_{ms}L_{rr}^{'}}{L_{ss}L_{rr}^{'} - L_{ms}^{2}}i_{ar}\mathbf{\bigoplus}^{'}\mathbf{\square}^{'}\mathbf{$$

The electrical angular velocity  $\mathbf{w}_r$  and displacement  $\mathbf{q}_r$  are used in (3.4.3) as the state variables. Therefore, the *torsional-mechanical* equation of motion must be incorporated to describe the evolution of  $\mathbf{w}_r$  and  $\mathbf{q}_r$ . From Newton's second law, we have

$$\mathbf{\mathring{a}} \ T = T_e - B_m \mathbf{w}_{rm} - T_L = J \frac{d\mathbf{w}_{rm}}{dt},$$

$$\frac{d\mathbf{q}_{rm}}{dt} = \mathbf{w}_{rm}.$$

The mechanical angular velocity  $\mathbf{w}_{rm}$  is expressed by using the electrical angular velocity  $\mathbf{w}_r$  and the number of poles *P*. In particular,

$$\boldsymbol{w}_{rm}=\frac{2}{P}\boldsymbol{w}_r.$$

The mechanical and electrical angular displacements  $\boldsymbol{q}_{rm}$  and  $\boldsymbol{q}_{r}$  are related as

$$\boldsymbol{q}_{rm} = \frac{2}{P} \boldsymbol{q}_r$$
.

Taking note of Newton's second law of motion, one obtains

$$\frac{d\boldsymbol{w}_r}{dt} = \frac{P}{2J}T_e - \frac{B_m}{J}\boldsymbol{w}_r - \frac{P}{2J}T_L,$$

$$\frac{d\boldsymbol{q}_r}{dt} = \boldsymbol{w}_r.$$

To find the expression for the electromagnetic torque developed by twophase induction motors, the coenergy  $W_c(\mathbf{i}_{abs}, \mathbf{j}_{abr}', \mathbf{q}_r)$  is used, and

$$T_e = \frac{P}{2} \frac{\P W_c(\mathbf{i}_{abs}, \mathbf{i}_{abr}, \mathbf{q}_r)}{\P \mathbf{q}_r}.$$

Assuming that the magnetic system is linear, one has

$$W_c = W_f = \frac{1}{2} \mathbf{i}_{abs}^T (\mathbf{L}_s - \mathbf{L}_{ls} \mathbf{I}) \mathbf{i}_{abs} + \mathbf{i}_{abs}^T \mathbf{L}_{sr} \mathbf{i}_{abr} + \frac{1}{2} \mathbf{i}_{abr}^T (\mathbf{L}_r - \mathbf{L}_{lr} \mathbf{I}) \mathbf{i}_{abr}.$$

The self-inductances  $L_{ss}$  and  $L_{rr}$ , as well as the leakage inductances  $L_{ls}$  and  $L_{lr}$ , are not functions of the angular displacement  $q_r$ , while the following expression for the matrix of stator-rotor mutual inductances  $\mathbf{L}_{sr}$  was derived

$$\mathbf{L}_{sr} = L_{ms} \stackrel{\text{\acute{e}cos}}{\underset{\text{e}s}{\text{e}}} \mathbf{q}_r \quad - \sin \mathbf{q}_r \stackrel{\text{``u}}{\underset{\text{``u}}{\text{e}}} \mathbf{u}$$

Then, for P-pole two-phase induction motors, the electromagnetic torque is given by

$$T_{e} = \frac{P}{2} \frac{\varPi W_{c}(\mathbf{i}_{abs}, \mathbf{i}_{abr}, \mathbf{q}_{r})}{\varPi \mathbf{q}_{r}} = \frac{P}{2} \mathbf{i}_{abs}^{T} \frac{\varPi \mathbf{L}_{sr}(\mathbf{q}_{r})}{\varPi \mathbf{q}_{r}} \mathbf{i}_{abr} = \frac{P}{2} L_{ms} \begin{bmatrix} i_{as} & i_{bs} \end{bmatrix}_{\mathbf{\hat{e}}}^{\mathbf{\hat{e}}} \frac{\sin \mathbf{q}_{r}}{\sin \mathbf{q}_{r}} - \frac{\cos \mathbf{q}_{r}}{\sin \mathbf{q}_{r}} \mathbf{i}_{debr}^{\mathsf{i}} \mathbf{\hat{e}} \mathbf{i}_{ds} \mathbf{i}_{ds} \mathbf{i}_{ds} \end{bmatrix} \mathbf{\hat{e}} \mathbf{i}_{ds} \mathbf{i}_{ds}$$

Using (3.4.4) for the electromagnetic torque  $T_e$  in the *torsional-mechanical* equations of motion, one obtains

$$\frac{d\boldsymbol{w}_{r}}{dt} = -\frac{P^{2}}{4J}L_{ms}\left[\left(i_{as}\dot{i_{ar}}+i_{bs}\dot{i_{br}}\right)\sin\boldsymbol{q}_{r}+\left(i_{as}\dot{i_{br}}-i_{bs}\dot{i_{ar}}\right)\cos\boldsymbol{q}_{r}\right]-\frac{B_{m}}{J}\boldsymbol{w}_{r}-\frac{P}{2J}T_{L}$$

$$\frac{d\boldsymbol{q}_{r}}{dt} = \boldsymbol{w}_{r}.$$
(3.4.5)

Augmenting differential equations (3.4.3) and (3.4.5), the following set of highly nonlinear differential equations results

$$\begin{aligned} \frac{di_{as}}{dt} &= -\frac{L_{rr}r_s}{L_S}i_{as} + \frac{L_{ms}^2}{L_S}i_{bs}\mathbf{w}_r + \frac{L_{ms}L_{rr}}{L_S}i_{ar}\overset{\sim}{\mathbf{\xi}}\overset{\sim}{\mathbf{w}}_r\sin\mathbf{q}_r + \frac{r_r}{L_{rr}}\cos\mathbf{q}_r\overset{\circ}{\pm}\\ &+ \frac{L_{ms}L_{rr}}{L_S}i_{br}\overset{\sim}{\mathbf{\xi}}\overset{\sim}{\mathbf{w}}_r\cos\mathbf{q}_r - \frac{r_r}{L_{rr}}\sin\mathbf{q}_r\overset{\circ}{\pm} + \frac{L_{rr}}{L_S}u_{as} - \frac{L_{ms}}{L_S}\cos\mathbf{q}_ru_{ar} + \frac{L_{ms}}{L_S}\sin\mathbf{q}_ru_{br},\\ \\ \frac{di_{bs}}{dt} &= -\frac{L_{rr}r_s}{L_S}i_{bs} - \frac{L_{ms}^2}{L_S}i_{as}\mathbf{w}_r - \frac{L_{ms}L_{rr}}{L_S}i_{ar}\overset{\sim}{\mathbf{\xi}}\overset{\circ}{\mathbf{w}}_r\cos\mathbf{q}_r - \frac{r_r}{L_{rr}}si\mathbf{q}_r\overset{\circ}{\pm}\\ \\ + \frac{L_{ms}L_{rr}}{L_S}i_{br}\overset{\sim}{\mathbf{\xi}}\overset{\sim}{\mathbf{w}}_r\sin\mathbf{q}_r + \frac{r_r}{L_{rr}}\cos\mathbf{q}_r\overset{\circ}{\pm} + \frac{L_{rr}}{L_S}u_{bs} - \frac{L_{ms}}{L_S}\sin\mathbf{q}_ru_{ar} - \frac{L_{ms}}{L_S}\cos\mathbf{q}_ru_{ar},\\ \\ \frac{di_{ar}}{dt} &= -\frac{L_{ss}r_r}{L_S}i_{br}\overset{\sim}{\mathbf{\xi}}\overset{\sim}{\mathbf{w}}_r\sin\mathbf{q}_r + \frac{r_r}{L_{rr}}\cos\mathbf{q}_r\overset{\circ}{\pm} + \frac{L_{rr}}{L_S}u_{bs} - \frac{L_{ms}}{L_S}\sin\mathbf{q}_ru_{ar} - \frac{L_{ms}}{L_S}\cos\mathbf{q}_ru_{br},\\ \\ \frac{di_{ar}}{dt} &= -\frac{L_{ss}r_r}{L_S}i_{br}\overset{\circ}{\mathbf{k}}_r\overset{\sim}{\mathbf{w}}_r\sin\mathbf{q}_r + \frac{r_r}{L_{rr}}\cos\mathbf{q}_r\overset{\circ}{\pm} + \frac{L_{ms}}{L_{ss}}\cos\mathbf{q}_r\overset{\circ}{\pm} - \frac{L_{ms}L_{ss}}{L_S}u_{bs}\overset{\circ}{\mathbf{k}}_s\overset{\circ}{\mathbf{w}}_r\cos\mathbf{q}_r - \frac{r_s}{L_S}\sin\mathbf{q}_r\overset{\circ}{\pm},\\ \\ -\frac{L_{ms}}^2L_S}i_{br}\overset{\circ}{\mathbf{w}}_r\overset{\circ}{\mathbf{w}}_r\overset{-}{\mathbf{w}}_s\overset{-$$

where  $L_{S} = L_{ss}L_{rr} - L_{ms}^{2}$ .

In matrix form, a set of six highly coupled nonlinear differential equations (3.4.6) is

 $\hat{\mathbf{e}} \stackrel{L^2_{ms}}{\overset{L_{ms}}{\leftarrow}} i_{bs} \mathbf{w}_r + \frac{L_{ms} L_{rr}}{L_{o}} i_{ar} \hat{\mathbf{e}} \mathbf{w}_r \sin \mathbf{q}_r + \frac{r_r}{L} \cos \mathbf{q}_r + \frac{L_{ms} L_{rr}}{L_{o}} i_{br} \hat{\mathbf{e}} \mathbf{w}_r \cos \mathbf{q}_r - \frac{r_r}{L} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \cos \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \cos \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \cos \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \cos \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \cos \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \cos \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}} \cos \mathbf{q}_r + \frac{v_r}{L_{o}} \sin \mathbf{q}_r + \frac{v_r}{L_{o}$  $\overset{\bullet}{\mathbf{e}} \frac{L_{ms}^2}{L_{\mathbf{e}}} i_{as} \mathbf{w}_r - \frac{L_{ms}L_{rr}}{L_{\mathbf{e}}} i_{ar} \overset{\bullet}{\mathbf{c}} \overset{\bullet}{\mathbf{w}}_r \cos \mathbf{q}_r - \frac{r_r}{L} \sin \mathbf{q}_r \overset{\bullet}{\mathbf{r}} + \frac{L_{ms}L_{rr}}{L_{\mathbf{e}}} i_{br} \overset{\bullet}{\mathbf{c}} \overset{\bullet}{\mathbf{w}}_r \sin \mathbf{q}_r + \frac{r_r}{L} \cos \mathbf{q}_r \overset{\bullet}{\mathbf{c}} \overset{\bullet}{\mathbf{w}}_r \overset{\bullet}{$  $\hat{\mathbf{e}} \quad L_{\mathbf{S}} \quad us \neq L_{\mathbf{S}} \quad us \neq L_{\mathbf{T}r} \quad v \neq L_{\mathbf{T}r} \quad v \neq L_{\mathbf{S}} \quad v \neq L_{rr} \quad v \neq L_{r$ 

s.

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$$\begin{array}{c} \stackrel{eL_{rr}}{\hat{e}L_{S}} & 0 & 0 & 0 & \stackrel{u}{\underline{u}} & \stackrel{e}{\underline{e}} & \frac{L_{ms}}{L_{S}} \cos q_{r} u_{ar} + \frac{L_{ms}}{L_{S}} \sin q_{r} u_{br} \stackrel{u}{\underline{u}} \stackrel{v}{\underline{e}} 0 & \stackrel{u}{\underline{u}} \\ \stackrel{e}{\underline{e}} 0 & \frac{L_{rr}}{L_{S}} & 0 & 0 & \stackrel{u}{\underline{u}} \stackrel{e}{\underline{e}} & \frac{L_{ms}}{L_{S}} \sin q_{r} u_{ar} - \frac{L_{ms}}{L_{S}} \cos q_{r} u_{br} \stackrel{u}{\underline{u}} \stackrel{v}{\underline{e}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \\ \stackrel{e}{\underline{e}} 0 & 0 & \frac{L_{ss}}{L_{S}} & 0 & \stackrel{u}{\underline{u}} \stackrel{e}{\underline{e}} & \frac{L_{ms}}{L_{S}} \sin q_{r} u_{ar} - \frac{L_{ms}}{L_{S}} \cos q_{r} u_{br} \stackrel{u}{\underline{u}} \stackrel{v}{\underline{e}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \\ \stackrel{e}{\underline{e}} 0 & 0 & \frac{L_{ss}}{L_{S}} & 0 & \stackrel{u}{\underline{u}} \stackrel{e}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{e}{\underline{L}} \stackrel{u}{\underline{u}} \cos q_{r} u_{as} - \frac{L_{ms}}{L_{S}} \sin q_{r} u_{bs} \stackrel{u}{\underline{u}} \stackrel{e}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \\ \stackrel{e}{\underline{e}} 0 & 0 & 0 & \frac{L_{ss}}{L_{S}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{L}} \stackrel{u}{\underline{e}} \sin q_{r} u_{as} - \frac{L_{ms}}{L_{S}} \cos q_{r} u_{bs} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \\ \stackrel{e}{\underline{e}} 0 & 0 & 0 & \frac{L_{ss}}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} - \frac{L_{ms}}{L_{S}} \cos q_{r} u_{bs} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \\ \stackrel{u}{\underline{e}} \stackrel{u}{\underline{e}} 0 & 0 & 0 \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} - \frac{L_{ms}}{L_{S}} \cos q_{r} u_{bs} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \\ \stackrel{u}{\underline{e}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{e}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}} \stackrel{u}{\underline{u}}$$

The mathematical model can be derived using Lagrange's equations. The generalized independent coordinates and the generalized forces are

$$q_{1} = \frac{i_{as}}{s}, \ q_{2} = \frac{i_{bs}}{s}, \ q_{3} = \frac{i_{ar}}{s}, \ q_{4} = \frac{i_{br}}{s}, \ q_{5} = \mathbf{q}_{r},$$
  
and  $Q_{1} = u_{as}, \ Q_{2} = u_{bs}, \ Q_{3} = u_{ar}, \ Q_{4} = u_{br}, \ Q_{5} = -T_{L}$ 

Five Lagrange equations are written as

$$\frac{d}{dt} \bigotimes_{\mathbf{e}}^{\mathbf{e}} \frac{\|\mathbf{G}\,\ddot{\mathbf{o}}\,}{\|\dot{q}_{1}\,\dot{\mathbf{o}}\,} - \frac{\|\mathbf{G}\,}{\|q_{1}} + \frac{\|D}{\|\dot{q}_{1}} + \frac{\|\mathbf{P}\,}{\|q_{1}} = Q_{1},$$

$$\frac{d}{dt} \bigotimes_{\mathbf{e}}^{\mathbf{e}} \frac{\|\mathbf{G}\,\ddot{\mathbf{o}}\,}{\|\dot{q}_{2}\,\dot{\mathbf{o}}\,} - \frac{\|\mathbf{G}\,}{\|q_{2}} + \frac{\|D}{\|\dot{q}_{2}} + \frac{\|\mathbf{P}\,}{\|q_{2}} = Q_{2},$$

$$\frac{d}{dt} \bigotimes_{\mathbf{e}}^{\mathbf{e}} \frac{\|\mathbf{G}\,\ddot{\mathbf{o}}\,}{\|\dot{q}_{3}\,\dot{\mathbf{o}}\,} - \frac{\|\mathbf{G}\,}{\|q_{3}} + \frac{\|D}{\|\dot{q}_{3}\,} + \frac{\|\mathbf{P}\,}{\|q_{3}\,} = Q_{3},$$

$$\frac{d}{dt} \bigotimes_{\mathbf{e}}^{\mathbf{e}} \frac{\|\mathbf{G}\,\ddot{\mathbf{o}}\,}{\|\dot{q}_{4}\,\dot{\mathbf{o}}\,} - \frac{\|\mathbf{G}\,}{\|q_{4}\,} + \frac{\|D}{\|\dot{q}_{4}\,} + \frac{\|\mathbf{P}\,}{\|q_{4}\,} = Q_{4},$$

$$\frac{d}{dt} \bigotimes_{\mathbf{e}}^{\mathbf{e}} \frac{\|\mathbf{G}\,\ddot{\mathbf{o}}\,}{\|\dot{q}_{4}\,\dot{\mathbf{o}}\,} - \frac{\|\mathbf{G}\,}{\|q_{5}\,} + \frac{\|D}{\|\dot{q}_{5}\,} + \frac{\|\mathbf{P}\,}{\|q_{5}\,} = Q_{5}.$$

The total kinetic, potential, and dissipated energies are  

$$\mathbf{G} = \frac{1}{2} L_{ss} \dot{q}_{1}^{2} + L_{ms} \dot{q}_{1} \dot{q}_{3} \cos q_{5} - L_{ms} \dot{q}_{1} \dot{q}_{4} \sin q_{5} + \frac{1}{2} L_{ss} \dot{q}_{2}^{2}$$

$$+ L_{ms} \dot{q}_{2} \dot{q}_{3} \sin q_{5} + L_{ms} \dot{q}_{2} \dot{q}_{4} \cos q_{5} + \frac{1}{2} L_{rr} \dot{q}_{3}^{2} + \frac{1}{2} L_{rr} \dot{q}_{4}^{2} + \frac{1}{2} J \dot{q}_{5}^{2},$$

$$\mathbf{P} = 0,$$

$$D = \frac{1}{2} \left( r_{s} \dot{q}_{1}^{2} + r_{s} \dot{q}_{2}^{2} + r_{r} \dot{q}_{3}^{2} + r_{r} \dot{q}_{4}^{2} + B_{m} \dot{q}_{5}^{2} \right).$$
Thus,  

$$\frac{\pi G}{\pi q_{1}} = 0, \quad \frac{\pi G}{\pi \dot{q}_{1}} = L_{ss} \dot{q}_{1} + L_{ms} \dot{q}_{3} \cos q_{5} - L_{ms} \dot{q}_{4} \sin q_{5},$$

$$\frac{\pi G}{\pi q_{2}} = 0, \quad \frac{\pi G}{\pi \dot{q}_{2}} = L_{ss} \dot{q}_{2} + L_{ms} \dot{q}_{3} \sin q_{5} + L_{ms} \dot{q}_{4} \cos q_{5},$$

$$\frac{\pi G}{\pi q_{3}} = 0, \quad \frac{\pi G}{\pi \dot{q}_{3}} = L_{rr} \dot{q}_{3} + L_{ms} \dot{q}_{1} \cos q_{5} + L_{ms} \dot{q}_{2} \sin q_{5},$$

$$\frac{\pi G}{\pi q_{4}} = 0, \quad \frac{\pi G}{\pi \dot{q}_{4}} = L_{rr} \dot{q}_{4} - L_{ms} \dot{q}_{1} \sin q_{5} + L_{ms} \dot{q}_{2} \cos q_{5},$$

$$\frac{\pi G}{\pi q_5} = -L_{ms} \dot{q}_1 \dot{q}_3 \sin q_5 - L_{ms} \dot{q}_1 \dot{q}_4 \cos q_5$$

$$+ L_{ms} \dot{q}_2 \dot{q}_3 \cos q_5 - L_{ms} \dot{q}_2 \dot{q}_4 \sin q_5$$

$$= -L_{ms} [(\dot{q}_1 \dot{q}_3 + \dot{q}_2 \dot{q}_4) \sin q_5 + (\dot{q}_1 \dot{q}_4 - \dot{q}_2 \dot{q}_3) \cos q_5],$$

$$\frac{\pi G}{\pi \dot{q}_5} = J \dot{q}_5,$$

$$\frac{\pi P}{\pi q_1} = 0, \quad \frac{\pi P}{\pi q_2} = 0, \quad \frac{\pi P}{\pi q_3} = 0, \quad \frac{\pi P}{\pi q_4} = 0, \quad \frac{\pi P}{\pi q_5} = 0,$$

$$\frac{\pi D}{\pi \dot{q}_1} = r_s \dot{q}_1, \quad \frac{\pi D}{\pi \dot{q}_2} = r_s \dot{q}_2, \quad \frac{\pi D}{\pi \dot{q}_3} = r_r \dot{q}_3, \quad \frac{\pi D}{\pi \dot{q}_4} = r_r \dot{q}_4, \quad \frac{\pi D}{\pi \dot{q}_5} = B_m \dot{q}_5.$$

Taking note of  $\dot{q}_1 = i_{as}$ ,  $\dot{q}_2 = i_{bs}$ ,  $\dot{q}_3 = i_{ar}$ ,  $\dot{q}_4 = i_{br}$  and  $\dot{q}_5 = \mathbf{W}_r$ , one obtains

$$L_{ss}\frac{di_{as}}{dt} + L_{ms}\frac{d(\dot{i}_{ar}\cos\boldsymbol{q}_{r})}{dt} - L_{ms}\frac{d(\dot{i}_{br}\sin\boldsymbol{q}_{r})}{dt} + r_{s}\dot{i}_{as} = u_{as},$$

$$L_{ss}\frac{di_{bs}}{dt} + L_{ms}\frac{d(\dot{i}_{ar}\sin\boldsymbol{q}_{r})}{dt} + L_{ms}\frac{d(\dot{i}_{br}\cos\boldsymbol{q}_{r})}{dt} + r_{s}\dot{i}_{bs} = u_{bs},$$

$$L_{ms}\frac{d(\dot{i}_{as}\cos\boldsymbol{q}_{r})}{dt} + L_{ms}\frac{d(\dot{i}_{bs}\sin\boldsymbol{q}_{r})}{dt} + L_{rr}\frac{d\dot{i}_{ar}}{dt} + r_{r}\dot{i}_{ar} = u_{ar},$$

$$- L_{ms}\frac{d(\dot{i}_{as}\sin\boldsymbol{q}_{r})}{dt} + L_{ms}\frac{d(\dot{i}_{bs}\cos\boldsymbol{q}_{r})}{dt} + L_{rr}\frac{d\dot{i}_{br}}{dt} + r_{r}\dot{i}_{ar} = u_{br},$$

$$J\frac{d^{2}\boldsymbol{q}_{r}}{dt^{2}} + L_{ms}\left[\left(\dot{i}_{as}\dot{i}_{ar}^{'} + i_{bs}\dot{i}_{br}\right)\sin\boldsymbol{q}_{r} + \left(\dot{i}_{as}\dot{i}_{br}^{'} - i_{bs}\dot{i}_{ar}\right)\cos\boldsymbol{q}_{r}\right] + B_{m}\frac{d\boldsymbol{q}_{r}}{dt} = -T_{L}$$
For P-pole induction motors, by making use of  $\frac{d\boldsymbol{q}_{r}}{d\boldsymbol{q}_{r}} = \boldsymbol{w}_{r}$ , six

differential equations, as found in (3.4.6), result.

# Control of Induction Motors

The angular velocity of induction motors must be controlled, and the torque-speed characteristic curves should be thoroughly examined. The electromagnetic torque developed by two-phase induction motors is given by equation (3.4.4). To guarantee the balanced operating condition for two-phase induction motors, one supplies the following phase voltages to the stator windings

$$u_{as}(t) = \sqrt{2}u_M \cos(\mathbf{w}_f t), \ u_{bs}(t) = \sqrt{2}u_M \sin(\mathbf{w}_f t),$$

and the sinusoidal steady-state phase currents are

 $i_{as}(t) = \sqrt{2}i_M \cos(\mathbf{w}_f t - \mathbf{j}_i)$  and  $i_{bs}(t) = \sqrt{2}i_M \sin(\mathbf{w}_f t - \mathbf{j}_i)$ .

Here the following notations are used:  $u_M$  is the magnitude of the voltages applied to the *as* and *bs* stator windings;  $i_M$  is the magnitude of the *as* and *bs* stator currents;  $w_f$  is the angular frequency of the applied phase voltages,  $w_f = 2pf$ ; f is the frequency of the supplied voltage;  $j_i$  is the phase difference.

The applied voltage to the motor windings cannot exceed the admissible voltage  $u_{M \max}$  . That is,

 $u_{M\min} \pounds u_M \pounds u_{M\max}$ .

The motor synchronous angular velocity  $\boldsymbol{w}_e$  is found using the number

of poles as  $\mathbf{w}_e = \frac{4\mathbf{p}f}{P}$ . It is evident that the synchronous velocity  $\mathbf{w}_e$  can be regulated by changing the frequency *f*. To regulate the angular velocity, one varies the magnitude of the applied voltages as well as the frequency. The torque-speed characteristic curves of induction motors must be thoroughly studied. Performing the transient analysis by solving the derived differential equations (3.4.6), one can find the steady-state curves  $\mathbf{w}_r = \mathbf{W}_T(T_e)$  by plotting the angular velocity versus the electromagnetic torque developed.

The following principles are used to control the angular velocity of induction motors.

*Voltage control.* By changing the magnitude  $u_M$  of the applied phase voltages to the stator windings, the angular velocity is regulated in the stable operating region, see Figure 3.4.2.a. It was emphasized that  $u_{M\min} < u_M < u_{M\max}$ , where  $u_{M\max}$  is the maximum allowed (rated) voltage.

Frequency control. The magnitude of the applied phase voltages is constant  $u_M^{constant}$ , and the angular velocity is regulated above and below the synchronous angular velocity by changing the frequency of the supplied voltages *f*. This concept can be clearly demonstrated using the formula  $\mathbf{w}_e = \frac{4\mathbf{p}f}{P}$ . The torque-speed characteristics for different values of the frequency are shown in Figure 3.4.2.b.

*Voltage-frequency control.* The angular frequency  $\mathbf{w}_f$  is proportional to the frequency of the supplied voltages,  $\mathbf{w}_f = 2\mathbf{p}f$ . To minimize losses, the applied voltages applied to the stator windings should be regulated if the frequency is changed. In particular, the magnitude of phase voltages can be decreased linearly with decreasing the frequency. That is, to guarantee the
constant volts per hertz control one maintains the following relationship  $\frac{u_{Mi}}{f_i} = const$  or  $\frac{u_{Mi}}{w_{fi}} = const$ . The corresponding torque-speed

 $f_i = const$  of  $w_{fi}$  = const. The corresponding torque speed characteristics are documented in Figure 3.4.2.c. Regulating the voltagefrequency patterns, one shapes the torque-speed curves. For example, the

following relation  $\sqrt{\frac{u_{Mi}}{f_i}} = const$  can be applied to adjust the magnitude  $u_M$ 

and frequency f of the supplied voltages. To attain the acceleration and settling time specified, overshoot and rise time needed, the general purpose (standard), soft- and high-starting torque patterns are implemented based upon the requirements and criteria imposed (see the standard, soft- and high-torque patterns as illustrated in Figure 3.4.2.d). That is, assigning  $\mathbf{w}_f = \mathbf{j} (u_M)$  with

domain  $u_{M\min} < u_M < u_{M\max}$  and range  $W_{f\min} < W_f < W_{f\max}$ , one

maintains  $\frac{u_{Mi}}{f_i} = \text{var}$  or  $\frac{u_{Mi}}{w_{fi}} = \text{var}$ . For example, the desired torque-speed

characteristics, as documented in Figure 3.4.2.e, can be guaranteed.







- a) voltage control; b) frequency control;
- c) voltage-frequency control: *constant volts per hertz* control;
- d) voltage-frequency patterns;
- e) variable voltage-frequency control

# S-Domain Block Diagram of Two-Phase Induction Motors

To perform the analysis of dynamics, to control induction machines, as well as to visualize the results, it is important to develop the *s*-domain block diagrams. For squirrel-cage induction motors, the rotor windings are short-circuited, and hence  $u_{ar} = u_{br} = 0$ . The block diagram is built using differential equations (3.4.6). The resulting *s*-domain block diagram is shown in Figure 3.4.3.



Figure 3.4.3.S-domain block diagram of squirrel-cage induction motors

### 3.4.2. Three-Phase Induction Motors

Dynamics of Induction Motors in the Machine Variables

Our goal is to develop the mathematical model of three-phase induction motors, as shown in Figure 3.4.4, using Kirchhoff's and Newton's second laws.



Figure 3.4.4. Three-phase symmetrical induction motor

Studying the magnetically coupled stator and rotor circuitry, Kirchhoff's voltage law relates the *abc* stator and rotor phase voltages, currents, and flux linkages through the set of differential equations.

For magnetically coupled stator and rotor windings, we have

$$u_{as} = r_{s}i_{as} + \frac{d\mathbf{y}_{as}}{dt}, \ u_{bs} = r_{s}i_{bs} + \frac{d\mathbf{y}_{bs}}{dt}, \ u_{cs} = r_{s}i_{cs} + \frac{d\mathbf{y}_{cs}}{dt}, u_{ar} = r_{r}i_{ar} + \frac{d\mathbf{y}_{ar}}{dt}, \ u_{br} = r_{r}i_{br} + \frac{d\mathbf{y}_{br}}{dt}, \ u_{cr} = r_{r}i_{cr} + \frac{d\mathbf{y}_{cr}}{dt}.$$
 (3.4.8)

It is clear that the *abc* stator and rotor voltages, currents, and flux linkages are used as the variables, and in matrix form equations (3.4.8) are rewritten as

$$\mathbf{u}_{abcs} = \mathbf{r}_{s} \mathbf{i}_{abcs} + \frac{d\mathbf{y}_{abcs}}{dt},$$
  
$$\mathbf{u}_{abcr} = \mathbf{r}_{r} \mathbf{i}_{abcr} + \frac{d\mathbf{y}_{abcr}}{dt},$$
(3.4.9)

where the abc stator and rotor voltages, currents, and flux linkages are

$$\mathbf{u}_{abcs} = \stackrel{\acute{\Theta}}{\stackrel{\bullet}{\mathbf{e}}} \stackrel{\acute{U}}{\stackrel{\bullet}{\mathbf{u}}}_{s} \stackrel{\acute{U}}{\stackrel{\bullet}{\mathbf{u}}}_{s} \mathbf{u}_{abcr} = \stackrel{\acute{\Theta}}{\stackrel{\bullet}{\mathbf{e}}} \stackrel{\acute{U}}{\stackrel{\bullet}{\mathbf{u}}}_{s} \stackrel{\acute{U}}{\stackrel{\acute{U}}{\mathbf{u}}}_{s} \stackrel{\acute{U}}{\stackrel{\acute{U}}{\vec{u}}}_{s} \stackrel{\acute{U}}{\vec{u}}}_{s} \stackrel{\acute{U}}{\stackrel{\acute{U}}{\vec{u}}}_{s} \stackrel{\acute{U}}{\vec{u}} \stackrel{\acute{U$$

In (3.4.9), the diagonal matrices of the stator and rotor resistances are

$$\mathbf{r}_{s} = \begin{pmatrix} \hat{\mathbf{e}}_{s}^{r} & 0 & 0 \dot{\mathbf{u}} \\ \hat{\mathbf{e}}_{0}^{0} & r_{s} & 0 \dot{\mathbf{u}} \\ \hat{\mathbf{e}}_{0}^{0} & 0 & r_{s} \dot{\mathbf{g}} \end{pmatrix} \quad \text{and} \quad \mathbf{r}_{r} = \begin{pmatrix} \hat{\mathbf{e}}_{r}^{r} & 0 & 0 \dot{\mathbf{u}} \\ \hat{\mathbf{e}}_{0}^{0} & r_{r} & 0 \dot{\mathbf{u}} \\ \hat{\mathbf{e}}_{0}^{0} & 0 & r_{r} \dot{\mathbf{g}} \end{pmatrix}$$

The flux linkages equations must be thoroughly examined, and one has

where the matrices of self- and mutual inductances  $\mathbf{L}_s$ ,  $\mathbf{L}_r$  and  $\mathbf{L}_{sr}$  are

$$\begin{aligned} & \begin{pmatrix} \dot{\mathbf{e}}L_{ls} + L_{ms} & -\frac{1}{2}L_{ms} & -\frac{1}{2}L_{ms} & \dot{\mathbf{u}} \\ & \hat{\mathbf{e}} - \frac{1}{2}L_{ms} & L_{ls} + L_{ms} & -\frac{1}{2}L_{ms} & \dot{\mathbf{u}}, \\ & \hat{\mathbf{g}} - \frac{1}{2}L_{ms} & -\frac{1}{2}L_{ms} & L_{ls} + L_{ms} & \dot{\mathbf{u}} \\ & \mathbf{L}_{r} = \hat{\mathbf{e}} - \frac{1}{2}L_{mr} & L_{lr} + L_{mr} & -\frac{1}{2}L_{mr} & \dot{\mathbf{u}} \\ & \hat{\mathbf{e}} - \frac{1}{2}L_{mr} & L_{lr} + L_{mr} & -\frac{1}{2}L_{mr} & \dot{\mathbf{u}}, \\ & \hat{\mathbf{e}} - \frac{1}{2}L_{mr} & -\frac{1}{2}L_{mr} & L_{lr} + L_{mr} & \dot{\mathbf{u}} \\ & \hat{\mathbf{e}} - \frac{1}{2}L_{mr} & -\frac{1}{2}L_{mr} & L_{lr} + L_{mr} & \dot{\mathbf{u}} \\ & \hat{\mathbf{e}} - \frac{1}{2}L_{mr} & -\frac{1}{2}L_{mr} & \cos(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) & \cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \dot{\mathbf{u}}, \\ & \hat{\mathbf{e}} \cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) & \cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) & \cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \\ & \hat{\mathbf{e}} \cos(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) & \cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) & \cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \end{aligned}$$

Using the number of turns  $N_s$  and  $N_r$ , one finds

$$\mathbf{u}_{abcr}^{'} = \frac{N_s}{N_r} \mathbf{u}_{abcr}, \ \mathbf{\dot{u}}_{abcr}^{'} = \frac{N_r}{N_s} \mathbf{\dot{u}}_{abcr} \text{ and } \mathbf{y}_{abcr}^{'} = \frac{N_s}{N_r} \mathbf{y}_{abcr}.$$

The inductances are expressed as

$$L_{ms} = \frac{N_s}{N_r} L_{sr}, \ L_{sr} = \frac{N_s N_r}{\hat{A}_m}, \text{ and } L_{ms} = \frac{N_s^2}{\hat{A}_m}$$

Then, we have

$$\mathbf{L}_{sr}^{'} = \frac{N_{s}}{N_{r}} \mathbf{L}_{sr} = L_{ms} \stackrel{\text{\acute{e}}}{\underset{\text{e}}{\overset{\text{cos}}} \mathbf{q}_{r}}{\underset{\text{cos}}{(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p})} \cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \sin(\mathbf{q}_{r} - \frac{2}{3$$

From (3.4.10), one finds

Substituting the matrices  $\mathbf{L}_{s}$ ,  $\mathbf{L}_{sr}^{'}$  and  $\mathbf{L}_{r}^{'}$ , we have

$$\begin{aligned} \mathbf{\hat{q}}_{r}^{r} \mathbf{\hat{s}}_{u}^{t} \mathbf{\hat{q}}_{r}^{r} \mathbf{\hat{q}}_{u}^{t} \mathbf{\hat{q}}_{r}^{r} \mathbf{\hat{q}}_{u}^{t} \mathbf{\hat{q}}_{r}^{r} \mathbf{\hat{q}}_{u}^{t} \mathbf{\hat{q}}_{r}^{r} \mathbf{\hat{q}}_{u}^{t} \mathbf{\hat{q}}_{r}^{r} \mathbf{\hat{q}}_{u}^{t} \mathbf{\hat{q}}_{r}^{r} \mathbf{\hat{q}}_{u}^{t} \mathbf{\hat{q}}_{u}^{r} \mathbf{\hat{q}}_{u}^{t} \mathbf{\hat{q}}_{u$$

Matrix equations (3.4.12) in expanded form using (3.4.11) are rewritten as

$$\begin{split} u_{as} &= r_{s}i_{as} + (L_{ls} + L_{ms})\frac{di_{as}}{dt} - \frac{1}{2}L_{ms}\frac{di_{bs}}{dt} - \frac{1}{2}L_{ms}\frac{di_{cs}}{dt} \\ &+ L_{ms}\frac{d(i_{cr}\cos(\mathbf{q}_{r}))}{dt} + L_{ms}\frac{d(i_{br}\cos(\mathbf{q}_{r} + \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{cr}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3}))}{dt}, \\ u_{bs} &= r_{s}i_{bs} - \frac{1}{2}L_{ms}\frac{di_{as}}{dt} + (L_{ls} + L_{ms})\frac{di_{bs}}{dt} - \frac{1}{2}L_{ms}\frac{di_{cs}}{dt} \\ &+ L_{ms}\frac{d(i_{ar}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{br}\cos(\mathbf{q}_{r}))}{dt} + L_{ms}\frac{d(i_{cr}\cos(\mathbf{q}_{r} + \frac{2\mathbf{p}}{3}))}{dt}, \\ u_{cs} &= r_{s}i_{cs} - \frac{1}{2}L_{ms}\frac{di_{as}}{dt} - \frac{1}{2}L_{ms}\frac{di_{bs}}{dt} + (L_{ls} + L_{ms})\frac{di_{cs}}{dt} \\ &+ L_{ms}\frac{d(i_{ar}\cos(\mathbf{q}_{r} + \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{br}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{cr}\cos(\mathbf{q}_{r} + \frac{2\mathbf{p}}{3}))}{dt}, \\ u_{cs} &= r_{s}i_{cs} - \frac{1}{2}L_{ms}\frac{di_{as}}{dt} - \frac{1}{2}L_{ms}\frac{di_{bs}}{dt} + (L_{ls} + L_{ms})\frac{di_{cs}}{dt} \\ &+ L_{ms}\frac{d(i_{ar}\cos(\mathbf{q}_{r} + \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{bs}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{cs}\cos(\mathbf{q}_{r} + \frac{2\mathbf{p}}{3}))}{dt} \\ &+ (L_{lr} + L_{ms})\frac{di_{ar}}{dt} - \frac{1}{2}L_{ms}\frac{di_{br}}{dt} - \frac{1}{2}L_{ms}\frac{di_{cr}}{dt}, \\ u_{br} &= r_{r}i_{br}^{*} + L_{ms}\frac{d(i_{as}\cos(\mathbf{q}_{r} + \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{bs}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{cs}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3}))}{dt} \\ &+ \frac{1}{2}L_{ms}\frac{di_{ar}}{dt} + (L_{lr}^{*} + L_{ms})\frac{di_{br}}{dt} - \frac{1}{2}L_{ms}\frac{di_{cr}}{dt}, \\ u_{cr}^{*} &= r_{r}i_{br}^{*} + L_{ms}\frac{d(i_{as}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{bs}\cos(\mathbf{q}_{r} + \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{cs}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3}))}{dt} \\ &+ \frac{1}{2}L_{ms}\frac{di_{ar}}{dt} - \frac{1}{2}L_{ms}\frac{di_{br}}{dt} - \frac{1}{2}L_{ms}\frac{di_{cr}}{dt}, \\ u_{cr}^{*} &= r_{r}i_{cr}^{*} + L_{ms}\frac{d(i_{as}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3}))}{dt} + L_{ms}\frac{d(i_{bs}\cos(\mathbf{q}_{r} + \frac{2\mathbf{p}}{3}))}{dt} \\ &+ L_{ms}\frac{d(i_{cs}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3})}{dt} \\ &+ L_{ms}\frac{d(i_{as}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3})}{dt} \\ &+ L_{ms}\frac{d(i_{as}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{3})}{dt} \\ &+ L_{ms}\frac{d(i_{as}\cos(\mathbf{q}_{r} - \frac{2\mathbf{p}}{$$

Cauchy's form differential equations, given in matrix form, are found to be

$$\begin{array}{l} & \frac{d}{dt} \frac{$$

Here, the following notations are used

$$L_{SL} = (3L_{ms} + L_{lr})L_{lr}, \ L_{Sm} = 2L_{ms} + L_{lr}, \ L_{Sms} = \frac{3}{2}L_{ms}^2 + L_{ms}L_{lr}$$

Newton's second law is applied to derive the *torsional-mechanical* equations, and the expression for the electromagnetic torque must be obtained.

For *P*-pole three-phase induction machines, as one finds the expression for coenergy  $W_c(\mathbf{i}_{abcs}, \mathbf{i}_{abcr}, \mathbf{q}_r)$ , the electromagnetic torque can be straightforwardly derived as  $T_e = \frac{P}{2} \frac{\Im W_c(\mathbf{i}_{abcs}, \mathbf{i}_{abcr}, \mathbf{q}_r)}{\Im q_r}$ . For three-phase induction motors we have

$$W_{c} = W_{f} = \frac{1}{2} \mathbf{i}_{abcs}^{T} (\mathbf{L}_{s} - \mathbf{L}_{ls} \mathbf{I}) \mathbf{i}_{abcs} + \mathbf{i}_{abcs}^{T} \mathbf{L}_{sr}^{'} (\mathbf{q}_{r}) \mathbf{i}_{abcr}^{'} + \frac{1}{2} \mathbf{i}_{abcr}^{'T} (\mathbf{L}_{r}^{'} - \mathbf{L}_{lr}^{'} \mathbf{I}) \mathbf{i}_{abcr}^{'}$$

Matrices  $\mathbf{L}_s$  and  $\mathbf{L}_r$ , as well as leakage inductances  $L_{ls}$  and  $L_{lr}$ , are not functions of the electrical displacement  $\mathbf{q}_r$ . Therefore, we have

$$T_{e} = \frac{P}{2} \mathbf{i}_{abcs}^{T} \frac{\mathbf{\int} \mathbf{L}_{sr}(\mathbf{q}_{r})}{\mathbf{\int} \mathbf{q}_{r}} \mathbf{i}_{abcr}^{'}$$

$$= -\frac{P}{2} L_{ms} \begin{bmatrix} i_{as} & i_{bs} & i_{cs} \end{bmatrix}_{es}^{\acute{e}} \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) & \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \\ \stackrel{\acute{e}}{\otimes} \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) & \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \\ \stackrel{\acute{e}}{\otimes} \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) & \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \\ \stackrel{\acute{e}}{\otimes} \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) & \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \\ \stackrel{\acute{e}}{\otimes} \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) & \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \\ = -\frac{P}{2} L_{ms} \Big\{ \Big[ i_{as} (i_{ar}^{'} - \frac{1}{2}i_{br}^{'} - \frac{1}{2}i_{cr}^{'} + i_{bs} (i_{br}^{'} - \frac{1}{2}i_{ar}^{'} - \frac{1}{2}i_{cr}^{'}) + i_{cs} (i_{cr}^{'} - \frac{1}{2}i_{br}^{'} - \frac{1}{2}i_{ar}^{'}) \Big] \sin \mathbf{q}_{r} \\ + \frac{\sqrt{3}}{2} \stackrel{\acute{e}}{}_{e}^{\acute{e}} a_{s} \stackrel{\acute{e}}{}_{br}^{\acute{e}} - i_{cr} \stackrel{\acute{e}}{}_{b}^{\acute{e}} + i_{bs} \stackrel{\acute{e}}{}_{cr}^{'} - i_{ar} \stackrel{\acute{e}}{}_{b}^{'} + i_{cs} \stackrel{\acute{e}}{}_{ar}^{'} - i_{br} \stackrel{\acute{e}}{}_{b0}^{'} \cos \mathbf{q}_{r} \Big\}.$$

$$(3.4.14)$$

Using Newton's second law and (3.4.14), the *torsional-mechanical* equations are found to be

$$\frac{d\mathbf{w}_{r}}{dt} = \frac{P}{2J}T_{e} - \frac{B_{m}}{J}\mathbf{w}_{r} - \frac{P}{2J}T_{L}$$

$$= -\frac{P^{2}}{4J}L_{ms}\left\{\left[i_{as}\left(\dot{i}_{ar} - \frac{1}{2}\dot{i}_{br} - \frac{1}{2}\dot{i}_{cr}\right) + i_{bs}\left(\dot{i}_{br} - \frac{1}{2}\dot{i}_{ar} - \frac{1}{2}\dot{i}_{cr}\right) + i_{cs}\left(\dot{i}_{cr} - \frac{1}{2}\dot{i}_{br} - \frac{1}{2}\dot{i}_{ar}\right)\right]\sin\mathbf{q}_{r}$$

$$+ \frac{\sqrt{3}}{2}\frac{\dot{\theta}}{\theta}as}\overset{\mathfrak{g}}{\theta}\dot{b}_{r} - \dot{i}_{cr}\overset{\mathfrak{o}}{\phi} + i_{bs}\overset{\mathfrak{g}}{\theta}\dot{c}_{r} - i_{ar}\overset{\mathfrak{o}}{\phi} + i_{cs}\overset{\mathfrak{g}}{\theta}ar - i_{br}\overset{\mathfrak{o}}{\theta}\dot{u}^{\mathsf{U}}\cos\mathbf{q}_{r}\right] - \frac{B_{m}}{J}\mathbf{w}_{r} - \frac{P}{2J}T_{L},$$

$$\frac{d\mathbf{q}_{r}}{dt} = \mathbf{w}_{r}.$$
(3.4.15)

Augmenting differential equations (3.4.13) and (3.4.15), the resulting model for three-phase induction motors in the *machine* variables, is found.

# Mathematical Model of Three-Phase Induction Motors in the Arbitrary Reference Frame

The *abc* stator and rotor variables must be transformed to the *quadrature*, *direct*, and *zero* quantities. To transform the *machine* (*abc*) stator voltages, currents, and flux linkages to the *quadrature-*, *direct-*, and *zero-*axis components of stator voltages, currents and flux linkages, the *direct* Park transformation is used. In particular,

$$\mathbf{u}_{qdos} = \mathbf{K}_{s} \mathbf{u}_{abcs}, \ \mathbf{i}_{qdos} = \mathbf{K}_{s} \mathbf{i}_{abcs}, \ \mathbf{y}_{qdos} = \mathbf{K}_{s} \mathbf{y}_{abcs}, \qquad (3.4.16)$$

where the stator transformation matrix  $\mathbf{K}_{s}$  is given by

Here, the angular displacement of the reference frame is

$$\boldsymbol{q} = \mathbf{\check{O}} \boldsymbol{v}(\boldsymbol{t}) d\boldsymbol{t} + \boldsymbol{q}_0$$

Using the rotor transformations matrix  $\mathbf{K}_r$ , the *quadrature-*, *direct-*, and *zero-*axis components of rotor voltages, currents, and flux linkages are found by using the *abc* rotor voltages, currents, and flux linkages.

In particular,

t

$$\mathbf{u}'_{qdor} = \mathbf{K}_{r} \mathbf{u}'_{abcr}, \ \mathbf{i}'_{qdor} = \mathbf{K}_{r} \mathbf{i}'_{abcr}, \ \mathbf{y}'_{qdor} = \mathbf{K}_{r} \mathbf{y}'_{abcr}, \qquad (3.4.18)$$

where the rotor transformation matrix is

$$\begin{aligned} & \stackrel{\text{écos}}{\mathbf{K}}_{r} = \frac{2}{3} \frac{\hat{\mathbf{e}}}{\hat{\mathbf{e}}} \sin(\mathbf{q} - \mathbf{q}_{r}) & \cos(\mathbf{q} - \mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) & \cos(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \dot{\mathbf{U}} \\ & \stackrel{\text{e}}{\mathbf{K}}_{r} = \frac{2}{3} \frac{\hat{\mathbf{e}}}{\hat{\mathbf{e}}} \sin(\mathbf{q} - \mathbf{q}_{r}) & \sin(\mathbf{q} - \mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) & \sin(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \overset{\text{U}}{\mathbf{U}} (3.4.19) \\ & \stackrel{\text{e}}{\mathbf{e}} \quad \frac{1}{2} & \frac{1}{2} & \frac{1}{2} & \overset{\text{U}}{\mathbf{U}} \end{aligned}$$

.

From differential equations (3.4.12)

$$\mathbf{u}_{abcs} = \mathbf{r}_{s} \mathbf{i}_{abcs} + \frac{d\mathbf{y}_{abcs}}{dt}, \ \mathbf{u}_{abcr} = \mathbf{r}_{r} \mathbf{i}_{abcr} + \frac{d\mathbf{y}_{abcr}}{dt},$$

by taking note of the inverse Park transformation matrices  $\mathbf{K}_{s}^{-1}$  and  $\mathbf{K}_{r}^{-1}$ , we have

$$\mathbf{K}_{s}^{-1}\mathbf{u}_{qdos} = \mathbf{r}_{s}\mathbf{K}_{s}^{-1}\mathbf{i}_{qdos} + \frac{d\left(\mathbf{K}_{s}^{-1}\mathbf{y}_{qdos}\right)}{dt},$$
  
$$\mathbf{K}_{r}^{-1}\mathbf{u}_{qdor}^{'} = \mathbf{r}_{r}^{'}\mathbf{K}_{r}^{-1}\mathbf{i}_{qdor}^{'} + \frac{d\left(\mathbf{K}_{r}^{-1}\mathbf{y}_{qdor}^{'}\right)}{dt}.$$
 (3.4.20)

Making use of (3.4.17) and (3.4.19) one finds inverse matrices  $\mathbf{K}_s^{-1}$  and  $\mathbf{K}_r^{-1}$ . In particular,

$$\mathbf{K}_{s}^{-1} = \stackrel{\text{\acute{e}}}{\underset{e}{\Theta}} \cos(\mathbf{q} - \frac{2}{3}\mathbf{p}) \quad \sin(\mathbf{q} - \frac{2}{3}\mathbf{p}) \quad 1\stackrel{\text{\acute{u}}}{\underset{u}{\mathsf{\acute{u}}}},$$

$$\stackrel{\text{\acute{e}}}{\underset{e}{\Theta}} \cos(\mathbf{q} - \frac{2}{3}\mathbf{p}) \quad \sin(\mathbf{q} - \frac{2}{3}\mathbf{p}) \quad 1\stackrel{\text{\acute{u}}}{\underset{u}{\mathsf{\acute{u}}}},$$

$$\stackrel{\text{\acute{e}}}{\underset{e}{\Theta}} \cos(\mathbf{q} - \mathbf{q}_{r}) \quad \sin(\mathbf{q} - \mathbf{q}_{r}) \quad 1\stackrel{\text{\acute{u}}}{\underset{u}{\mathsf{\acute{u}}}},$$
and
$$\mathbf{K}_{r}^{-1} = \stackrel{\text{\acute{e}}}{\underset{e}{\Theta}} \cos(\mathbf{q} - \mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \quad \sin(\mathbf{q} - \mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \quad 1\stackrel{\text{\acute{u}}}{\underset{u}{\mathsf{\acute{u}}}},$$

$$\stackrel{\text{\acute{e}}}{\underset{e}{\Theta}} \cos(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \quad \sin(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \quad 1\stackrel{\text{\acute{u}}}{\underset{u}{\mathsf{\acute{u}}}},$$

Multiplying left and right sides of equations (3.4.20) by  $\mathbf{K}_s$  and  $\mathbf{K}_r$ , one has

$$\mathbf{u}_{qdos} = \mathbf{K}_{s} \mathbf{r}_{s} \mathbf{K}_{s}^{-1} \mathbf{i}_{qdos} + \mathbf{K}_{s} \frac{d\mathbf{K}_{s}^{-1}}{dt} \mathbf{y}_{qdos} + \mathbf{K}_{s} \mathbf{K}_{s}^{-1} \frac{d\mathbf{y}_{qdos}}{dt},$$
$$\mathbf{u}_{qdor}^{'} = \mathbf{K}_{r} \mathbf{r}_{r}^{'} \mathbf{K}_{r}^{-1} \mathbf{i}_{qdor}^{'} + \mathbf{K}_{r} \frac{d\mathbf{K}_{r}^{-1}}{dt} \mathbf{y}_{qdor}^{'} + \mathbf{K}_{r} \mathbf{K}_{r}^{-1} \frac{d\mathbf{y}_{qdor}^{'}}{dt}.$$
(3.4.21)

The matrices of the stator and rotor resistances  $\mathbf{r}_s$  and  $\mathbf{r}_r$  are diagonal, and hence,

 $\mathbf{K}_{s}\mathbf{r}_{s}\mathbf{K}_{s}^{-1} = \mathbf{r}_{s}$  and  $\mathbf{K}_{r}\mathbf{r}_{r}^{T}\mathbf{K}_{r}^{-1} = \mathbf{r}_{r}^{T}$ .

Performing differentiation, one finds

$$\frac{d\mathbf{K}_{s}^{-1}}{dt} = \mathbf{w}_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} - \sin\mathbf{q} \quad \cos\mathbf{q} \quad 0\dot{\mathbf{u}} \\ \hat{\mathbf{e}} \sin\left(\mathbf{q} - \frac{2}{3}\mathbf{p}\right) \quad \cos\left(\mathbf{q} - \frac{2}{3}\mathbf{p}\right) \quad 0\dot{\mathbf{u}}, \\ \hat{\mathbf{e}} \sin\left(\mathbf{q} + \frac{2}{3}\mathbf{p}\right) \quad \cos\left(\mathbf{q} + \frac{2}{3}\mathbf{p}\right) \quad 0\dot{\mathbf{u}} \\ \frac{d\mathbf{K}_{r}^{-1}}{dt} = \left(\mathbf{w} - \mathbf{w}_{r}\right)_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} \sin\left(\mathbf{q} - \mathbf{q}_{r}\right) \quad \cos\left(\mathbf{q} - \mathbf{q}_{r}\right) \quad \cos\left(\mathbf{q} - \mathbf{q}_{r}\right) \quad 0\dot{\mathbf{u}} \\ \hat{\mathbf{e}} \sin\left(\mathbf{q} - \mathbf{q}_{r} - \frac{2}{3}\mathbf{p}\right) \quad \cos\left(\mathbf{q} - \mathbf{q}_{r} - \frac{2}{3}\mathbf{p}\right) \quad 0\dot{\mathbf{u}} \\ \hat{\mathbf{e}} \sin\left(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) \quad \cos\left(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) \quad 0\dot{\mathbf{u}} \\ \hat{\mathbf{e}} \sin\left(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) \quad \cos\left(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) \quad 0\dot{\mathbf{u}} \\ \hat{\mathbf{u}} = \left(\mathbf{w} - \mathbf{w}_{r}\right)_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} \sin\left(\mathbf{q} - \mathbf{q}_{r} - \frac{2}{3}\mathbf{p}\right) \quad \cos\left(\mathbf{q} - \mathbf{q}_{r} - \frac{2}{3}\mathbf{p}\right) \quad 0\dot{\mathbf{u}} \\ \hat{\mathbf{u}} = \left(\mathbf{w} - \mathbf{w}_{r}\right)_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} \sin\left(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) \quad \cos\left(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) \quad 0\dot{\mathbf{u}} \\ \hat{\mathbf{u}} = \left(\mathbf{w} - \mathbf{w}_{r}\right)_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} \sin\left(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) \quad \cos\left(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) \quad 0\dot{\mathbf{u}} \\ \hat{\mathbf{u}} = \left(\mathbf{w} - \mathbf{w}_{r}\right)_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} \sin\left(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) \quad \cos\left(\mathbf{q} - \mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) \quad 0\dot{\mathbf{u}} \\ \hat{\mathbf{u}} = \left(\mathbf{w} - \mathbf{w}_{r}\right)_{\hat{\mathbf{u}}}^{\hat{\mathbf{u}}} = \left(\mathbf{w} - \mathbf$$

Therefore,

One obtains the voltage equations for stator and rotor circuits in the *arbitrary* reference frame when the angular velocity of the reference frame  $\boldsymbol{W}$  is not specified. From (3.4.21) the following matrix differential equations result

$$\mathbf{u}_{qdos} = \mathbf{r}_{s} \mathbf{i}_{qdos} + \stackrel{\acute{\mathbf{e}}}{\underset{\mathbf{e}}{\mathbf{e}}} \stackrel{\mathbf{w}}{\mathbf{w}} \stackrel{\mathbf{0}}{\mathbf{0}} \stackrel{\mathbf{w}}{\underset{\mathbf{u}}{\mathbf{u}}} \stackrel{\mathbf{u}}{\mathbf{v}}_{qdos} + \frac{d\mathbf{y}_{qdos}}{dt},$$
  
$$\mathbf{u}_{qdor}^{'} = \mathbf{r}_{r}^{'} \mathbf{i}_{qdor}^{'} + \stackrel{\acute{\mathbf{e}}}{\underset{\mathbf{e}}{\mathbf{e}}} \stackrel{\mathbf{w}}{\mathbf{w}} + \mathbf{w}_{r} \stackrel{\mathbf{0}}{\mathbf{u}} \stackrel{\mathbf{w}}{\mathbf{u}} \stackrel{\mathbf{w}}{\mathbf{u}} \stackrel{\mathbf{u}}{\mathbf{u}} \stackrel{\mathbf{v}}{\mathbf{u}} \stackrel{\mathbf{v}}{\mathbf{u}} \stackrel{\mathbf{v}}{\mathbf{u}} + \frac{d\mathbf{y}_{qdos}}{dt}, \quad (3.4.22)$$

From (3.4.22), six differential equations in expanded form are found to model the stator and rotor circuitry dynamics. In particular,

$$u_{qs} = r_{s}i_{qs} + \mathbf{w}\mathbf{y}_{ds} + \frac{d\mathbf{y}_{qs}}{dt},$$

$$u_{ds} = r_{s}i_{ds} - \mathbf{w}\mathbf{y}_{qs} + \frac{d\mathbf{y}_{ds}}{dt},$$

$$u_{os} = r_{s}i_{os} + \frac{d\mathbf{y}_{os}}{dt},$$

$$u_{qr} = r_{r}i_{qr} + (\mathbf{w} - \mathbf{w}_{r})\mathbf{y}_{dr} + \frac{d\mathbf{y}_{qr}}{dt},$$

$$u_{dr} = r_{r}i_{dr} - (\mathbf{w} - \mathbf{w}_{r})\mathbf{y}_{qr} + \frac{d\mathbf{y}_{dr}}{dt},$$

$$u_{or} = r_{r}i_{or} + \frac{d\mathbf{y}_{or}}{dt}.$$
(3.4.23)

$$\mathbf{y}_{abcs} = \mathbf{L}_s \mathbf{i}_{abcs} + \mathbf{L}'_{sr} \mathbf{i}'_{abcr}$$
 and  $\mathbf{y}'_{abcr} = \mathbf{L}'_{sr}^T \mathbf{i}_{abcs} + \mathbf{L}'_{r} \mathbf{i}'_{abcr}$ 

These equations can be represented using the *quadrature*, *direct*, and *zero* quantities. Employing the Park transformation matrices one has

$$\mathbf{K}_{s}^{-1}\mathbf{y}_{qdos} = \mathbf{L}_{s}\mathbf{K}_{s}^{-1}\mathbf{i}_{qdos} + \mathbf{L}_{sr}\mathbf{K}_{r}^{-1}\mathbf{i}_{qdor}^{\prime}$$
  
and 
$$\mathbf{K}_{r}^{-1}\mathbf{y}_{qdor}^{\prime} = \mathbf{L}_{sr}^{-T}\mathbf{K}_{s}^{-1}\mathbf{i}_{qdos} + \mathbf{L}_{r}\mathbf{K}_{r}^{-1}\mathbf{i}_{abcr}^{\prime}$$

Thus

$$\mathbf{y}_{qdos} = \mathbf{K}_{s} \mathbf{L}_{s} \mathbf{K}_{s}^{-1} \mathbf{i}_{qdos} + \mathbf{K}_{s} \mathbf{L}_{sr}^{-1} \mathbf{K}_{r}^{-1} \mathbf{i}_{qdor},$$
  
$$\mathbf{y}_{qdor} = \mathbf{K}_{r} \mathbf{L}_{sr}^{-T} \mathbf{K}_{s}^{-1} \mathbf{i}_{qdos} + \mathbf{K}_{r} \mathbf{L}_{r}^{-1} \mathbf{K}_{r}^{-1} \mathbf{i}_{abcr}.$$
 (3.4.24)

Taking note of the Park transformation matrices and applying the derived expressions for  $\mathbf{L}_s$ ,  $\mathbf{L}_{sr}$  and  $\mathbf{L}_r$ , by multiplying the matrices we have

$$\mathbf{K}_{s}\mathbf{L}_{s}\mathbf{K}_{s}^{-1} = \stackrel{\acute{\mathbf{e}}}{\stackrel{\bullet}{\mathbf{e}}} 0 \qquad L_{ls} + M \qquad 0 \qquad \dot{\mathbf{u}}$$
$$\stackrel{\acute{\mathbf{e}}}{\stackrel{\bullet}{\mathbf{e}}} 0 \qquad L_{ls} + M \qquad 0 \stackrel{\acute{\mathbf{u}}}{\stackrel{\acute{\mathbf{u}}}{\mathbf{u}}},$$
$$\stackrel{\acute{\mathbf{e}}}{\stackrel{\acute{\mathbf{e}}}{\mathbf{e}}} 0 \qquad 0 \qquad L_{ls} \stackrel{\acute{\mathbf{u}}}{\stackrel{\acute{\mathbf{u}}}{\mathbf{u}}},$$
$$\mathbf{K}_{s}\mathbf{L}_{sr}^{'}\mathbf{K}_{r}^{-1} = \mathbf{K}_{r}\mathbf{L}_{sr}^{'}\mathbf{K}_{s}^{-1} = \stackrel{\acute{\mathbf{e}}}{\stackrel{\acute{\mathbf{e}}}{\mathbf{e}}} 0 \qquad M \qquad 0 \stackrel{\acute{\mathbf{u}}}{\stackrel{\acute{\mathbf{u}}}{\mathbf{u}}},$$
$$\stackrel{\acute{\mathbf{e}}}{\stackrel{\acute{\mathbf{e}}}{\mathbf{e}}} 0 \qquad 0 \qquad \dot{\mathbf{u}}$$
$$\stackrel{\acute{\mathbf{e}}}{\stackrel{\acute{\mathbf{e}}}{\mathbf{e}}} 0 \qquad 0 \qquad \dot{\mathbf{u}}$$

and 
$$\mathbf{K}_{r}\mathbf{L}_{r}\mathbf{K}_{r}^{-1} = \stackrel{\acute{\mathbf{e}}L_{lr}}{\stackrel{\acute{\mathbf{e}}}{\mathbf{e}}} 0 \qquad L_{lr} + M \qquad 0 \stackrel{\acute{\mathbf{u}}}{\overset{\acute{\mathbf{u}}}{\mathbf{u}}}, \quad M = \frac{3}{2}L_{ms}.$$
  
 $\stackrel{\acute{\mathbf{e}}}{\stackrel{\acute{\mathbf{e}}}{\mathbf{e}}} 0 \qquad 0 \qquad L_{lr}\stackrel{\acute{\mathbf{u}}}{\overset{\acute{\mathbf{u}}}{\mathbf{u}}}$ 

In expanded form, the flux linkage equations (3.4.24) are

$$\mathbf{y}_{qs} = L_{ls}i_{qs} + Mi_{qs} + Mi_{qr},$$
  

$$\mathbf{y}_{ds} = L_{ls}i_{ds} + Mi_{ds} + Mi'_{dr},$$
  

$$\mathbf{y}_{os} = L_{ls}i_{os},$$
  

$$\mathbf{y}_{qr} = L'_{lr}i'_{qr} + Mi_{qs} + Mi'_{qr},$$
  

$$\mathbf{y}_{dr} = L'_{lr}i'_{dr} + Mi_{ds} + Mi'_{dr},$$
  

$$\mathbf{y}_{or} = L'_{lr}i'_{or}.$$
(3.4.25)

Using the expressions (3.4.25) in (3.4.23), the differential equations result

$$\begin{split} u_{qs} &= r_{s}i_{qs} + \mathbf{w} \Big( L_{ls}i_{ds} + Mi_{ds} + Mi_{dr}^{'} \Big) + \frac{d \Big( L_{ls}i_{qs} + Mi_{qs} + Mi_{qr}^{'} \Big)}{dt} ,\\ u_{ds} &= r_{s}i_{ds} - \mathbf{w} \Big( L_{ls}i_{qs} + Mi_{qs} + Mi_{qr}^{'} \Big) + \frac{d \Big( L_{ls}i_{ds} + Mi_{ds} + Mi_{dr}^{'} \Big)}{dt} ,\\ u_{os} &= r_{s}i_{os} + \frac{d \big( L_{ls}i_{os} \big)}{dt} ,\\ u_{qr} &= r_{r}^{'}i_{qr}^{'} + \big( \mathbf{w} - \mathbf{w}_{r} \big) \Big( L_{lr}^{'}i_{dr}^{'} + Mi_{ds} + Mi_{dr}^{'} \Big) + \frac{d \Big( L_{lr}^{'}i_{qr}^{'} + Mi_{qs} + Mi_{qr}^{'} \Big)}{dt} ,\\ u_{dr}^{'} &= r_{r}^{'}i_{dr}^{'} - \big( \mathbf{w} - \mathbf{w}_{r} \big) \Big( L_{lr}^{'}i_{qr}^{'} + Mi_{qs} + Mi_{qr}^{'} \Big) + \frac{d \Big( L_{lr}^{'}i_{dr}^{'} + Mi_{ds} + Mi_{dr}^{'} \Big)}{dt} ,\\ u_{or}^{'} &= r_{r}^{'}i_{or}^{'} + \frac{d \Big( L_{lr}^{'}i_{or}^{'} \Big)}{dt} . \end{split}$$

Cauchy's form of differential equations is

$$\frac{di_{qs}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ -L_{RM}r_{s}i_{qs} - (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{ds} + Mr_{r}i_{qr} - M(Mi_{ds} + L_{RM}i_{dr})\mathbf{w}_{r} + L_{RM}u_{qs} - Mu_{qr} \right],$$

$$\frac{di_{ds}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{qs} - L_{RM}r_{s}i_{ds} + Mr_{r}i_{dr} + M(Mi_{qs} + L_{RM}i_{qr})\mathbf{w}_{r} + L_{RM}u_{ds} - Mu_{dr} \right],$$

$$\frac{di_{os}}{dt} = \frac{1}{L_{ls}} \left( -r_{s}i_{os} + u_{os} \right),$$

$$\frac{di_{qr}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{qs} - L_{SM}r_{r}i_{qr} - (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{dr} + L_{SM}(Mi_{ds} + L_{RM}i_{dr})\mathbf{w}_{r} - Mu_{qs} + L_{SM}u_{qr} \right],$$

$$\frac{di_{dr}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{ds} + (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{qr} - L_{SM}r_{r}i_{dr} - L_{SM}(Mi_{qs} + L_{RM}i_{qr})\mathbf{w}_{r} - Mu_{ds} + L_{SM}u_{qr} \right],$$

$$\frac{di_{or}}{dt} = \frac{1}{L_{br}} \left( -r_{r}i_{or} + u_{or} \right),$$
(3.4.26)

where  $L_{SM} = L_{ls} + M = L_{ls} + \frac{3}{2}L_{ms}$  and  $L_{RM} = L_{lr} + M = L_{lr} + \frac{3}{2}L_{ms}$ .

One concludes that the nonlinear differential equations are found to describe the stator-rotor circuitry transient behavior. To complete the model developments, the *torsional-mechanical* equations

$$T_e - B_m \mathbf{w}_{rm} - T_L = J \frac{d\mathbf{w}_{rm}}{dt},$$
  
$$\frac{d\mathbf{q}_{rm}}{dt} = \mathbf{w}_{rm},$$
 (3.4.27)

must be used.

The equation for the electromagnetic torque must be obtained in terms of the *quadrature-* and *direct-*axis components of stator and rotor currents.

Using the formula for coenergy

$$W_{c} = \frac{1}{2} \mathbf{i}_{abcs}^{T} \left( \mathbf{L}_{s} - L_{ls} \mathbf{I} \right) \mathbf{i}_{abcs} + \mathbf{i}_{abcs}^{T} \mathbf{L}_{sr}^{T} \left( \mathbf{q}_{r} \right) \mathbf{i}_{abcr}^{T} + \frac{1}{2} \mathbf{i}_{abcr}^{T} \left( \mathbf{L}_{r}^{T} - L_{lr}^{T} \mathbf{I} \right) \mathbf{i}_{abcr}^{T},$$
  
one finds  $T_{e} = \frac{P}{2} \frac{\# W_{c} \left( \mathbf{i}_{abcs}, \mathbf{i}_{abcr}^{T}, \mathbf{q}_{r} \right)}{\# q_{r}} = \frac{P}{2} \mathbf{i}_{abcs}^{T} \frac{\# L_{sr}^{T} \left( \mathbf{q}_{r} \right)}{\# q_{r}} \mathbf{i}_{abcr}^{T}.$ 

Hence, we have

By performing multiplication of matrices, the following formula results

$$T_e = \frac{3P}{4} M \left( \dot{i}_{qs} \dot{i}_{dr} - \dot{i}_{ds} \dot{i}_{qr} \right).$$
(3.4.28)

Thus, from (3.4.27) and (3.4.28), one has

$$\frac{d\boldsymbol{w}_r}{dt} = \frac{3P^2}{8J} M \left( i_{qs} \dot{i_{dr}} - i_{ds} \dot{i_{qr}} \right) - \frac{B_m}{J} \boldsymbol{w}_r - \frac{P}{2J} T_L,$$

$$\frac{d\boldsymbol{q}_r}{dt} = \boldsymbol{w}_r.$$
(3.4.29)

Augmenting the circuitry and *torsional-mechanical* dynamics, as given by differential equations (3.4.26) and (3.4.29), the model for three-phase induction motors in the *arbitrary* reference frame results.

We have a set of eight highly coupled nonlinear differential equations

$$\frac{di_{qs}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ -L_{RM}r_{s}i_{qs} - (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{ds} + Mr_{r}i_{qr} - M(Mi_{ds} + L_{RM}i_{dr})\mathbf{w}_{r} + L_{RM}u_{qs} - Mu_{qr} \right] 
\frac{di_{ds}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{qs} - L_{RM}r_{s}i_{ds} + Mr_{r}i_{dr} + M(Mi_{qs} + L_{RM}i_{qr})\mathbf{w}_{r} + L_{RM}u_{ds} - Mu_{dr} \right] 
\frac{di_{os}}{dt} = \frac{1}{L_{Is}} \left( -r_{s}i_{os} + u_{os} \right), 
\frac{di_{qr}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{qs} - L_{SM}r_{r}i_{qr} - (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{dr} + L_{SM}(Mi_{ds} + L_{RM}i_{dr})\mathbf{w}_{r} - Mu_{qs} + L_{SM}u_{qr}^{*} \right] 
\frac{di_{os}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{qs} + (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{qr} - L_{SM}r_{r}i_{dr} - L_{SM}r_{r}i_{dr} + L_{SM}(Mi_{qs} + L_{RM}i_{qr})\mathbf{w}_{r} - Mu_{ds} + L_{SM}u_{qr}^{*} \right] 
\frac{di_{or}}{dt} = \frac{1}{L_{Ir}} \left( -r_{r}i_{or} + u_{or}^{*} \right), 
\frac{di_{or}}{dt} = \frac{1}{L_{Ir}} \left( -r_{r}i_{or} + u_{or}^{*} \right),$$

$$(3.4.30)$$

The last differential equation in (3.4.30) can be omitted in the analysis and simulations if induction motors are used in electric drive applications. That is, for electric drives one finds

$$\frac{di_{qs}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ -L_{RM}r_{s}i_{qs} - (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{ds} + Mr_{r}i_{qr}^{\dagger} - M(Mi_{ds} + L_{RM}i_{dr})\mathbf{w}_{r} + L_{RM}u_{qs} - Mu_{qr}^{\dagger} \right] \\
\frac{di_{ds}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{qs} - L_{RM}r_{s}i_{ds} + Mr_{r}i_{dr}^{\dagger} + M(Mi_{qs} + L_{RM}i_{qr})\mathbf{w}_{r} + L_{RM}u_{ds} - Mu_{dr}^{\dagger} \right] \\
\frac{di_{os}}{dt} = \frac{1}{L_{Is}} \left( -r_{s}i_{os} + u_{os} \right), \\
\frac{di_{qr}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{qs} - L_{SM}r_{r}i_{qr}^{\dagger} - (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{dr}^{\dagger} + L_{SM}(Mi_{ds} + L_{RM}i_{dr})\mathbf{w}_{r} - Mu_{qs} + L_{SM}u_{qr}^{\dagger} \right] \\
\frac{di_{dr}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{ds} + (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{qr}^{\dagger} - L_{SM}r_{r}i_{dr}^{\dagger} - L_{SM}(Mi_{qs} + L_{RM}i_{qr})\mathbf{w}_{r} - Mu_{qs} + L_{SM}u_{qr}^{\dagger} \right] \\
\frac{di_{or}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{ds} + (L_{SM}L_{RM} - M^{2})\mathbf{w}i_{qr} - L_{SM}r_{r}i_{dr}^{\dagger} - L_{SM}(Mi_{qs} + L_{RM}i_{qr})\mathbf{w}_{r} - Mu_{ds} + L_{SM}u_{qr}^{\dagger} \right] \\
\frac{di_{or}}{dt} = \frac{1}{L_{Ir}} \left( -r_{r}i_{or} + u_{or}^{\dagger} \right), \quad (3.4.31)$$

In matrix form, nonlinear differential equations (3.4.31) are given as

The block diagram for three-phase induction motors, modeled in the *arbitrary* reference frame is developed using (3.4.31). Applying the Laplace operator, one finds the block diagram as shown in Figure 3.4.5.



Figure 3.4.5. Block diagram of three-phase squirrel-cage induction motors in the *arbitrary* reference frame

Micro- and miniscale induction motors are squirrel-cage motors, and the rotor windings are short-circuited. To guarantee the balanced operating conditions, one supplies the following balanced three-phase voltages

$$\begin{aligned} u_{as}(t) &= \sqrt{2}u_M \cos\left(\mathbf{w}_f t\right), \ u_{bs}(t) = \sqrt{2}u_M \cos\left(\mathbf{w}_f t - \frac{2}{3}\mathbf{p}\right), \\ u_{cs}(t) &= \sqrt{2}u_M \cos\left(\mathbf{w}_f t + \frac{2}{3}\mathbf{p}\right), \end{aligned}$$

where the frequency of the applied voltage is  $w_f = 2pf$ .

The *quadrature-*, *direct-*, and *zero-*axis components of stator voltages are obtained by using the stator Park transformation matrix as

$$\mathbf{u}_{qdos} = \mathbf{K}_{s} \mathbf{u}_{abcs}, \ \mathbf{K}_{s} = \frac{2}{3} \frac{\hat{\mathbf{e}}}{\hat{\mathbf{e}}} \sin q \quad \sin\left(\mathbf{q} - \frac{2}{3}\mathbf{p}\right) \quad \cos\left(\mathbf{q} + \frac{2}{3}\mathbf{p}\right) \overset{\text{u}}{\mathbf{u}}_{u}$$

The stationary, rotor, and synchronous reference frames are commonly used. For stationary, rotor, and synchronous reference frames, the reference frame angular velocities are  $\mathbf{w} = 0$ ,  $\mathbf{w} = \mathbf{w}_r$  and  $\mathbf{w} = \mathbf{w}_e$ , and the corresponding angular displacement  $\mathbf{q}$  results. In particular, for zero initial conditions for stationary, rotor, and synchronous reference frames one finds  $\mathbf{q} = 0$ ,  $\mathbf{q} = \mathbf{q}_r$  and  $\mathbf{q} = \mathbf{q}_e$ . Hence, the *quadrature-*, *direct-*, and *zero-*axis components of voltages can be obtained to guarantee the balance operation of induction motors.

### Mathematical Model of Three-Phase Induction Motors in the Synchronous Reference Frame

The most commonly used is the synchronous reference frame. The mathematical model of three-phase induction motors in the synchronous reference frame is found by substituting the frame angular velocity in the differential equations obtained for the *arbitrary* reference frame (3.4.31). Using  $\mathbf{w} = \mathbf{w}_e$  in (3.4.31), we have

$$\frac{di_{qs}^{e}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ -L_{RM}r_{s}i_{qs}^{e} - (L_{SM}L_{RM} - M^{2})\mathbf{w}_{e}i_{ds}^{e} + Mr_{r}i_{qr}^{e} - M(Mi_{ds}^{e} + L_{RM}i_{dr}^{e})\mathbf{w}_{r} + L_{RM}u_{qs}^{e} - Mu_{qr}^{e} \right] \\
\frac{di_{ds}^{e}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ (L_{SM}L_{RM} - M^{2})\mathbf{w}_{e}i_{qs}^{e} - L_{RM}r_{s}i_{ds}^{e} + Mr_{r}i_{dr}^{e} + M(Mi_{qs}^{e} + L_{RM}i_{qr}^{e})\mathbf{w}_{r} + L_{RM}u_{ds}^{e} - Mu_{dr}^{e} \right] \\
\frac{di_{os}^{e}}{dt} = \frac{1}{L_{Is}} \left( -r_{s}i_{os}^{e} + u_{os}^{e} \right), \\
\frac{di_{qr}^{e}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{qs}^{e} - L_{SM}r_{r}i_{qr}^{e} - (L_{SM}L_{RM} - M^{2})\mathbf{w}_{e}i_{dr}^{e} + L_{SM}u_{dr}^{e} \right] \\
\frac{di_{dr}^{e}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{qs}^{e} + L_{SM}i_{dr}^{e} \right] \mathbf{w}_{r} - Mu_{qs}^{e} + L_{SM}u_{qr}^{e} \right] \\
\frac{di_{dr}^{e}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{ds}^{e} + (L_{SM}L_{RM} - M^{2})\mathbf{w}_{e}i_{qr}^{e} - L_{SM}r_{r}i_{dr}^{e} - L_{SM}r_{r}i_{dr}^{e} \right] \\
\frac{di_{dr}^{e}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{ds}^{e} + (L_{SM}L_{RM} - M^{2})\mathbf{w}_{e}i_{qr}^{e} - L_{SM}r_{r}i_{dr}^{e} - L_{SM}r_{r}i_{dr}^{e} \right] \\
\frac{di_{dr}^{e}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{ds}^{e} + (L_{SM}L_{RM} - M^{2})\mathbf{w}_{e}i_{qr}^{e} - L_{SM}r_{r}i_{dr}^{e} \right] \\
\frac{di_{dr}^{e}}{dt} = \frac{1}{L_{SM}L_{RM} - M^{2}} \left[ Mr_{s}i_{ds}^{e} + (L_{SM}L_{RM} - M^{2})\mathbf{w}_{e}i_{qr}^{e} - L_{SM}r_{r}i_{dr}^{e} \right] \\
\frac{di_{dr}^{e}}{dt} = \frac{1}{L_{os}} \left( -r_{r}i_{or}^{e} + u_{or}^{e} \right), \quad (3.4.32)$$

The superscript e denotes the synchronous frame of reference. In matrix form, using (3.4.32), we have the following differential equation for electric drives

$$\begin{array}{c} \underbrace{\operatorname{dif}_{w}^{r}}_{u}^{v} \stackrel{o}{\operatorname{dif}_{w}^{r}} \underbrace{\operatorname{dif}_{u}^{r}}_{L_{M}L_{RM}^{r}, M^{2}} & - \mathbf{w}_{e} & 0 & \frac{Mr_{e}^{r}}{L_{M}L_{RM}^{r}, M^{2}} & 0 & 0 & 0 & \bigcup_{u}^{u} \\ \underbrace{\operatorname{dif}_{w}^{r}}_{u}^{v} \stackrel{o}{\operatorname{dif}_{w}^{r}} \stackrel{o}{\operatorname{di}_{w}^{r}} \stackrel{o}{\operatorname{dif}_{w}^{r}} \stackrel{o}{\operatorname{di}_{w}^{r}} \stackrel{o}{\operatorname{di}_{w}$$

The quadrature, direct and zero voltages  $u_{qs}^e$ ,  $u_{ds}^e$  and  $u_{os}^e$  to guarantee the balanced operation of induction motors are found from

$$\mathbf{u}_{qdos}^{e} = \mathbf{K}_{s}^{e} \mathbf{u}_{abcs} \,.$$

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é é Taking note that  $\mathbf{q} = \mathbf{q}_e$  in  $\mathbf{K}_s = \frac{2}{3} \frac{\hat{\mathbf{e}}}{\hat{\mathbf{e}}} \sin \mathbf{q} \quad \sin(\mathbf{q} - \frac{2}{3}\mathbf{p}) \quad \sin(\mathbf{q} + \frac{2}{3}\mathbf{p}) \overset{\circ}{\mathbf{u}},$  $\hat{\mathbf{e}} \frac{1}{2} \quad \frac{1}{2} \quad \frac{1}{2} \quad \frac{1}{2} \quad \overset{\circ}{\mathbf{u}}$ 

one finds

$$\mathbf{K}_{s}^{e} = \frac{2}{3} \frac{\hat{\mathbf{e}}}{\hat{\mathbf{e}}} \sin \boldsymbol{q}_{e} \quad \sin(\boldsymbol{q}_{e} - \frac{2}{3}\boldsymbol{p}) \quad \cos(\boldsymbol{q}_{e} + \frac{2}{3}\boldsymbol{p}) \dot{\mathbf{u}}_{u}^{u}$$
$$\mathbf{K}_{s}^{e} = \frac{2}{3} \frac{\hat{\mathbf{e}}}{\hat{\mathbf{e}}} \sin \boldsymbol{q}_{e} \quad \sin(\boldsymbol{q}_{e} - \frac{2}{3}\boldsymbol{p}) \quad \sin(\boldsymbol{q}_{e} + \frac{2}{3}\boldsymbol{p}) \dot{\mathbf{u}}_{u}^{u}$$
$$\frac{\hat{\mathbf{e}}}{\hat{\mathbf{e}}} \quad \frac{1}{2} \qquad \frac{1}{2} \qquad \frac{1}{2} \qquad \frac{1}{2} \qquad \frac{1}{2}$$

Therefore,

$$\begin{array}{cccc} \dot{\mathbf{e}}_{d} \boldsymbol{\ell}_{s}^{e} \dot{\mathbf{u}} & \dot{\mathbf{e}} \cos \boldsymbol{q}_{e} & \cos (\boldsymbol{q}_{e} - \frac{2}{3}\boldsymbol{p}) & \cos (\boldsymbol{q}_{e} + \frac{2}{3}\boldsymbol{p}) \dot{\mathbf{u}} \dot{\boldsymbol{e}}_{ds} \boldsymbol{u}_{as} \dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{d} \boldsymbol{\ell}_{s} \dot{\mathbf{u}} = \frac{2}{3} \dot{\mathbf{e}} \sin \boldsymbol{q}_{e} & \sin (\boldsymbol{q}_{e} - \frac{2}{3}\boldsymbol{p}) & \sin (\boldsymbol{q}_{e} + \frac{2}{3}\boldsymbol{p}) \dot{\mathbf{u}} \dot{\boldsymbol{e}}_{ds} \boldsymbol{u}_{bs} \dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{ds} \boldsymbol{\ell}_{os}^{e} \dot{\mathbf{u}} & \dot{\mathbf{e}} & \frac{1}{2} & \frac{1}{2} & \frac{1}{2} & \dot{\mathbf{u}} \dot{\mathbf{e}}_{ds} \boldsymbol{\ell}_{cs} \dot{\boldsymbol{u}} \\ \dot{\mathbf{e}}_{ds} \boldsymbol{\ell}_{os}^{e} \dot{\mathbf{u}} & \dot{\mathbf{e}} & \frac{1}{2} & \frac{1}{2} & \dot{\mathbf{u}} \dot{\mathbf{e}}_{ds} \boldsymbol{\ell}_{cs} \dot{\boldsymbol{u}} \\ \end{array}$$

That is,

$$u_{qs}^{e}(t) = \frac{2}{3} \frac{e}{6} u_{as} \cos \mathbf{q}_{e} + u_{bs} \cos(\mathbf{q}_{e} - \frac{2}{3}\mathbf{p}) + u_{cs} \cos(\mathbf{q}_{e} + \frac{2}{3}\mathbf{p})^{\dot{\mathbf{u}}}_{\dot{\mathbf{f}}}$$
$$u_{ds}^{e}(t) = \frac{2}{3} \frac{e}{6} u_{as} \sin \mathbf{q}_{e} + u_{bs} \sin(\mathbf{q}_{e} - \frac{2}{3}\mathbf{p}) + u_{cs} \sin(\mathbf{q}_{e} + \frac{2}{3}\mathbf{p})^{\dot{\mathbf{u}}}_{\dot{\mathbf{f}}}$$
$$u_{os}^{e}(t) = \frac{1}{3} (u_{as} + u_{bs} + u_{cs}).$$
Taking note of a balanced three phase voltage set

Taking note of a balanced uncerphase voltage set  

$$u_{as}(t) = \sqrt{2}u_M \cos(\mathbf{w}_f t), \ u_{bs}(t) = \sqrt{2}u_M \cos(\mathbf{w}_f t - \frac{2}{3}\mathbf{p}),$$

$$u_{cs}(t) = \sqrt{2}u_M \cos(\mathbf{w}_f t + \frac{2}{3}\mathbf{p}),$$

and assuming that the initial displacement of the *quadrature* magnetic axis is zero, from  $\mathbf{q}_e = \mathbf{w}_f t$ , we have that the following *quadrature*, *direct*, and *zero* stator voltages must be supplied to guarantee the balance operation

$$u_{qs}^{e}(t) = \sqrt{2}u_{M}, u_{ds}^{e}(t) = 0, u_{os}^{e}(t) = 0.$$
(3.4.33)

It should be emphasized that the *quadrature-*, *direct-*, and *zero-*axis components of stator and rotor voltages, currents, and flux linkages have dc form. Furthermore, to control induction motors, only the dc *quadrature* voltage  $u_{as}^{e}(t)$  is regulated because  $u_{ds}^{e}(t) = 0$  and  $u_{os}^{e}(t) = 0$ .

Using (3.4.32), the block diagram is developed, see Figure 3.4.6.



Figure 3.4.6. Block diagram for three-phase squirrel-cage induction motors modeled in the synchronous reference frame

## **3.5. MICROSCALE SYNCHRONOUS MACHINES**

In this section, the following variables and symbols are used:

 $u_{as}$ ,  $u_{bs}$  and  $u_{cs}$  are the phase voltages in the stator windings *as*, *bs* and *cs*;  $u_{qs}$ ,  $u_{ds}$  and  $u_{os}$  are the *quadrature-*, *direct-*, and *zero-*axis stator voltage components;

 $i_{as}$ ,  $i_{bs}$  and  $i_{cs}$  are the phase currents in the stator windings *as*, *bs* and *cs*;  $i_{qs}$ ,  $i_{ds}$  and  $i_{os}$  are the *quadrature*-, *direct*-, and *zero*-axis stator current components;

 $y_{as}, y_{bs}$  and  $y_{cs}$  are the stator flux linkages;

 $\mathbf{y}_{qs}$ ,  $\mathbf{y}_{ds}$  and  $\mathbf{y}_{0s}$  are the *quadrature-*, *direct-*, and *zero-*axis stator flux linkages components;

 $\mathbf{y}_m$  is the magnitude of the flux linkages established by the permanent-magnets;

 $\boldsymbol{w}_r$  and  $\boldsymbol{w}_{rm}$  are the electrical and rotor angular velocities;

 $\boldsymbol{q}_r$  and  $\boldsymbol{q}_{rm}$  are the electrical and rotor angular displacements;

 $T_e$  is the electromagnetic torque developed;

 $T_L$  is the load torque applied;

 $B_m$  is the viscous friction coefficient;

J is the equivalent moment of inertia;

 $r_s$  is the resistances of the stator windings;

 $L_{ss}$  is the self-inductances of the stator windings;

 $L_{ms}$  and  $L_{ls}$  are the stator magnetizing and leakage inductances;

 $L_{mq}$  and  $L_{md}$  are the magnetizing inductances in the *quadrature* and *direct* axes;

 $\hat{A}_{md}$  and  $\hat{A}_{mq}$  are the magnetizing reluctances in the *direct* and *quadrature* axes;

 $N_s$  is the number of turns of the stator windings;

*P* is the number of poles;

w and q are the angular velocity and displacement of the reference frame.

Micro- and miniscale synchronous machines can be used as motors and generators. Generators convert mechanical energy into electrical energy, while motors convert electrical energy into mechanical energy. A broad spectrum of synchronous electric machines can be used in electric drives, *servos*, and power systems applications. We will develop nonlinear mathematical models, and perform nonlinear modeling and analysis of synchronous machines.

#### 3.5.1. Single-Phase Reluctance Motors

We consider single-phase reluctance motors to study the operation of synchronous machines, analyze important features, as well as to visualize mathematical model developments. It should be emphasized that micro- and miniscale synchronous reluctance motors can be easily manufactured. A single-phase reluctance motor is documented in Figure 3.5.1.



Figure 3.5.1. Microscale single-phase reluctance motor

The *quadrature* and *direct* magnetic axes are fixed with the rotor, which rotates with angular velocity  $\mathbf{w}_r$ . These magnetic axes rotate with the angular velocity  $\mathbf{w}$ . It should be emphasized that under normal operation the angular velocity of synchronous machines is equal to the synchronous angular velocity  $\mathbf{w}_e$ . Hence,  $\mathbf{w}_r = \mathbf{w}_e$  and  $\mathbf{w} = \mathbf{w}_r = \mathbf{w}_e$ . Assuming that the initial conditions are zero. Hence, the angular displacements of the rotor  $\mathbf{q}_r$  and the angular displacement of the *quadrature* magnetic axis  $\mathbf{q}$  are equal, and

$$\boldsymbol{q}_r = \boldsymbol{q} = \mathop{\mathbf{\check{O}}}_{t_0}^{t} \boldsymbol{w}_r(t) dt = \mathop{\mathbf{\check{O}}}_{t_0}^{t} \boldsymbol{w}(t) dt \cdot$$

The magnetizing reluctance  $\hat{A}_m$  is a function of the rotor angular displacement  $\boldsymbol{q}_r$ . Using the number of turns  $N_s$ , the magnetizing inductance is  $L_m(\boldsymbol{q}_r) = \frac{N_s^2}{\hat{A}_m(\boldsymbol{q}_r)}$ . This magnetizing inductance varies twice per one revolution of the rotor and has minimum and maximum values, and

$$L_{m\min} = \frac{N_s^2}{\hat{\mathsf{A}}_{m\max}(\boldsymbol{q}_r)} \bigg|_{\boldsymbol{q}_r=0,\boldsymbol{p},2\boldsymbol{p},\dots}, \ L_{m\max} = \frac{N_s^2}{\hat{\mathsf{A}}_{m\min}(\boldsymbol{q}_r)} \bigg|_{\boldsymbol{q}_r=\frac{1}{2}\boldsymbol{p},\frac{3}{2}\boldsymbol{p},\frac{5}{2}\boldsymbol{p},\dots}$$

Assume that this variation is a sinusoidal function of the rotor angular displacement. Then,

 $L_m(\boldsymbol{q}_r) = \overline{L}_m - L_{\mathsf{D}m} \cos 2\boldsymbol{q}_r,$ 

where  $\overline{L}_m$  is the average value of the magnetizing inductance;  $L_{Dm}$  is the half of amplitude of the sinusoidal variation of the magnetizing inductance.

The plot for  $L_m(\boldsymbol{q}_r)$  is documented in Figure 3.5.2.



Figure 3.5.2. Magnetizing inductance  $L_m(\boldsymbol{q}_r)$ 

The electromagnetic torque, developed by single-phase reluctance motors is found using the expression for the coenergy  $W_c(i_{as}, \mathbf{q}_r)$ . From  $W_c(i_{as}, \mathbf{q}_r) = \frac{1}{2} (L_{ls} + \overline{L}_m - L_{Dm} \cos 2\mathbf{q}_r) i_{as}^2$ , one finds  $T_e = \frac{\P W_c(i_{as}, \mathbf{q}_r)}{\P \mathbf{q}_r} = \frac{\P (\frac{1}{2} i_{as}^2 (L_{ls} + \overline{L}_m - L_{Dm} \cos 2\mathbf{q}_r))}{\P \mathbf{q}_r} = L_{Dm} i_{as}^2 \sin 2\mathbf{q}_r$ .

It is clear that the electromagnetic torque is not developed by synchronous reluctance motors if one feeds the dc current or voltage to the motor winding. Hence, <u>conventional control algorithms cannot be applied</u>, and new methods, which are based upon electromagnetic features must be researched. The average value of  $T_e$  is not equal to zero if the current is a function of  $q_r$ . As an illustration, we fed the following current to the motor winding

$$i_{as} = i_M \operatorname{Re}\left(\sqrt{\sin 2\boldsymbol{q}_r}\right).$$

Then, the electromagnetic torque is

$$T_e = L_{\text{Dm}} i_{as}^2 \sin 2\boldsymbol{q}_r = L_{\text{Dm}} i_M^2 \left( \text{Re} \sqrt{\sin 2\boldsymbol{q}_r} \right)^2 \sin 2\boldsymbol{q}_r \ 1 \ 0,$$
  
and 
$$T_{eav} = \frac{1}{\boldsymbol{p}} \sum_{0}^{\boldsymbol{p}} L_{\text{Dm}} i_{as}^2 \sin 2\boldsymbol{q}_r d\boldsymbol{q}_r = \frac{1}{4} L_{\text{Dm}} i_M^2.$$

The mathematical model of the single-phase reluctance motor is found by using Kirchhoff's and Newton's second laws

$$u_{as} = r_s i_{as} + \frac{d\mathbf{y}_{as}}{dt}, \qquad \text{(circuitry equation)}$$
$$T_e - B_m \mathbf{w}_r - T_L = J \frac{d^2 \mathbf{q}_r}{dt^2}. \quad (torsional-mechanical equation)$$

From  $\mathbf{y}_{as} = (L_{ls} + \overline{L}_m - L_{Dm} \cos 2\mathbf{q}_r) i_{as}$ , one obtains a set of three first-order nonlinear differential equations which models single-phase reluctance motors. In particular, we have

$$\begin{aligned} \frac{di_{as}}{dt} &= -\frac{r_s}{L_{ls} + \overline{L}_m - L_{Dm} \cos 2\boldsymbol{q}_r} i_{as} - \frac{2L_{Dm}}{L_{ls} + \overline{L}_m - L_{Dm} \cos 2\boldsymbol{q}_r} i_{as} \boldsymbol{w}_r \sin 2\boldsymbol{q}_r \\ &+ \frac{1}{L_{ls} + \overline{L}_m - L_{Dm} \cos 2\boldsymbol{q}_r} u_{as}, \\ \frac{d\boldsymbol{w}_r}{dt} &= \frac{1}{J} \left( L_{Dm} i_{as}^2 \sin 2\boldsymbol{q}_r - B_m \boldsymbol{w}_r - T_L \right), \\ \frac{d\boldsymbol{q}_r}{dt} &= \boldsymbol{w}_r. \end{aligned}$$

#### **3.5.2.** Permanent-Magnet Synchronous Machines

Permanent-magnet synchronous machines are brushless machines because the excitation flux is produced by permanent magnets.

Permanent-Magnet Synchronous Machines in the Machine Variables

Three-phase two-pole permanent-magnet synchronous motors and generators are illustrated in Figures 3.5.3 and 3.5.4.



Figure 3.5.3. Two-pole permanent-magnet synchronous motor



Figure 3.5.4. Three-phase wye-connected synchronous generator

From Kirchhoff's second law, one obtains three differential equations for the *as*, *bs* and *cs* stator windings. In particular,

$$u_{as} = r_s i_{as} + \frac{d\mathbf{y}_{as}}{dt},$$
  

$$u_{bs} = r_s i_{bs} + \frac{d\mathbf{y}_{bs}}{dt},$$
  

$$u_{cs} = r_s i_{cs} + \frac{d\mathbf{y}_{cs}}{dt},$$
  
(3.5.1)

where the flux linkages  $y_{as}, y_{bs}$  and  $y_{cs}$  are

$$\mathbf{y}_{as} = L_{asas}i_{as} + L_{asbs}i_{bs} + L_{ascs}i_{cs} + \mathbf{y}_{asm},$$
  

$$\mathbf{y}_{bs} = L_{bsas}i_{as} + L_{bsbs}i_{bs} + L_{bscs}i_{cs} + \mathbf{y}_{bsm},$$
  

$$\mathbf{y}_{cs} = L_{csas}i_{as} + L_{csbs}i_{bs} + L_{cscs}i_{cs} + \mathbf{y}_{csm}.$$
  
From (3.5.1), one finds

$$\mathbf{u}_{abcs} = \mathbf{r}_{s} \mathbf{i}_{abcs} + \frac{d\mathbf{y}_{abcs}}{dt}, \begin{array}{l} \dot{\mathbf{e}} u_{as} \dot{\mathbf{u}} \quad \mathbf{e}^{s}, \quad 0 \quad 0 \, \dot{\mathbf{u}} \mathbf{e}^{s}_{as} \dot{\mathbf{u}} \quad \dot{\mathbf{e}}^{s}_{dt} \mathbf{u}^{t}_{dt} \\ \dot{\mathbf{e}}^{d} \mathbf{y}_{bs} \dot{\mathbf{u}}^{t}_{s} = \mathbf{e}^{0}, \quad r_{s} \quad 0 \, \dot{\mathbf{u}} \mathbf{e}^{s}_{ds} \dot{\mathbf{u}} \quad \dot{\mathbf{e}}^{d} \mathbf{y}_{bs} \dot{\mathbf{u}} \\ \dot{\mathbf{e}}^{d} \mathbf{y}_{bs} \dot{\mathbf{u}}^{t}_{s} = \mathbf{e}^{0}, \quad r_{s} \quad 0 \, \dot{\mathbf{u}} \mathbf{e}^{s}_{ds} \dot{\mathbf{u}} \quad \dot{\mathbf{e}}^{d} \mathbf{y}_{bs} \dot{\mathbf{u}} \\ \dot{\mathbf{e}}^{d} \mathbf{y}_{cs} \dot{\mathbf{u}} \quad \dot{\mathbf{e}}^{d} \mathbf{y}_{cs} \dot{\mathbf{u}} \\ \dot{\mathbf{e}}^{d} \mathbf{y}_{cs} \dot{\mathbf{u}} \quad \dot{\mathbf{e}}^{d} \mathbf{y}_{cs} \dot{\mathbf{u}} \\ \dot{\mathbf{e}}^{d} \mathbf{y}_{cs} \dot{\mathbf{u}} \quad \dot{\mathbf{u}} \\ \dot{\mathbf{e}}^{d} \mathbf{y}_{cs} \dot{\mathbf{u}} \\ \dot$$

The flux linkages  $y_{asm}$ ,  $y_{bsm}$ , and  $y_{csm}$ , established by the permanent magnet, are periodic functions of  $q_r$ . We assume that  $y_{asm}$ ,  $y_{bsm}$ , and  $y_{csm}$  vary obeying the sine law. The stator windings are displaced by 120 electrical degrees, and using the magnitude of the flux linkages  $y_m$ , established by the permanent magnet, one has

$$\boldsymbol{y}_{asm} = \boldsymbol{y}_m \sin \boldsymbol{q}_r, \boldsymbol{y}_{bsm} = \boldsymbol{y}_m \sin \left( \boldsymbol{q}_r - \frac{2}{3} \boldsymbol{p} \right), \boldsymbol{y}_{csm} = \boldsymbol{y}_m \sin \left( \boldsymbol{q}_r + \frac{2}{3} \boldsymbol{p} \right).$$

Self- and mutual inductances for three-phase permanent-magnet synchronous machines can be derived. Equations for the magnetizing *quadrature* and *direct* inductances are

$$L_{mq} = \frac{N_s^2}{\hat{A}_{mq}}$$
 and  $L_{md} = \frac{N_s^2}{\hat{A}_{md}}$ 

In general, the *quadrature* and *direct* magnetizing reluctances can be different, and  $\hat{A}_{mq} > \hat{A}_{md}$ . Hence, we have  $L_{mq} < L_{md}$ . The minimum value of  $L_{asas}$  occurs periodically at  $\boldsymbol{q}_r = 0$ ,  $\boldsymbol{p}$ ,  $2\boldsymbol{p},...$ , while the maximum value of  $L_{asas}$  occurs at  $\boldsymbol{q}_r = \frac{1}{2}\boldsymbol{p}$ ,  $\frac{3}{2}\boldsymbol{p}$ ,  $\frac{5}{2}\boldsymbol{p}$ , ....

One concludes that the self-inductance  $L_{asas}(\boldsymbol{q}_r)$ , which is bounded as  $L_{ls} + L_{mq} \ \boldsymbol{\pounds} \ L_{asas} \ \boldsymbol{\pounds} \ L_{ls} + L_{md}$ , is a periodic function of  $\boldsymbol{q}_r$ . Assuming that  $L_{asas}(\boldsymbol{q}_r)$  varies as a sine function with a dc component, we have

 $L_{asas} = L_{ls} + \overline{L}_m - L_{Dm} \cos 2\boldsymbol{q}_r \,.$ 

Here,  $\overline{L}_m$  is the average value of the magnetizing inductance;  $L_{Dm}$  is the half of amplitude of the sinusoidal variation of the magnetizing inductance.

The relationships between  $L_{mq}$ ,  $L_{md}$ , and  $\overline{L}_m$ ,  $L_{Dm}$  must be found, and for three-phase synchronous motors, one obtains

$$L_{mq} = \frac{3}{2} \left( \overline{L}_m - \overline{L}_{Dm} \right)$$
 and  $L_{md} = \frac{3}{2} \left( \overline{L}_m + \overline{L}_{Dm} \right).$ 

Therefore,  $\overline{L}_m = \frac{1}{3} (L_{mq} + L_{md})$  and  $L_{Dm} = \frac{1}{3} (L_{md} - L_{mq})$ . Using the expressions for  $L_{mq}$  and  $L_{md}$ , we have

$$\overline{L}_{m} = \frac{1}{3} \underbrace{\underbrace{\mathbf{\mathcal{E}}}_{n} N_{s}^{2}}_{\mathbf{\mathbf{\mathcal{E}}} \mathbf{\mathbf{A}}_{mq}} + \frac{N_{s}^{2}}{\mathbf{\mathbf{\mathbf{\mathcal{E}}}}_{md}^{2}} \stackrel{\mathbf{O}}{\Rightarrow} \text{ and } L_{\mathbf{D}m} = \frac{1}{3} \underbrace{\underbrace{\mathbf{\mathcal{E}}}_{n} N_{s}^{2}}_{\mathbf{\mathbf{\mathbf{\mathcal{E}}}} \mathbf{\mathbf{A}}_{mq}} - \frac{N_{s}^{2}}{\mathbf{\mathbf{\mathbf{\mathcal{E}}}}_{mq}^{2}} \stackrel{\mathbf{O}}{\Rightarrow}$$

Therefore, the following equations for 
$$\mathbf{y}_{as}, \mathbf{y}_{bs}$$
 and  $\mathbf{y}_{cs}$  result  

$$\mathbf{y}_{as} = \left(L_{ls} + \overline{L}_{m} - L_{Dm}\cos 2\mathbf{q}_{r}\right)i_{as} + \left(-\frac{1}{2}\overline{L}_{m} - L_{Dm}\cos 2\left(\mathbf{q}_{r} - \frac{1}{3}\mathbf{p}\right)\right)i_{bs}$$

$$+ \left(-\frac{1}{2}\overline{L}_{m} - L_{Dm}\cos 2\left(\mathbf{q}_{r} + \frac{1}{3}\mathbf{p}\right)\right)i_{cs} + \mathbf{y}_{m}\sin \mathbf{q}_{r},$$

$$\mathbf{y}_{bs} = \left(-\frac{1}{2}\overline{L}_{m} - L_{Dm}\cos 2\left(\mathbf{q}_{r} - \frac{1}{3}\mathbf{p}\right)\right)i_{as} + \left(L_{ls} + \overline{L}_{m} - L_{Dm}\cos 2\left(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}\right)\right)i_{bs}$$

$$+ \left(-\frac{1}{2}\overline{L}_{m} - L_{Dm}\cos 2\mathbf{q}_{r}\right)i_{cs} + \mathbf{y}_{m}\sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}),$$

$$\mathbf{y}_{cs} = \left(-\frac{1}{2}\overline{L}_{m} - L_{Dm}\cos 2\mathbf{q}_{r}\right)i_{cs} + \mathbf{y}_{m}\sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}),$$

$$\mathbf{y}_{cs} = \left(-\frac{1}{2}\overline{L}_{m} - L_{Dm}\cos 2\left(\mathbf{q}_{r} + \frac{1}{3}\mathbf{p}\right)\right)i_{as} + \left(-\frac{1}{2}\overline{L}_{m} - L_{Dm}\cos 2\mathbf{q}_{r}\right)i_{bs}$$

$$+ \left(L_{ls} + \overline{L}_{m} - L_{Dm}\cos 2\left(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right)\right)i_{cs} + \mathbf{y}_{m}\sin(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}).$$
(3.5.2)

From (3.5.2), one has  $\mathbf{y}_{abcs} = \mathbf{L}_s \mathbf{i}_{abcs} + \mathbf{y}_m$ 

$$\begin{array}{c} \overset{\bullet}{\text{e}} \quad L_{ls} + \overline{L}_{m} - L_{\text{Dm}} \cos 2\mathbf{q}_{r} \quad -\frac{1}{2}\overline{L}_{m} - L_{\text{Dm}} \cos 2(\mathbf{q}_{r} - \frac{1}{3}\mathbf{p}) \quad -\frac{1}{2}\overline{L}_{m} - L_{\text{Dm}} \cos 2(\mathbf{q}_{r} + \frac{1}{3}\mathbf{p}) \stackrel{\bullet}{\underline{U}} \overset{\bullet}{\text{d}} \overset{\bullet}{\text$$

The inductance matrix  $\mathbf{L}_s$  is given by

$$\begin{split} & \stackrel{\bullet}{\mathbf{\hat{e}}} \quad L_{ls} + \overline{L}_m - L_{\text{D}m} \cos 2(\mathbf{q}_r - \frac{1}{3}\mathbf{p}) \quad -\frac{1}{2}\overline{L}_m - L_{\text{D}m} \cos 2(\mathbf{q}_r - \frac{1}{3}\mathbf{p}) \quad -\frac{1}{2}\overline{L}_m - L_{\text{D}m} \cos 2(\mathbf{q}_r + \frac{1}{3}\mathbf{p}) \stackrel{\flat}{\mathbf{\hat{u}}} \\ & \stackrel{\bullet}{\mathbf{\hat{e}}} \quad \frac{1}{2}\overline{L}_m - L_{\text{D}m} \cos 2(\mathbf{q}_r - \frac{1}{3}\mathbf{p}) \quad L_{ls} + \overline{L}_m - L_{\text{D}m} \cos 2(\mathbf{q}_r - \frac{2}{3}\mathbf{p}) \quad -\frac{1}{2}\overline{L}_m - L_{\text{D}m} \cos 2(\mathbf{q}_r - \frac{1}{3}\mathbf{p}) \stackrel{\flat}{\mathbf{\hat{u}}} \\ & \stackrel{\bullet}{\mathbf{\hat{e}}} \quad \frac{1}{2}\overline{L}_m - L_{\text{D}m} \cos 2(\mathbf{q}_r + \frac{1}{3}\mathbf{p}) \quad -\frac{1}{2}\overline{L}_m - L_{\text{D}m} \cos 2(\mathbf{q}_r - \frac{2}{3}\mathbf{p}) \quad -\frac{1}{2}\overline{L}_m - L_{\text{D}m} \cos 2(\mathbf{q}_r + \frac{2}{3}\mathbf{p}) \stackrel{\flat}{\mathbf{\hat{u}}} \end{split}$$

It was shown that  $\overline{L}_m$  and  $L_{Dm}$  are expressed as

$$\overline{L}_{m} = \frac{1}{3} \underbrace{\widehat{\mathbf{g}} \widehat{\mathbf{A}}_{mq}}_{\mathbf{k}_{mq}} + \frac{N_{s}^{2}}{\widehat{\mathbf{A}}_{md}} \underbrace{\overset{\mathbf{O}}{\mathbf{p}}}_{\mathbf{k}_{mq}} \text{ and } L_{\mathsf{D}m} = \frac{1}{3} \underbrace{\overset{\mathbf{O}}{\mathbf{g}} \widehat{\mathbf{A}}_{md}}_{\mathbf{k}_{mq}} - \frac{N_{s}^{2}}{\widehat{\mathbf{A}}_{mq}} \underbrace{\overset{\mathbf{O}}{\mathbf{p}}}_{\mathbf{k}_{mq}}$$

Permanent-magnet synchronous machines are round-rotor electrical machines (the magnetic paths in the *quadrature* and *direct* magnetic axes are identical, and  $\hat{A}_{mq} = \hat{A}_{md}$ ). Thus,

$$\overline{L}_m = \frac{2N_s^2}{3\hat{A}_{mq}} = \frac{2N_s^2}{3\hat{A}_{md}}$$

and  $L_{Dm} = 0$ .

Therefore, the inductance matrix is

$$\mathbf{L}_{s} = \begin{pmatrix} \mathbf{\hat{e}}L_{ls} + \overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & \mathbf{\hat{u}} \\ \mathbf{\hat{e}} & -\frac{1}{2}\overline{L}_{m} & L_{ls} + \overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & \mathbf{\hat{u}} \\ \mathbf{\hat{e}} & -\frac{1}{2}\overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & L_{ls} + \overline{L}_{m} \mathbf{\hat{u}} \end{pmatrix}$$

From (3.5.2) the expressions for the flux linkages are

$$\mathbf{y}_{as} = \left(L_{ls} + \overline{L}_{m}\right)i_{as} - \frac{1}{2}\overline{L}_{m}i_{bs} - \frac{1}{2}\overline{L}_{m}i_{cs} + \mathbf{y}_{m}\sin\mathbf{q}_{r},$$
  

$$\mathbf{y}_{bs} = -\frac{1}{2}\overline{L}_{m}i_{as} + \left(L_{ls} + \overline{L}_{m}\right)i_{bs} - \frac{1}{2}\overline{L}_{m}i_{cs} + \mathbf{y}_{m}\sin\left(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}\right),$$
  

$$\mathbf{y}_{cs} = -\frac{1}{2}\overline{L}_{m}i_{as} - \frac{1}{2}\overline{L}_{m}i_{bs} + \left(L_{ls} + \overline{L}_{m}\right)i_{cs} + \mathbf{y}_{m}\sin\left(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right),$$
 (3.5.3)

or in matrix form

$$\mathbf{y}_{abcs} = \mathbf{L}_{s}\mathbf{i}_{abcs} + \mathbf{y}_{m} = \begin{pmatrix} \mathbf{\dot{e}}L_{ls} + \overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & \mathbf{\dot{\nu}}\mathbf{\dot{e}}_{as}\mathbf{\dot{\nu}} & \mathbf{\dot{e}}_{bs}\mathbf{\dot{\nu}} + \mathbf{y}_{m} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{e}} - \frac{1}{2}\overline{L}_{m} & L_{ls} + \overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & \mathbf{\dot{\nu}}\mathbf{\dot{e}}_{bs}\mathbf{\dot{\nu}} + \mathbf{y}_{m} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p})\mathbf{\dot{\nu}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{e}} - \frac{1}{2}\overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & L_{ls} + \overline{L}_{m} & \mathbf{\dot{\nu}}\mathbf{\dot{e}}_{bs}\mathbf{\dot{\nu}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p})\mathbf{\dot{\nu}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p})\mathbf{\dot{\nu}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p})\mathbf{\dot{n}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}(\mathbf{n})\mathbf{\dot{n}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}(\mathbf{n})\mathbf{\dot{n}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}(\mathbf{n})\mathbf{\dot{n}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}(\mathbf{n})\mathbf{\dot{n}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}(\mathbf{n})\mathbf{\dot{n}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}(\mathbf{n})\mathbf{\dot{n}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}} \\ \mathbf{\dot{e}}_{bs}\mathbf{\dot{n}}$$

Using (3.5.1) and (3.5.3), we have

$$\mathbf{u}_{abcs} = \mathbf{r}_{s}\mathbf{i}_{abcs} + \frac{d\mathbf{y}_{abcs}}{dt} = \mathbf{r}_{s}\mathbf{i}_{abcs} + \mathbf{L}_{s}\frac{d\mathbf{i}_{abcs}}{dt} + \frac{d\mathbf{y}_{m}}{dt},$$
  
where  $\frac{d\mathbf{y}_{m}}{dt} = \mathbf{y}_{m} \stackrel{\text{\acute{e}}}{\mathbf{e}} \mathbf{w}_{r}\cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p})\overset{\text{\acute{e}}}{\mathbf{u}},$   
 $\stackrel{\text{\acute{e}}}{\mathbf{e}} \mathbf{w}_{r}\cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p})\overset{\text{\acute{e}}}{\mathbf{u}},$ 

Cauchy's form can be found by making use of  $\mathbf{L}_{s}^{-1}$ . In particular,

$$\frac{d\mathbf{\dot{i}}_{abcs}}{dt} = -\mathbf{L}_{s}^{-1}\mathbf{r}_{s}\mathbf{\dot{i}}_{abcs} - \mathbf{L}_{s}^{-1}\frac{d\mathbf{y}_{m}}{dt} + \mathbf{L}_{s}^{-1}\mathbf{u}_{abcs}.$$

The stator circuitry dynamics in Cauchy's form is given as

$$\begin{split} & \frac{\det_{as} \hat{\mathbf{u}}}{\det_{as} \hat{\mathbf{u}}} \stackrel{\bullet}{\mathbf{e}} \frac{r_{s} \left( 2L_{ss} - \overline{L_{m}} \right)}{2L_{ss}^{2} - L_{ss} \overline{L_{m}} - \overline{L_{m}}^{2}} - \frac{r_{s} \overline{L_{m}} - \overline{L_{m}}}{2L_{ss}^{2} - L_{ss} \overline{L_{m}} - \overline{L_{m}}^{2}} - \frac{r_{s} \overline{L_{m}} - \overline{L_{m}}}{2L_{ss}^{2} - L_{ss} \overline{L_{m}} - \overline{L_{m}}^{2}} - \frac{r_{s} \overline{L_{m}} - \overline{L_{m}}}{2L_{ss}^{2} - L_{ss} \overline{L_{m}} - \overline{L_{m}}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}$$

In expanded form, we have the following nonlinear differential equations which allow the designer to model the circuitry transient behavior

$$\begin{aligned} \frac{di_{as}}{dt} &= -\frac{r_{s}\left(2L_{ss}-\bar{L}_{m}\right)}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}i_{as} - \frac{r_{s}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}i_{bs} - \frac{r_{s}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}i_{cs} \\ &- \frac{\mathbf{y}_{m}\left(2L_{ss}-\bar{L}_{m}\right)}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\mathbf{q}_{r} - \frac{\mathbf{y}_{m}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}-\frac{2}{3}\mathbf{p}\right) \\ &- \frac{\mathbf{y}_{m}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &+ \frac{2L_{ss}-\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}u_{as} + \frac{\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}u_{bs} + \frac{\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}u_{cs}, \\ &\frac{di_{bs}}{dt} = -\frac{r_{s}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}i_{as} - \frac{r_{s}\left(2L_{ss}-\bar{L}_{m}\right)}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}i_{bs} - \frac{r_{s}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}i_{cs} \\ &- \frac{\mathbf{y}_{m}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\mathbf{q}_{r} - \frac{\mathbf{y}_{m}\left(2L_{ss}-\bar{L}_{m}\right)}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}-\frac{2}{3}\mathbf{p}\right) \\ &+ \frac{\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &+ \frac{\bar{L}_{m}}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &+ \frac{\bar{L}_{m}}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &+ \frac{\bar{L}_{m}}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}-\frac{2}{3}\mathbf{p}\right) \\ &+ \frac{\bar{L}_{m}}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}-\frac{2}{$$

Having derived the differential equations to model the circuitry dynamics, the transient behavior of the rotor (mechanical system) must be incorporated. One cannot solve (3.5.4) where the electrical angular velocity  $W_r$  and angular displacement  $q_r$  are used as the state variables.

Making use of Newton's second law

$$T_e - B_m \boldsymbol{w}_{rm} - T_L = J \frac{d^2 \boldsymbol{q}_{rm}}{dt^2}$$

we have a set of two differential equations. In particular,

$$\frac{d\boldsymbol{w}_{rm}}{dt} = \frac{1}{J} (T_e - B_m \boldsymbol{w}_{rm} - T_L),$$
$$\frac{d\boldsymbol{q}_{rm}}{dt} = \boldsymbol{w}_{rm}.$$

The expression for the electromagnetic torque developed must be found using the coenergy

$$W_{c} = \frac{1}{2} \begin{bmatrix} i_{as} & i_{bs} & i_{cs} \end{bmatrix} \mathbf{L}_{s} \stackrel{\text{\acute{e}}}{\underset{e}{\partial}} \stackrel{\text{\acute{u}}}{\underset{b}{\partial}} + \begin{bmatrix} i_{as} & i_{bs} & i_{cs} \end{bmatrix} \stackrel{\text{\acute{e}}}{\underset{e}{\partial}} \stackrel{\text{J}}{\underset{m}{\partial}} \stackrel{\text{J}}{\underset{m}{\partial}} \stackrel{\text{\acute{u}}}{\underset{m}{\partial}} \stackrel{\text{\acute{e}}}{\underset{m}{\partial}} \stackrel{\text{J}}{\underset{m}{\partial}} \stackrel{\text{J}}{\underset{m}{\partial}} \stackrel{\text{J}}{\underset{m}{\partial}} \stackrel{\text{J}}{\underset{m}{\partial}} + W_{PM} \cdot \frac{1}{2} \frac{$$

Here,  $W_{PM}$  is the energy stored in the permanent magnet. For round-rotor synchronous machines

$$\mathbf{L}_{s} = \begin{array}{ccc} \dot{\mathbf{e}}L_{ls} + \overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & \dot{\mathbf{u}}\\ \dot{\mathbf{e}} & -\frac{1}{2}\overline{L}_{m} & L_{ls} + \overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & \dot{\mathbf{u}}\\ \dot{\mathbf{e}} & -\frac{1}{2}\overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & L_{ls} + \overline{L}_{m} & \dot{\mathbf{u}} \end{array}$$

The inductance matrix  $\mathbf{L}_s$  and  $W_{PM}$  are not functions of  $\mathbf{q}_r$ . One obtains the following formula to calculate the electromagnetic torque for three-phase *P*-pole permanent-magnet synchronous motors

$$T_e = \frac{P}{2} \frac{\P W_c}{\P q_r} = \frac{P y_m}{2} \left( i_{as} \cos q_r + i_{bs} \cos \left( q_r - \frac{2}{3} p \right) + i_{cs} \cos \left( q_r + \frac{2}{3} p \right) \right).$$

Therefore, we have

$$\frac{d\boldsymbol{w}_{rm}}{dt} = \frac{P\boldsymbol{y}_m}{2J} \left( i_{as} \cos \boldsymbol{q}_r + i_{bs} \cos \left( \boldsymbol{q}_r - \frac{2}{3} \boldsymbol{p} \right) + i_{cs} \cos \left( \boldsymbol{q}_r + \frac{2}{3} \boldsymbol{p} \right) \right) - \frac{B_m}{J} \boldsymbol{w}_{rm} - \frac{1}{J} T_L,$$
  
$$\frac{d\boldsymbol{q}_{rm}}{dt} = \boldsymbol{w}_{rm}.$$

Using the electrical angular velocity  $\mathbf{w}_r$  and displacement  $\mathbf{q}_r$ , related to the mechanical angular velocity and displacement as  $\mathbf{w}_{rm} = \frac{2}{P}\mathbf{w}_r$  and

 $\mathbf{q}_{rm} = \frac{2}{P} \mathbf{q}_r$ , the following differential equations to model the *torsional-mechanical* transient dynamics finally result

$$\frac{d\boldsymbol{w}_r}{dt} = \frac{P^2 \boldsymbol{y}_m}{4J} \left( i_{as} \cos \boldsymbol{q}_r + i_{bs} \cos \left( \boldsymbol{q}_r - \frac{2}{3} \boldsymbol{p} \right) + i_{cs} \cos \left( \boldsymbol{q}_r + \frac{2}{3} \boldsymbol{p} \right) \right) - \frac{B_m}{J} \boldsymbol{w}_r - \frac{P}{2J} T_L,$$

$$\frac{d\boldsymbol{q}_r}{dt} = \boldsymbol{w}_r.$$
(3.5.5)

From (3.5.4) and (3.5.5), one obtains a nonlinear mathematical model of permanent-magnet synchronous motors in Cauchy's form as given by a system of five highly nonlinear differential equations

$$\begin{aligned} \frac{di_{as}}{dt} &= \cdot \frac{r_s \left[ 2L_{ss} - \bar{L}_m \right]}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} i_{as} - \frac{r_s \bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} i_{bs} - \frac{r_s \bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} i_{cs} \\ &- \frac{\mathbf{y}_m \left[ 2L_{ss} - \bar{L}_m \right]}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \mathbf{q}_r - \frac{\mathbf{y}_m \bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{2L_{ss}}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{2L_{ss}}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} u_{as} + \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} u_{bs} + \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} u_{cs}, \\ &\frac{di_{bs}}{dt} = \cdot \frac{r_s \bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} u_{as} + \frac{r_s \left( 2L_{ss} - \bar{L}_m \right)}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) \\ &- \frac{\mathbf{y}_m \bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m} \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) \\ &+ \frac{\bar{L}_m} \frac{\bar{L}_m}{2L_{ss}^2 - L_{ss} \bar{L}_m - \bar{L}_m^2} \mathbf{w}_r \cos \left( \mathbf{q}_r - \frac{2$$

In matrix for, from (3.5.6), we have

$$\begin{array}{c} \stackrel{\acute{e}}{\underline{6}} \frac{2L_{ss} - \overline{L}_m}{L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} & \frac{\overline{L}_m}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} & \frac{\overline{L}_m}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} & \frac{\overline{L}_m}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} \\ \stackrel{\acute{e}}{\underline{6}} \frac{\overline{L}_m}{L_m} & \frac{2L_{ss} - \overline{L}_m}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} & \frac{\overline{L}_m}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} & \frac{\overline{L}_m}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} & \frac{\acute{e} 0 \ \acute{u}}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} \\ \stackrel{\acute{e}}{\underline{6}} \frac{\overline{L}_m}{L_m} & \frac{2L_{ss} - L_{ss}\overline{L}_m - \overline{L}_m^2}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} & \frac{2L_{ss} - L_{ss}\overline{L}_m - \overline{L}_m^2 \ \acute{u} \ \acute{e} 0 \ \acute{u}}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} & \stackrel{\acute{e} P \ \acute{u}}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} \\ \stackrel{\acute{e} 2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2 \ \acute{u} \ \acute{e} 2J \ \acute{u} \ \acute{e} 0 \ \acute{u} \ \acute{e} 0 \ \acute{u} \\ \stackrel{\acute{e} 2J \ \acute{e} 0}{0} & 0 & 0 \end{array}$$

To control the angular velocity, one regulates the currents fed or voltages applied to the stator *abc* windings. Neglecting the viscous friction coefficient, the analysis of Newton's second law

$$T_e - T_L = J \frac{d \mathbf{w}_{rm}}{dt}$$

indicates that

- the angular velocity  $\boldsymbol{w}_{rm}$  increases if  $T_e > T_L$ ,
- the angular velocity  $\mathbf{w}_{rm}$  decreases if  $T_e < T_L$ ,
- the angular velocity  $\mathbf{w}_{rm}$  is constant ( $\mathbf{w}_{rm} = const$ ) if  $T_e = T_L$ . That is, to regulate the electromagnetic torque, which was found as

$$T_e = \frac{P \boldsymbol{y}_m}{2} \left( i_{as} \cos \boldsymbol{q}_r + i_{bs} \cos \left( \boldsymbol{q}_r - \frac{2}{3} \boldsymbol{p} \right) + i_{cs} \cos \left( \boldsymbol{q}_r + \frac{2}{3} \boldsymbol{p} \right) \right),$$

must be changed.

If the *abc* motor windings are fed by a balanced three-phase current set  $i_{as}(t) = \sqrt{2}i_M \cos(\mathbf{w}_r t) = \sqrt{2}i_M \cos(\mathbf{w}_e t) = \sqrt{2}i_M \cos \mathbf{q}_r$ ,  $i_{bs}(t) = \sqrt{2}i_M \cos(\mathbf{w}_r t - \frac{2}{3}\mathbf{p}) = \sqrt{2}i_M \cos(\mathbf{w}_e t - \frac{2}{3}\mathbf{p}) = \sqrt{2}i_M \cos(\mathbf{q}_r - \frac{2}{3}\mathbf{p})$ ,  $i_{cs}(t) = \sqrt{2}i_M \cos(\mathbf{w}_r t + \frac{2}{3}\mathbf{p}) = \sqrt{2}i_M \cos(\mathbf{w}_e t + \frac{2}{3}\mathbf{p}) = \sqrt{2}i_M \cos(\mathbf{q}_r + \frac{2}{3}\mathbf{p})$ , using the trigonometric identity

$$\cos^2 \boldsymbol{q}_r + \cos^2 \left( \boldsymbol{q}_r - \frac{2}{3} \boldsymbol{p} \right) + \cos^2 \left( \boldsymbol{q}_r + \frac{2}{3} \boldsymbol{p} \right) = \frac{3}{2},$$

one obtains

$$T_e = \frac{P \boldsymbol{y}_m}{2} \sqrt{2} i_M \left( \cos^2 \boldsymbol{q}_r + \cos^2 \left( \boldsymbol{q}_r - \frac{2}{3} \boldsymbol{p} \right) + \cos^2 \left( \boldsymbol{q}_r + \frac{2}{3} \boldsymbol{p} \right) \right) = \frac{3P \boldsymbol{y}_m}{2\sqrt{2}} i_M.$$

One concludes that to regulate the angular velocity,  $i_M$  must be changed. Furthermore, the phase currents  $i_{as}(t)$ ,  $i_{bs}(t)$  and  $i_{cs}(t)$ , which are shifted by  $\frac{2}{3}\mathbf{p}$ , are the functions of the electrical angular displacement  $\mathbf{q}_r$  (measured using the Hall sensors).

If the voltage-fed power converters are used, one changes the magnitude of voltages  $u_{as}(t)$ ,  $u_{bs}(t)$  and  $u_{cs}(t)$ . The angular displacement  $\mathbf{q}_r$  is needed to be measured (or estimated) in order to generate phase voltages.

In particular, the *abc* voltages needed to be supplied are

$$u_{as}(t) = \sqrt{2}u_M \cos(\mathbf{q}_r + \mathbf{j}_u),$$
  

$$u_{bs}(t) = \sqrt{2}u_M \cos(\mathbf{q}_r - \frac{2}{3}\mathbf{p} + \mathbf{j}_u),$$
  

$$u_{cs}(t) = \sqrt{2}u_M \cos(\mathbf{q}_r + \frac{2}{3}\mathbf{p} + \mathbf{j}_u).$$

Neglecting the circuitry transients (assuming that inductances are negligible small), we have

$$\begin{split} u_{as}(t) &= \sqrt{2} u_M \cos \mathbf{q}_r \,, \\ u_{bs}(t) &= \sqrt{2} u_M \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) , \\ u_{cs}(t) &= \sqrt{2} u_M \cos \left( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \right) . \end{split}$$

Using a set of nonlinear differential equations (3.5.6), the block diagram is developed and documented in Figure 3.5.5.


Figure 3.5.5. Block diagram of three-phase permanent-magnet synchronous motors controlled by supplying  $u_{as}(t) = \sqrt{2}u_M \cos q_r$ ,  $u_{bs}(t) = \sqrt{2}u_M \cos \left( \mathbf{q}_r - \frac{2}{3}\mathbf{p} \right), u_{cs}(t) = \sqrt{2}u_M \cos \left( \mathbf{q}_r + \frac{2}{3}\mathbf{p} \right).$ Here,  $T_s = \frac{r_s \left( 2L_{ss} - \overline{L}_m \right)}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2}$ 

The Lagrange Equations of Motion and Dynamics of Permanent-Magnet Synchronous Motors

Having derived the mathematical model for three-phase permanentmagnet synchronous motors using Kirchhoff's voltage law (to model the circuitry dynamics), Newtonian's mechanics (to model the *torsionalmechanical* dynamics), and the coenergy concept (to find the electromagnetic torque), let us attack the problem of model development using Lagrange's concept.

The generalized coordinates are the electric charges in the *abc* stator windings  $q_1 = \frac{i_{as}}{s}$ ,  $\dot{q}_1 = i_{as}$ ,  $q_2 = \frac{i_{bs}}{s}$ ,  $\dot{q}_2 = i_{bs}$ ,  $q_3 = \frac{i_{cs}}{s}$ ,  $\dot{q}_3 = i_{cs}$ , and the angular displacement  $q_4 = \mathbf{q}_r$ ,  $\dot{q}_4 = \mathbf{w}_r$ . The generalized forces are the applied voltages to the *abc* windings  $Q_1 = u_{as}$ ,  $Q_2 = u_{bs}$ ,  $Q_3 = u_{cs}$  and the load torque  $Q_4 = -T_L$ .

The resulting Lagrange equations are

$$\begin{split} &\frac{d}{dt} \bigotimes_{\mathbf{e}}^{\mathbf{e} \mathbf{f} \mathbf{f} \dot{\mathbf{G}}} \overset{\mathbf{o}}{\overset{\mathbf{o}}{\mathbf{o}}} - \frac{\mathbf{f} \mathbf{G}}{\mathbf{f} q_1} + \frac{\mathbf{f} D}{\mathbf{f} \dot{q}_1} + \frac{\mathbf{f} \mathbf{P}}{\mathbf{f} q_1} = Q_1, \\ &\frac{d}{dt} \bigotimes_{\mathbf{e}}^{\mathbf{e} \mathbf{f} \mathbf{f} \dot{\mathbf{G}}} \overset{\mathbf{o}}{\overset{\mathbf{o}}{\mathbf{o}}} - \frac{\mathbf{f} \mathbf{G}}{\mathbf{f} q_2} + \frac{\mathbf{f} D}{\mathbf{f} \dot{q}_2} + \frac{\mathbf{f} \mathbf{P}}{\mathbf{f} q_2} = Q_2, \\ &\frac{d}{dt} \bigotimes_{\mathbf{e}}^{\mathbf{e} \mathbf{f} \mathbf{f} \dot{\mathbf{G}}} \overset{\mathbf{o}}{\overset{\mathbf{o}}{\mathbf{o}}} - \frac{\mathbf{f} \mathbf{G}}{\mathbf{f} q_3} + \frac{\mathbf{f} D}{\mathbf{f} \dot{q}_3} + \frac{\mathbf{f} \mathbf{P}}{\mathbf{f} q_3} = Q_3, \\ &\frac{d}{dt} \bigotimes_{\mathbf{e}}^{\mathbf{e} \mathbf{f} \mathbf{f} \dot{\mathbf{G}}} \overset{\mathbf{o}}{\overset{\mathbf{o}}{\mathbf{o}}} - \frac{\mathbf{f} \mathbf{G}}{\mathbf{f} q_3} + \frac{\mathbf{f} D}{\mathbf{f} \dot{q}_3} + \frac{\mathbf{f} \mathbf{P}}{\mathbf{f} q_3} = Q_3, \\ &\frac{d}{dt} \bigotimes_{\mathbf{e}}^{\mathbf{e} \mathbf{f} \mathbf{f} \dot{\mathbf{G}}} \overset{\mathbf{o}}{\overset{\mathbf{o}}{\mathbf{o}}} - \frac{\mathbf{f} \mathbf{G}}{\mathbf{f} q_4} + \frac{\mathbf{f} D}{\mathbf{f} \dot{q}_4} + \frac{\mathbf{f} \mathbf{P}}{\mathbf{f} q_4} = Q_4. \end{split}$$

The total kinetic energy includes kinetic energies of electrical and mechanical systems. In particular,

$$G = G_E + G_M = \frac{1}{2} L_{asas} \dot{q}_1^2 + \frac{1}{2} (L_{asbs} + L_{bsas}) \dot{q}_1 \dot{q}_2 + \frac{1}{2} (L_{ascs} + L_{csas}) \dot{q}_1 \dot{q}_3 + \frac{1}{2} L_{bsbs} \dot{q}_2^2 + \frac{1}{2} (L_{bscs} + L_{csbs}) \dot{q}_2 \dot{q}_3 + \frac{1}{2} L_{cscs} \dot{q}_3^2 + \boldsymbol{y}_m \dot{q}_1 \sin q_4 + \boldsymbol{y}_m \dot{q}_2 \sin (q_4 - \frac{2}{3} \boldsymbol{p}) + \boldsymbol{y}_m \dot{q}_3 \sin (q_4 + \frac{2}{3} \boldsymbol{p}) + \frac{1}{2} J \dot{q}_4^2.$$
  
Then, we have

$$\frac{\P \mathbf{G}}{\P q_1} = 0,$$
  
$$\frac{\P \mathbf{G}}{\P \dot{q}_1} = L_{asas} \dot{q}_1 + \frac{1}{2} \left( L_{asbs} + L_{bsas} \right) \dot{q}_2 + \frac{1}{2} \left( L_{ascs} + L_{csas} \right) \dot{q}_3 + \mathbf{y}_m \sin q_4,$$

$$\frac{\pi \mathbf{G}}{\pi q_2} = 0,$$

$$\frac{\pi \mathbf{G}}{\pi q_2} = \frac{1}{2} (L_{asbs} + L_{bsas}) \dot{q}_1 + L_{bsbs} \dot{q}_2 + \frac{1}{2} (L_{bscs} + L_{csbs}) \dot{q}_3 + \mathbf{y}_m \sin(q_4 - \frac{2}{3}\mathbf{p}),$$

$$\frac{\pi \mathbf{G}}{\pi q_3} = 0,$$

$$\frac{\pi \mathbf{G}}{\pi q_3} = \frac{1}{2} (L_{ascs} + L_{csas}) \dot{q}_1 + \frac{1}{2} (L_{bscs} + L_{csbs}) \dot{q}_2 + L_{cscs} \dot{q}_3 + \mathbf{y}_m \sin(q_4 + \frac{2}{3}\mathbf{p}),$$

$$\frac{\pi \mathbf{G}}{\pi q_4} = \mathbf{y}_m \dot{q}_1 \cos q_4 + \mathbf{y}_m \dot{q}_2 \cos(q_4 - \frac{2}{3}\mathbf{p}) + \mathbf{y}_m \dot{q}_3 \cos(q_4 + \frac{2}{3}\mathbf{p}),$$

$$\frac{\pi \mathbf{G}}{\pi q_4} = J \dot{q}_4.$$

The total potential energy is P = 0.

The total dissipated energy is found as a sum of the heat energy dissipated by the electrical system and the heat energy dissipated by the mechanical system. That is,

$$D = \frac{1}{2} \left( r_s \dot{q}_1^2 + r_s \dot{q}_2^2 + r_s \dot{q}_3^2 + B_m \dot{q}_4^2 \right).$$

One obtains

$$\frac{\P D}{\P \dot{q}_1} = r_s \dot{q}_1, \quad \frac{\P D}{\P \dot{q}_2} = r_s \dot{q}_2, \quad \frac{\P D}{\P \dot{q}_3} = r_s \dot{q}_3 \text{ and } \quad \frac{\P D}{\P \dot{q}_4} = B_m \dot{q}_4.$$

Taking note of  $\dot{q}_1 = i_{as}$ ,  $\dot{q}_2 = i_{bs}$ ,  $\dot{q}_3 = i_{cs}$  and  $\dot{q}_4 = \mathbf{W}_r$ , the Lagrange equations lead us to four differential equations

$$\begin{aligned} L_{asas} \frac{di_{as}}{dt} + \frac{1}{2} (L_{asbs} + L_{bsas}) \frac{di_{bs}}{dt} + \frac{1}{2} (L_{ascs} + L_{csas}) \frac{di_{cs}}{dt} \\ + \mathbf{y}_m \mathbf{w}_r \cos \mathbf{q}_r + r_s i_{as} = u_{as}, \\ \frac{1}{2} (L_{asbs} + L_{bsas}) \frac{di_{as}}{dt} + L_{bsbs} \frac{di_{bs}}{dt} + \frac{1}{2} (L_{bscs} + L_{csbs}) \frac{di_{cs}}{dt} \\ + \mathbf{y}_m \mathbf{w}_r \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) + r_s i_{bs} = u_{bs}, \\ \frac{1}{2} (L_{ascs} + L_{csas}) \frac{di_{as}}{dt} + \frac{1}{2} (L_{bscs} + L_{csbs}) \frac{di_{bs}}{dt} + L_{cscs} \frac{di_{cs}}{dt} \\ + \mathbf{y}_m \mathbf{w}_r \cos \left( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \right) + r_s i_{cs} = u_{cs}, \\ J \frac{d^2 \mathbf{q}_r}{dt^2} - \mathbf{y}_m i_{as} \cos \mathbf{q}_r - \mathbf{y}_m i_{bs} \cos \left( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \right) - \mathbf{y}_m i_{cs} \cos \left( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \right) + B_m \frac{d\mathbf{q}_r}{dt} = -T_L \\ For round roter permanent magnet superpreservations. \end{aligned}$$

For round-rotor permanent-magnet synchronous motors, one obtains

$$\left(L_{ls} + \overline{L}_{m}\right) \frac{di_{as}}{dt} - \frac{1}{2} \overline{L}_{m} \frac{di_{bs}}{dt} - \frac{1}{2} \overline{L}_{m} \frac{di_{cs}}{dt} + \mathbf{y}_{m} \mathbf{w}_{r} \cos \mathbf{q}_{r} + r_{s} i_{as} = u_{as} ,$$

$$- \frac{1}{2} \overline{L}_{m} \frac{di_{as}}{dt} + \left(L_{ls} + \overline{L}_{m}\right) \frac{di_{bs}}{dt} - \frac{1}{2} \overline{L}_{m} \frac{di_{cs}}{dt} + \mathbf{y}_{m} \mathbf{w}_{r} \cos \left(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}\right) + r_{s} i_{bs} = u_{bs} ,$$

$$- \frac{1}{2} \overline{L}_{m} \frac{di_{as}}{dt} - \frac{1}{2} \overline{L}_{m} \frac{di_{bs}}{dt} + \left(L_{ls} + \overline{L}_{m}\right) \frac{di_{cs}}{dt} + \mathbf{y}_{m} \mathbf{w}_{r} \cos \left(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right) + r_{s} i_{cs} = u_{cs} ,$$

$$J \frac{d\mathbf{w}_{r}}{dt} + B_{m} \mathbf{w}_{r} - \mathbf{y}_{m} \left[i_{as} \cos \mathbf{q}_{r} + i_{bs} \cos \left(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}\right) + i_{cs} \cos \left(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}\right)\right] = -T_{L} ,$$

$$\frac{d\mathbf{q}_{r}}{dt} = \mathbf{w}_{r} .$$

From the fourth differential equation one finds that the electromagnetic torque as

$$T_e = \mathbf{y}_m \Big[ i_{as} \cos \mathbf{q}_r + i_{bs} \cos \Big( \mathbf{q}_r - \frac{2}{3} \mathbf{p} \Big) + i_{cs} \cos \Big( \mathbf{q}_r + \frac{2}{3} \mathbf{p} \Big) \Big].$$

Differential equations in Cauchy's form, as given by (3.5.6) for *P*-pole permanent-magnet synchronous motors, result. It was demonstrated that applying Lagrange's concept, a complete mathematical model for permanent-magnet synchronous motors was straightforwardly developed.

## Three-Phase Permanent-Magnet Synchronous Generators

For permanent-magnet synchronous generators, as shown in Figure 3.5.4, the mathematical model can be developed using Kirchhoff's second law

$$\mathbf{u}_{abcs} = -\mathbf{r}_{s}\mathbf{i}_{abcs} + \frac{d\mathbf{y}_{abcs}}{dt}, \quad \begin{pmatrix} \dot{\mathbf{e}}_{as}\dot{\mathbf{u}} & \dot{\mathbf{e}}_{s} & 0 & 0\dot{\mathbf{u}}\dot{\mathbf{e}}_{as}\dot{\mathbf{u}} & \dot{\mathbf{e}}_{as}\dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{dt}\dot{\mathbf{u}} & \dot{\mathbf{u}}_{s}\dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{bs}\dot{\mathbf{u}} & - \dot{\mathbf{e}}_{0} & r_{s} & 0\dot{\mathbf{u}}\dot{\mathbf{e}}_{as}\dot{\mathbf{u}} & \dot{\mathbf{e}}_{d}\mathbf{y}_{bs}\dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{dt}\dot{\mathbf{u}}_{s}\dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{dt}\dot{\mathbf{u}}_{cs}\dot{\mathbf{u}} & \dot{\mathbf{e}}_{0} & 0 & r_{s}\dot{\mathbf{u}}\dot{\mathbf{e}}_{cs}\dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{dt}\dot{\mathbf{u}} & \dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{dt}\dot{\mathbf{u}} & \dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{dt}\dot{\mathbf{u}}_{s}\dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{dt}\dot{\mathbf{u}} \\ \dot{\mathbf{u}} \\ \dot{$$

and Newton's second law of motion -  $T_e - B_m \mathbf{w}_{rm} + T_{pm} = J \frac{u \mathbf{q}_{rm}}{dt^2}$ , which

gives

$$\frac{d\boldsymbol{w}_{rm}}{dt} = \frac{1}{J} \left( - T_e - B_m \boldsymbol{w}_{rm} + T_{pm} \right), \ \frac{d\boldsymbol{q}_{rm}}{dt} = \boldsymbol{w}_{rm}.$$

The striking application of the results presented for the permanentmagnet synchronous motors results in the following set of differential equations

$$\begin{aligned} \frac{di_{as}}{dt} &= -\frac{r_{s}\left(2L_{ss}-\bar{L}_{m}\right)}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}i_{as} - \frac{r_{s}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}i_{bs} - \frac{r_{s}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}i_{cs} \\ &+ \frac{\mathbf{y}_{m}\left(2L_{ss}-\bar{L}_{m}\right)}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &+ \frac{\mathbf{y}_{m}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &- \frac{2L_{ss}-\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}u_{as} - \frac{\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}u_{bs} - \frac{\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}u_{cs}, \\ &\frac{di_{bs}}{dt} = -\frac{r_{s}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &+ \frac{\mathbf{y}_{m}\bar{L}_{m}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &+ \frac{\mathbf{y}_{m}^{2}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &- \frac{\bar{L}_{m}}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &- \frac{\bar{L}_{m}}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &- \frac{\bar{L}_{m}}}{2L_{ss}^{2}-L_{ss}\bar{L}_{m}-\bar{L}_{m}^{2}}\mathbf{w}_{r}\cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \\ &- \frac{\bar{L}_{m}}}{2L_{ss}^{2}-L_{ss}$$

In matrix form, from (3.5.7), we have the following mathematical model of three-phase permanent-magnet synchronous generators

$$\begin{array}{c} \underbrace{\acute{e}di_{as}}{\acute{e}di} \underbrace{\acute{u}}_{\acute{e}} \stackrel{\acute{e}}{\acute{e}} \frac{r_{s}\left(2L_{ss} - \overline{L}_{m}\right)}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & - \frac{r_{s}\overline{L}_{m}}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & - \frac{r_{s}\overline{L}_{m}}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & 0 & 0 \\ \underbrace{\acute{e}di}_{\acute{e}} \stackrel{\acute{u}}{\acute{u}} \stackrel{\acute{e}}{\acute{e}} \frac{i}{dt} \stackrel{\acute{u}}{\acute{u}} \stackrel{\acute{e}}{\acute{e}} \frac{r_{s}\overline{L}_{m}}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & - \frac{r_{s}(2L_{ss} - \overline{L}_{ss}\overline{L}_{m} - \overline{L}_{m}^{2})}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & - \frac{r_{s}\overline{L}_{m}}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & 0 & 0 \\ \underbrace{\acute{e}di}_{\acute{e}} \stackrel{\acute{u}}{\acute{u}} \stackrel{\acute{e}}{\acute{e}} \frac{r_{s}\overline{L}_{m}}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & - \frac{r_{s}\overline{L}_{m}}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & - \frac{r_{s}(2L_{ss} - \overline{L}_{m})}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & 0 & 0 \\ \underbrace{\acute{e}di}_{\acute{e}} \stackrel{\acute{u}}{\acute{u}} \stackrel{\acute{e}}{\acute{e}} \frac{r_{s}\overline{L}_{m}}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & - \frac{r_{s}\overline{L}_{m}}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & - \frac{r_{s}(2L_{ss} - \overline{L}_{m})}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} & 0 & 0 \\ \underbrace{\acute{e}di}_{\acute{e}} \stackrel{\acute{u}}{\acute{u}} \stackrel{\acute{u}}{\acute{e}} \frac{\acute{e}}{dt} \stackrel{\acute{u}}{\acute{u}} \stackrel{\acute{e}}{\acute{e}} \frac{i}{dt} \stackrel{\acute{u}}{\acute{u}} \stackrel{\acute{e}}{\acute{e}} \frac{i}{dt} \stackrel{\acute{u}}{\acute{u}} \stackrel{\acute{e}}{\acute{e}} \frac{i}{dt} \stackrel{\acute{u}}{\acute{e}} \frac{\acute{e}}{\acute{e}} 0 & 0 & 0 & - \frac{R_{m}}{2L_{ss}^{2} - L_{ss}\overline{L}_{m} - \overline{L}_{m}^{2}} \\ i \underbrace{\acute{e}} \stackrel{\acute{e}}{\acute{e}} \frac{\acute{e}}{\acute{e}} \frac{i}{\acute{e}} \stackrel{\acute{e}}{\acute{e}} \frac{\acute{e}}{\acute{e}} \frac{\acute{e}}$$

$$\begin{array}{c} \underbrace{ \stackrel{\bullet}{\hat{\mathbf{e}}} 2L_{ss} - \overline{L}_m}_{\hat{\mathbf{e}}} & \overline{L}_m - \overline{L}_m^2}_{\hat{\mathbf{e}}} & \overline{L}_{ss}\overline{L}_m - \overline{L}_m^2} & \frac{\overline{L}_m}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2}} & \frac{\overline{L}_m}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2} & \underbrace{\frac{\overline{L}_m}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2}}_{\hat{\mathbf{e}}_{ss}\overline{L}_m - \overline{L}_m^2} & \underbrace{\frac{\overline{L}_m}{2L_{ss}^2 - L_{ss}\overline{L}_m - \overline{L}_m^2}}_{\hat{\mathbf{e}}_{s}\overline{L}_m - \overline{L}_m^2} & \underbrace{\frac{\overline{L}_m}{2L_{s}^2 - L_{ss}\overline{L}_m - L_m^2}}_{\hat{\mathbf{e}}_{s}\overline{L}_m - \underline{L}_m^2} & \underbrace{\frac{\overline{L}_m}}{2L_{s}\overline{L}_m - L_m^2}}_{\hat{\mathbf{e}}_{s}\overline{L}_m - L_m^2} & \underbrace{\frac{\overline{L}_m$$

One concludes that nonlinear mathematical model of permanent-magnet synchronous generators is derived to be used in analysis, modeling, and control.

Mathematical Models of Permanent-Magnet Synchronous Machines in the Arbitrary, Rotor, and Synchronous Reference Frames

## Arbitrary Reference Frame

By fixing the reference frame with the rotor and making use of the *direct* Park transformations

$$\mathbf{u}_{qd0s} = \mathbf{K}_{s} \mathbf{u}_{abcs}, \ \mathbf{i}_{qd0s} = \mathbf{K}_{s} \mathbf{i}_{abcs}, \ \mathbf{y}_{qd0s} = \mathbf{K}_{s} \mathbf{y}_{abcs},$$

$$\begin{aligned} & \stackrel{\text{\acute{e}cos}\boldsymbol{q}}{\mathbf{K}_{s}} = \frac{2}{3} \frac{\hat{\mathbf{e}}}{\hat{\mathbf{e}}} \sin \boldsymbol{q} & \sin \left(\boldsymbol{q} - \frac{2}{3}\boldsymbol{p}\right) & \cos \left(\boldsymbol{q} + \frac{2}{3}\boldsymbol{p}\right) \hat{\mathbf{u}}, \\ & \stackrel{\text{\acute{e}cos}}{\mathbf{e}} \frac{1}{2} & \sin \left(\boldsymbol{q} - \frac{2}{3}\boldsymbol{p}\right) & \sin \left(\boldsymbol{q} + \frac{2}{3}\boldsymbol{p}\right) \hat{\mathbf{u}}, \\ & \stackrel{\text{\acute{e}cos}}{\mathbf{e}} \frac{1}{2} & \frac{1}{2} & \frac{1}{2} & \stackrel{\text{\acute{u}cos}}{\mathbf{u}} \end{aligned}$$

circuitry differential equation (3.5.1)  $\mathbf{u}_{abcs} = \mathbf{r}_s \mathbf{i}_{abcs} + \frac{d\mathbf{y}_{abcs}}{dt}$  is rewritten in the *qd*0 variables as

$$\mathbf{K}_{s}^{-1}\mathbf{u}_{qd0s} = \mathbf{r}_{s}\mathbf{K}_{s}^{-1}\mathbf{i}_{qd0s} + \frac{d\left(\mathbf{K}_{s}^{-1}\mathbf{y}_{qd0s}\right)}{dt},$$
  
$$\mathbf{K}_{s}^{-1} = \frac{\mathbf{\hat{e}}}{\mathbf{\hat{e}}}\cos(\mathbf{q} - \frac{2}{3}\mathbf{p}) \quad \sin(\mathbf{q} - \frac{2}{3}\mathbf{p}) \quad \mathbf{1}\mathbf{\hat{u}}.$$
  
$$\mathbf{\hat{e}}\cos(\mathbf{q} + \frac{2}{3}\mathbf{p}) \quad \sin(\mathbf{q} + \frac{2}{3}\mathbf{p}) \quad \mathbf{1}\mathbf{\hat{u}}.$$

Multiplying left and right sides by  $\mathbf{K}_{s}$ , one obtains

$$\mathbf{K}_{s}\mathbf{K}_{s}^{-1}\mathbf{u}_{qdos} = \mathbf{K}_{s}\mathbf{r}_{s}\mathbf{K}_{s}^{-1}\mathbf{i}_{qd0s} + \mathbf{K}_{s}\frac{d\mathbf{K}_{s}^{-1}}{dt}\mathbf{y}_{qd0s} + \mathbf{K}_{s}\mathbf{K}_{s}^{-1}\frac{d\mathbf{y}_{qd0s}}{dt}$$

The matrix  $\mathbf{r}_{s}$  is diagonal, and thus  $\mathbf{K}_{s}\mathbf{r}_{s}\mathbf{K}_{s}^{-1} = \mathbf{r}_{s}$ .

From 
$$\frac{d\mathbf{K}_{s}^{-1}}{dt} = \mathbf{w}_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} - \sin \mathbf{q} \qquad \cos \mathbf{q} \qquad 0\dot{\mathbf{u}} \\ \hat{\mathbf{e}}^{\hat{\mathbf{e}}} \sin(\mathbf{q} - \frac{2}{3}\mathbf{p}) \qquad \cos(\mathbf{q} - \frac{2}{3}\mathbf{p}) \qquad 0\dot{\mathbf{u}}^{\hat{\mathbf{u}}}, \text{ we have} \\ \hat{\mathbf{e}}^{\hat{\mathbf{e}}} \sin(\mathbf{q} + \frac{2}{3}\mathbf{p}) \qquad \cos(\mathbf{q} - \frac{2}{3}\mathbf{p}) \qquad 0\dot{\mathbf{u}}^{\hat{\mathbf{u}}} \\ \mathbf{K}_{s} \frac{d\mathbf{K}_{s}^{-1}}{dt} = \mathbf{w}_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} \qquad 1 \qquad 0 \qquad 0\dot{\mathbf{u}} \\ \hat{\mathbf{e}}^{\hat{\mathbf{e}}} 0 \qquad 0 \qquad 0\dot{\mathbf{u}} \\ \hat{\mathbf{e}}^{\hat{\mathbf{u}}} 0 \qquad 0 \qquad 0\dot{\mathbf{u}} \end{aligned}$$

Hence, (3.5.1) is rewritten in the qd0 variables as

$$\mathbf{u}_{qd\,0s} = \mathbf{r}_{s}\mathbf{i}_{qd\,0s} + \mathbf{w}_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} \mathbf{y}_{qs\,\hat{\mathbf{u}}}^{\hat{\mathbf{u}}} + \frac{d\mathbf{y}_{qd\,0s}}{dt}.$$

$$(3.5.8)$$

Using the Park transformation, the *quadrature-*, *direct-*, and *zero-*axis components of stator flux linkages are found as

$$\mathbf{y}_{qd0s} = \mathbf{K}_{s} \mathbf{y}_{abcs},$$

where

$$\mathbf{y}_{abcs} = \mathbf{L}_{s}\mathbf{i}_{abcs} + \mathbf{y}_{m} = \begin{pmatrix} \mathbf{\acute{e}}L_{ls} + \overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & \mathbf{\acute{u}}\mathbf{\acute{e}}_{as}\mathbf{\acute{u}} & \mathbf{\acute{e}}_{as}\mathbf{\acute{u}} & \mathbf{\acute{e}}_{as}\mathbf{\acute{u}} \\ \mathbf{\acute{e}} - \frac{1}{2}\overline{L}_{m} & L_{ls} + \overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & \mathbf{\acute{u}}\mathbf{\acute{e}}_{as}\mathbf{\acute{u}} + \mathbf{y}_{m}\mathbf{\acute{e}sin}(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p})\mathbf{\acute{u}} \\ \mathbf{\acute{e}} & \mathbf{\acute{e}} - \frac{1}{2}\overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & L_{ls} + \overline{L}_{m}\mathbf{\acute{u}}\mathbf{\acute{e}}_{as}\mathbf{\acute{u}} + \mathbf{y}_{m}\mathbf{\acute{e}sin}(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p})\mathbf{\acute{u}} \\ \mathbf{\acute{e}} & \mathbf{\acute{e}} + \frac{1}{2}\overline{L}_{m} & -\frac{1}{2}\overline{L}_{m} & L_{ls} + \overline{L}_{m}\mathbf{\acute{u}}\mathbf{\acute{e}}_{as}\mathbf{\acute{u}} + \mathbf{y}_{m}\mathbf{\acute{e}} \\ \mathbf{\acute{e}} & \mathbf{\acute{e}} + \mathbf{\acute$$

Hence,

$$\mathbf{y}_{qd0s} = \mathbf{K}_{s} \mathbf{L}_{s} \mathbf{K}_{s}^{-1} \mathbf{i}_{qd0s} + \mathbf{K}_{s} \mathbf{y}_{m}, \qquad (3.5.9)$$
where  $\mathbf{K}_{s} \mathbf{L}_{s} \mathbf{K}_{s}^{-1} = \stackrel{\acute{e}}{\overset{\acute{e}}{e}} 0 \qquad L_{ls} + \frac{3}{2} \overline{L}_{m} \qquad 0 \qquad \dot{\mathbf{u}}_{u};$ 
 $\stackrel{\acute{e}}{\overset{\acute{e}}{e}} 0 \qquad 0 \qquad L_{ls} \stackrel{\acute{u}}{\overset{\acute{u}}{u}}$ 

$$\mathbf{K}_{s} \mathbf{y}_{m} = \stackrel{2}{\overset{\acute{e}}{\overset{\acute{e}}{s}} \sin \mathbf{q}} \frac{\cos(\mathbf{q} - \frac{2}{3}\mathbf{p})}{\sin(\mathbf{q} - \frac{2}{3}\mathbf{p})} \stackrel{\cos(\mathbf{q} + \frac{2}{3}\mathbf{p})\stackrel{\acute{u}}{\overset{\acute{u}}{u}} \stackrel{\acute{e}}{\overset{\acute{e}}{s}} \sin \mathbf{q}, \qquad \dot{\mathbf{u}}_{u} \stackrel{\acute{e}}{\overset{\acute{e}}{s}} \sin(\mathbf{q} - \mathbf{q}_{r})\stackrel{\acute{u}}{\overset{\acute{u}}{u}}$$

$$\mathbf{K}_{s} \mathbf{y}_{m} = \stackrel{2}{\overset{\acute{e}}{\overset{\acute{e}}{s}} \sin \mathbf{q} \sin(\mathbf{q} - \frac{2}{3}\mathbf{p}) \quad \sin(\mathbf{q} + \frac{2}{3}\mathbf{p})\stackrel{\acute{u}}{\overset{\acute{u}}{u}} \stackrel{\acute{e}}{\overset{\acute{e}}{s}} \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p})\stackrel{\acute{u}}{\overset{\acute{u}}{u}} \stackrel{\acute{e}}{\overset{\acute{e}}{s}} \cos(\mathbf{q} - \mathbf{q}_{r})\stackrel{\acute{u}}{\overset{\acute{u}}{u}}$$

$$\stackrel{\acute{e}}{\overset{\acute{e}}{t}} \frac{1}{2} \qquad \stackrel{1}{2} \stackrel{\acute{u}}{\overset{\acute{u}}{\overset{\acute{e}}{s}} \sin(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p})\stackrel{\acute{u}}{\overset{\acute{u}}{u}} \stackrel{\acute{e}}{\overset{\acute{e}}{s}} 0 \quad \acute{u}$$

$$\qquad \mathbf{From} (3.5.9) \text{ we obtain}$$

$$\mathbf{y}_{qd0s} = \stackrel{\acute{e}}{\overset{\acute{e}}{e}} 0 \qquad L_{ls} + \frac{3}{2} \overline{L}_{m} \qquad 0 \stackrel{\acute{u}}{\overset{\acute{u}}{u}} \stackrel{\acute{e}}{\overset{\acute{e}}{s}} \sin(\mathbf{q} - \mathbf{q}_{r})\stackrel{\acute{u}}{\overset{\acute{u}}{u}}$$

$$\stackrel{\acute{e}}{\overset{\acute{e}}{s}} 0 \qquad 0 \qquad L_{ls} \stackrel{\acute{u}}{\overset{\acute{u}}{u}} \stackrel{\acute{e}}{\overset{\acute{e}}{s}} 0 \quad \acute{u}\stackrel{\acute{u}}{\overset{\acute{u}}{u}}$$

Using (3.5.8) one finds

$$\mathbf{u}_{qd0s} = \mathbf{r}_{s}\mathbf{i}_{qd0s} + \mathbf{w}_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} \mathbf{y}_{qs} \overset{\hat{\mathbf{u}}}{\underline{\mathbf{i}}} \overset{\hat{\mathbf{e}}L_{ls}}{\underline{\mathbf{e}}} + \frac{3}{2}\overline{L}_{m} \qquad 0 \qquad 0 \overset{\hat{\mathbf{u}}}{\underline{\mathbf{i}}} \overset{\hat{\mathbf{d}}}{\underline{\mathbf{i}}} = \mathbf{v}_{s}\mathbf{i}_{qd0s} + \mathbf{w}_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} \mathbf{y}_{qs} \overset{\hat{\mathbf{u}}}{\underline{\mathbf{i}}} + \overset{\hat{\mathbf{e}}}{\underline{\mathbf{e}}} \qquad 0 \qquad 0 \overset{\hat{\mathbf{u}}}{\underline{\mathbf{i}}} \overset{\hat{\mathbf{i}}}{\underline{\mathbf{i}}} = \mathbf{v}_{s}\mathbf{i}_{qd0s} + \mathbf{w}_{\hat{\mathbf{e}}}^{\hat{\mathbf{e}}} \mathbf{y}_{qs} \overset{\hat{\mathbf{u}}}{\underline{\mathbf{i}}} + \overset{\hat{\mathbf{e}}}{\underline{\mathbf{e}}} \qquad 0 \qquad 0 \overset{\hat{\mathbf{u}}}{\underline{\mathbf{i}}} \overset{\hat{\mathbf{i}}}{\underline{\mathbf{i}}} = \mathbf{v}_{s}\mathbf{i}_{qd0s} + \mathbf{v}_{m} \frac{\overset{\hat{\mathbf{e}}}{\underline{\mathbf{i}}} = \mathbf{v}_{s}\mathbf{i}_{qd0s} + \mathbf{v}_{s}\mathbf{i}_{qd0s} + \mathbf{v}_{m} \frac{\overset{\hat{\mathbf{e}}}{\underline{\mathbf{i}}} \overset{\hat{\mathbf{i}}}{\underline{\mathbf{i}}} = \mathbf{v}_{s}\mathbf{i}_{qd0s} + \mathbf{v}_{s}\mathbf{i}_$$

Three differential equations which model the permanent-magnet circuitry dynamics in the *arbitrary* reference frame are found as

$$\mathbf{u}_{qd0s} = \mathbf{r}_{s}\mathbf{i}_{qd0s} + \mathbf{w}_{\mathbf{\hat{e}}}^{\mathbf{\hat{e}}} \mathbf{y}_{qs} \overset{\mathbf{\hat{u}}}{\mathbf{\hat{u}}} + \overset{\mathbf{\hat{e}}}{\mathbf{\hat{e}}} \mathbf{0} \qquad L_{ls} + \frac{3}{2}\overline{L}_{m} \qquad \mathbf{0} \qquad \overset{\mathbf{\hat{u}}}{\mathbf{\hat{u}}} \overset{\mathbf{\hat{d}}}{\mathbf{\hat{a}}}_{qd0s} \\ \overset{\mathbf{\hat{e}}}{\mathbf{\hat{e}}} \mathbf{0} \qquad \overset{\mathbf{\hat{u}}}{\mathbf{\hat{e}}} \overset{\mathbf{\hat{e}}}{\mathbf{0}} \qquad \mathbf{0} \qquad L_{ls} + \frac{3}{2}\overline{L}_{m} \qquad \overset{\mathbf{\hat{u}}}{\mathbf{\hat{u}}} \overset{\mathbf{\hat{d}}}{\mathbf{\hat{d}}}_{dt} \\ \overset{\mathbf{\hat{e}}}{\mathbf{\hat{e}}} \cos(\mathbf{q} - \mathbf{q}_{r}) \overset{\mathbf{\hat{u}}}{\mathbf{\hat{u}}} \\ \overset{\mathbf{\hat{e}}}{\mathbf{\hat{e}}} \cos(\mathbf{q} - \mathbf{q}_{r}) \overset{\mathbf{\hat{u}}}{\mathbf{\hat{u}}} \\ + \mathbf{y}_{m} \frac{\overset{\mathbf{\hat{e}}}{\mathbf{\hat{e}}} \mathbf{0} \qquad \overset{\mathbf{\hat{u}}}{\mathbf{d}t} . \end{cases}$$

# Rotor Reference Frame

The electrical angular velocity is equal to the synchronous angular velocity. We assign the angular velocity of the reference frame to be  $\mathbf{w} = \mathbf{w}_r = \mathbf{w}_e$ . Then, taking note of  $\mathbf{q} = \mathbf{q}_r$ , we have the Park transformation matrix

$$\mathbf{K}_{s}^{r} = \frac{2}{3} \frac{\mathbf{\hat{e}}}{\mathbf{\hat{e}}} \sin \mathbf{q}_{r} \quad \cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \quad \cos(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \dot{\mathbf{\hat{u}}}$$
$$\frac{\mathbf{\hat{e}}}{\mathbf{\hat{e}}} \sin \mathbf{q}_{r} \quad \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \quad \sin(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \dot{\mathbf{\hat{u}}}.$$
$$\frac{\mathbf{\hat{e}}}{\mathbf{\hat{e}}} \quad \frac{1}{2} \qquad \frac{1}{2} \qquad \frac{1}{2} \qquad \mathbf{\hat{u}}$$

One finds

$$\mathbf{K}_{s}^{r}\mathbf{y}_{m} = \frac{2}{3} \frac{\hat{\mathbf{e}}}{\hat{\mathbf{e}}} \sin \mathbf{q}_{r} \quad \cos(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \quad \cos(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \overset{\mathbf{i}}{\mathbf{U}} \quad \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} \quad \sin \mathbf{q}_{r} \quad \overset{\mathbf{i}}{\mathbf{U}} \quad \overset{\mathbf{\acute{e}}}{\mathbf{0}} \overset{\mathbf{i}}{\mathbf{U}} \\ \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} \sin \mathbf{q}_{r} \quad \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \quad \sin(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \overset{\mathbf{i}}{\mathbf{U}} \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} \sin(\mathbf{q}_{r} - \frac{2}{3}\mathbf{p}) \overset{\mathbf{i}}{\mathbf{U}} = \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} \mathbf{y}_{m} \overset{\mathbf{\acute{u}}}{\mathbf{U}} \\ \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} \quad \frac{1}{2} \qquad \frac{1}{2} \qquad \frac{1}{2} \qquad \overset{\mathbf{\acute{U}}}{\mathbf{U}} \quad \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} \sin(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \overset{\mathbf{\acute{U}}}{\mathbf{U}} \quad \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} 0 \quad \overset{\mathbf{\acute{U}}}{\mathbf{U}} \\ \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} \sin(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \overset{\mathbf{\acute{U}}}{\mathbf{U}} \quad \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} 0 \quad \overset{\mathbf{\acute{U}}}{\mathbf{U}} \\ \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} 0 \quad \overset{\mathbf{\acute{U}}}{\mathbf{U}} \quad \overset{\mathbf{\acute{e}}}{\hat{\mathbf{e}}} 0 \quad \overset{\mathbf{\acute{U}}}{\mathbf{U}} \\ \overset{\mathbf{\acute{E}}}{\hat{\mathbf{e}}} \sin(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \overset{\mathbf{\acute{U}}}{\mathbf{U}} \quad \overset{\mathbf{\acute{E}}}{\hat{\mathbf{e}}} 0 \quad \overset{\mathbf{\acute{U}}}{\mathbf{U}} \\ \overset{\mathbf{\acute{E}}}{\hat{\mathbf{e}}} 0 \quad \overset{\mathbf{\acute{U}}}{\mathbf{U}} \\ \overset{\mathbf{\acute{E}}}{\hat{\mathbf{E}}} \sin(\mathbf{q}_{r} + \frac{2}{3}\mathbf{p}) \overset{\mathbf{\acute{U}}}{\mathbf{U}} \quad \overset{\mathbf{\acute{E}}}{\hat{\mathbf{e}}} 0 \quad \overset{\mathbf{\acute{U}}}{\mathbf{U}} \\ \overset{\mathbf{\acute{E}}}{\hat{\mathbf{E}}} 0 \quad \overset{\mathbf{\acute{U}}}{\mathbf{U}} \\ \overset{\mathbf{\acute{E}}}{\hat{\mathbf{E}}} 0 \quad \overset{\mathbf{\acute{E}}}{\mathbf{U}} \\ \overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}} \quad \overset{\mathbf{\acute{E}}}{\hat{\mathbf{E}}} 0 \quad \overset{\mathbf{\acute{U}}}{\mathbf{U}} \\ \overset{\mathbf{\acute{E}}}{\hat{\mathbf{E}}} 0 \quad \overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}} \\ \overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}} \end{aligned}{\overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}} \\ \overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}} \end{aligned}{\overset{\mathbf{\acute{E}}}}{\hat{\mathbf{U}}} \end{aligned}{\overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}} \end{aligned}{\overset{\mathbf{\acute{E}}}}{\hat{\mathbf{U}}} \end{aligned}{\overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}} \end{aligned}{\overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}}} \end{aligned}{\overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}}$$
 
$$\overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}} \end{aligned}{\overset{\mathbf{\acute{E}}}{\hat{\mathbf{U}}}$$

From (3.5.9) we have

$$\mathbf{y}_{qd\,0s}^{r} = \stackrel{\text{\acute{e}L}_{ls}}{\stackrel{\textbf{\acute{e}}}}}}}}}}}}}}}}}}}}}}}{ \mathbf{\acute{e}}} \mathbf{\acute{e}}$$
}

In expanded form, the quadrature, direct, and zero flux linkages are found to be

$$\mathbf{y}_{qs}^{r} = \left(L_{ls} + \frac{3}{2}\,\overline{L}_{m}\right)i_{qs}^{r}, \\\mathbf{y}_{ds}^{r} = \left(L_{ls} + \frac{3}{2}\,\overline{L}_{m}\right)i_{ds}^{r} + \mathbf{y}_{m}, \\\mathbf{y}_{0s}^{r} = L_{ls}i_{0s}^{r}. \\ \text{In the rotor reference frame using (3.5.8), one finds} \\ \frac{di_{qs}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}i_{qs}^{r} - \frac{\mathbf{y}_{m}}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}\mathbf{w}_{r} - i_{ds}^{r}\mathbf{w}_{r} + \frac{1}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}u_{qs}^{r}, \\ \frac{di_{ds}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}i_{ds}^{r} + i_{qs}^{r}\mathbf{w}_{r} + \frac{1}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}u_{ds}^{r}, \\ \frac{di_{0s}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}i_{ds}^{r} + i_{qs}^{r}\mathbf{w}_{r} + \frac{1}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}u_{ds}^{r}, \\ (3.5.10)$$

The electromagnetic torque

$$T_e = \frac{P \boldsymbol{y}_m}{2} \left[ i_{as} \cos \boldsymbol{q}_r + i_{bs} \cos \left( \boldsymbol{q}_r - \frac{2}{3} \boldsymbol{p} \right) + i_{cs} \cos \left( \boldsymbol{q}_r + \frac{2}{3} \boldsymbol{p} \right) \right]$$

should be found in terms of the quadrature, direct and zero currents. Using the Park transformation

$$\begin{aligned} & \stackrel{\text{\'e}}{\text{e}}_{s} \stackrel{\text{\'u}}{\text{u}} \stackrel{\text{\'e}}{\text{e}}_{c} \cos(\boldsymbol{q}_{r} - \frac{2}{3}\boldsymbol{p}) & \sin(\boldsymbol{q}_{r} - \frac{2}{3}\boldsymbol{p}) & 1 \stackrel{\text{\'u} \stackrel{\text{\'e}}{\text{u}}_{qs} \stackrel{\text{\'u}}{\text{u}}_{u} \stackrel{\text{\'e}}{\text{e}}_{r} \stackrel{\text{\'u}}{\text{u}}_{u} \stackrel{\text{\'e}}{\text{e}}_{r} \stackrel{\text{\'u}}{\text{u}}_{u} \stackrel{\text{\'e}}{\text{e}}_{r} \stackrel{\text{\'u}}{\text{u}}_{u} \stackrel{\text{\'e}}{\text{e}}_{r} \stackrel{\text{\'u}}{\text{u}}_{u} \stackrel{\text{\'e}}{\text{e}}_{r} \stackrel{\text{\'u}}{\text{u}} , \\ & \stackrel{\text{\'e}}{\text{\'e}}_{cs} \stackrel{\text{\'u}}{\text{u}} \stackrel{\text{\'e}}{\text{e}} \cos(\boldsymbol{q}_{r} + \frac{2}{3}\boldsymbol{p}) & \sin(\boldsymbol{q}_{r} - \frac{2}{3}\boldsymbol{p}) & 1 \stackrel{\text{\'u} \stackrel{\text{\'e}}{\text{u}}_{u} \stackrel{\text{\'u}}{\text{u}}_{0s} \stackrel{\text{`u}}{\text{u}} \\ & \stackrel{\text{\'e}}{\text{e}} \cos(\boldsymbol{q}_{r} + \frac{2}{3}\boldsymbol{p}) & \sin(\boldsymbol{q}_{r} + \frac{2}{3}\boldsymbol{p}) & 1 \stackrel{\text{\'u} \stackrel{\text{\'e}}{\text{u}}_{0s} \stackrel{\text{`u}}{\text{u}} \end{aligned}$$

and substituting

$$i_{as} = \cos q_{r} i_{qs}^{r} + \sin q_{r} i_{ds}^{r} + i_{0s}^{r},$$
  

$$i_{bs} = \cos (q_{r} - \frac{2}{3}p) i_{qs}^{r} + \sin (q_{r} - \frac{2}{3}p) i_{ds}^{r} + i_{0s}^{r},$$
  

$$i_{cs} = \cos (q_{r} + \frac{2}{3}p) i_{qs}^{r} + \sin (q_{r} + \frac{2}{3}p) i_{ds}^{r} + i_{0s}^{r}$$

in the expression for  $T_e$ , one finds

$$T_e = \frac{3P y_m}{4} i_{qs}^r.$$

For *P*-pole permanent-magnet synchronous motors, the *torsional-mechanical* dynamics is

$$\frac{d\boldsymbol{w}_r}{dt} = \frac{3P^2\boldsymbol{y}_m}{8J}i_{qs}^r - \frac{B_m}{J}\boldsymbol{w}_r - \frac{P}{2J}T_L,$$

$$\frac{d\boldsymbol{q}_r}{dt} = \boldsymbol{w}_r.$$
(3.5.11)

Augmenting differential equations (3.5.10) and (3.5.11), we have

$$\frac{di_{qs}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}i_{qs}^{r} - \frac{\mathbf{y}_{m}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}\mathbf{w}_{r} - i_{ds}^{r}\mathbf{w}_{r} + \frac{1}{L_{ls} + \frac{3}{2}\overline{L}_{m}}u_{qs}^{r}, 
\frac{di_{ds}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}i_{ds}^{r} + i_{qs}^{r}\mathbf{w}_{r} + \frac{1}{L_{ls} + \frac{3}{2}\overline{L}_{m}}u_{ds}^{r}, 
\frac{di_{0s}^{r}}{dt} = -\frac{r_{s}}{L_{ls}}i_{0s}^{r} + \frac{1}{L_{ls}}u_{0s}^{r}, 
\frac{d\mathbf{w}_{r}}{dt} = \frac{3P^{2}\mathbf{y}_{m}}{8J}i_{qs}^{r} - \frac{B_{m}}{J}\mathbf{w}_{r} - \frac{P}{2J}T_{L}, 
\frac{d\mathbf{q}_{r}}{dt} = \mathbf{w}_{r}.$$
(3.5.12)

In matrix form, the mathematical model of permanent-magnet synchronous motors in the rotor reference frame is

$$\begin{array}{c} \stackrel{e}{\Theta} \frac{di}{q_s} \stackrel{r}{u} \stackrel{v}{u} \stackrel{e}{\Theta} \frac{r_s}{L_{ls} + \frac{3}{2}\overline{L_m}} & 0 & 0 & - \frac{y_m}{L_{ls} + \frac{3}{2}\overline{L_m}} & 0 \stackrel{v}{u} \stackrel{v}{e} \stackrel{v}{q_s} \stackrel{v}{u} \stackrel{v}{\Theta} \stackrel{v}{e} \stackrel{v}{dt} \stackrel{v}{u} \stackrel{e}{\Theta} \stackrel{v}{\theta} \stackrel{v}{dt} \stackrel{v}{u} \stackrel{e}{\Theta} \stackrel{o}{\Theta} \stackrel{o}{\theta} \stackrel{- \frac{r_s}{L_{ls} + \frac{3}{2}\overline{L_m}}} & 0 & 0 & 0 \stackrel{v}{u} \stackrel{v}{e} \stackrel{v}{dt} \stackrel{v}{u} \stackrel{v}{\Theta} \stackrel{e}{\Theta} \stackrel{o}{\theta} \stackrel{o}{dt} \stackrel{v}{u} \stackrel{e}{\Theta} \stackrel{o}{\Theta} \stackrel{o}{\theta} \stackrel{o}{\theta} \stackrel{o}{dt} \stackrel{v}{u} \stackrel{v}{e} \stackrel{e}{\Theta} \stackrel{o}{\theta} \stackrel{o}{\theta} \stackrel{o}{dt} \stackrel{v}{u} \stackrel{v}{e} \stackrel{e}{\Theta} \stackrel{o}{\theta} \stackrel{o}{\theta} \stackrel{o}{\theta} \stackrel{o}{dt} \stackrel{v}{u} \stackrel{e}{\Theta} \stackrel{o}{\Theta} \stackrel{o}$$

A balanced three-phase current set, to be fed to the stator windings, is

$$\begin{split} i_{as}(t) &= \sqrt{2}i_M \cos \boldsymbol{q}_r, \\ i_{bs}(t) &= \sqrt{2}i_M \cos \left( \boldsymbol{q}_r - \frac{2}{3}\boldsymbol{p} \right), \\ i_{cs}(t) &= \sqrt{2}i_M \cos \left( \boldsymbol{q}_r + \frac{2}{3}\boldsymbol{p} \right). \end{split}$$

Using the *direct* Park transformation

$$\begin{array}{c} \underbrace{\mathbf{\acute{e}}_{qs}^{r}}_{\mathbf{\acute{e}}_{qs}} \underbrace{\mathbf{\acute{u}}}_{\mathbf{\acute{e}}_{qs}} \underbrace{\mathbf{\acute{e}}_{cs}}_{\mathbf{\acute{e}}_{s}r} \underbrace{\mathbf{\acute{u}}}_{\mathbf{\acute{e}}_{qs}} \underbrace{\mathbf{\acute{e}}_{cs}}_{\mathbf{\acute{e}}_{s}r} \underbrace{\mathbf{\acute{e}}_{cs}}_{\mathbf{\acute{e}}_{s}} \underbrace{\mathbf{\acute{e}}_{cs}}_{\mathbf{\acute{e}}_{s}} \underbrace{\mathbf{\acute{e}}_{cs}} \underbrace{\mathbf{\acute{e}}_{cs}}_{\mathbf{\acute{e}}_{s}} \underbrace{\mathbf{\acute{e}}_{cs}} \underbrace{\mathbf{\acute{e}}}_{cs} \underbrace{\mathbf{\acute{e}}}_{cs} \underbrace{\mathbf{\acute{e}}}_{cs} \underbrace{\mathbf{\acute{e}}}_{cs$$

one obtains the *quadrature*, *direct* and *zero* currents to regulate the angular velocity of permanent-magnet synchronous motors and guarantee the balanced operating conditions. We have

$$\begin{array}{cccc} & \left( \dot{\mathbf{q}}_{gs}^{r} \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{\overset{\mathbf{\dot{e}}}{gs}}}, & \left( \cos \mathbf{q}_{r} & \cos \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) & \left( \cos \left( \mathbf{q}_{r} + \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{\overset{\mathbf{\dot{e}}}{us}}} & \sqrt{2} i_{M} \cos \mathbf{q}_{r} & \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{u}}}{us}} \\ & \left( \dot{\mathbf{q}}_{s}^{r} \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}}, & \left( \sin \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) & \left( \sin \left( \mathbf{q}_{r} + \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{\overset{\mathbf{\dot{e}}}{us}}} & \left( \cos \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \\ & \left( \dot{\mathbf{\dot{e}}} \right) & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \dot{\mathbf{\dot{e}}} \right) & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{\overset{\mathbf{\dot{e}}}{us}} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \overset{\mathbf{\dot{u}}}{us} \right) \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{us} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \overset{\mathbf{\dot{u}}}{us} \right) \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \overset{\mathbf{\dot{u}}}{us} \right) \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{us} \\ & \left( \sin \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) \overset{\mathbf{\dot{u}}}{us} \right) \\ & \left( \sin \left( \mathbf{q}_{r$$

Hence, one obtains

$$i_{qs}^{r}(t) = \sqrt{2}i_{M}, \ i_{ds}^{r}(t) = 0, \ i_{0s}^{r}(t) = 0.$$

Due to the self-inductances, the *abc* voltages should be supplied with advanced phase shifting. One supplies the following phase voltages

$$u_{as}(t) = \sqrt{2}u_M \cos(\mathbf{q}_r + \mathbf{j}_u), \ u_{bs}(t) = \sqrt{2}u_M \cos(\mathbf{q}_r - \frac{2}{3}\mathbf{p} + \mathbf{j}_u),$$
$$u_{cs}(t) = \sqrt{2}u_M \cos(\mathbf{q}_r + \frac{2}{3}\mathbf{p} + \mathbf{j}_u).$$

Taking note of the direct Park transformation

$$\begin{array}{c} \stackrel{\bullet}{\mathbf{u}}_{qs} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{e}} \left( \cos \mathbf{q}_{r} - \cos \left( \mathbf{q}_{r} - \frac{2}{3} \mathbf{p} \right) \right) & \cos \left( \mathbf{q}_{r} + \frac{2}{3} \mathbf{p} \right) \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}}_{as} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u$$

one finds

$$\begin{array}{cccc} \dot{\mathbf{e}}_{d_{qs}}^{r} \dot{\mathbf{u}} & \dot{\mathbf{e}}_{\cos}^{r} \mathbf{q}_{r} & \cos\left(\mathbf{q}_{r}-\frac{2}{3}\mathbf{p}\right) & \cos\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \dot{\mathbf{u}} \dot{\mathbf{e}} & \sqrt{2}u_{M}\cos\left(\mathbf{q}_{r}+\mathbf{j}_{u}\right) & \dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{d_{ds}}^{r} \dot{\mathbf{u}} & = \frac{2}{3} \dot{\mathbf{e}}_{\sin}^{r} \mathbf{q}_{r} & \sin\left(\mathbf{q}_{r}-\frac{2}{3}\mathbf{p}\right) & \sin\left(\mathbf{q}_{r}+\frac{2}{3}\mathbf{p}\right) \dot{\mathbf{u}} \dot{\mathbf{e}} & \sqrt{2}u_{M}\cos\left(\mathbf{q}_{r}-\frac{2}{3}\mathbf{p}+\mathbf{j}_{u}\right) \dot{\mathbf{u}} \\ \dot{\mathbf{e}}_{d_{0s}}^{r} \dot{\mathbf{u}} & \dot{\mathbf{e}} & \frac{1}{2} & \frac{1}{2$$

Using the trigonometric identities, we have

$$u_{qs}^{r}(t) = \sqrt{2}u_{M} \cos \mathbf{j}_{u}, \ u_{ds}^{r}(t) = -\sqrt{2}u_{M} \sin \mathbf{j}_{u}, \ u_{0s}^{r}(t) = 0.$$

Due to small inductances,  $\mathbf{j}_u \ge 0$ , and the following phase voltages can be supplied

$$u_{qs}^{r}(t) = \sqrt{2}u_{M}, \ u_{ds}^{r}(t) = 0, \ u_{0s}^{r}(t) = 0.$$

To visualize the results, an *s*-domain block diagram in the qd0 variables is developed using (3.5.12), see Figure 3.5.6.



Figure 3.5.6. *S*-domain block diagram of permanent-magnet synchronous motors modeled in the rotor reference frame

Analyzing permanent-magnet synchronous machines in the synchronous reference frame, one specifies the angular velocity of the reference frame to be  $\mathbf{w} = \mathbf{w}_e$ . Hence,  $\mathbf{q} = \mathbf{q}_e$ , and the Park transformation matrix is given as

$$\begin{aligned} & \stackrel{\text{\acute{e}cos}}{\mathbf{e}} \mathbf{q}_{e} & \cos(\mathbf{q}_{e} - \frac{2}{3}\mathbf{p}) & \cos(\mathbf{q}_{e} + \frac{2}{3}\mathbf{p})\dot{\mathbf{u}} \\ & \stackrel{\text{\acute{e}cos}}{\mathbf{e}} \sin \mathbf{q}_{e} & \sin(\mathbf{q}_{e} - \frac{2}{3}\mathbf{p}) & \sin(\mathbf{q}_{e} + \frac{2}{3}\mathbf{p})\dot{\mathbf{u}} \\ & \stackrel{\text{\acute{e}cos}}{\mathbf{e}} \frac{1}{2} & \frac{1}{2} & \frac{1}{2} & \dot{\mathbf{u}} \end{aligned}$$

Substituting  $\mathbf{w}_r = \mathbf{w}_e$  in (3.5.12) we have the following system of differential equations which model the permanent-magnet motor dynamics in the synchronous reference frame

$$\begin{split} \frac{di_{qs}^{e}}{dt} &= -\frac{r_{s}}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}i_{qs}^{e} - \frac{\boldsymbol{\mathcal{Y}}_{m}}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}\boldsymbol{w}_{r} - i_{ds}^{e}\boldsymbol{w}_{r} + \frac{1}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}u_{qs}^{e},\\ \frac{di_{ds}^{e}}{dt} &= -\frac{r_{s}}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}i_{ds}^{e} + i_{qs}^{e}\boldsymbol{w}_{r} + \frac{1}{L_{ls} + \frac{3}{2}\,\overline{L}_{m}}u_{ds}^{e},\\ \frac{di_{0s}^{e}}{dt} &= -\frac{r_{s}}{L_{ls}}i_{0s}^{e} + \frac{1}{L_{ls}}u_{0s}^{e},\\ \frac{d\boldsymbol{w}_{r}}{dt} &= \frac{3P^{2}\boldsymbol{\mathcal{Y}}_{m}}{8J}i_{qs}^{e} - \frac{B_{m}}{J}\boldsymbol{w}_{r} - \frac{P}{2J}T_{L},\\ \frac{d\boldsymbol{q}_{r}}{dt} &= \boldsymbol{w}_{r}\,. \end{split}$$

The *quadrature, direct,* and *zero* currents, needed to be fed to guarantee the balanced operation, are

$$\begin{split} i^{e}_{qs}(t) &= \sqrt{2} i_{M} , \\ i^{e}_{ds}(t) &= 0 , \\ i^{e}_{0s}(t) &= 0 . \end{split}$$

1.0

To control the angular velocity (in the drive application) of permanentmagnet synchronous motors or the displacement (in servo-system application), one supplies the phase voltages to the *abc* stator windings as a function of the angular displacement (measured by the Hall-effect sensors). Correspondingly, ICs must is used, and the permanent-magnet synchronous motors driver MC33035 is manufactured by Motorola, see the data, description, and operation given below.

# Monolithic ICs: Permanent-Magnet Synchronous Motors Driver MC33035

(Copyright of Motorola, used with permission)



## Representative Schematic Diagram



This device contains 285 active transistors.

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	VCC	40	V
Digital Inputs (Pins 3, 4, 5, 6, 22, 23)	_	Vref	V
Oscillator Input Current (Source or Sink)	losc	30	mA
Error Amp Input Voltage Range	VIR	-0.3 to Vref	V
(Pins 11, 12, Note 1)			
Error Amp Output Current	lout	10	mA
(Source or Sink, Note 2)			
Current Sense Input Voltage Range (Pins 9, 15)	V <sub>Sense</sub>	-0.3 to 5.0	V
Fault Output Voltage	VCE(Fault)	20	V
Fault Output Sink Current	Sink(Fault)	20	mA
Top Drive Voltage (Pins 1, 2, 24)	V <sub>CE(top)</sub>	40	V
Top Drive Sink Current (Pins 1, 2, 24)	ISink(top)	50	mA
Bottom Drive Supply Voltage (Pin 18)	VC	30	V
Bottom Drive Output Current	IDRV	100	mA
(Source or Sink, Pins 19, 20, 21)			
Power Dissipation and Thermal Characteristics			
P Suffix, Dual In Line, Case 724		007	
Maximum Power Dissipation @ T <sub>A</sub> = 85°C	PD	867	°C/W
Thermal Resistance, Junction-to-Air	Ч	75	0/11
DW Suffix, Surface Mount, Case 751 E	PD	650	mW
Maximum Power Dissipation @ TA = 85°C	R <sub>0JA</sub>	100	°C/W
Thermal Resistance, Junction-to-Air			
Operating Junction Temperature	ТJ	150	°C
Operating Ambient Temperature Range	TA	-40 to +85	°C
Storage Temperature Range	Tstg	-65 to +150	°C

ELECTRICAL CHARACTERISTICS (V<sub>CC</sub> = V<sub>C</sub> = 20 V,  $R_T$  = 4.7 k,  $C_T$  = 10 nF,  $T_A$  = 25°C, unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
REFERENCE SECTION					
Reference Output Voltage (Iref = 1.0 mA)	Vref				V
$T_A = 25^{\circ}C$		5.9	6.24	6.5	
$T_A = -40^{\circ}C$ to $+85^{\circ}C$		5.82	-	6.57	
Line Regulation (V <sub>CC</sub> = 10 to 30 V, $I_{ref}$ = 1.0 mA)	Regline	_	1.5	30	mV
Load Regulation (Iref = 1.0 to 20 mA)	Regload	_	16	30	mV
Output Short Circuit Current (Note 3)	ISC	40	75	-	mA
Reference Under Voltage Lockout Threshold	V <sub>th</sub>	4.0	4.5	5.0	V
ERROR AMPLIFIER					
Input Offset Voltage ( $T_A = -40^{\circ} \text{ to } +85^{\circ}\text{C}$ )	VIO	—	0.4	10	mV
Input Offset Current ( $T_A = -40^{\circ} \text{ to } +85^{\circ}\text{C}$ )	١O	_	8.0	500	nA
Input Bias Current ( $T_A = -40^\circ$ to $+85^\circ$ C)	Ι <sub>IB</sub>	-	-46	-1000	nA
Input Common Mode Voltage Range	VICR		(0 V to Vref)		V
Open Loop Voltage Gain (VO = 3.0 V, RL = 15 k)	AVOL	70	80	_	dB
Input Common Mode Rejection Ratio	CMRR	55	86	_	dB
Power Supply Rejection Ratio ( $V_{CC} = V_C = 10$ to 30 V)	PSRR	65	105	-	dB

NOTES: 1. The input common mode voltage or input signal voltage should not be allowed to go negative by more than 0.3 V. 2. The compliance voltage must not exceed the range of –0.3 to V<sub>ref</sub>. 3. Maximum package power dissipation limits must be observed.

ELECTRICAL CHARACTERISTICS (continued) (V <sub>CC</sub> =	= V <sub>C</sub> = 20 V, R <sub>T</sub>	= 4.7 k, C <sub>T</sub> = 10	0 nF, T <sub>A</sub> = 25°C,	unless otherwis	e noted.)
Characteristic	Symbol	Min	Тур	Max	Unit
ERROR AMPLIFIER					
Output Voltage Swing					V
High State ( $R_L = 15$ k to Gnd)	VOH	4.6	5.3	-	
Low State (RL = 15 k to Vref)	VOL	-	0.5	1.0	
OSCILLATOR SECTION					
Oscillator Frequency	fosc	22	25	28	kHz
Frequency Change with Voltage (V <sub>CC</sub> = 10 to 30 V)	∆fOSC/∆V	-	0.01	5.0	%
Sawtooth Peak Voltage	VOSC(P)	—	4.1	4.5	V
Sawtooth Valley Voltage	VOSC(V)	1.2	1.5		V
LOGIC INPUTS					
Input Threshold Voltage (Pins 3, 4, 5, 6, 7, 22, 23)					V
High State	VIH	3.0	2.2	_	
Low State	VIL	-	1.7	0.8	
Sensor Inputs (Pins 4, 5, 6)					μA
High State Input Current (VIH = 5.0 V)	Чн	-150	-70	-20	
Low State Input Current (VIL = 0 V)	μL	-600	-337	-150	
Forward/Reverse, 60°/120° Select (Pins 3, 22, 23)					uА
High State Input Current (VIH = 5.0 V)	ЦН	-75	-36	-10	r
Low State Input Current (VIL = 0 V)	1 III	-300	-175	-75	
Output Enable					μA
High State Input Current (VIH = 5.0 V)	ЧΗ	-60	-29	-10	r.
Low State Input Current (VIL = 0 V)	ΙL	-60	-29	-10	
CURRENT-LIMIT COMPARATOR					
Threshold Voltage	Vth	85	101	115	mV
Input Common Mode Voltage Range	VICR	_	3.0	_	V
Input Bias Current	liB	_	-0.9	-5.0	μA
OUTPUTS AND POWER SECTIONS					
Top Drive Output Sink Saturation (Isink = 25 mA)	VCE(sat)	_	0.5	1.5	V
Top Drive Output Off-State Leakage (VCF = 30 V)		_	0.06	100	μA
Top Drive Output Switching Time (CL = 47 pE BL = 1.0 k)	Di W (ieak)				ns
Rise Time	tr	_	107	300	
Fall Time	tr	_	26	200	
Bottom Drive Output Voltage					V
High State (V <sub>CC</sub> = 20 V, V <sub>C</sub> = 30 V, $I_{SOURCE} = 50$ mA)	VOH	$(V_{CC} - 2.0)$	$(V_{CC} - 1.1)$	_	-
Low State ( $V_{CC}$ = 20 V, $V_C$ = 30 V, $I_{sink}$ = 50 mA)	Voi		1.5	2.0	
Bottom Drive Output Switching Time (CI = 1000 pF)					ns
Rise Time	tr	_	38	200	
Fall Time	tf	_	30	200	
Fault Output Sink Saturation (Isink = 16 mA)	V <sub>CE(sat)</sub>	_	225	500	mV
Fault Output off-State leakage (ICE = 20 V)	FIT(leak)	_	1.0	100	uА
	·FLI(leak)				V
Drive Output Enabled (VCC or VC Increasing)	Vth(on)	8.2	8.9	10	•
Hysteresis	V <sub>H</sub>	0.1	0.2	0.3	
Power Supply Current		-			
Pin 17 ( $V_{CC} = V_C = 20 V$ )	lcc	_	12	16	mA
Pin 17 (V <sub>CC</sub> = 20 V, V <sub>C</sub> = 30 V)		_	14	20	
Pin 18 (V <sub>CC</sub> = V <sub>C</sub> = 20 V)	IC IC	-	3.5	6.0	
Pin 18 (V <sub>CC</sub> = 20 V, V <sub>C</sub> = 30 V)	Ĭ	-	5.0	10	







Figure 4. Error Amp Output Saturation





Figure 6. Error Amp Large–Signal Transient Response







Figure 12. Fault Output Saturation versus Sink Current

40







Figure 15. Bottom Drive Output Waveform



Figure 16. Bottom Drive Output Waveform





Figure 18. Power and Bottom Drive Supply Current versus Supply Voltage



#### PIN FUNCTION DESCRIPTION

Pin	Symbol	Description						
1, 2, 24	B <sub>T</sub> , A <sub>T</sub> , C <sub>T</sub>	These three open collector Top Drive outputs, are designed to drive the external upper power switch transistors.						
3	Fwd/Rev	The Forward/Reverse Input is used to change the direction of motor rotation.						
4, 5, 6	S <sub>A</sub> , S <sub>B</sub> , S <sub>C</sub>	These three Sensor Inputs control the commutation sequence.						
7	Output Enable	A logic high at this input causes the motor to run, while a low causes it to coast.						
8	Reference Output	This output provides charging current for the oscillator timing capacitor $C_T$ and a reference for the error amplifier. It may also serve to furnish sensor power.						
9	Current Sense Noninverting Input	A 100mV signal, with respect to Pin 15, at this input terminates output switch conduction during a given oscillator cycle. This pin normally connects to the top side of the current sense resistor.						
10	Oscilator	The Oscillator frequency is programmed by the values selected for the timing components, $R_T$ and $C_T$ .						
11	Error Amp Noninverting Input	This Input is normally connected to the speed set potentiometer.						
12	Error Amp Inverting Input	This input is normally connected to the Error Amp Output in open loop appli- cations.						
13	Error Amp Out/PWM Input	This pin is available for compensation in closed loop applications.						
14	Fault Output	This open collector output is active low during one or more of the following conditions: Invaild Sensor Input code, Enable Input at logic 0, Current Sense Input greater than 100 mV (Pin 9 with respect to Pin 15), Undervoltage Lockout activation, and Thermal Shutdown.						
15	Current Sense Inverting Input	Reference pin for internal 100 mV threshold. This pin is normally connected to the bottom side of the current sense resistor.						
16	Gnd	This pin supplies a ground for the control circuit and should be referenced back to the power source ground.						
17	VCC	This pin is the positive supply of the control IC. The controller is functional over a minimum $V_{CC}$ range of 10 to 30 V.						
18	VC	The high state (V <sub>OH</sub> ) of the Bottom Drive Outputs is set by the voltage applied to this pin. The controller is operational over a minimum V <sub>C</sub> range of 10 to 30 V.						
19, 20, 21	C <sub>B</sub> , B <sub>B</sub> , A <sub>B</sub>	These three totem pole Bottom Drive Outputs are designed for direct drive of the external bottom power switch transistors.						
22	60°/120° Select	The electrical state of this pin configures the control circuit operation for either $60^{\circ}$ (high state) or $120^{\circ}$ (low state) sensor electrical phasing inputs.						
23	Brake	A logic low state at this input allows the motor to run, while a high state does not allow motor operation and if operating causes rapid deceleration.						

## INTRODUCTION

The MC33035 is one of a series of high performance monolithic DC brushless motor controllers produced by Motorola. It contains all of the functions required to implement a full-featured, open loop, three or four phase motor control system. In addition, the controller can be made to operate DC brush motors. Constructed with Bipolar Analog technology, it offers a high degree of performance and ruggedness in hostile industrial environments. The MC33035 contains a rotor position decoder for proper commutation sequencing, a temperature compensated reference capable of supplying a sensor power, a frequency programmable savtooth oscillator, a fully accessible error amplifier, a pulse width modulator comparator, three open collector top drive outputs, and three high current totem pole bottom driver outputs ideally suited for driving power MOSFETs.

Included in the MC33035 are protective features consisting of undervoltage lockout, cycle-by-cycle current limiting with a selectable time delayed latched shutdown mode, internal thermal shutdown, and a unique fault output that can easily be interfaced to a microprocessor controller.

Typical motor control functions Include open loop speed control, forward or reverse rotation, run enable, and dynamic braking. In addition, the MC33035 has a  $60^{\circ}/120^{\circ}$  select pin which configures the rotor position decoder for either  $60^{\circ}$  or  $120^{\circ}$  sensor electrical phasing inputs.

## FUNCTIONAL DESCRIPTION

A representative internal block diagram Is shown in Figure 19 with various applications shown in Figures 36, 38, 39, 43, 45, and 46. A discussion of the features and function of each of the internal blocks given below is referenced to Figures 19 and 36.

#### **Rotor Position Decoder**

An internal rotor position decoder monitors the three sensor inputs (Pins 4, 5, 6) to provide the proper sequencing of the top and bottom drive outputs. The sensor inputs are designed to interface directly with open collector type Hall Effect switches or opto slotted couplers. Internal pull-up resistors are included to minimize the required number of external components. The inputs are TTL compatible, with their thresholds typically at 2.2 V. The MC33035 series is designed to control three phase motors and operate with four of the most common conventions of sensor phasing. A 60°/120° Select (Pin 22) is conveniently provided and affords the MC33035 to configure itself to control motors having either 61°, 120°, 240° or 300° electrical sensor phasing. With three sensor inputs there are eight possible input code combinations, six of which are valid rotor positions. The remaining two codes are invalid and are usually caused by an open or shorted sensor line. With six valid input codes, the

decoder can resolve the motor rotor position to within a window of 60 electrical degrees.

The Forward/Reverse input (Pin 3) is used to change the direction of motor rotation by reversing the voltage across the stator winding. When the input changes state, from high to low with a given sensor input code (for example 100), the enabled top and bottom drive outputs with the same alpha designation are exchanged (A<sub>T</sub> to A<sub>B</sub>, B<sub>T</sub> to B<sub>B</sub>, C<sub>T</sub> to C<sub>B</sub>). In effect, the commutation sequence is reversed and the motor changes directional rotation.

Motor on/off control Is accomplished by the Output Enable (Pin 7). When left disconnected, an internal 25  $\mu$ A current source enables sequencing of the top and bottom drive outputs. When grounded, the top drive outputs turn off and the bottom drives are forced low, causing the motor to coast and the Fault output to activate.

Dynamic motor braking allows an additional margin of safety to be designed into the final product. Braking is accomplished by placing the Brake Input (Pin 23) in a high state. This causes the top drive outputs to turn off and the bottom drives to turn on, shorting the motor-generated back EMF. The brake input has unconditional priority over all other inputs. The internal 40 kΩ pull-up resistor simplifies interfacing with the system safety–switch by insuring brake activation if opened or disconnected. The commutation logic truth table is shown in Figure 20. A four input NOR gate is used to monitor the brake input and the inputs to the three top drive output transistors. Its purpose is to disable braking until the top drive outputs attain a high state. This helps to prevent simultaneous conduction of the top and bottom power switches. In half wave motor drive applications, the top drive outputs are not required and are normally left disconnected. Under these conditions braking will still be accomplished since the NOR gate senses the base voltage to the top drive output transistors.

## Error Amplifier

A high performance, fully compensated error amplifier with access to both inputs and output (Pins 11, 12, 13) is provided to facilitate the implementation of closed loop motor speed control. The amplifier features a typical DC voltage gain of 80 dB, 0.6 MHz gain bandwidth, and a wide input common mode voltage range that extends from ground to V<sub>ref</sub>. In most open loop speed control applications, the amplifier is configured as a unity gain voltage follower with the noninverting input connected to the speed set voltage source. Additional configurations are shown in Figures 31 through 35.

## Oscillator

The frequency of the internal ramp oscillator is programmed by the values selected for timing components R<sub>T</sub> and C<sub>T</sub>. Capacitor C<sub>T</sub> is charged from the Reference Output (Pin 8) through resistor R<sub>T</sub> and discharged by an internal discharge transistor. The ramp peak and valley voltages are typically 4.1 V and 1.5 V respectively. To provide a good compromise between audible noise and output switching efficiency, an oscillator frequency in the range of 20 to 30 kHz is recommended. Refer to Figure 1 for component selection.



Figure 20. Three Phas	se, Six Step Comn	nutation Truth Table (Note 1	)
-----------------------	-------------------	------------------------------	---

	Inputs (Note 2)							Outputs (Note 3)									
Sen	sor Ele	ctrical	Phasi	ng (No	te 4)		Top Drives Bottom Drives										
	60°			120°					Current								
SA	SB	sc	SA	SB	sc	F/R	Enable	Brake	Sense	AT	Вт	Ст	AB	BB	СB	Fault	
1	0	0	1	0	0	1	1	0	0	0	1	1	0	0	1	1	(Note 5)
1	1	0	1	1	0	1	1	0	0	1	0	1	0	0	1	1	F/R = 1
1	1	1	0	1	0	1	1	0	0	1	0	1	1	0	0	1	
0	1	1	0	1	1	1	1	0	0	1	1	0	1	0	0	1	
0	0	1	0	0	1	1	1	0	0	1	1	0	0	1	0	1	
0	0	0	1	0	1	1	1	0	0	0	1	1	0	1	0	1	
1	0	0	1	0	0	0	1	0	0	1	1	0	1	0	0	1	(Note 5)
1	1	0	1	1	0	0	1	0	0	1	1	0	0	1	0	1	F/R = 0
1	1	1	0	1	0	0	1	0	0	0	1	1	0	1	0	1	
0	1	1	0	1	1	0	1	0	0	0	1	1	0	0	1	1	
0	0	1	0	0	1	0	1	0	0	1	0	1	0	0	1	1	
0	0	0	1	0	1	0	1	0	0	1	0	1	1	0	0	1	
1	0	1	1	1	1	Х	Х	0	Х	1	1	1	0	0	0	0	(Note 6)
0	1	0	0	0	0	X	х	0	х	1	1	1	0	0	0	0	Brake = 0
1	0	1	1	1	1	Х	Х	1	Х	1	1	1	0	0	0	0	(Note 7)
0	1	0	0	0	0	X	х	1	х	1	1	1	0	0	0	0	Brake = 1
V	V	V	V	V	V	Х	1	1	Х	1	1	1	1	1	1	1	(Note 8)
V	V	V	V	V	V	Х	0	1	Х	1	1	1	1	1	1	0	(Note 9)
V	V	V	V	V	V	Х	0	0	Х	1	1	1	0	0	0	0	(Note 10)
V	V	V	V	V	V	Х	1	0	1	1	1	1	0	0	0	0	(Note 11)

NOTES: 1. V = Any one of six valid Sensor or drive combinations X = Don't care. 2. The digital inputs (Pins 3, 4, 5, 6, 7, 22, 23) are all TTL compatible. The current sense input (Pin 9) has a 100 mV threshold with respect

to Pin 15. A logic 0 for this input is defined as <85 mV, and a logic 1 is >115 mV.

3. The fault and top drive outputs are open collector design and active in the low (0) state.

4. With 60°/120° select (Pin 22) in the high (1) state, configuration Is for 60° sensor electrical phasing inputs. With Pin 22 in low (0) state, configuration is for 120° sensor electrical phasing inputs.

5. Valid 60° or 120° sensor combinations for corresponding valid top and bottom drive outputs.

6. Invalid sensor inputs with brake = 0; All top and bottom drives off, Fault low.

7. Invalid sensor inputs with brake = 1; All top drives off; all bottom drives on, Fault low.

8. Valid 60° or 120° sensor inputs with brake = 1: All top drives off, all bottom drives on, Fault high.

Valid sensor inputs with brake = 1 and enable = 0; All top drives off, all bottom drives on, Fault low.
 Valid sensor inputs with brake = 0 and enable = 0; All top and bottom drives off, Fault low.

11. All bottom drives off. Fault low.

#### **Pulse Width Modulator**

The use of pulse width modulation provides an energy efficient method of controlling the motor speed by varying the average voltage applied to each stator winding during the commutation sequence. As CT discharges, the oscillator sets both latches, allowing conduction of the top and bottom drive outputs. The PWM comparator resets the upper latch, terminating the bottom drive output conduction when the positive–going ramp of CT becomes greater than the error amplifier output. The pulse width modulator timing diagram is shown in Figure 21. Pulse width modulation for speed control appears only at the bottom drive outputs.

#### Current Limit

Continuous operation of a motor that is severely over-loaded results in overheating and eventual failure. This destructive condition can best be prevented with the use of cycle-by-cycle current limiting. That is, each on-cycle is treated as a separate event. Cycle-by-cycle current limiting is accomplished by monitoring the stator current build-up each time an output switch conducts, and upon sensing an over current condition, immediately turning off the switch and holding it off for the remaining duration of oscillator ramp-up period. The stator current is converted to a voltage by inserting a ground-referenced sense resistor Rs (Figure 36) in series with the three bottom switch transistors (Q<sub>4</sub>, Q5, Q6). The voltage developed across the sense resistor is monitored by the Current Sense Input (Pins 9 and 15). and compared to the internal 100 mV reference. The current sense comparator inputs have an input common mode range of approximately 3.0 V. If the 100 mV current sense threshold is exceeded, the comparator resets the lower sense latch and terminates output switch conduction. The value for the current sense resistor is:

$$R_{S} = \frac{0.1}{I_{stator(max)}}$$

The Fault output activates during an over current condition. The dual-latch PWM configuration ensures that only one single output conduction pulse occurs during any given oscillator cycle, whether terminated by the output of the error amp or the current limit comparator.



Figure 21. Pulse Width Modulator Timing Diagram

#### Reference

The on-chip 6.25 V regulator (Pin 8) provides charging current for the oscillator timing capacitor, a reference for the error amplifier, and can supply 20 mA of current suitable for directly powering sensors In low voltage applications. In higher voltage applications, it may become necessary to transfer the power dissipated by the regulator off the IC. This Is easily accomplished with the addition of an external pass transistor as shown in Figure 22. A 6.25 V reference level was chosen to allow implementation of the simpler NPN circuit, where  $V_{ref} - V_{BE}$  exceeds the minimum voltage required by Hall Effect sensors over temperature. With proper transistor selection and adequate heatsinking, up to one amp of load current can be obtained.



The NPN circuit is recommended for powering Hall or opto sensors, where the output voltage temperature coefficient is not critical. The PNP circuit is slightly more complex. but is also more, accurate over temperature. Neither circuit has current limiting.

#### Undervoltage Lockout

A triple Undervoltage Lockout has been incorporated to prevent damage to the IC and the external power switch transistors. Under low power supply conditions, it guarantees that the IC and sensors are fully functional, and that there is sufficient bottom drive output voltage. The positive power supplies to the IC (VCC) and the bottom drives (VC) are each monitored by separate comparators that have their thresholds at 9.1 V. This level ensures sufficient gate drive necessary to attain low RDS(on) when driving standard power MOSFET devices. When directly powering the Hall sensors from the reference, improper sensor operation can result if the reference output voltage falls below 4.5 V. A third comparator is used to detect this condition. If one or more of the comparators detects an undervoltage condition. the Fault Output is activated, the top drives are turned off and the bottom drive outputs are held in a low state. Each of the comparators contain hysteresis to prevent oscillations when crossing their respective thresholds.

#### Fault Output

The open collector Fault Output (Pin 14) was designed to provide diagnostic information in the event of a system malfunction. It has a sink current capability of 16 mA and can directly drive a light emitting diode for visual indication. Additionally, it is easily interfaced with TTL/CMOS logic for use in a microprocessor controlled system. The Fault Output is active low when one or more of the following conditions occur:

- 1) Invalid Sensor Input code
- Output Enable at logic (0)
   Current Sense Input greater than
- 3) Current Sense Input greater than 100 mV
- Undervoltage Lockout, activation of one or more of the comparators
- 5) Thermal Shutdown, maximum junction temperature being exceeded

This unique output can also be used to distinguish between motor start-up or sustained operation in an overloaded condition. With the addition of an RC network between the Fault Output and the enable input, it is possible to create a time-delayed latched shutdown for overcurrent. The added circuitry shown in Figure 23 makes easy starting of motor systems which have high inertial loads by providing additional starting torque, while still preserving overcurrent protection. This task is accomplished by setting the current limit to a higher than nominal value for a predetermined time. During an excessively long overcurrent condition, capacitor CDLY will charge. causing the enable input to cross its threshold to a low state. A latch is then formed by the positive feedback loop from the Fault Output to the Output Enable. Once set, by the Current Sense Input, It can only be reset by shorting CDLY or cycling the power supplies.

#### **Drive Outputs**

The three top drive outputs (Pins 1, 2, 24) are open collector NPN transistors capable of sinking 50 mA with a minimum breakdown of 30 V. Interfacing into higher voltage applications is easily accomplished with the circuits shown in Figures 24 and 25.

The three totem pole bottom drive outputs (Pins 19, 20, 21) are particularly suited for direct drive of N–Channel MOSFETs or NPN bipolar transistors (Figures 26, 27, 28 and 29). Each output is capable of sourcing and sinking up to 100 mA. Power for the bottom drives is supplied from V<sub>C</sub> (Pin 18). This separate supply input allows the designer added flexibility in tailoring the drive voltage, independent of V<sub>CC</sub>. A zener clamp should be connected to this input when driving power MOSFETs in systems where V<sub>CC</sub> is greater than 20 V so as to prevent rupture of the MOSFET

The control circuitry ground (Pin 16) and current sense inverting input (Pin 15) must return on separate paths to the central input source ground.

#### Thermal Shutdown

Internal thermal shutdown circuitry is provided to protect the IC in the event the maximum junction temperature is exceeded. When activated, typically at 170°C, the IC acts as though the Output Enable was grounded.







Figure 24. High Voltage Interface with NPN Power Transistors



Transistor Q<sub>1</sub> is a common base stage used to level shift from V<sub>CC</sub> to the high motor voltage, V<sub>M</sub>. The collector diode is required If V<sub>CC</sub> is present while V<sub>M</sub> is low.

Figure 26. Current Waveform Spike Suppression



The addition of the RC filter will eliminate current–limit instability caused by the leading edge spike on the current waveform, resistor  $R_S$  should be a low inductance type.



Series gate resistor Rg will dampen any high frequency oscillations caused by the MOSFET input capacitance and any series wining induction in the gate-source circuit. Diode D is required if the negative current into the Bottom Drive Outputs exceeds 50 mA.

Figure 29. Current Sensing Power MOSFETs



Control Circuitry Ground (Pin 16) and Current Sense Inverting Input (Pin 15) must return on separate paths to the Central Input Source Ground. Virtually lossless current sensing can be achieved with the implementation of SENSEFET power switches.

## Figure 28. Bipolar Transistor Drive



The totem-pole output can furnish negative base current for enhanced transistor turn-off, with the addition of capacitor C.

Figure 30. High Voltage Boost Supply



This circuit generates VBoost for Figure 25.

#### Figure 31. Differential Input Speed Controller



## Figure 33. Digital Speed Controller



The SN74LS145 is an open collector BCD to One of Ten decoder. When connected as shown, input codes 0000 through 1001 steps the PWM in increments of approximately 10% from 0 to 90% on-times. Input codes 1010 through 1111 will produce 100% on-time or full motor speed.

Figure 32. Controlled Acceleration/Deceleration



Resistor R<sub>1</sub> with capacitor C sets the acceleration time constant while R<sub>2</sub> controls the deceleration. The values of R<sub>1</sub> and R<sub>2</sub> should be at least ten times greater than the speed set potentiometer to minimize time constant variations with different speed settings.

## Figure 34. Closed Loop Speed Control



The rotor position sensors can be used as a tachometer. By differentiating the positive-going edges and then integrating them over time, a voltage proportional to speed can be generated. The error amp compares this voltage to that of the speed set to control the PWM.

## Figure 35. Closed Loop Temperature Control



This circuit can control the speed of a cooling fan proportional to the difference between the sensor and set temperatures. The control loop is closed as the forced air cools the NTC thermistor. For controlled heating applications, exchange the positions of  $R_1$  and  $R_2$ .

## SYSTEM APPLICATIONS

#### **Three Phase Motor Commutation**

The three phase application shown in Figure 36 is a fullfeatured open loop motor controller with full wave, six step drive. The upper power switch transistors are Darlingtons while the lower devices are power MOSFETs. Each of these devices contains an internal parasitic catch diode that is used to return the stator inductive energy back to the power supply. The outputs are capable of driving a delta or wye connected stator, and a grounded neutral wye if split supplies are used. At any given rotor position, only one top and one bottom power switch (of different totem poles) is enabled. This configuration switches both ends of the stator winding from supply to ground which causes the current flow to be bidirectional or full wave. A leading edge spike is usually present on the current waveform and can cause a current-limit instability. The spike can be eliminated by adding an RC filter in series with the Current Sense Input. Using a low inductance type resistor for RS will also aid in spike reduction. Care must be taken in the selection of the bottom power switch transistors so that the current during braking does not exceed the device rating. During braking, the peak current generated is limited only by the series resistance of the conducting bottom switch and winding.

$$I_{peak} = \frac{V_{M} + EMF}{R_{switch} + R_{winding}}$$

If the motor is running at maximum speed with no load, the generated back EMF can be as high as the supply voltage, and at the onset of braking, the peak current may approach twice the motor stall current. Figure 37 shows the commutation waveforms over two electrical cycles. The first cycle (0° to 360°) depicts motor operation at full speed while the second cycle (360° to 720°) shows a reduced speed with about 50% pulse width modulation. The current waveforms reflect a constant torque load and are shown synchronous to the commutation frequency for clarity.

## Figure 36. Three Phase, Six Step, Full Wave Motor Controller





**Rotor Electrical Position (Degrees)** 

Figure 38 shows a three phase, three step, hall wave motor controller. This configuration is ideally suited for automotive and other low voltage applications since there is only one power switch voltage drop In series with a given stator winding. Current flow is unidirectional or half wave because only one end of each winding is switched. Continuous braking with the typical half wave arrangement presents a motor overheating problem since stator current is limited only by the winding resistance. This is due to the lack of upper power switch transistors, as in the full wave circuit, used to disconnect the windings from the supply voltage VM. A unique solution is to provide braking until the motor stops and then turn off the bottom drives. This can be accomplished by using the Fault Output in conjunction with the Output Enable as an over current timer. Components RpLy and CpLy are selected to give the motor sufficient time to stop before latching the Output Enable and the top drive AND gates low. When enabling the motor, the brake switch is closed and the PNP transistor (along with resistors R1 and RpLy) are used to reset the latch by discharging CpLy. The stator flyback voltage is clamped by a single zener and three diodes.



Figure 38. Three Phase, Three Step, Half Wave Motor Controller

## Three Phase Closed Loop Controller

The MC33035, by itself, is only capable of open loop motor speed control. For closed loop motor speed control, the MC33035 requires an input voltage proportional to the motor speed. Traditionally, this has been accomplished by means of a tachometer to generate the motor speed feedback voltage. Figure 39 shows an application whereby an MC33039, powered from the 6.25 V reference (Pin 8) of the MC33035, is used to generate the required feedback voltage without the need of a costly tachometer. The same Hall sensor signals used by the MC33035 for rotor position decoding are utilized by the MC33035 tor rotor position decoding are utilized by the MC33035 is produce an output pulse of defined amplitude and time duration, as determined by the external resistor R<sub>1</sub> and capacitor C<sub>1</sub>. The output train of pulses at Pin 5 of the MC33039 are integrated by the error amplifier of the MC33035 configured as an integrator to produce a DC voltage level which is proportional to the motor speed. This speed proportional voltage establishes the PWM reference level at Pin 13 of the MC33035 motor controller and closes the feedback loop. The MC33035 outputs drive a TMOS power MOSFET 3-phase bridge. High currents can be expected during conditions of start-up, breaking, and change of direction of the motor.

The system shown in Figure 39 is designed for a motor having 120/240 degrees Hall sensor electrical phasing. The system can easily be modified to accommodate 60/300degree Hall sensor electrical phasing by removing the jumper (J<sub>2</sub>) at Pin 22 of the MC33035.

#### Figure 39. Closed Loop Brushless DC Motor Control Using The MC33035 and MC33039



### Sensor Phasing Comparison

There are four conventions used to establish the relative phasing of the sensor signals in three phase motors. With six step drive, an input signal change must occur every 60 electrical degrees; however, the relative signal phasing is dependent upon the mechanical sensor placement. A comparison of the conventions in electrical degrees is shown in Figure 40. From the sensor phasing table in Figure 41, note that the order of input codes for 60° phasing is the reverse of 300°. This means the MC3303S, when configured for 60° sensor electrical phasing, but resulting in opposite directions of rotation. The same is true for the part when it is configured for 120° sensor electrical phasing; the motor will operate or 120° sensor electrical phasing the motor rotation for 120° for 240° conventions.

#### Figure 40. Sensor Phasing Comparison



### Figure 41. Sensor Phasing Table

Sensor Electrical Phasing (Degrees)												
	<b>60</b> °			120°		240°			300°			
SA	SB	sc	SA	SB	sc	SA	SB	sc	SA	SB	SC	
1	0	0	1	0	1	1	1	0	1	$\wedge$	1	
1	1	0	1	0	0	1	0	0	1	1	0	
1	$\mathbb{V}$	1	1	1	0	1	0	1	1	0	0	
0	1	1	0	1	0	0	0	1	0	0	0	
0	0	1	0	1	1	0	1	1	0	0	1	
0	0	0	0	0	1	0	1	0	0	1	1	

In this data sheet, the rotor position is always given in electrical degrees since the mechanical position is a function of the number of rotating magnetic poles. The relationship between the electrical and mechanical position is:

Electrical Degrees = Mechanical Degrees 
$$\left(\frac{\#Rotor Poles}{2}\right)$$

An increase in the number of magnetic poles causes more electrical revolutions for a given mechanical revolution. General purpose three phase motors typically contain a four pole rotor which yields two electrical revolutions for one mechanical.

#### Two and Four Phase Motor Commutation

The MC33035 is also capable of providing a four stop output that can be used to drive two or four phase motors. The truth table in Figure 42 shows that by connecting sensor inputs S<sub>B</sub> and S<sub>C</sub> together, it is possible to truncate the number of drive output states from six to four. The output power switches are connected to B<sub>T</sub>. C<sub>T</sub>. B<sub>B</sub>, and C<sub>E</sub>. Figure 43 shows a four phase, four step, full wave motor control application. Power switch transistors Q<sub>1</sub> through Q<sub>8</sub> are Darlington type, each with an internal paralitic catch diode. With four step drive, only two rotor position sensors spaced at 90 electrical degrees are required. The commutation waveforms are shown in Figure 44.

Figure 45 shows a four phase, four step, half wave motor controller. It has the same features as the circuit in Figure 38, except for the deletion of speed control and braking.

Figure 42. Two and Four Phase, Four Step, Commutation Truth Table

MC33035 (60°/120° Select Pin Open)										
	Inputs			0	utputs					
Sensor I Spacin	Electrical g* = 90°		Тор [	Drives	Bottom	n Drives				
SA	SB	F/R	Вт	Ст	BB	с <sub>В</sub>				
1	0	1	1	1	0	1				
1	1	1	0	1	0	0				
0	1	1	1	0	0	0				
0	0	1	1	1	1	0				
1	0	0	1	0	0	0				
1	1	0	1	1	1	0				
0	1	0	1	1	0	1				
0	0	0	0	1	0	0				

\*With MC33035 sensor input SB connected to SC.



Figure 43. Four Phase, Four Step, Full Wave Motor Controller

## Figure 44. Four Phase, Four Step, Full Wave Motor Controller



#### **Rotor Electrical Position (Degrees)**



Figure 45. Four Phase, Four Step, Half Wave Motor Controller

### **Brush Motor Control**

Though the MC33035 was designed to control brushless DC motors, it may also be used to control DC brush type motors. Figure 46 shows an application of the MC33035 driving a MOSFET H-bridge affording minimal parts count to operate a brush-type motor. Key to the operation is the input sensor code [100] which produces a top-left (Q1) and a bottom-right (Q3) drive when the controller's forward/reverse pin is at logic [1]; top-right (Q4), bottom-left (Q2) drive is realized when the Forward/Reverse pin is at logic [0]. This code supports the requirements necessary for H-bridge drive accomplishing both direction and speed control.

The controller functions in a normal manner with a pulse width modulated frequency of approximately 25 kHz. Motor speed is controlled by adjusting the voltage presented to the noninverting input of the error amplifier establishing the PWM's slice or reference level. Cycle-by-cycle current limiting of the motor current is accomplished by sensing the voltage (100 mV) across the Rg resistor to ground of the H-bridge motor current. The over current sense circuit makes it possible to reverse the direction of the motor, using

the normal forward/reverse switch, on the fly and not have to completely stop before reversing.

### LAYOUT CONSIDERATIONS

Do not attempt to construct any of the brushless motor control circuits on wire-wrap or plug-in prototype boards. High frequency printed circuit layout techniques are imperative to prevent pulse jitter. This is usually caused by excessive noise pick-up imposed on the current sense or error amp inputs. The printed circuit layout should contain a ground plane with low current signal and high drive and output buffer grounds returning on separate paths back to the power supply input filter capacitor VM. Ceramic bypass capacitors (0.1 µF) connected close to the integrated circuit at VCC, VC, Vref and the error amp noninverting input may be required depending upon circuit layout. This provides a low impedance path for filtering any high frequency noise. All high current loops should be kept as short as possible using heavy copper runs to minimize radiated EMI.


## **3.6. MICROSCALE PERMANENT-MAGNET STEPPER MOTORS**

In MEMS and microscale devices, permanent-magnet stepper motors can be used. Translational and rotational microscale stepper motors (which are synchronous electric machines) have been designed, fabricated, and tested. These motors develop high electromagnetic torque, while the mechanical angular velocity is relatively low. Therefore, permanent-magnet stepper motors can be easily integrated into servos as direct-drive servo-motors. This direct connection of micromotors without matching mechanical coupling allows one to achieve a remarkable level of efficiency, reliability, and performance. Stepper motors must be controlled to ensure stability, precision tracking, desired steady-state and dynamic performance, disturbance rejection, and zero steady-state error. To approach the analysis and control, complete nonlinear mathematical models of stepper motors must be found. By energizing the stator windings in the proper sequence, the rotor rotates in the counterclockwise or clockwise direction due to the electromagnetic torque developed. In particular, the rotor displaces by a full or half step. Hence, energizing windings, one achieves the angular increment equal to a full or half step. The angular velocity is regulated by changing the frequency of the phase currents fed or voltages supplied to the phase windings as was shown for permanent-magnet synchronous motors.

## 3.6.1. Mathematical Model in the Machine Variables

For two-phase permanent-magnet stepper motors, we have

$$u_{as} = r_s i_{as} + \frac{d\mathbf{y}_{as}}{dt},$$

$$u_{bs} = r_s i_{bs} + \frac{d\mathbf{y}_{bs}}{dt},$$
(3.6.1)

where the flux linkages are

$$\mathbf{y}_{as} = L_{asas}i_{as} + L_{asbs}i_{bs} + \mathbf{y}_{asm},$$
  

$$\mathbf{y}_{bs} = L_{bsas}i_{as} + L_{bsbs}i_{bs} + \mathbf{y}_{bsm}.$$
(3.6.2)

The electrical angular velocity and displacement are found using the number of rotor teeth,  $\mathbf{w}_r = RT\mathbf{w}_{rm}$  and  $\mathbf{q}_r = RT\mathbf{q}_{rm}$ . Therefore, the flux linkages are function of the number of the rotor teeth RT, and

$$\mathbf{y}_{asm} = \mathbf{y}_m \cos(RT\mathbf{q}_{rm}),$$
  
$$\mathbf{y}_{bsm} = \mathbf{y}_m \sin(RT\mathbf{q}_{rm}).$$
 (3.6.3)

The self-inductance of the stator windings is

$$L_{ss} = L_{asas} = L_{bsbs} = L_{ls} + \overline{L}_m \,. \tag{3.6.4}$$

The stator windings are displaced by 90 electrical degrees. Hence, the mutual inductances between the stator windings are zero,

$$L_{asbs} = L_{bsas} = 0.$$
From (3.6.2), (3.6.3) and (3.6.4), we have
$$y_{as} = L_{ss}i_{as} + y_m \cos(RTq_{rm}),$$

$$y_{bs} = L_{ss}i_{bs} + y_m \sin(RTq_{rm}).$$
(3.6.5)
Taking note of (3.6.1) and (3.6.5), one has
$$u_{as} = r_s i_{as} + \frac{d(L_{ss}i_{as} + y_m \cos(RTq_{rm}))}{dt}$$

$$= r_s i_{as} + L_{ss} \frac{di_{as}}{dt} - RTy_m w_{rm} \sin(RTq_{rm}),$$

$$u_{bs} = r_s i_{bs} + \frac{d(L_{ss}i_{bs} + y_m \sin(RTq_{rm}))}{dt}$$

$$= r_s i_{bs} + L_{ss} \frac{di_{bs}}{dt} + RTy_m w_{rm} \cos(RTq_{rm}).$$
Therefore

Therefore,

$$\frac{di_{as}}{dt} = -\frac{r_s}{L_{ss}}i_{as} + \frac{RT\mathbf{y}_m}{L_{ss}}\mathbf{w}_{rm}\sin(RT\mathbf{q}_{rm}) + \frac{1}{L_{ss}}u_{as},$$

$$\frac{di_{bs}}{dt} = -\frac{r_s}{L_{ss}}i_{bs} - \frac{RT\mathbf{y}_m}{L_{ss}}\mathbf{w}_{rm}\cos(RT\mathbf{q}_{rm}) + \frac{1}{L_{ss}}u_{bs}.$$
(3.6.6)

Using Newton's second law we have

$$\frac{d\boldsymbol{w}_{rm}}{dt} = \frac{1}{J} (T_e - B_m \boldsymbol{w}_{rm} - T_L),$$
$$\frac{d\boldsymbol{q}_{rm}}{dt} = \boldsymbol{w}_{rm}.$$

The expression for the electromagnetic torque developed by permanentmagnet stepper motors must be found. Taking note of

$$W_c = \frac{1}{2} \left( L_{ss} i_{as}^2 + L_{ss} i_{bs}^2 \right) + \mathbf{y}_m i_{as} \cos(RT \boldsymbol{q}_{rm}) + \mathbf{y}_m i_{bs} \sin(RT \boldsymbol{q}_{rm}) + W_{PM} ,$$

one finds the electromagnetic torque

$$T_e = \frac{\P W_c}{\P \boldsymbol{q}_{rm}} = -RT \boldsymbol{y}_m [i_{as} \sin(RT \boldsymbol{q}_{rm}) - i_{bs} \cos(RT \boldsymbol{q}_{rm})].$$

Hence, the transient evolution of the rotor angular velocity  $\mathbf{w}_{rm}$  and displacement  $\mathbf{q}_{rm}$  is modeled by the following differential equations

$$\frac{d\boldsymbol{w}_{rm}}{dt} = -\frac{RT\boldsymbol{y}_m}{J} \left[ i_{as} \sin(RT\boldsymbol{q}_{rm}) - i_{bs} \cos(RT\boldsymbol{q}_{rm}) \right] - \frac{B_m}{J} \boldsymbol{w}_{rm} - \frac{1}{J} T_L,$$

$$\frac{d\boldsymbol{q}_{rm}}{dt} = \boldsymbol{w}_{rm} \,. \tag{3.6.7}$$

Augmenting (3.6.6) and (3.6.7), one has

$$\frac{di_{as}}{dt} = -\frac{r_s}{L_{ss}}i_{as} + \frac{RT\boldsymbol{y}_m}{L_{ss}}\boldsymbol{w}_{rm}\sin(RT\boldsymbol{q}_{rm}) + \frac{1}{L_{ss}}u_{as},$$

$$\frac{di_{bs}}{dt} = -\frac{r_s}{L_{ss}}i_{bs} - \frac{RT\boldsymbol{y}_m}{L_{ss}}\boldsymbol{w}_{rm}\cos(RT\boldsymbol{q}_{rm}) + \frac{1}{L_{ss}}u_{bs},$$

$$\frac{d\boldsymbol{w}_{rm}}{dt} = -\frac{RT\boldsymbol{y}_m}{J}\left[i_{as}\sin(RT\boldsymbol{q}_{rm}) - i_{bs}\cos(RT\boldsymbol{q}_{rm})\right] - \frac{B_m}{J}\boldsymbol{w}_{rm} - \frac{1}{J}T_L,$$

$$\frac{d\boldsymbol{q}_{rm}}{dt} = \boldsymbol{w}_{rm}.$$
(3.6.8)

These four nonlinear differential equations are rewritten in the state-space form as

$$\begin{array}{c} \stackrel{\bullet}{\mathbf{e}} \frac{di_{as}}{dt} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{e}} \frac{T_s}{L_{ss}} & 0 & 0 & 0 \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{e}} \frac{di_{as}}{dt} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{e}} \stackrel{\bullet}{\mathbf{e}} \frac{1}{L_{ss}} & 0 & 0 \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{e}} \stackrel{\bullet}{\mathbf{e}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{e}} \stackrel{\bullet}{\mathbf{e}} 0 & - \frac{T_s}{L_{ss}} & 0 & 0 \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{e}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{e}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{e}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf{e}} \stackrel{\bullet}{\mathbf{u}} \stackrel{\bullet}{\mathbf$$

From (3.6.8), an *s*-domain block diagram is developed and illustrated in Figure 3.6.1.



Figure 3.6.1. Block diagram of permanent-magnet stepper motors

The analysis of the torque equation

$$T_e = -RT \boldsymbol{y}_m [i_{as} \sin(RT \boldsymbol{q}_{rm}) - i_{bs} \cos(RT \boldsymbol{q}_{rm})]$$

guides one to the conclusion that the expressions for a balanced two-phase current sinusoidal set is

$$i_{as} = -\sqrt{2}i_M \sin(RT\boldsymbol{q}_{rm}),$$
  

$$i_{bs} = \sqrt{2}i_M \cos(RT\boldsymbol{q}_{rm}),$$
(3.6.9)

because the electromagnetic torque is a function of the current magnitude  $\boldsymbol{i}_{M},$  and

$$T_e = \sqrt{2} R T \mathbf{y}_m i_M \,.$$

The phase currents (3.6.9) needed to be fed are the functions of the rotor angular displacement. Assuming that the inductances are negligibly small, we have the following phase voltages needed to be supplied

$$u_{as} = -\sqrt{2}u_M \sin(RT\boldsymbol{q}_{rm}),$$
  

$$u_{bs} = \sqrt{2}u_M \cos(RT\boldsymbol{q}_{rm}).$$
(3.6.10)

An *s*-domain block diagram of permanent-magnet stepper motors which is controlled by changing the phase voltages, as given by (3.6.10), is shown in Figure 3.6.2.



Figure 3.6.2. S-domain block diagram of permanent-magnet stepper motors,  $u_{as} = -\sqrt{2}u_M \sin(RT\boldsymbol{q}_{rm})$  and  $u_{bs} = \sqrt{2}u_M \cos(RT\boldsymbol{q}_{rm})$ 

# 3.6.2. Mathematical Models of Permanent-Magnet Stepper Motors in the Rotor and Synchronous Reference Frames

It was shown that using the *machine* variables, Kirchhoff's voltage law results in two nonlinear differential equations

$$u_{as} = r_s i_{as} + L_{ss} \frac{d i_{as}}{d t} - RT \mathbf{y}_m \mathbf{w}_{rm} \sin(RT \mathbf{q}_{rm}),$$
  
$$u_{bs} = r_s i_{bs} + L_{ss} \frac{d i_{bs}}{d t} + RT \mathbf{y}_m \mathbf{w}_{rm} \cos(RT \mathbf{q}_{rm}).$$

Applying the *direct* Park formation, which in the rotor reference frame is given as

$$\begin{array}{lll} & \underbrace{\boldsymbol{e}}_{r}^{r} \overset{\mathbf{u}}{\mathbf{u}} & \underbrace{\boldsymbol{e}}^{r} \sin(RT\boldsymbol{q}_{rm}) & \cos(RT\boldsymbol{q}_{rm}) \overset{\mathbf{u}}{\mathbf{e}} \boldsymbol{u}_{as} \overset{\mathbf{u}}{\mathbf{u}} \\ & \underbrace{\boldsymbol{e}}_{r}^{r} \overset{\mathbf{u}}{\mathbf{u}} & \underbrace{\boldsymbol{e}}_{c} \cos(RT\boldsymbol{q}_{rm}) & \sin(RT\boldsymbol{q}_{rm}) \overset{\mathbf{u}}{\mathbf{e}} \boldsymbol{u}_{bs} \overset{\mathbf{u}}{\mathbf{u}} \\ & \underbrace{\boldsymbol{e}}_{rs}^{r} \overset{\mathbf{u}}{\mathbf{u}} & \underbrace{\boldsymbol{e}}_{c} \sin(RT\boldsymbol{q}_{rm}) & \cos(RT\boldsymbol{q}_{rm}) \overset{\mathbf{u}}{\mathbf{e}} \overset{\mathbf{u}}{\mathbf{u}}_{bs} \overset{\mathbf{u}}{\mathbf{u}} \\ & \underbrace{\boldsymbol{e}}_{r}^{r} \overset{\mathbf{u}}{\mathbf{u}} & \underbrace{\boldsymbol{e}}_{c} \sin(RT\boldsymbol{q}_{rm}) & \cos(RT\boldsymbol{q}_{rm}) \overset{\mathbf{u}}{\mathbf{e}} \overset{\mathbf{u}}{\mathbf{u}}_{bs} \overset{\mathbf{u}}{\mathbf{u}} \\ & \underbrace{\boldsymbol{e}}_{r}^{r} \overset{\mathbf{u}}{\mathbf{u}} & \underbrace{\boldsymbol{e}}_{c} \cos(RT\boldsymbol{q}_{rm}) & \sin(RT\boldsymbol{q}_{rm}) \overset{\mathbf{u}}{\mathbf{u}} \overset{\mathbf{u}}{\mathbf{e}} \overset{\mathbf{u}}{\mathbf{u}} \overset{\mathbf{u}}{\mathbf{u}} \\ & \underbrace{\boldsymbol{e}}_{r}^{r} \overset{\mathbf{u}}{\mathbf{u}} & \underbrace{\boldsymbol{e}}_{c} \cos(RT\boldsymbol{q}_{rm}) & \sin(RT\boldsymbol{q}_{rm}) \overset{\mathbf{u}}{\mathbf{u}} \overset{\mathbf{u}}{\mathbf{e}} \overset{\mathbf{u}}{\mathbf{u}} \overset{\mathbf{u}}{\mathbf{u}} \end{array} \right)$$

the following differential equations in the qd quantities are found

$$u_{qs}^{r} = r_{s}i_{qs}^{r} + L_{ss}\frac{di_{qs}^{\prime}}{dt} + RT\boldsymbol{y}_{m}\boldsymbol{w}_{rm} + RTL_{ss}i_{ds}^{r}\boldsymbol{w}_{rm},$$

$$u_{ds}^{r} = r_{s}i_{ds}^{r} + L_{ss}\frac{di_{ds}^{r}}{dt} \cdot RTL_{ss}i_{qs}^{r}\boldsymbol{w}_{rm}$$

Hence, the resulting nonlinear circuitry dynamics is

$$\frac{di_{qs}^{r}}{dt} = -\frac{r_{s}}{L_{ss}}i_{qs}^{r} - \frac{RT\mathbf{y}_{m}}{L_{ss}}\mathbf{w}_{rm} - RTi_{ds}^{r}\mathbf{w}_{rm} + \frac{1}{L_{ss}}u_{qs}^{r},$$

$$\frac{di_{ds}^{r}}{dt} = -\frac{r_{s}}{L_{ss}}i_{ds}^{r} + RTi_{qs}^{r}\mathbf{w}_{rm} + \frac{1}{L_{ss}}u_{ds}^{r}.$$
(3.6.11)

From

.

$$T_e = -RT \boldsymbol{y}_m [i_{as} \sin(RT \boldsymbol{q}_{rm}) - i_{bs} \cos(RT \boldsymbol{q}_{rm})],$$

using the *inverse* Park transformation

$$\begin{array}{ll} \dot{\boldsymbol{\theta}}_{as} \dot{\boldsymbol{\mathsf{u}}} & \dot{\boldsymbol{\mathsf{e}}} & \sin(RT\boldsymbol{q}_{rm}) & \cos(RT\boldsymbol{q}_{rm}) \dot{\boldsymbol{\mathsf{u}}} \dot{\boldsymbol{\mathsf{e}}}_{qs}^{r} \dot{\boldsymbol{\mathsf{u}}} \\ \dot{\boldsymbol{\mathsf{e}}} & \dot{\boldsymbol{\mathsf{u}}} = \dot{\boldsymbol{\mathsf{e}}} \\ \dot{\boldsymbol{\mathsf{e}}}_{bs} \dot{\boldsymbol{\mathsf{u}}} & \ddot{\boldsymbol{\mathsf{e}}} \cos(RT\boldsymbol{q}_{rm}) & \sin(RT\boldsymbol{q}_{rm}) \dot{\boldsymbol{\mathsf{u}}} \ddot{\boldsymbol{\mathsf{e}}}_{ds}^{r} \dot{\boldsymbol{\mathsf{u}}} \\ \end{array} \right.$$

we have

$$T_e = RT \mathbf{y}_m i_{qs}^r \,.$$

From Newton's second law of motions, one has

$$\frac{d\boldsymbol{w}_{rm}}{dt} = \frac{RT\boldsymbol{y}_m}{J}i_{qs}^r - \frac{B_m}{J}\boldsymbol{w}_{rm} - \frac{1}{J}T_L,$$

$$\frac{d\boldsymbol{q}_{rm}}{dt} = \boldsymbol{w}_{rm}.$$
(3.6.12)

Augmenting differential equations (3.6.11) and (3.6.12), the following mathematical model of permanent-magnet synchronous motors in the rotor reference frame results

$$\frac{di_{qs}^{r}}{dt} = -\frac{r_{s}}{L_{ss}}i_{qs}^{r} - \frac{RT\boldsymbol{y}_{m}}{L_{ss}}\boldsymbol{w}_{rm} - RTi_{ds}^{r}\boldsymbol{w}_{rm} + \frac{1}{L_{ss}}u_{qs}^{r},$$

$$\frac{di_{ds}^{r}}{dt} = -\frac{r_{s}}{L_{ss}}i_{ds}^{r} + RTi_{qs}^{r}\boldsymbol{w}_{rm} + \frac{1}{L_{ss}}u_{ds}^{r},$$

$$\frac{d\boldsymbol{w}_{rm}}{dt} = \frac{RT\boldsymbol{y}_{m}}{J}i_{qs}^{r} - \frac{B_{m}}{J}\boldsymbol{w}_{rm} - \frac{1}{J}T_{L},$$

$$\frac{d\boldsymbol{q}_{rm}}{dt} = \boldsymbol{w}_{rm}.$$
(3.6.13)

In matrix form, we have



The phase currents and voltages to the *ab* motor windings must be fed using the rotor angular displacement, and

$$\begin{split} i_{as} &= -\sqrt{2}i_{M}\sin(RT\boldsymbol{q}_{rm}), \ i_{bs} = \sqrt{2}i_{M}\cos(RT\boldsymbol{q}_{rm}), \\ u_{as} &= -\sqrt{2}u_{M}\sin(RT\boldsymbol{q}_{rm}), \ u_{bs} = \sqrt{2}u_{M}\cos(RT\boldsymbol{q}_{rm}). \\ \text{From} \\ \dot{\boldsymbol{\varphi}}_{qs}^{r} \overset{i}{\mathbf{u}} \overset{e}{\mathbf{e}} \sin(RT\boldsymbol{q}_{rm}) \quad \cos(RT\boldsymbol{q}_{rm}) \overset{i}{\mathbf{u}} \overset{e}{\mathbf{e}}_{as} \overset{i}{\mathbf{u}} \\ \dot{\hat{\mathbf{e}}}_{rs}^{r} \overset{i}{\mathbf{u}} \overset{e}{\mathbf{e}} \cos(RT\boldsymbol{q}_{rm}) \quad \sin(RT\boldsymbol{q}_{rm}) \overset{i}{\mathbf{u}} \overset{e}{\mathbf{e}}_{bs} \overset{i}{\mathbf{u}} \end{split}$$

$$\ddot{\mathbf{e}}_{ds}' \hat{\mathbf{u}} \quad \ddot{\mathbf{e}} \cos(RT \mathbf{q}_{rm})$$

we have

$$\begin{split} i_{qs}^{r} &= -i_{as} \sin(RT\boldsymbol{q}_{rm}) + i_{bs} \cos(RT\boldsymbol{q}_{rm}) ,\\ i_{ds}^{r} &= i_{as} \cos(RT\boldsymbol{q}_{rm}) + i_{bs} \sin(RT\boldsymbol{q}_{rm}) .\\ \text{Therefore,}\\ i_{qs}^{r} &= \sqrt{2}i_{M} \sin^{2}(RT\boldsymbol{q}_{rm}) + \sqrt{2}i_{M} \cos^{2}(RT\boldsymbol{q}_{rm}) = \sqrt{2}i_{M} , \end{split}$$

and

 $i_{ds}^{r} = -\sqrt{2}i_{M}\sin(RT\boldsymbol{q}_{rm})\cos(RT\boldsymbol{q}_{rm}) + \sqrt{2}i_{M}\sin(RT\boldsymbol{q}_{rm})\cos(RT\boldsymbol{q}_{rm}) = 0.$ Thus,

$$i_{qs}^{r} = \sqrt{2}i_{M}$$
 and  $i_{ds}^{r} = 0$ .

Similarly, for the quadrature and direct voltages, from

$$\begin{array}{l} \dot{\boldsymbol{\epsilon}}\boldsymbol{u}_{rs}^{r} \dot{\boldsymbol{u}} & \dot{\boldsymbol{\epsilon}} \cdot \sin(RT\boldsymbol{q}_{rm}) \quad \cos(RT\boldsymbol{q}_{rm}) \dot{\boldsymbol{u}} \dot{\boldsymbol{\epsilon}}\boldsymbol{u}_{as} \dot{\boldsymbol{u}} \\ \dot{\boldsymbol{\epsilon}}_{rs}^{r} \dot{\boldsymbol{u}} = \dot{\boldsymbol{\epsilon}} \\ \ddot{\boldsymbol{\epsilon}}_{ds}^{r} \dot{\boldsymbol{u}} & \dot{\boldsymbol{\epsilon}}_{ds}^{r} \cos(RT\boldsymbol{q}_{rm}) \quad \sin(RT\boldsymbol{q}_{rm}) \dot{\boldsymbol{u}} \dot{\boldsymbol{\epsilon}}\boldsymbol{u}_{bs} \dot{\boldsymbol{u}} \\ \end{array}$$

one has the following expressions for the quadrature and direct voltages

$$u_{qs}^r = \sqrt{2}u_M$$
 and  $u_{ds}^r = 0$ .

If advanced shifting is used, we obtain

$$u_{qs}^{r} = \sqrt{2}u_{M}\cos j_{u}$$
 and  $u_{ds}^{r} = -\sqrt{2}u_{M}\sin j_{u}$ . (3.6.14)

Using the nonlinear differential equations (3.6.13), the block diagram of permanent-magnet stepper motors, modeled in the rotor reference frame, is developed and illustrated in Figure 3.6.3.



Figure 3.6.3. Block diagram of permanent-magnet stepper motors modeled in the rotor reference frame

Synchronous motors rotate with the synchronous angular velocity. Therefore, we have  $\mathbf{w}_r = \mathbf{w}_e$ . From (3.6.13), the resulting model of permanent-magnet stepper motors in the synchronous reference frame can be found. In particular, four nonlinear differential equations which describe the circuitry and *torsional-mechanical* dynamics are

$$\begin{aligned} \frac{di_{qs}^{e}}{dt} &= -\frac{r_{s}}{L_{ss}}i_{qs}^{e} - \frac{RT\boldsymbol{y}_{m}}{L_{ss}}\boldsymbol{w}_{rm} - RTi_{ds}^{e}\boldsymbol{w}_{rm} + \frac{1}{L_{ss}}u_{qs}^{e} \,,\\ \frac{di_{ds}^{e}}{dt} &= -\frac{r_{s}}{L_{ss}}i_{ds}^{e} + RTi_{qs}^{e}\boldsymbol{w}_{rm} + \frac{1}{L_{ss}}u_{ds}^{e} \,,\\ \frac{d\boldsymbol{w}_{rm}}{dt} &= \frac{RT\boldsymbol{y}_{m}}{J}i_{qs}^{e} - \frac{B_{m}}{J}\boldsymbol{w}_{rm} - \frac{1}{J}T_{L} \,,\\ \frac{d\boldsymbol{q}_{rm}}{dt} &= \boldsymbol{w}_{rm} \,. \end{aligned}$$

It is evident that these nonlinear differential equations cannot be linearized. Straightforward analytical and numerical analysis can be performed using the developed mathematical models.

To control the angular velocity and rotor displacement of stepper motors, one properly energizes the *as* and *bs* windings (the so-called step-by-step open-loop operation). Correspondingly, ICs must be used, and the stepper motor driver MC3479 is manufactured by Motorola, see the data, description, and operation given below.

# Monolithic ICs: Stepper Motors Driver MC3479

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#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	VM	+18	Vdc
Clamp Diode Cathode Voltage (Pin 1)	VD	V <sub>M</sub> + 5.0	Vdc
Driver Output Voltage	VOD	V <sub>M</sub> + 6.0	Vdc
Drive Output Current/Coil	IOD	±500	mA
Input Voltage (Logic Controls)	Vin	-0.5 to +7.0	Vdc
Bias/Set Current	IBS	-10	mA
Phase A output Voltage	VOA	+18	Vdc
Phase A Sink Current	IOA	20	mA
Junction Temperature	TJ	+150	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

### RECOMMENDED OPERATING CONDITIONS

Characteristic	Symbol	Min	Max	Unit
Supply Voltage	VM	+7.2	16.5	Vdc
Clamp Diode Cathode Voltage	VD	VM	V <sub>M</sub> + 4.5	Vdc
Driver Output Current (Per Coil) (Note 1)	IOD	—	350	mA
Input Voltage (Logic Controls)	Vin	0	+5.5	Vdc
Bias/Set Current (Outputs Active)	IBS	-300	-75	μA
Phase A Output Voltage	VOA	-	VM	Vdc
Phase A Sink Current	IOA	0	8.0	mA
Operating Ambient Temperature	TA	0	+70	°C

NOTE: 1. See section on Power Dissipation in Application Information.

DC ELECTRICAL CHARACTERISTICS (Specifications apply over the recommended supply voltage and temperature range, [Notes 2, 3] unless otherwise noted.)

Characteristic	Pins	Symbol	Min	Тур	Max	Unit
INPUT LOGIC LEVELS						
Threshold Voltage (Low-to-High)	7, 8,	VTLH	—	_	2.0	Vdc
Threshold Voltage (High-to-Low)	9,10	VTHL	0.8	_	-	Vdc
Hysteresis	1	VHYS	0.4	_	-	Vdc
Current: (VI = 0.4 V)	1	ΙL	-100	_	-	μA
(VI = 5.5 V)	]		-	_	+100	
(VI = 2.7 V)		—	_	+20		
DRIVER OUTPUT LEVELS						
Output High Voltage	2, 3,	VOHD				Vdc
$(I_{BS} = -300 \ \mu A): (I_{OD} = -350 \ mA)$ $(I_{OD} = -0.1 \ mA)$	14, 15		$V_{M} - 2.0$	_		
Output Low Veltage	-	Vere	v  v  -,∠		0.0	Vdo
$(I_{BS} = -300 \ \mu\text{A}, I_{OD} = 350 \ \text{mA})$		VOLD			0.0	vuc
Differential Mode Output Voltage Difference (Note 4) $(I_{BS} = -300 \ \mu A, I_{OD} = 350 \ m A)$	]	DVOD	-	—	0.15	Vdc
Common Mode Output Voltage Difference (Note 5) (IBS = $-300 \ \mu$ A, IOD = $-0.1 \ m$ A)	]	CVOD	-	_	0.15	Vdc
Output Leakage, Hi Z State	1					μA
$(0 \le V_{OD} \le V_M, I_{BS} = -5.0 \ \mu\text{A})$ $(0 \le V_{OD} \le V_M, I_{BS} = -300 \ \mu\text{A}, F/H = 2.0 \ V, OIC = 0.8 \ V)$		lOZ1 lOZ2	-100 -100	_	+100 +100	
NOTES: 2. Algebraic convention rather than absolute values is used to designate limit values.           3. Current into a pin is designated as positive. Current out of a pin is designated as negative.           4. DVDD = IVOD1,2 - VOD3,4   where: VOD1,2 = (VOHD1 - VOLD2) or (VOHD2 - VOLD1), and VOD3,4 = (VOHD3 - VOLD4) or (VOHD4 - VOLD3).           5. CVDD = IVOD1 - VOHD3 - VOLD4) or (VOHD4 - VOLD3).           5. CVDD = IVOHD1 - VOHD4 - VOHD4 .						

DC ELECTRICAL CHARACTERISTICS (Specifications apply over the recommended supply voltage and temperature range. [Notes 2, 3] unless otherwise noted.)

Characteristic	Pins	Symbol	Min	Тур	Max	Unit
CLAMP DIODES						
Forward Voltage $(I_D = 350 \text{ mA})$	1, 2, 3, 14,15	VDF	_	2.5	3.0	Vdc
Leakage Current (Per Diode) (Pin 1 = 21 V; Outputs = 0 V; I <sub>BS</sub> = 0 µA)	]	IDR	—	—	100	μA
PHASE A OUTPUT						
Output Low Voltage (I <sub>OA</sub> = 8.0 mA)	11	VOLA	—	—	0.4	Vdc
Off State Leakage Current (V <sub>OHA</sub> = 16.5 V)		IOHA	-	-	100	μA
POWER SUPPLY						
Power Supply Current (IOD = 0 μA, IBS = -300 μA) (L1 = V <sub>OHD</sub> , L2 = V <sub>OLD</sub> , L3 = V <sub>OHD</sub> , L4 = V <sub>OLD</sub> )	16	IMW	_	_	70	mA
(L1 = V <sub>OHD</sub> , L2 = V <sub>OLD</sub> , L3 = Hi Z, L4 = Hi Z) (L1 = V <sub>OHD</sub> , L2 = V <sub>OLD</sub> , L3 = V <sub>OHD</sub> , L4 = V <sub>OHD</sub> )		IMZ I <sub>MN</sub>	_	=	40 75	
BIAS/SET CURRENT						
To Set Phase A	6	IBS	-5.0	—	-	μA
PACKAGE THERMAL CHARACTERISTICS						
Characteristic			Min	Тур	Max	Unit
Thermal Resistance, Junction-to-Ambient (No Heatsink)			_	45	-	°C/W
AC SWITCHING CHARACTERISTICS. (T <sub>A</sub> = +25°C, V <sub>M</sub> = 12 V) (See Figures 2, 3, 4)						
Characteristic	Pins	Symbol	Min	Тур	Max	Unit
Clock Frequency	7	<sup>t</sup> CK	0	-	50	kHz
Clock Pulse Width (High)		PWCKH	10	—	—	μs
Clock Pulse Width (Low)		PWCKL	10	—	—	μs
Bias/Set Pulse Width		PWBS	10	—	—	μs
Setup Time (CW/CCW and F/HS)		tsu	5.0	—	—	μs
Hold Time (CW/CCW and F/HS)	10–7 9–7	tn	10	-	-	μs
Propagation Delay (Clk-to-Driver Output)		<sup>t</sup> PCD	_	8.0	_	μs
Propagation Delay (Bias/Set-to-Driver Output)		tPBSD	—	1.0	—	μs
Propagation Delay (Clk-to-Phase A Low)	7–11	<sup>t</sup> PHLA	—	12	_	μs

7–11

<sup>t</sup>PLHA

5.0

μs

NOTES: 1. Algebraic convention rather than absolute values is used to designate limit values. 2. Current into a pin is designated as positive. Current out of a pin is designated as negative.

Propagation Delay (Clk-to-Phase A High

Figure 2. AC Test Circuit

#### Figure 3. Bias/Set Timing (Refer to Figure 2)





Note:  $t_r$ ,  $t_f$  (10% to 90%) for input signals are  $\leq$  25ns.

#### PIN FUNCTION DESCRIPTION

Pin No.				
20-Pin	16-Pin	Function	Symbol	Description
20	16	Power Supply	VM	Power supply pin for both the logic circuit and the motor coil current. Voltage range is +7.2 to +16.5 volts.
4, 5, 6, 7, 14, 15, 16, 17	4, 5, 12, 13	Ground	Gnd	Ground pins for the logic circuit and the motor coil current. The physical configuration of the pins aids In dissipating heat from within the IC package.
1	1	Clamp Diode Voltage	VD	This pin is used to protect the outputs where large voltage spikes may occur as the motor coils are switched. Typically a diode is connected between this pin and Pin 16. See Figure 11.
2, 3, 18, 19	2, 3, 14, 15	Driver Outputs	L1, L2 L3, L4	High current outputs for the motor coils. L1 and L2 are connected to one coil, and L3 and L4 to the other coil.
8	6	Bias/Set	Ē/S	This pin is typically 0.7 volts below V <sub>M</sub> . The current out of this pin (through a resistor to ground) determines the maximum output sink current. it the pin is opened (I <sub>BS</sub> < $5.0 \mu$ A) the outputs assume a high impedance condition, while the internal logic presets to a Phase A condition.
9	7	Clock	Clk	The positive edge of the clock input switches the outputs to the next position. This input has no effect if Pin 6 is open.
11	9	Full/Half Step	F/HS	When low (Logic "0"), each clock input pulse will causes the motor to rotate one full step. When high, each clock pulse will cause the motor to rotate one–half step. See Figure 7 for sequence.
12	10	Clockwise/ Counterclockwise	CW/CCW	This input allows reversing the rotation of the motor. Sea Figure 7 for sequence.
10	8	Output Impedance Control	OIC	This input is relevant only in the hall step mode (Pin 9 > 2.0 V). When low (Logic "O"), the two driver outputs of the non-energized coil will be in a high Impedance condition. Mum high the same driver outputs will be at a low impedance referenced to V <sub>M</sub> . See Figure 7.
13	11	Phase A	Ph A	This open-collector output indicates (when low) that the driver outputs are in the Phase A condition (L1 = L3 = V <sub>OHD</sub> , L2 = L4 = V <sub>OLD</sub> ).

#### APPLICATION INFORMATION

#### General

The MC3479 integrated circuit is designed to drive a stepper positioning motor in applications such as disk drives and robotics. The outputs can provide up to 350 mA to each of two coils of a two-phase motor. The outputs change state with each low-to-high transition of the clock input, with the new output state depending on the previous state, as well as the input conditions at the logic controls.

#### Outputs

The outputs (L1–L4) are high current outputs (see Figure 5), which when connected to a two-phase motor, provide two full-bridge configurations (L3 and L4 are not shown in Figure 5). The polarities applied to the motor coils depend on which transistor ( $Q_H$  or  $Q_L$ ) of each output is on, which in turn depends on the inputs and the decoding circling circuitry.



The maximum sink current available at the outputs is a function of the resistor connected between Pin 6 and ground (see section on Bias/Set operation). Whenever the outputs are to be in a high impedance state, both transistors (Q<sub>H</sub> and Q<sub>L</sub> of Figure 5) of each output are off.

#### VD

This pin allows for provision of a current path for the motor coil current during switching, in order to suppress back-EMF voltage spikes. Vp is normally connected to VM (Pin 16) through a diode (zener or regular), a resistor, or directly. The peaks instantaneous voltage at the outputs must not exceed VM by more than 6.0 V. The voltage drop across the internal clamping diodes must be included in this portion of the design (see Figure 6). Note the parasitic diodes (Figure 5) across each QL of each output provide for a complete circuit path for the switched current.

Figure 6. Clamp Diode Characteristics



### Full/Half Step

When this input is at a Logic "0" (<0.8 V), the outputs change a full step with each clock cycle, with the sequence direction depending on the  $\overline{CW}/CCW$  input. There are four steps (Phase A, B, C, D) for each complete cycle of the sequencing logic. Current flows through both motor coils during each step, as shown in Figure 7.

When taken to a Logic "1" (>2.0 V), the outputs change a half step with each clock cycle, with the sequence direction depending on the  $\overline{CW}/CCW$  input, Eight steps (Phase A to  $\overline{H}$ ) result for each complete cycle of the sequencing logic. Phase  $\overline{A}, \overline{C}, \overline{E}$  and  $\overline{G}$  correspond (in polarity) to Phase  $\overline{A}, \overline{B}, \overline{C}$ , and  $\overline{D}$ , respectively, of the full step sequence. Phase  $\overline{B}, \overline{D}, \overline{F}$  and  $\overline{H}$  provide current to one motor coil, while de-energizing the other coil. The condition of the outputs of the de-energized coil depends on the OIC input, see Figure 7 timing diagram.

#### OIC

The output impedance control input determines the output impedance to the de-energized coil when <u>operating</u> in the half-step mode. When the outputs are in <u>Phase B</u>, D,  $\bar{F}$  or  $\bar{H}$  (Figure 7) and this input is at a Logic "0" (<0.8 V), the two outputs to the de-energized coil are in a high impedance condition—QL and QH of both outputs (Figure 5) are off. When this input is at a Logic "1" (>2.0 V), a low impedance output is provided to the de-energized coil as both outputs have QH on (QL off). To complete the low impedance path requires connecting VD to VM as described elsewhere in this data sheet.

#### Bias/Set

This pin can be used for three functions: a) determining the maximum output sink current; b) setting the internal logic to a known state; and c) reducing power consumption.

a) The maximum output sink current is determined by the base drive current supplied to the lower transistors ( $O_{LS}$ of Figure 5) of each output, which in turn, is a function of Igs. The appropriate value of Igs is determined by:

$$I_{BS} = I_{OD} \times 0.86$$

where  $\mathsf{I}_{BS}$  is in microamps, and  $\mathsf{I}_{OD}$  is the motor current/coil in milliamps.



The value of  $\mathsf{R}_\mathsf{B}$  (between this pin and ground) is then determined by:

$$R_{B} = \frac{V_{M} - 0.7 V}{I_{BS}}$$

b) When this pin is opened (raised to V<sub>M</sub>) such that I<sub>BS</sub> is <5.0 µA, the internal logic is set to the Phase A condition, and the four driver outputs are put into a high impedance state. The Phase A output (Pin 11) goes active (low), and input signals at the controls are ignored during this time. Upon re-establishing I<sub>BS</sub>, the driver outputs become active, and will be in the Phase A position (L1 = L3 = V<sub>OHD</sub>. L2 = L4 = V<sub>OLD</sub>). The circuit will then respond to the inputs at the controls.

The Set function (opening this pin) can be used as a power-up reset while supply voltages are settling. A CMOS logic gate (powered by V<sub>M</sub>) can be used to control this pin as shown in Figure 11.

c) Whenever the motor is not being stepped, power dissipation in the IC and in the motor may be lowered by reducing IgS, so as to reduce the output (motor) current. Setting I<sub>BS</sub> to 75  $\mu$ A will reduce the motor current, but will not reset the internal logic as described above. See Figure 12 for a suggested circuit.

#### **Power Dissipation**

The power dissipated by the MC3479 must be such that the junction temperature (T<sub>J</sub>) does not exceed 150°C. The power dissipated can be expressed as:

$$P = (V_M \times I_M) + (2 \times I_{OD}) [(V_M - V_{OHD}) + V_{OLD}]$$

where V<sub>M</sub> = Supply voltage;

 $I_{M}$  = Supply current other than I<sub>OD</sub>; I<sub>OD</sub> = Output current to each motor coil; V<sub>OHD</sub> = Driver output high voltage;

VOHD - Driver output high voltage

 $V_{OLD} = Driver output low voltage.$ 

The power supply current  $(I_M)$  is obtained from Figure 8. After the power dissipation is calculated, the junction temperature can be calculated using:

 $T_J = (P \times R_{\theta JA}) + T_A$ 

where  $R_{\theta JA}$  = Junction-to-ambient thermal resistance (52°C/W for the DIP, 72°C/W for the FN Package);

T<sub>A</sub> = Ambient Temperature.



For example, assume an application where V<sub>M</sub> = 12 V, the motor requires 200 mA/coil, operating at room temperature with no heatsink on the IC. IBS is calculated:

$$\begin{split} I_{BS} &= 200 \times 0.86 \\ I_{BS} &= 172 \ \mu A \\ R_B \text{ is calculated:} \end{split}$$

From Figure 8, I<sub>M</sub> (max) is determined to be 40 mA. From Figure 9, V<sub>OLD</sub> is 0.46 volts, and from Figure 10, (V<sub>M</sub>-V<sub>OHD</sub>) is 1.4 volts.

$$\begin{array}{l} \mathsf{P} = (12 \times 0.040) + (2 \times 0.2) \; (1.4 + 0.46) \\ \mathsf{P} = 1.22 \; \mathsf{W} \\ \mathsf{T}_J = (1.22 \; \mathsf{W} \times 52^\circ \mathsf{C}/\mathsf{W}) + 25^\circ \mathsf{C} \\ \mathsf{T}_J = 88^\circ \mathsf{C} \end{array}$$

This temperature is well below the maximum limit. If the calculated T<sub>J</sub> had been higher than 150°C, a heatsink such as the Staver Co. V–7 Series, Aavid #5802, or Thermalloy #6012 could be used to reduce  $R_{0,JA}$ . In extreme cases, forced air cooling should be considered.

The above calculation, and  $R_{0,JA}$ , assumes that a ground plane is provided under the MC3479 (either or both sides of the PC board) to aid in the heat dissipation. Single nominal width traces leading from the four ground pins should be avoided as this will increase TJ, as well as provide potentially disruptive ground noise and I<sub>R</sub> drops when switching the motor current.





Figure 10. Maximum Saturation Voltage — Driver Output High



### Figure 11. Typical Applications Circuit



Figure 12. Power Reduction



<sup>-</sup> Suggested value for R<sub>B1</sub> (V<sub>M</sub> = 12 V) is 150 kΩ - R<sub>B</sub> calculation (see text) must take into account the current through R<sub>B1</sub>.

## 3.7. NANOMACHINES: NANOMOTORS AND NANOGENERATORS

Molecular nanomotors and nanogenerators with moving components will be briefly studied in this section. Nanomachines must satisfy the general performance specifications such as efficiency, reliability, quality, environmental requirements (electromagnetic interference, temperature, pressure, contamination, radiation, vibration), etc. High levels of performance, efficiency, reliability, and robustness are desired. Based upon the results covered in the previous sections, rotational and translational nanoscale machines are illustrated in Figure 3.7.1.





Figure 3.7.1. Rotational and translational (linear) nanomachines:

(a) rotating nanomotor and nanogenerator with molecular poles (formed by  $+e_q$  and  $-e_q$ ) and molecular bearing (formed by  $+e_b$  and  $-e_b$ );

It is evident that these low cost nanomachines are high-performance, manufacturable, easy-to-assemble (using nanoscale building blocks through the "bottom-up" and "top-down" approaches), robust, and reliable nanodevices.

Two rotating molecules (positive and negative doped molecules with charges  $+e_q$  and  $-e_q$ ) and molecular nanocylinder form the rotor (motion nanostructure). The electromagnetic field is developed by nanoantenna or nanocircuitry (nanoICs). The electromagnetic torque is produced, and nanomotor rotates.

The rotational and translational nanomotors can be used as nanoswitches, nanologics, and nanomemories which are the basic components of nanocomputers.

The nanomachines, given in Figure 3.7.1, can be used as nanogenerators because the voltage is induced if the force or torque are applied to the rotors. The rotational and translational nanogenerators can be used as nanoaccelerometers and nanogyroscopes (to measure linear and angular accelerations), nanoscale shear stress sensors, nanoscale flow sensors, etc.

These rotational and translational nanomachines can be comprehensively studied using the results reported in this and previous chapters. The documented nanomachines, which are efficient, robust, highly reliable, and can be operated in severe environments, are the departure from the biomolecular (DNA) based nanomachines which usually cannot meet the imposed requirements and standards. Thus, the proposed nanomachines allow one to overcome the well-known difficulties. The researched solution, augmented with the fundamental results covered, provides an unified benchmarking avenue to analyze actuation/sensing – energy transfer – controlling – feedback mechanism – fabrication at the nano- and microscale level.

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## CHAPTER 4

# CONTROL OF NANO- AND MICROELECTROMECHANICAL SYSTEMS

# 4.1. FUNDAMENTALS OF ELECTROMAGNETIC RADIATION AND ANTENNAS IN NANO- AND MICROSCALE ELECTROMECHANICAL SYSTEMS

The electromagnetic power is generated and radiated by antennas. Timevarying current radiates electromagnetic waves (radiated electromagnetic fields). Radiation pattern, beam width, directivity, and other major characteristics can be studied using Maxwell's equations, see Section 2.2. We use the vectors of the electric field intensity E, electric flux density D, magnetic field intensity H, and magnetic flux density B. The constitutive equations are

 $\mathbf{D} = e\mathbf{E}$  and  $\mathbf{B} = m\mathbf{H}$ 

where  $\boldsymbol{e}$  is the permittivity;  $\boldsymbol{m}$  is the permiability.

It was shown in Section 2.2 that in the static (time-invariant) fields, electric and magnetic field vectors form separate and independent pairs. That is, E and D are not related to H and B, and vice versa. However, for time-varying electric and magnetic fields, we have the following fundamental electromagnetic equations

$$\begin{split} \tilde{\mathsf{N}} &\stackrel{\cdot}{\to} \mathbf{E}(x, y, z, t) = -\mathbf{m} \frac{ \sqrt{\mathbf{M}}(x, y, z, t)}{\sqrt{\mathbf{n}}t}, \\ \tilde{\mathsf{N}} &\stackrel{\cdot}{\to} \mathbf{H}(x, y, z, t) = \mathbf{s} \mathbf{E}(x, y, z, t) + \mathbf{e} \frac{ \sqrt{\mathbf{E}}(x, y, z, t)}{\sqrt{\mathbf{n}}t} + \mathbf{J}(x, y, z, t), \\ \tilde{\mathsf{N}} &\stackrel{\times}{\to} \mathbf{E}(x, y, z, t) = \frac{\mathbf{r}_v(x, y, z, t)}{\mathbf{e}}, \\ \tilde{\mathsf{N}} &\stackrel{\times}{\to} \mathbf{H}(x, y, z, t) = 0, \end{split}$$

where **J** is the current density, and using the conductivity **S**, we have  $\mathbf{J} = \mathbf{S}\mathbf{E}$ ;  $\mathbf{r}_{v}$  is the volume charge density.

The total current density is the sum of the source current  $\mathbf{J}_s$  and the conduction current density  $\mathbf{sE}$  (due to the field created by the source  $\mathbf{J}_s$ ). Thus,

 $\mathbf{J}_{S} = \mathbf{J}_{S} + \mathbf{s}\mathbf{E}$ .

The equation of conservation of charge (continuity equation) is

$$\overset{\bullet}{\mathbf{O}} \times d\mathbf{s} = -\frac{d}{dt} \overset{\bullet}{\mathbf{O}}_{v} dv,$$

and in the point form one obtains

$$\tilde{\mathsf{N}} \times \mathbf{J}(x, y, z, t) = - \frac{\|\mathbf{r}_{v}(x, y, z, t)\|}{\|t\|}.$$

Therefore, the net outflow of current from a closed surface results in decrease of the charge enclosed by the surface.

The electromagnetic waves transfer the electromagnetic power. That is, the energy is delivered by means of electromagnetic waves. Using equations

$$\tilde{\mathsf{N}} \stackrel{\prime}{=} \mathbf{E} = -\mathbf{m} \frac{\boldsymbol{\Pi} \mathbf{H}}{\boldsymbol{\Pi} t}$$
 and  $\tilde{\mathsf{N}} \stackrel{\prime}{=} \mathbf{H} = \mathbf{e} \frac{\boldsymbol{\Pi} \mathbf{E}}{\boldsymbol{\Pi} t} + \mathbf{J}$ 

we have

$$\tilde{\mathsf{N}} \times (\mathbf{E} \cdot \mathbf{H}) = \mathbf{H} \times (\tilde{\mathsf{N}} \cdot \mathbf{E}) - \mathbf{E} \times (\tilde{\mathsf{N}} \cdot \mathbf{H}) = -\mathbf{H} \times \mathbf{m} \frac{\mathbf{\Pi}\mathbf{H}}{\mathbf{\Pi}t} - \mathbf{E} \times \mathbf{e}^{\mathbf{H}}_{\mathbf{e}} \frac{\mathbf{\Pi}\mathbf{E}}{\mathbf{\Pi}t} + \mathbf{J}^{\mathbf{O}}_{\mathbf{e}}.$$

In a media, where the constitute parameters are constant (time-invariant), we have the so-called point-function relationship

$$\tilde{\mathbf{N}} \times (\mathbf{E}' \mathbf{H}) = -\frac{\boldsymbol{\varPi}}{\boldsymbol{\varPi} t} \left( \frac{1}{2} \boldsymbol{e} E^2 + \frac{1}{2} \boldsymbol{n} \boldsymbol{H}^2 \right) - \boldsymbol{s} E^2.$$

In integral form one obtains

$$\mathbf{\check{O}E'H} \times d\mathbf{s} = -\frac{\mathbf{\int}}{\mathbf{\int}t} \mathbf{\check{O}}_{v} \frac{1}{2} \mathbf{e}E^{2} + \frac{1}{2} \mathbf{m}H^{2} dv - \mathbf{\check{O}E}^{2} dv.$$
  
time-rate of change of energy stored in  
the electric field E and magnetic field H ohmic power dissipated  
in the presence of E

The right side of the equation derived gives the rate of decrease of the electric and magnetic energies stored minus the ohmic power dissipated as heat in the volume v. The pointing vector, which is a power density vector, represents the power flows per unit area, and

# $\mathbf{P} = \mathbf{E'H}$ .

Furthermore,

$$\overset{\bullet}{\mathbf{O}} \mathbf{E} \stackrel{\bullet}{\mathbf{H}} \times d\mathbf{s} = \overset{\bullet}{\mathbf{O}} \mathbf{P} \times d\mathbf{s} = \frac{\mathscr{I}}{\mathscr{I}} \underbrace{\mathsf{H}}_{v} \underbrace{\mathsf{O}}_{v} w_{E} + w_{H} dv + \overset{\bullet}{\mathbf{O}} \mathbf{s} dv$$

power leaving the enclosed volume

where  $w_E = \frac{1}{2} e E^2$  and  $w_H = \frac{1}{2} m H^2$  are the electric and magnetic energy densities;  $\mathbf{r}_s = \mathbf{s} E^2 = \frac{1}{\mathbf{s}} J^2$  is the ohmic power density.

The important conclusion is that the total power transferred into a closed surface s at any instant equals the sum of the rate of increase of the stored electric and magnetic energies and the ohmic power dissipated within the enclosed volume v.

If the source charge density  $\mathbf{r}_{v}(x, y, z, t)$  and the source current density  $\mathbf{J}(x, y, z, t)$  vary sinusoidally, the electromagnetic field also vary sinusoidally. Hence, we have deal with the so-called time-harmonic electromagnetic fields. The sinusoidal time-varying electromagnetic fields will be studied. Hence, the phasor analysis is applied. For example,

$$\mathbf{E}(\mathbf{r}) = E_x(\mathbf{r})\mathbf{a}_x + E_y(\mathbf{r})\mathbf{a}_y + E_z(\mathbf{r})\mathbf{a}_z$$

The electric field intensity components are the complex functions. In particular,

$$E_x(\mathbf{r}) = E_{x\text{Re}} + jE_{x\text{Im}}, \ E_y(\mathbf{r}) = E_{y\text{Re}} + jE_{y\text{Im}}, \ E_z(\mathbf{r}) = E_{z\text{Re}} + jE_{z\text{Im}}.$$

For the real electromagnetic field, we have

 $E_x(\mathbf{r},t) = E_{x\text{Re}}(\mathbf{r})\cos wt - E_{x\text{Im}}(\mathbf{r})\sin wt$ .

One obtains the time-harmonic electromagnetic field equations. In particular,

• Faraday's law  $\tilde{N} \in E = -j wmH$ ,

• generalized Amphere's law  $\tilde{N}' H = sE + jweE + J = jwE + e = jwE + J$ ,

- Gauss's law  $\tilde{N} \times E = \frac{r_v}{\frac{s}{iw} + e}$ ,
- Continuity of magnetic flux  $\tilde{N} \times \mathbf{H} = 0$ ,
- Continuity law  $\tilde{\mathbf{N}} \times \mathbf{J} = -j \boldsymbol{w} \boldsymbol{r}_{v},$  (4.1.1)

where  $\hat{\vec{e}}_{jw} = \hat{\vec{e}}_{jw} + \hat{\vec{e}}_{jw}$  is the complex permittivity. However, for simplicity we will

use **e** keeping in mind that the expression for the complex permittivity  $\frac{s}{iW} + e$ must be applied.

The electric field intensity E, electric flux density D, magnetic field intensity H, magnetic flux density B, and current density J are complex-valued functions of spatial coordinates.

From the equation (4.1.1) taking the curl of  $\tilde{N} \in E = -jwmH$ , which is rewritten as  $\tilde{N} \in E = -jwB$ , and using  $\tilde{N} \in H = jwD + J$ , one obtains

$$\tilde{\mathbf{N}} \stackrel{\prime}{} \tilde{\mathbf{N}} \stackrel{\prime}{} \mathbf{E} = \mathbf{w}^2 \mathbf{m} \mathbf{E} = k_v^2 \mathbf{E} = -j \mathbf{w} \mathbf{m} \mathbf{J}$$

,

where  $k_v$  is the wave constant  $k_v = \mathbf{w}\sqrt{\mathbf{m}\mathbf{e}}$ , and in free space  $k_{v0} = \mathbf{w}\sqrt{\mathbf{m}_0\mathbf{e}_0} = \frac{\mathbf{w}}{c}$  because the speed of light is  $c = \frac{1}{\sqrt{\mathbf{m}_0\mathbf{e}_0}}$ ,

 $c=3'10^8 \, \frac{\mathrm{m}}{\mathrm{sec}} \, .$ 

The wavelength is found as

$$\boldsymbol{I}_{v} = \frac{2\boldsymbol{p}}{k_{v}} = \frac{2\boldsymbol{p}}{\boldsymbol{w}\sqrt{\boldsymbol{m}\boldsymbol{e}}}$$

and in free space  $\boldsymbol{l}_{v0} = \frac{2\boldsymbol{p}}{k_{v0}} = \frac{2\boldsymbol{p}c}{\boldsymbol{w}}$ .

Using the magnetic vector potential A, we have  $\mathbf{B} = \tilde{\mathbf{N}} \cdot \mathbf{A}$ . Hence,

 $\tilde{\mathbf{N}}'(\mathbf{E}+j\mathbf{w}\mathbf{A})=0,$ 

and thus

 $\mathbf{E} + j \mathbf{W} \mathbf{A} = - \tilde{\mathbf{N}} \ddot{\mathbf{E}} ,$ 

where  $\mathbf{\ddot{E}}$  is the scalar potential.

To guarantee that  $\tilde{N}' H = jwD + J$  holds, it is required that

$$\tilde{N}' mH = \tilde{N}' \tilde{N}' A = \tilde{N}\tilde{N} \times A - \tilde{N}^2 A = jwmeE + mJ$$

Therefore, one finally finds the equation needed to be solved

$$\tilde{\mathbf{N}}^2 \mathbf{A} + k_v^2 \mathbf{A} = \tilde{\mathbf{N}} (\tilde{\mathbf{N}} \times \mathbf{A} + j \mathbf{w} \mathbf{m} \mathbf{e} \ddot{\mathbf{E}}) - \mathbf{m} \mathbf{J}$$

Taking note of the Lorentz condition  $\tilde{N} \times A = -j wme \dot{E}$ , one obtains.

$$\tilde{\mathbf{N}}^2 \mathbf{A} + k_v^2 \mathbf{A} = - \mathbf{m} \mathbf{J} \,.$$

Thus, the equation for  $\mathbf{\ddot{E}}$  is found. In particular,

$$\tilde{\mathbf{N}}^2 \ddot{\mathbf{E}} + k_v^2 \ddot{\mathbf{E}} = -\frac{\mathbf{r}_v}{\mathbf{e}}$$

The equation for the magnetic vector potential is found solving the following inhomogeneous Helmholtz equation

 $\tilde{\mathbf{N}}^2 \mathbf{A} + k_v^2 \mathbf{A} = - \mathbf{m} \mathbf{J} \,.$ 

The expression for the electromagnetic field intensity, in terms of the vector potential, is

$$\mathbf{E} = -j\mathbf{w}\mathbf{A} + \frac{\tilde{\mathbf{N}}\tilde{\mathbf{N}}\times\mathbf{A}}{j\mathbf{w}\mathbf{m}\mathbf{e}}.$$

To derive **E**, one must have **A**. The Laplacian for **A** in different coordinate systems can be found. For example, we have

$$\begin{split} \tilde{\mathbf{N}}^2 A_x + k_v^2 A_x &= - \mathbf{m} J_x, \\ \tilde{\mathbf{N}}^2 A_y + k_v^2 A_y &= - \mathbf{m} J_y, \\ \tilde{\mathbf{N}}^2 A_z + k_v^2 A_z &= - \mathbf{m} J_z. \end{split}$$

It was shown that the magnetic vector potential and the scalar potential obey the time-dependent inhomogeneous wave equation

$$\underbrace{\overset{\bullet}{\mathsf{g}}}_{\mathsf{g}} \overset{\bullet}{\mathsf{h}}^2 - k \frac{\P^2 \overset{\bullet}{\mathsf{g}}}{\P t^2 \overset{\bullet}{\overset{\bullet}{\mathsf{g}}}} \mathcal{W}(\mathbf{r}, t) = -F(\mathbf{r}, t) \,.$$

The solution of this equation is found using Green's function as

$$W(\mathbf{r},t) = -\overleftarrow{\mathbf{OOOO}}^F(\mathbf{r}',t')G(\mathbf{r}-\mathbf{r}';t-t')dt'd\mathbf{t}',$$

where  $G(\mathbf{r} - \mathbf{r}'; t - t') = -\frac{1}{4p|\mathbf{r} - \mathbf{r}'|}d(t - t' - k|\mathbf{r} - \mathbf{r}|).$ 

The so-called retarded solution is

$$W(\mathbf{r},t) = -\overleftarrow{\mathbf{OO}} \frac{F(\mathbf{r}',t'-k|\mathbf{r}-\mathbf{r}'|)}{|\mathbf{r}-\mathbf{r}'|} dt'$$

For sinusoidal electromagnetic fields, we apply the Fourier analysis to obtain

$$W(\mathbf{r}) = -\frac{1}{4p} \overleftarrow{\mathrm{cov}}^{e^{-jk_{v}|\mathbf{r}-\mathbf{r}'|}} F(\mathbf{r}')dt'.$$

Thus, we have the expressions for the phasor retarded potentials

$$\mathbf{A}(\mathbf{r}) = \frac{\mathbf{m}}{4\mathbf{p}} \underbrace{\mathbf{o}}_{v} \underbrace{\mathbf{e}^{-jk_{v}|\mathbf{r}-\mathbf{r}'|}}_{\mathbf{r}|\mathbf{r}-\mathbf{r}'|} \mathbf{J}(\mathbf{r}') dv,$$
$$\mathbf{\ddot{E}}(\mathbf{r}) = \frac{1}{4\mathbf{p}\mathbf{e}} \underbrace{\mathbf{o}}_{v} \underbrace{\mathbf{e}^{-jk_{v}|\mathbf{r}-\mathbf{r}'|}}_{\mathbf{r}|\mathbf{r}-\mathbf{r}'|} \mathbf{r}(\mathbf{r}') dv.$$

*Example 4.1.1.* 

Consider a short (dl) thin filament of current located in the origin, see Figure 4.1.1. Derive the expressions for magnetic vector potential and electromagnetic field intensities.



Figure 4.1.1. Current filament in the spherical coordinate system

Solution.

The magnetic vector potential has only a *z* component, and thus, from  $\tilde{N}^2 \mathbf{A} + k_y^2 \mathbf{A} = -\mathbf{m}\mathbf{J}$ ,

we have

$$\tilde{\mathbf{N}}^2 A_z + k_v^2 A_z = -\mathbf{m} J_z = -\mathbf{m} \frac{l}{ds},$$

where *ds* is the cross-sectional area of the filament.

Taking note of the spherical symmetry, we conclude that the magnetic vector potential  $A_{z}$  is not a function of the polar and azimuth angles q and f. In particular, the following equation results

$$\frac{1}{r^2} \frac{\P}{\P r} r^2 \frac{\P A_z}{\P r} + k_v^2 A_z = 0.$$

It is well-known that the solution of equation  $\frac{d^2 \mathbf{y}}{d \mathbf{y}^2} + k_v^2 \mathbf{y} = 0$  has two

components. In particular,  $e^{jk_v r}$  (outward propagation) and  $e^{-jk_v r}$  (inward propagation). The inward propagation is not a part of solution for the filament located in the origin. Thus, we have

 $\mathbf{y}(t,r) = ae^{j\mathbf{w}t - jk_v r}$  (outward propagating spherical wave).

In free space, we have

$$\mathbf{y}(t,r) = a e^{j \mathbf{w}(t-r/c)}.$$

Substituting 
$$A_z = \frac{\mathbf{y}}{r}$$
, one obtains  $A_z(r) = \frac{a}{r}e^{-\frac{j\mathbf{w}r}{c}}$ 

To find the constant *a*, we use the volume integral

$$\bigotimes_{v}^{n} A_{z} dv = \bigotimes_{s}^{n} A_{z} \times \mathbf{a}_{r} r_{d}^{2} \sin \mathbf{q} d\mathbf{q} d\mathbf{f} = -\frac{\mathbf{w}^{2}}{c^{2}} \bigotimes_{v}^{n} A_{z} dv - \mathbf{m}_{0} \bigotimes_{v}^{n} J_{z} dv,$$

where the differential spherical volume is  $dv = r_d^2 \sin q dq df dr$ ;  $r_d$  is the differential radius.

Making use of

$$\tilde{N}A_z \rtimes \mathbf{a}_r = \frac{\P A_z}{\P r} = - \mathop{\mathrm{e}}\limits_{\mathbf{e}}^{\mathbf{e}} + j \frac{\mathbf{w}}{c} r \frac{\ddot{\mathbf{o}} a}{\dot{\mathbf{p}} r^2} e^{-j \frac{\mathbf{w}}{c} r},$$

we have

one

$$\lim_{r_d \circledast 0} \bigotimes_{0 \ 0}^{2pp} \bigotimes_{c=0}^{2p} \stackrel{w}{\underset{c}{\text{c}}} f_d + j \frac{w}{c} r_d \frac{\ddot{o}}{a} e^{-j \frac{w}{c} r_d} \sin q dq df = -4pa = -m_0 i dl,$$
has  $a = \frac{m_0 i dl}{4p}.$ 

Thus, the following expression results

$$A_z(r) = \frac{\mathbf{m}_0 i dl}{4\mathbf{p} r} e^{-\frac{j\mathbf{w}r}{c}}.$$

Therefore, the final equation for the magnetic vector potential (outward propagating spherical wave) is

$$\mathbf{A}(r) = \frac{\mathbf{m}_0 i dl}{4\mathbf{p} r} e^{-\frac{j \mathbf{w} r}{c}} \mathbf{a}_z.$$

From  $\mathbf{a}_z = \mathbf{a}_r \cos q - \mathbf{a}_q \sin q$ , we have

$$\mathbf{A}(r) = \frac{\mathbf{m}_0 i dl}{4\mathbf{p} r} e^{-\frac{j \mathbf{w} r}{c}} (\mathbf{a}_r \cos \mathbf{q} - \mathbf{a}_q \sin \mathbf{q})$$

The magnetic and electric field intensities are found using

$$\mathbf{B} = \tilde{\mathbf{N}}' \mathbf{A} \text{ and } \mathbf{E} = -jw\mathbf{A} + \frac{\mathbf{NN} \times \mathbf{A}}{jwme}$$

Then, one finds

$$\mathbf{H}(r) = \frac{1}{\mathbf{m}_{0}} \tilde{\mathbf{N}} \cdot \mathbf{A}(r) = \frac{idl \sin q}{4pr} \overset{\text{gej}}{\mathbf{c}} \frac{\mathbf{w}}{cr} + \frac{1}{r^{2}} \overset{\text{o}}{\mathbf{c}} e^{-\frac{j\mathbf{w}r}{c}} \mathbf{a}_{f},$$
$$\mathbf{E}(r) = \frac{j\sqrt{\frac{\mathbf{m}_{0}}{\mathbf{e}_{0}}} cidl}{4pw} \cos q \overset{\text{gej}}{\mathbf{c}} \frac{\mathbf{w}}{cr^{2}} + \frac{1}{r^{3}} \overset{\text{o}}{\mathbf{c}} e^{-\frac{j\mathbf{w}r}{c}} \mathbf{a}_{r},$$
$$- \frac{j\sqrt{\frac{\mathbf{m}_{0}}{\mathbf{e}_{0}}} cidl}{4pw} \sin q \overset{\text{ge}}{\mathbf{c}} \frac{\mathbf{w}^{2}}{c^{2}r} + \frac{j\mathbf{w}}{cr^{2}} + \frac{1}{r^{3}} \overset{\text{o}}{\mathbf{c}} e^{-\frac{j\mathbf{w}r}{c}} \mathbf{a}_{q}.$$

The intrinsic impedance is given as

$$Z_0 = \sqrt{\frac{\boldsymbol{m}_0}{\boldsymbol{e}_0}}$$
, and  $Y_0 = \frac{1}{Z_0} = \sqrt{\frac{\boldsymbol{e}_0}{\boldsymbol{m}_0}}$ .

Near-field and far-field electromagnetic radiation fields can be found, simplifying the expressions for H(r) and E(r).

For near-field, we have

$$\mathbf{H}(r) = \frac{1}{\mathbf{m}_0} \tilde{\mathbf{N}} \cdot \mathbf{A}(r) = j \frac{i dl \sin q \mathbf{w}}{4\mathbf{p} c r^2} e^{-\frac{j \mathbf{w} r}{c}} \mathbf{a}_f$$
  
and  $\mathbf{E}(r) = j \frac{\sqrt{\frac{\mathbf{m}_0}{\mathbf{e}_0}} c i dl \mathbf{w}}{4\mathbf{p} c^2 r} \sin q \mathbf{a}_q.$ 

The complex Pointing vector can be found as

$$\frac{1}{2}\mathbf{E}(r)'\mathbf{H}^{*}(r)$$

The following expression for the complex power flowing out of a sphere of radius r results

$$\frac{1}{2} \bigotimes_{s} \mathbf{E}(r) \mathbf{H}^{*}(r) \mathbf{k} = \frac{\mathbf{w}^{2} \mathbf{m}_{0} \sqrt{\mathbf{m}_{0} \mathbf{e}_{0} l^{2} dl^{2}}}{12 \mathbf{p}} = \frac{\mathbf{w} \mathbf{m}_{0} k_{v} l^{2} dl^{2}}{12 \mathbf{p}}$$

The real quality is found, and the power dissipated in the sense that it travels away from source and cannot be recovered.

## *Example 4.1.2.*

Derive the expressions for the magnetic vector potential and electromagnetic field intensities for a magnetic dipole (small current loop) which is shown in Figure 4.1.2.



Figure 4.1.2. Current loop in the xy plane

## Solution.

The magnetic dipole moment is equal to the current loop are times current. That is,

$$\mathbf{M} = \boldsymbol{p} r_0^2 i \mathbf{a}_z = M \mathbf{a}_z$$

For the short current filament, it was derived in Example 4.1.1 that

$$\mathbf{A}(r) = \frac{\mathbf{m}_0 i dl}{4\mathbf{p}r} e^{-\frac{j\mathbf{W}r}{c}} \mathbf{a}_z.$$

In contrast, we have

$$\mathbf{A} = \frac{\mathbf{m}_0 i}{4\mathbf{p}} \mathbf{\partial}_{\mathbf{r}'} dl$$

The distance between the source element dl and point  $O(r, q, \frac{p}{2})$  is denoted as r'. It should be emphasized that the current filament is lies in the xy plane, and

$$dl = \mathbf{a}_{f} r_{0} d\mathbf{f} = (-\mathbf{a}_{x} \sin \mathbf{f} + \mathbf{a}_{y} \cos \mathbf{f}) r_{0} d\mathbf{f}.$$

Thus, due to the symmetry

$$\mathbf{A} = \mathbf{a}_{f} \frac{\boldsymbol{m}_{0} i r_{0}}{2\boldsymbol{p}} \mathop{\triangleright}\limits_{-\boldsymbol{p}/2}^{\boldsymbol{p}/2} \frac{\sin \boldsymbol{f}}{r'} d\boldsymbol{f},$$

where using the trigonometric identities one finds

 $r'^{2} = r^{2} + r_{0}^{2} - 2rr_{0}\sin q \sin f.$ 

Assuming that 
$$r^2 >> r_0^2$$
, we have  $\frac{1}{r'} \approx \frac{1}{r} \stackrel{\otimes}{\in} \frac{r_0}{r} \sin q \sin f \stackrel{\circ}{\div} \frac{\sigma}{\varphi}$ 

Therefore

$$\mathbf{A} = \mathbf{a}_{f} \frac{\mathbf{m}_{0} i r_{0}}{2\mathbf{p}} \sum_{p/2}^{p/2} \frac{\sin \mathbf{f}}{r'} d\mathbf{f}$$
  
=  $\mathbf{a}_{f} \frac{\mathbf{m}_{0} i r_{0}}{2\mathbf{p}r} \sum_{p/2}^{p/2} \bigotimes_{r}^{p/2} \bigotimes_{r}^{Q} \sin q \sin f \underset{\emptyset}{\text{sin}} \mathbf{f} d\mathbf{f} = \mathbf{a}_{f} \frac{\mathbf{m}_{0} i r_{0}^{2}}{4r^{2}} \sin q$ 

Having obtained the explicit expression for the vector potential, the magnetic flux density is found. In particular,

$$\mathbf{B} = \tilde{\mathbf{N}} \cdot \mathbf{A} = \tilde{\mathbf{N}} \cdot \mathbf{a}_f \frac{\mathbf{m}_0 i r_0^2}{4r^2} \sin \mathbf{q} = \frac{\mathbf{m}_0 i r_0^2}{4r^3} (2\mathbf{a}_r \cos \mathbf{q} + \mathbf{a}_q \sin \mathbf{q}).$$

Taking note of the expression for the magnetic dipole moment  $\mathbf{M} = \mathbf{p}r_0^2 i\mathbf{a}_z$ , one has

$$\mathbf{A} = \mathbf{a}_f \frac{\mathbf{m}_0 i r_0^2}{4r^2} \sin \mathbf{q} = \frac{\mathbf{m}_0}{4pr^2} \mathbf{M} \cdot \mathbf{a}_r$$

It was shown that using  $\mathbf{A} = \frac{\mathbf{m}_{0}i}{4\mathbf{p}} \partial_{l}^{T'} dl$ , the desired results are obtained.

Let us apply 
$$\mathbf{A} = \frac{\mathbf{m}_0 i}{4\mathbf{p}} \underbrace{\mathbf{o}_l^{-j \frac{\mathbf{w}}{c} r'}}_{l} dl$$
.

From 
$$e^{-j\frac{\mathbf{w}}{c}r'} \approx \hat{\mathbf{g}} - j\frac{\mathbf{w}}{c}(r'-r)\hat{\mathbf{u}}_{c}e^{-j\frac{\mathbf{w}}{c}r}$$
, we have

$$\mathbf{A} = \frac{\mathbf{m}_{0}i}{4\mathbf{p}} \underbrace{\mathbf{O}_{l}^{[1-j\frac{\mathbf{w}}{c}(r'-r)]e^{-j\frac{\mathbf{w}}{c}}}_{l} dl}_{r'} dl = \mathbf{a}_{f} \frac{\mathbf{m}_{0}M}{4\mathbf{p}r^{2}} (1+j\frac{\mathbf{w}}{c}r)e^{-j\frac{\mathbf{w}}{c}r} \sin q .$$

Therefore, one finds

The electromagnetic fields in near- and far-fields can be straightforwardly derived, and thus, the corresponding approximations for the  $E_f$ ,  $H_r$  and  $H_q$  can be obtained.

Let the current density distribution in the volume is given as  $\mathbf{J}(\mathbf{r}_0)$ , and for far-field from Figure 4.1.3 one has  $\mathbf{r} * \mathbf{r}' - \mathbf{r}_0$ .



Figure 4.1.3. Radiation from volume current distribution

The formula to calculate far-field magnetic vector potential is

$$\mathbf{A}(\mathbf{r}) = \frac{\mathbf{m}}{4\mathbf{p}\mathbf{r}} e^{-jk_v \mathbf{r}} \mathbf{\partial}_v (\mathbf{r}_0) e^{-jk_v \mathbf{r}_0} dv$$

and the electric and magnetic field intensities are found using

$$\mathbf{E} = -j\mathbf{w}\mathbf{A} + \frac{\ddot{\mathbf{N}}\ddot{\mathbf{N}}\times\mathbf{A}}{j\mathbf{w}\mathbf{m}\mathbf{e}}$$

and  $\mathbf{B} = \mathbf{\tilde{N}' A}$ .

We have

$$\mathbf{E}(\mathbf{r}) = \frac{jk_v Z_v}{4pr} e^{-jk_v r} \oint_v \mathbf{a}_r \times \mathbf{J}(\mathbf{r}_0) \mathbf{a}_r - \mathbf{J}(\mathbf{r}_0) e^{-jk_v \mathbf{r}_0} dv,$$
  
$$\mathbf{H}(\mathbf{r}) = Y_v \mathbf{a}_r \cdot \mathbf{E}(\mathbf{r}).$$

Example 4.1.3.

Consider the half-wave dipole antenna fed from a two-wire transmission line, as shown in Figure 4.1.4 The antenna is one-quarter wavelength; that is,  $-\frac{1}{4}\boldsymbol{I}_{v} \boldsymbol{\pounds} \boldsymbol{z} \boldsymbol{\pounds} \frac{1}{4}\boldsymbol{I}_{v}$ . The current distribution is  $i(z) = i_{0} \cos k_{v} z$ . Obtain the equations for electromagnetic field intensities and radiated power.



Figure 4.1.4. Half-wave dipole antenna

Solution.

The wavelength is given as  $I_v = \frac{2p}{k_v} = \frac{2p}{w\sqrt{me}}$ , and in free space we

have 
$$l_{v0} = \frac{2p}{k_{v0}} = \frac{2pc}{w}$$
.

It was emphasized that and  $k_{v0} = \mathbf{W} \sqrt{\mathbf{m}_0 \mathbf{e}_0}$ .

Making use of

$$\mathbf{E}(\mathbf{r}) = \frac{jk_v Z_v}{4\mathbf{p}r} e^{-jk_v r} \oint_v \mathbf{a}_r \times \mathbf{J}(\mathbf{r}_0) \mathbf{a}_r - \mathbf{J}(\mathbf{r}_0) e^{-jk_v \mathbf{r}_0} dv,$$

we have the following line integral

$$\mathbf{E}(\mathbf{r}) = \frac{jk_{\nu}Z_{\nu}}{4pr} e^{-jk_{\nu}r} \mathbf{\partial}_{l} (\mathbf{a}_{r} \times \mathbf{a}_{l}) \mathbf{a}_{r} - \mathbf{a}_{l} \mathbf{i}(l) e^{-jk_{\nu}\mathbf{r}_{0}} dl ,$$

where  $\mathbf{a}_l$  is the unit vector in the current direction.

Then,

$$\mathbf{E}(\mathbf{r}) = \frac{jk_{v}Z_{v}i_{0}}{4pr}e^{-jk_{v}r} \sum_{-\frac{1}{4}I_{v}}^{\frac{1}{4}I_{v}} \mathbf{a}_{r}\cos q - \mathbf{a}_{z}\cos k_{v}ze^{-jk_{v}z\cos q} dz$$
$$= \frac{jZ_{v}i_{0}\cos(\frac{1}{2}p\cos q)}{2pr\sin q}e^{-jk_{v}r}\mathbf{a}_{q}.$$

Having found the magnetic field intensity as

$$\mathbf{H}(\mathbf{r}) = Y_{v} \mathbf{a}_{r} \mathbf{E}(\mathbf{r}) = H_{f} \mathbf{a}_{f} = \frac{j i_{0} \cos(\frac{1}{2} \boldsymbol{p} \cos \boldsymbol{q})}{2 \boldsymbol{p} r \sin \boldsymbol{q}} e^{-j k_{v} r} \mathbf{a}_{f}$$

the power flux per unit area is

$$\frac{1}{2}\operatorname{Re}\left(\mathbf{E}(\mathbf{r}) \cdot \mathbf{H}(\mathbf{r})^* \rtimes_r\right) = \frac{1}{2}E_f H_f^* = \frac{\left|i_0\right|^2 Z_0 \cos^2\left(\frac{1}{2}\boldsymbol{p}\cos\boldsymbol{q}\right)}{8\boldsymbol{p}^2 r^2 \sin^2\boldsymbol{q}},$$

2

and integrating the derived expression over the surface  $\frac{|i_0|^2 Z_0}{8p^2} \bigotimes_{0 \ 0}^{2pp} \frac{\cos^2(\frac{1}{2}p\cos q)}{\sin^2 q} \sin q dq df$ , the total radiated power is found to be  $36.6|i_0|^2$ .

If the current density distribution is known, the radiation field can be found. Using Maxwell's equations, using the electric and magnetic vector potentials  $A_E$  and  $A_H$ , we have the following equations

$$\begin{split} & \left(\tilde{\mathbf{N}}^2 + k_v^2\right) \mathbf{A}_E = -\mathbf{m} \mathbf{J}_E, \\ & \left(\tilde{\mathbf{N}}^2 + k_v^2\right) \mathbf{A}_H = -\mathbf{e} \mathbf{J}_H, \\ & \mathbf{E} = -j\mathbf{w} \mathbf{A}_E + \frac{1}{j\mathbf{w}\mathbf{m}\mathbf{e}} \tilde{\mathbf{N}} \tilde{\mathbf{N}} \times \mathbf{A}_E - \frac{1}{\mathbf{e}} \tilde{\mathbf{N}} \stackrel{\prime}{\prec} \mathbf{A}_H, \\ & \mathbf{H} = -j\mathbf{w} \mathbf{A}_H + \frac{1}{j\mathbf{w}\mathbf{m}\mathbf{e}} \tilde{\mathbf{N}} \tilde{\mathbf{N}} \times \mathbf{A}_H - \frac{1}{\mathbf{m}} \tilde{\mathbf{N}} \stackrel{\prime}{\prec} \mathbf{A}_E. \end{split}$$

The solutions are

$$\mathbf{A}_{E}(\mathbf{r}) = \frac{\mathbf{m}}{4\mathbf{p}r} e^{-jk_{v}r} \mathbf{\check{o}}_{v}^{jk_{v}\mathbf{r}} \mathbf{J}_{E}(\mathbf{r})d\mathbf{r} ,$$
$$\mathbf{A}_{H}(\mathbf{r}) = \frac{\mathbf{e}}{4\mathbf{p}r} e^{-jk_{v}r} \mathbf{\check{o}}_{v}^{jk_{v}\mathbf{r}} \mathbf{J}_{H}(\mathbf{r})d\mathbf{r} .$$

Example 4.1.4.

Consider the slot (one-half wavelength long slot is dual to the half-wave dipole antenna studied in Example 4.1.3), which is exited from the coaxial line, see Figure 4.1.5. The electric field intensity in the *z*-direction is  $E = E_0 \sin k_v (l - |z|)$ . Derive the expressions for the magnetic vector potential and electromagnetic field intensities.



Figure 4.1.5. Slot antenna

Solution.

Using the magnetic current density  $\mathbf{J}_{H}$ , from

$$\bigotimes_{s} \mathbf{E} \times d\mathbf{s} = \bigotimes_{l} \mathbf{E} \times dl = -\bigotimes_{s} \mathbf{W} \mathbf{B} \times d\mathbf{s} - \bigotimes_{s} \mathbf{H} \times d\mathbf{s}$$

the boundary conditions for the magnetic current sheet are found as

$$\mathbf{a}_n \, \mathbf{E}_1 - \mathbf{a}_n \, \mathbf{E}_2 = - \mathbf{J}_H.$$

The slot antenna is exited by the magnetic current with strength  $2E_0 \sin k_v (l - |z|)$  in the *z* axis. For half-wave slot we have  $i_H = i_0 \sin k_v (l - |z|)$ , and

$$\begin{split} & (\tilde{\mathbf{N}}^2 + k_v^2) \mathbf{A}_H = -\mathbf{e} \mathbf{J}_H, \\ & \mathbf{H} = -j \mathbf{w} \mathbf{A}_H + \frac{\tilde{\mathbf{N}} \tilde{\mathbf{N}} \times \mathbf{A}_H}{j \mathbf{w} \mathbf{m} \mathbf{e}} = j \frac{i_0 Y_0 \cos(\frac{1}{2} \mathbf{p} \cos \mathbf{q})}{2 \mathbf{p} r \sin \mathbf{q}} e^{-jk_v r} \mathbf{a}_q, \\ & \mathbf{E} = -\frac{\tilde{\mathbf{N}}^* \mathbf{A}_H}{\mathbf{e}} = -j \frac{i_0 \cos(\frac{1}{2} \mathbf{p} \cos \mathbf{q})}{2 \mathbf{p} r \sin \mathbf{q}} e^{-jk_v r} \mathbf{a}_{\mathbf{f}}, \\ & \mathbf{A}_H(\mathbf{r}) = \frac{\mathbf{e}}{16\mathbf{p}} e^{-jk_v r} \mathbf{\delta}_{\mathbf{r}}^{jk_v \mathbf{r}} \mathbf{J}(\mathbf{r}) d\mathbf{s}. \end{split}$$

The boundary condition  $\mathbf{a}_n \mathbf{i} \mathbf{E} = -\frac{1}{2} \mathbf{J}_H = \mathbf{a}_n \mathbf{i} \mathbf{a}_x E_0 \sin k_v (l - |z|)$  is satisfied by the radiated electromagnetic field.

The radiation pattern of the slot antenna is the same as for the dipole antenna.

## References

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# 4.2. DESIGN OF CLOSED-LOOP NANO- AND MICROELECTROMECHANICAL SYSTEMS USING THE LYAPUNOV STABILITY THEORY

The solution of a spectrum of problems in nonlinear analysis, structural synthesis, modeling, and optimization of NEMS and MEMS lead to the development of superior high-performance NEMS and MEMS. In this section, we address introductory control issues. Mathematical models of NEMS and MEMS were derived, and the application of the Lyapunov theory is studied as applied to solve the motion control problem.

It was illustrated that NEMS and MEMS must be controlled. Nano- and microelectromechanical systems augment a great number of subsystems, and to control microscale electric motors, as discussed in previous chapters, power amplifiers (ICs) regulate the voltage or current fed to the motor windings. These power amplifiers are controlled based upon the reference (command), output, decision making, and other variables. Studying the end-to-end NEMS and MEMS behavior, usually the output is the nano- or microactuator linear and angular displacements. There exist infinite number of possible NEMS and MEMS configurations, and it is impossible to cover all possible scenarios. Therefore, our efforts will be concentrated on the generic results which can be obtained describing NEMS and MEMS by differential equations. That is, using the mathematical model, as given by differential equations, our goal is develop control algorithms to guarantee the desired performance characteristics addressing the motion control problem (settling time, accuracy, overshoot, controllability, stability, disturbance attenuation, et cetera).

Several methods have been developed to address and solve nonlinear design and motion control problems for multi-input/multi-output dynamic systems. In particular, the Hamilton-Jacobi and Lyapunov theories are found to be the most straightforward in the design of control laws.

The NEMS and MEMS dynamics is described as

$$\dot{x}(t) = F(x, r, d) + B(x)u, \quad y = H(x), \quad u_{\min} \ \pounds \ u \ \pounds \ u_{\max}, \quad x(t_0) = x_0,$$
(4.2.1)

where  $x\hat{l} \ X\hat{l} \ \hat{l}$  is the state vector;  $u\hat{l} \ U\hat{l} \ \hat{l}^{m}$  is the bounded control vector;  $r\hat{l} \ R\hat{l} \ \hat{l}^{p}$  and  $y\hat{l} \ Y\hat{l} \ \hat{l}^{p}$  are the measured reference and output vectors;  $d\hat{l} \ D\hat{l} \ \hat{l}^{p}$  is the disturbance vector;  $F(\aleph): |c'| |_{\infty} \ \hat{l}_{\infty} \ \hat{l} |_{\infty} \ \hat{l}$ 

Before engaged in the design of closed-loop systems, which will be based upon the Lyapunov stability theory, let us study stability of time-varying nonlinear dynamic systems described by

 $\dot{x}(t) = F(t, x), \ x(t_0) = x_0, \ t^3 \ 0.$ 

The following Theorem is formulated.

## Theorem.

Consider the system described by nonlinear differential equations  $\dot{x}(t) = F(t,x)$ ,  $x(t_0) = x_0$ ,  $t^3 0$ .

If there exists a positive-definite scalar function V(t, x) (called Lyapunov function) with continuous first-order partial derivatives with respect to t and x

$$\frac{dV}{dt} = \frac{\P V}{\P t} + \mathop{\mathbf{c}}\limits_{\mathbf{e}} \underbrace{\P V}_{\mathbf{q}} \stackrel{\mathbf{o}^T}{\overset{\mathbf{o}}{\overset{\mathbf{o}}}} \frac{dx}{dt} = \frac{\P V}{\P t} + \mathop{\mathbf{c}}\limits_{\mathbf{e}} \underbrace{\P V}_{\P x} \stackrel{\mathbf{o}^T}{\overset{\mathbf{o}}{\overset{\mathbf{o}}{\overset{\mathbf{o}}}} F(t,x)$$

then

• the equilibrium state is stable if the total derivative of the positive-definite function V(t,x) > 0 is  $\frac{dV}{dt} \pounds 0$ ;

- the equilibrium state is uniformly stable if the total derivative of the positive-definite decreasing function V(t,x) > 0 is  $\frac{dV}{dt} \pounds 0$ ;
- the equilibrium state is uniformly asymptotically stable in the large if the total derivative of V(t,x) > 0 is negative definite; that is,  $\frac{dV}{dt} < 0$ ;
- the equilibrium state is exponentially stable in the large if the exist the  $K_{\star}$ -functions  $\mathbf{r}_1(\mathfrak{A})$  and  $\mathbf{r}_2(\mathfrak{A})$ , and K-function  $\mathbf{r}_3(\mathfrak{A})$  such that

$$\mathbf{r}_1(\|x\|) \not\in V(t,x) \not\in \mathbf{r}_2(\|x\|) \text{ and } \frac{dV(x)}{dt} \not\in \mathbf{r}_3(\|x\|).$$

Examples are studied to illustrate how this Theorem can be straightforwardly applied.

## Example 4.2.1.

Study stability of the following nonlinear system

$$\dot{x}_1(t) = -x_1^3 - x_1 x_2^2,$$
  
$$\dot{x}_2(t) = -x_2^7, t^3 0.$$

Solution.

A scalar positive-definite function is expressed in the quadratic form as  $V(x_1, x_2) = \frac{1}{2}(x_1^2 + x_2^2)$ .

The total derivative is found to be

$$\frac{dV(x_1, x_2)}{dt} = \overset{\bullet}{\mathbf{e}} \overset{\bullet}{\mathbf{f}} \overset{\bullet}{\mathbf{f}} \frac{dx}{x} \overset{\bullet}{\mathbf{\phi}} \frac{dx}{dt} = \overset{\bullet}{\mathbf{e}} \overset{\bullet}{\mathbf{f}} \overset{\bullet}{\mathbf{f}} \overset{\bullet}{\mathbf{\phi}} F(x)$$
$$= \frac{\P V}{\P x_1} \left( -x_1^3 - x_1 x_2^2 \right) + \frac{\P V}{\P x_2} \left( -x_2^7 \right) = -x_1^4 - x_1^2 x_2^2 - x_2^8.$$
Thus, we have  $\frac{dV(x_1, x_2)}{dt} < 0.$ The total derivative of  $V(x_1, x_2) > 0$  is negative definite

Therefore, the equilibrium state is uniformly asymptotically stable.

## Example 4.2.2.

Study stability of the time-varying nonlinear system modeled by the following differential equations

$$\begin{aligned} \dot{x}_1(t) &= -x_1 + x_2^3, \\ \dot{x}_2(t) &= -e^{-10t}x_1x_2^2 - 5x_2 - x_2^3, t^3 0. \end{aligned}$$

Solution. A scalar positive-definite function is  $V(t, x_1, x_2) = \frac{1}{2} (x_1^2 + e^{10t} x_2^2), V(t, x_1, x_2) > 0.$ 

Then, the total derivative, which is expressed as

$$\frac{dV(t, x_1, x_2)}{dt} == \frac{\P V}{\P t} + \frac{\P V}{\P x_1} \left( -x_1 + x_2^3 \right) + \frac{\P V}{\P x_2} \left( -e^{-10t} x_1 x_2^2 - 5x_2 - x_2^3 \right)$$
$$= -x_1^2 - e^{10t} x_2^4,$$

is negative definite. In particular,  $\frac{dV(x_1, x_2)}{dt} < 0$ .

Hence, the equilibrium state is uniformly asymptotically stable.

## *Example* 4.2.3.

Study stability of the systems

$$\dot{x}_1(t) = -x_1 + x_2,$$
  
 $\dot{x}_2(t) = -x_1 - x_2 - x_2 |x_2|, t^3 0$ 

Solution.

The positive-definite scalar Lyapunov candidate is chosen as  $V(x_1, x_2) = \frac{1}{2} (x_1^2 + x_2^2)$ . Thus,  $V(x_1, x_2) > 0$ . The total derivative is
$$\frac{dV(x_1, x_2)}{dt} = x_1 \dot{x}_1 + x_2 \dot{x}_2 = -x_1^2 - x_2^2 (1 + |x_2|).$$

Therefore,  $\frac{dV(x_1, x_2)}{dt} < 0$ . Hence, the equilibrium state is uniformly

asymptotically stable, and the quadratic function  $V(x_1, x_2) = \frac{1}{2} (x_1^2 + x_2^2)$  is the Lyapunov function which can be used to study stability.

# Example 4.2.4.

Consider a microdrive actuated by permanent-magnet synchronous motor if  $T_L=0$ . In drive applications, using equations (3.5.12), three nonlinear differential equations in the rotor reference frame are

$$\frac{di_{qs}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}i_{qs}^{r} - \frac{\mathbf{y}_{m}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}\mathbf{w}_{r} - i_{ds}^{r}\mathbf{w}_{r} + \frac{1}{L_{ls} + \frac{3}{2}\overline{L}_{m}}u_{qs}^{r},$$

$$\frac{di_{ds}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}i_{ds}^{r} + i_{qs}^{r}\mathbf{w}_{r} + \frac{1}{L_{ls} + \frac{3}{2}\overline{L}_{m}}u_{ds}^{r},$$

$$\frac{d\mathbf{w}_{r}}{dt} = \frac{3P^{2}\mathbf{y}_{m}}{8J}i_{qs}^{r} - \frac{B_{m}}{J}\mathbf{w}_{r}.$$

Study the stability letting

1. 
$$u_{qs}^r = 0$$
 and  $u_{ds}^r = 0$  (open-loop system),

2. 
$$u_{qs}^r = 0$$
,  $u_{qs}^r = -k_w W_r$  and  $u_{ds}^r = 0$  (closed-loop system).

#### Solution.

For open-loop system we have  $u_{qs}^r = 0$  and  $u_{ds}^r = 0$ . Hence,

$$\frac{di_{qs}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}i_{qs}^{r} - \frac{\mathbf{y}_{m}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}\mathbf{w}_{r} - i_{ds}^{r}\mathbf{w}_{r},$$

$$\frac{di_{ds}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}i_{ds}^{r} + i_{qs}^{r}\mathbf{w}_{r},$$

$$\frac{d\mathbf{w}_{r}}{dt} = \frac{3P^{2}\mathbf{y}_{m}}{8J}i_{qs}^{r} - \frac{B_{m}}{J}\mathbf{w}_{r}.$$
In matrix form, one obtains

In matrix form, one obtains

$$\dot{x}(t) = \begin{pmatrix} \dot{\mathbf{e}} & \frac{r_s}{L_{ls} + \frac{3}{2}\overline{L}_m} & 0 & -\frac{\mathbf{y}_m}{L_{ls} + \frac{3}{2}\overline{L}_m} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \mathbf{w}_{r} \dot{\mathbf{u}} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \mathbf{w}_{r} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \mathbf{w}_{r} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \mathbf{w}_{r} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \mathbf{w}_{r} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \mathbf{w}_{r} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \mathbf{w}_{r} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \mathbf{w}_{r} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{u}} \dot{\mathbf{e}}} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{u}} \dot{\mathbf{e}}} \dot{\mathbf{u}} \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}}_{qs}^{r} \dot{\mathbf{u}} \dot{\mathbf{u}} \dot{\mathbf{e}}} \dot{\mathbf{u}} \dot{\mathbf{u}} \dot{\mathbf{e}}} \dot{\mathbf{u}} \dot{\mathbf{u}} \dot{\mathbf{e}} \dot{\mathbf{u}} \dot{\mathbf{u}} \dot{\mathbf{e}}} \dot{\mathbf{u}} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{u}}$$

Using the quadratic positive-definite Lyapunov function

$$V(i_{qs}^{r}, i_{ds}^{r}, \mathbf{W}_{r}) = \frac{1}{2}(i_{qs}^{r^{2}} + i_{ds}^{r^{2}} + \mathbf{W}_{r}^{2}),$$

the expression for the total derivative is found to be

$$\frac{dV(i_{qs}^r, i_{ds}^r, \mathbf{w}_r)}{dt} = -\frac{r_s}{L_{ss}} \mathbf{\hat{g}}_{qs}^{r^2} + i_{ds}^{r^2} \mathbf{\ddot{\Theta}} - \frac{B_m}{J} \mathbf{w}_r^2 - \frac{8J\mathbf{y}_m - 3P^2 L_{ss}\mathbf{y}_m}{8JL_{ss}} i_{qs}^r \mathbf{w}_r$$
Thus,
$$\frac{dV(i_{qs}^r, i_{ds}^r, \mathbf{w}_r)}{dt} < 0.$$

One concludes that the equilibrium state of a microdrive is uniformly asymptotically stable.

Consider the closed-loop system.

To guarantee the balanced operation we let

 $u_{qs}^r = -k_w w_r$  and  $u_{ds}^r = 0$ .

Therefore, the following differential equations result

$$\frac{di_{qs}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}i_{qs}^{r} - \frac{\mathbf{y}_{m}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}\mathbf{w}_{r} - i_{ds}^{r}\mathbf{w}_{r} - \frac{1}{L_{ls} + \frac{3}{2}\overline{L}_{m}}k_{w}\mathbf{w}_{r},$$

$$\frac{di_{ds}^{r}}{dt} = -\frac{r_{s}}{L_{ls} + \frac{3}{2}\overline{L}_{m}}i_{ds}^{r} + i_{qs}^{r}\mathbf{w}_{r},$$

$$\frac{d\mathbf{w}_{r}}{dt} = \frac{3P^{2}\mathbf{y}_{m}}{8J}i_{qs}^{r} - \frac{B_{m}}{J}\mathbf{w}_{r},$$

or

$$\dot{x}(t) = \begin{pmatrix} \dot{\mathbf{e}} & \frac{r_s}{L_{ls} + \frac{3}{2}\overline{L}_m} & 0 & -\frac{\mathbf{y}_m + k_w}{L_{ls} + \frac{3}{2}\overline{L}_m} \dot{\mathbf{u}} \dot{\mathbf{e}} i_{qs}^r \dot{\mathbf{u}} \dot{\mathbf{e}} i_{ds}^r \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{u}} \\ \dot{\mathbf{e}} \dot{\mathbf{e}} & 0 & -\frac{r_s}{L_{ls} + \frac{3}{2}\overline{L}_m} & 0 & \overset{\mathsf{u}}{\mathbf{u}} \dot{\mathbf{e}} i_{ds}^r \dot{\mathbf{u}} + \dot{\mathbf{e}} i_{qs}^r \mathbf{w}_r \dot{\mathbf{u}} \\ \dot{\mathbf{e}} \dot{\mathbf{e}} & \dot{\mathbf{u}} \dot{\mathbf{e}} \dot{\mathbf{u}} \dot{\mathbf{u}} \dot{\mathbf{e}} \dot{\mathbf{u}} \\ \dot{\mathbf{e}} \dot{\mathbf{e}} i_{ds}^r \dot{\mathbf{u}} \dot{\mathbf{u}} \dot{\mathbf{e}} \dot{\mathbf{u}} \\ \dot{\mathbf{e}} \dot{\mathbf{e}} i_{ds}^r \dot{\mathbf{u}} \dot{\mathbf{e}} \dot{\mathbf{u}} \\ \dot{\mathbf{e}} \dot{\mathbf{e}} i_{ds}^r \dot{\mathbf{u}} \dot{\mathbf{e}} \dot{\mathbf{e}} i_{qs}^r \mathbf{w}_r \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} i_{ds}^r \dot{\mathbf{u}} \dot{\mathbf{e}} \dot{\mathbf{e}} i_{qs}^r \mathbf{w}_r \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} i_{ds}^r \dot{\mathbf{u}} \dot{\mathbf{e}} \dot{\mathbf{e}} i_{qs}^r \mathbf{w}_r \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} i_{ds}^r \dot{\mathbf{u}} \dot{\mathbf{e}} \dot{\mathbf{e}} i_{qs}^r \mathbf{w}_r \dot{\mathbf{u}} \\ \dot{\mathbf{e}} \dot{\mathbf{w}} i_{ds}^r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} 0 & \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \dot{\mathbf{e}} \mathbf{w}_r \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \\ \dot{\mathbf{u}} & \dot{\mathbf{u}} \\ \dot{\mathbf{u}} \\$$

Taking note of the quadratic positive-definite Lyapunov function

$$V(i_{qs}^{r}, i_{ds}^{r}, \mathbf{W}_{r}) = \frac{1}{2}(i_{qs}^{r^{2}} + i_{ds}^{r^{2}} + \mathbf{W}_{r}^{2}),$$

one has

$$\frac{dV(i_{qs}^{r}, i_{ds}^{r}, \mathbf{w}_{r})}{dt} = -\frac{r_{s}}{L_{ss}} \underbrace{\widehat{\mathbf{e}}}_{qs}^{r^{2}} + i_{ds}^{r^{2}} \underbrace{\overset{\circ}{\mathbf{o}}}_{\mathbf{o}} - \frac{B_{m}}{J} \mathbf{w}_{r}^{2} - \frac{8J(\mathbf{y}_{m} + k_{\mathbf{w}}) - 3P^{2}L_{ss}\mathbf{y}_{m}}{8JL_{ss}} i_{qs}^{r} \mathbf{w}_{r}.$$
Hence,  $V(i_{qs}^{r}, i_{ds}^{r}, \mathbf{w}_{r}) > 0$  and  $\frac{dV(i_{qs}^{r}, i_{ds}^{r}, \mathbf{w}_{r})}{dt} < 0.$ 

Therefore, the conditions for asymptotic stability are guaranteed.

In Example 4.2.4 it was shown that dynamic systems can be controlled to attain the desired transient dynamics, stability margins, etc. Let us study how to solve the motion control problem with the ultimate goal to synthesize tracking controllers applying Lyapunov's stability theory.

Using the reference (command) vector r(t) and the system output y(t), the tracking error (which ideally must be zero) is

e(t) = Nr(t) - y(t). (4.2.2)

The Lyapunov theory is applied to derive the *admissible* control laws (voltages and currents are bounded, and therefore the saturation effect is always the reality). That is, the *admissible* bounded controller should be designed as continuous function within the constrained rectangular control set

 $U = \{ u \hat{\mathbf{l}} \mid |^{\mathrm{m}} : u_{\min} \pounds u \pounds u_{\max}, u_{\min} < 0, u_{\max} > 0 \} \hat{\mathbf{l}} \mid |^{\mathrm{m}}.$ 

Making use of the Lyapunov candidate V(t, x, e), the bounded proportional-integral controller with the state feedback extension is expressed as

$$u = \operatorname{sat}_{u_{\min}}^{u_{\max}} \overset{\mathcal{\mathcal{C}}}{\underset{e}{\circ}} G_x(t) B(x)^T \frac{\P V(t, x, e)}{\P x} + G_e(t) B_e^T \frac{\P V(t, x, e)}{\P e} + G_i(t) B_e^T \frac{1}{s} \frac{\P V(t, x, e)}{\P e} \overset{\mathbf{o}}{\underset{e}{\circ}} \overset{\mathbf{o}}{\underset{e}{\circ}}$$

$$(4.2.3)$$

where  $G_x(\mathfrak{F}; |_{\mathfrak{s}_0} \otimes \mathfrak{K}^m, G_e(\mathfrak{F}; |_{\mathfrak{s}_0} \otimes \mathfrak{K}^m)$  and  $G_i(\mathfrak{F}; |_{\mathfrak{s}_0} \otimes \mathfrak{K}^m)$  are the bounded symmetric matrix-functions defined on  $[t_0, \mathfrak{F})$ ,  $G_x > 0$ ,  $G_e > 0$ ,  $G_i > 0$ ;  $V(\mathfrak{F}; |_{\mathfrak{s}_0}) \in \mathfrak{K}^m \otimes \mathfrak{K}_0$  is the continuously differentiable real-analytic  $C^k$  ( $k^3$  1) function with respect to  $x^{\hat{l}} X$  and  $e^{\hat{l}} E$  on  $[t_0, \mathfrak{F})$ .

It was emphasized that the control signal is saturated as documented in Figure 4.2.1.



Figure 4.2.1. Bounded control,  $u_{\min} \pounds u \pounds u_{\max}$ 

For closed-loop NEMS and MEMS (4.2.1)–(4.2.3) with  $X_{0}=\{x_{0}\hat{l} \mid k\}\phi X\hat{l} \mid k,u\hat{l} \mid U\hat{l} \mid m, r\hat{l} \mid R\hat{l} \mid b$  and  $d\hat{l} \mid D\hat{l} \mid k$ , it is straightforward to find the evolution set  $X(X_{0}, U, R, D)\hat{l}$   $\hat{k}$ . Furthermore, using the output equation, one has  $X \stackrel{3}{\not\sim} A \stackrel{2}{\not\sim} B \stackrel{2}{\not\sim} Y$ . Thus, the system (4.2.1)-(4.2.3) evolves in  $XY(X_{0}, U, R, D)=\{(x,y)\hat{l} \mid X' \mid Y: x_{0}\hat{l} \mid X_{0}, u\hat{l} \mid U, r\hat{l} \mid R, d\hat{l} \mid D, t\hat{l} \mid [t_{0}, ¥)\}\hat{l} \mid \hat{k} \stackrel{*}{ } \hat{p}$ . The tracking error  $e(t) = Nr(t) - y(t), e(*):[t_{0}, ¥)B \stackrel{1}{ } B$  gives the difference between the reference input  $r(*):[t_{0}, ¥)B \stackrel{1}{ } B$  and system output  $v(*):[t_{0}, ¥)B \stackrel{1}{ } D$ . Our goal is to find the feedback coefficients of

output  $y(*):[t_0,*]$  (B) <sup>b</sup>. Our goal is to find the feedback coefficients of controller (4.2.3) to guarantee that the closed-loop NEMS and MEMS will evolve in the desired manner. The following Lyapunov-based Lemma is formulated to study the stability of closed-loop dynamic systems as well as to find the feedback coefficients to guarantee the criteria imposed on the Lyapunov pair.

# Lemma.

Consider the closed-loop systems (4.2.1) - (4.2.3).

- 1. Solutions of system are uniformly ultimately bounded;
- 2. equilibrium point is exponentially stable in the convex and compact state evolution set  $X(X_0, U, R, D)$   $\models$ ;
- 3. tracking is ensured and disturbance attenuation is guaranteed in the stateerror evolution set  $XE(X_0, E_0, U, R, D)$   $\models \uparrow \models$ ,

if there exists a  $C^k$  function V(t,x,e) in XE such that for all  $x \hat{I} X$ ,  $e \hat{I} E$ ,  $u \hat{I} U$ ,  $r \hat{I} R$  and  $d \hat{I} D$  on  $[t_0, \forall)$ 

(i) 
$$\mathbf{r}_1 \| x \| + \mathbf{r}_2 \| e \| \mathbf{\pounds} V(t, x, e) \mathbf{\pounds} \mathbf{r}_3 \| x \| + \mathbf{r}_4 \| e \|$$
, (4.2.4)

(ii) along (4.2.1) with (4.2.3), the following inequality holds

$$\frac{dV(t,x,e)}{dt} \mathbf{\hat{E}} - \mathbf{r}_5 \| \mathbf{x} \| - \mathbf{r}_6 \| e \|.$$
(4.2.5)

*Here*,  $\mathbf{r}_1(\mathfrak{Y})$ :  $\mathbf{b}_0 \mathbb{B}$ ,  $\mathbf{b}_0$ ,  $\mathbf{r}_2(\mathfrak{Y})$ :  $\mathbf{b}_0 \mathbb{B}$ ,  $\mathbf{b}_0$ ,  $\mathbf{r}_3(\mathfrak{Y})$ :  $\mathbf{b}_0 \mathbb{B}$ ,  $\mathbf{b}_0$  and  $\mathbf{r}_4(\mathfrak{Y})$ :  $\mathbf{b}_0 \mathbb{B}$ ,  $\mathbf{b}_0$  are the *K*<sub>**x**</sub>-functions;  $\mathbf{r}_5(\mathfrak{Y})$ :  $\mathbf{b}_0 \mathbb{B}$ ,  $\mathbf{b}_0$  and  $\mathbf{r}_6(\mathfrak{Y})$ :  $\mathbf{b}_0 \mathbb{B}$ ,  $\mathbf{b}_0$  are the *K*-functions.

The major problem is to design the Lyapunov candidate functions. Let us apply a family of nonquadratic Lyapunov candidates

$$V(t, x, e) = \bigotimes_{i=0}^{h} \frac{2g+1}{2(i+g+1)} \bigotimes_{e}^{e} X^{\frac{i+g+1}{2g+1}} \stackrel{o}{\Rightarrow}^{T} K_{xi}(t) x^{\frac{i+g+1}{2g+1}} + \bigotimes_{i=0}^{y} \frac{2b+1}{2(i+b+1)} \bigotimes_{e}^{e} e^{\frac{i+b+1}{2b+1}} \stackrel{o}{\Rightarrow}^{T} K_{ei}(t) e^{\frac{i+b+1}{2b+1}} + \bigotimes_{i=0}^{y} \frac{2b+1}{2(i+b+1)} \stackrel{o}{=} e^{\frac{i+b+1}{2b+1}} \stackrel{o}{\Rightarrow}^{T} K_{ei}(t) e^{\frac{i+b+1}{2b+1}} + \bigotimes_{i=0}^{y} \frac{2b+1}{2(i+b+1)} \stackrel{o}{=} e^{\frac{i+b+1}{2b+1}} \stackrel{o}{=} e^{\frac{i+b+1}{2b+1}} \stackrel{o}{=} e^{\frac{i+b+1}{2b+1}} + \bigotimes_{i=0}^{y} \frac{2b+1}{2(i+b+1)} \stackrel{o}{=} e^{\frac{i+b+1}{2b+1}} \stackrel{o}{=} e^{\frac{i+b+1$$

To design the Lyapunov functions, the nonnegative integers were used. In particular,  $\mathbf{h} = 0,1,2,..., \mathbf{g} = 0,1,2,..., \mathbf{V} = 0,1,2,..., \mathbf{b} = 0,1,2...,$  $\mathbf{s} = 0,1,2,...,$  and  $\mathbf{m} = 0,1,2,...$ 

From (4.2.3) and (4.2.6), one obtains a bounded *admissible* controller as

$$u = \mathbf{sat}_{u_{\min}}^{u_{\max}} \overset{\mathcal{\mathcal{R}}}{\underset{e}{\overset{V}{\overset{}}}} (t) B(x)^{T} \overset{h}{\overset{h}{\overset{}}} \operatorname{diag}_{\overset{e}{\overset{}}{\overset{}}} (t) \overset{\frac{i \cdot g}{2g+1}}{\underset{e}{\overset{V}{\overset{}}} (t) x^{\frac{i \cdot g}{2g+1}}} \overset{\tilde{u}}{\underset{e}{\overset{V}{\overset{}}} (t) x^{\frac{i \cdot g}{2g+1}}} + G_{i}(t) B_{e}^{T} \frac{1}{s} \overset{s}{\underset{i=0}{\overset{}}} \operatorname{diag}_{\overset{e}{\overset{}}{\overset{}}{\overset{}}} (t) e^{\frac{i \cdot m}{2m+1}} \overset{\tilde{u}}{\underset{e}{\overset{}}} (t) e^{\frac{i \cdot m}{2m+1}} \overset{\tilde{u}}{\underset{e}{\overset{}}} (t) x^{\frac{i \cdot g}{2g+1}}} + G_{i}(t) B_{e}^{T} \frac{1}{s} \overset{s}{\underset{i=0}{\overset{}}} \operatorname{diag}_{\overset{e}{\overset{}}{\overset{}}{\overset{}}} (t) e^{\frac{i \cdot m}{2m+1}} \overset{\tilde{u}}{\underset{e}{\overset{}}} (t) e^{\frac{$$

Here,  $K_{xi}(\mathfrak{X}; |_{\mathfrak{z}_0} \mathbb{B} |_{\mathfrak{s}_0} \mathbb{B} |_{\mathfrak{s}_0$ 

It is evident that assigning the integers to be zero, the well-known quadratic Lyapunov candidate results, and

$$V(t, x, e) = \frac{1}{2}x^{T}K_{x0}(t)x + \frac{1}{2}e^{T}K_{e0}(t)e + \frac{1}{2}e^{T}K_{s0}(t)e.$$

The bounded controller is found to be

$$u = \mathbf{sat}_{u_{\min}}^{u_{\max}} \Big( G_x(t) B(x)^T K_{x0}(t) x + G_e(t) B_e^T K_{e0}(t) e + G_i(t) B_e^T K_{s0}(t) \frac{1}{s} e_{\Rightarrow}^{\ddot{\mathbf{o}}} \Big)$$

Substituting (4.2.7) into (4.2.1), the total derivative of the Lyapunov candidate V(t, x, e) is obtained. Solving (4.2.5), the feedback coefficients are obtained.

#### *Example 4.2.5*.

Consider a micro-electric drive actuated by a permanent-magnet DC motor with *step-down* converter, see Figure 4.2.2. Find the control algorithm.



Figure 4.2.2. Permanent-magnet DC motor with step-down converter

# Solution.

Using the Kirchhoff laws and the *averaging* concept, we have the following nonlinear state-space model with bounded control

$$\begin{array}{c} \underbrace{\operatorname{\acute{e}du}_{a} \grave{\mathsf{u}}}_{e} \stackrel{\acute{\mathsf{e}}}{\operatorname{\acute{e}dt}} \underbrace{\mathsf{u}}_{u} \stackrel{\acute{\mathsf{e}}}{\operatorname{\acute{e}dt}} 0 & \underbrace{1}_{C_{L}} - \underbrace{1}_{C_{L}} & 0 \stackrel{\acute{\mathsf{u}}\acute{\mathsf{u}}}{\operatorname{\acute{e}dt}} \underbrace{\mathsf{u}}_{u} \stackrel{\acute{\mathsf{e}}}{\operatorname{\acute{e}dt}} \underbrace{\mathsf{u}}_{u} \stackrel{\acute{\mathsf{e}}}{\operatorname{\acute{e}dt}} 0 & \underbrace{\mathsf{u}}_{u} \stackrel{\acute{\mathsf{e}}}{\operatorname{\acute{e}dt}} \underbrace{\mathsf{u}}_{u} \stackrel{\acute{\mathsf{u}}}{\operatorname{\acute{e}dt}} \underbrace{\mathsf{u}}_{u} \stackrel{\acute{\mathsf{e}}}{\operatorname{\acute{e}dt}} \underbrace{\mathsf{u}} \overset{\acute{\mathsf{$$

 $u_c$  **î** [0 10] V.

A bounded control law should be synthesized.

From (4.2.6), letting V = s = 1 and b = m = h = g = 0, one finds the nonquadratic function V(e, x). In particular, we apply the following Lyapunov candidate

$$V(e,x) = \frac{1}{2}k_{e0}e^{2} + \frac{1}{4}k_{e1}e^{4} + \frac{1}{2}k_{ei0}e^{2} + \frac{1}{4}k_{ei1}e^{4} + \frac{1}{2}[u_{a} \quad i_{L} \quad i_{a} \quad \mathbf{W}_{r}]K_{x0} \stackrel{\text{é}u_{a}}{\underset{e}{\overset{i}{e}}_{l}} \stackrel{\text{i}}{\underset{e}{\overset{i}{e}}_{l}} \stackrel{\text{i}}{\underset{e}{\overset{i}{e}}} \stackrel{\text{i}}{\underset{e}{\overset{i}{e}}} \stackrel{\text{i}}{\underset{e}{\overset{i}{e}}} \stackrel{\text{i}}{\underset{e}{\overset{i}{e}}} \stackrel{\text{i}}{\underset{e}{\overset{i}{e}}} \stackrel{\text{i}}{\underset{e}{\overset{i}{e}}} \stackrel{\text{i}}{\underset{e}{\overset{i}{e}}} \stackrel{\text{i}}{\underset{e}{\overset{i}{e}}} \stackrel{\text{i}}{\underset{e}{\overset{i}}} \stackrel{\text{i}}{\underset{e}{\overset{i}}} \stackrel{\text{i}}{\underset{e}{\overset{i}{e}}} \stackrel{\text{i}}{\underset{e}{\overset{i}}} \stackrel{\text{i}}{\underset{e}}} \stackrel{\text{i}}{\underset{e}{\overset{i}}} \stackrel{\text{i}}{\underset{e}{\overset{i}}} \stackrel{\text{i}}{\underset{e}} \stackrel{\text{i}}{\underset{e}{\overset{i}}} \stackrel{\text{i}}{\underset{e}}} \stackrel{\text{i}}{\underset{e}}} \stackrel{\text{i}}{\underset{e}} \stackrel{\text{i}}{\underset{e}}} \stackrel{\text{i}}{\underset{e}}} \stackrel{\text{i}}{\underset{e}} \stackrel{\text{i}}{\underset{e}}} \stackrel{\text{i}}{\underset{e}} \stackrel{\text{i}}{\underset{e}} \stackrel{i}{\underset{e}} \stackrel{i}}{\underset{e}} \stackrel{i}{\underset{e}}} \stackrel{i}{\underset{e}} \stackrel{i}}{\underset{e}} \stackrel{i}}{\underset{e}} \stackrel{i}}{\underset{e}} \stackrel{i}}{\underset{e}} \stackrel{i}{\underset{e}} \stackrel{i}}{\underset{e}} \stackrel{i}}{\underset{e}} \stackrel{i}}{\underset{e}} \stackrel{i}}{\underset{e}} \stackrel{i}}{\underset{e}} \stackrel{i}}{\underset{i}} \stackrel{i}}{\underset{e}} \stackrel{i}$$

where  $K_{x0} \hat{\mathbf{i}} \stackrel{|\mathbf{i}'^4}{=}$ . Therefore, from (4.2.7), one obtains  $\hat{\mathbf{i}} = \hat{\mathbf{i}} \frac{10}{u}$  for  $u^3 = 10$ ,  $u_c = \hat{\mathbf{i}} \frac{10}{u}$  for 0 < u < 10,  $\hat{\mathbf{i}} = 0$  for  $u \neq 0$ ,  $u = k_1 e + k_2 e^3 + k_3 \partial e dt + k_4 \partial e^3 dt - k_5 u_a - k_6 i_L - k_7 i_a - k_8 \mathbf{w}_r$ . If the criteria, imposed on the Lyapunov pair are guaranteed, one concludes that the stability conditions are satisfied. The positive-definite nonquadratic function V(e, x) was used. The feedback gains must be found by solving inequality  $\frac{dV(e, x)}{dt} < 0$ . For example, the following inequality can be solved

$$\frac{dV(e,x)}{dt} \mathbf{\pounds} - \frac{1}{2} \|e\|^2 - \frac{1}{4} \|e\|^4 - \frac{1}{2} \|x\|^2.$$

Thus, from V(e,x) > 0 and  $\frac{dV(e,x)}{dt} < 0$ , one concludes that stability

is guaranteed.

It must be emphasized that a great number of examples in design of tracking controllers for electromechanical systems are reported in the references cited below.

### *Example* 4.2.6.

Study the flip-chip MEMS: eight-layered lead magnesium niobate actuator (3 mm diameter, 0.25 mm thickness), actuated by a monolithic high-voltage switching regulator,  $-1 \pounds u \pounds 1$  A. A set of differential equations to model the microactuator dynamics is

$$\begin{aligned} \frac{dF_y}{dt} &= -9472F_y + 13740F_y u + 48593u ,\\ \frac{dv_y}{dt} &= 947F_y - 94100v_y - 2609v_y^{1/3} - 2750x_y ,\\ \frac{dx_y}{dt} &= v_y . \end{aligned}$$

## Solution.

The control authority is bounded, and hence, the control is constrained. In particular,  $-1 \pounds u \pounds 1$ .

The error is the difference between the reference and microactuator position. That is,

e(t) = r(t) - y(t),

where  $y(t) = x_v$  and  $r(t) = r_v(t)$ .

Using (4.2.6) setting the nonnegative integers to be V = s = 1 and b = m = h = g = 0, we have

$$V(e,x) = \frac{1}{2}k_{e0}e^{2} + \frac{1}{4}k_{e1}e^{4} + \frac{1}{2}k_{ei0}e^{2} + \frac{1}{4}k_{ei1}e^{4} + \frac{1}{2}[F_{y}v_{y}x_{y}]K_{xo}\overset{\text{e}F_{y}u}{\hat{e}v_{y}u}.$$
  
$$\overset{\text{e}F_{y}u}{\hat{e}x_{y}u}$$

Applying the design procedure, a bounded control law is synthesized, and making use of (4.2.7), one has.

$$u = \operatorname{sat}_{-1}^{+1} \left( 94827e + 2614e^3 + 4458 \mathbf{\dot{o}} dt + 817 \mathbf{\dot{o}}^3 dt \right).$$

The feedback gains were found by solving inequality

$$\frac{dV(e,x)}{dt} \mathbf{\pounds} - ||e||^2 - ||e||^4 - ||x||^2$$

The criteria imposed on the Lyapunov pair are satisfied. In fact,

$$V(e,x) > 0$$
 and  $\frac{dV(e,x)}{dt} \pounds 0$ 

Hence, the bounded control law guarantees stability and ensures tracking. The experimental validation of stability and tracking is important. The controller is tested, and Figure 4.2.3 illustrates the transient dynamics for the position for a reference signal (desired position)  $r_y(t) = 4 \cdot 10^{-6} \sin 1000t$ .

Figure 4.2.4 illustrates the actuator position if  $r_y(t) = const = 4' 10^{-6}$ .

From these end-to-end transient dynamics it is evident that the desired performance has been achieved, and the output precisely follows the reference position  $r_v(t)$ .



Figure 4.2.3. Transient output dynamics if  $r_v(t) = 4 \cdot 10^{-6} \sin 1000t$ 



Figure 4.2.4. Actuator position,  $r_v(t) = const = 4' 10^{-6}$ 

# Example 2.4.7.

Consider a flip-chip MEMS with permanent-magnet stepper motor controlled by ICs. The mathematical model in the *ab* variables, in the form of nonlinear differential equations (see section 3.6), is given as

$$\begin{aligned} \frac{di_{as}}{dt} &= -\frac{r_s}{L_{ss}}i_{as} + \frac{RT\boldsymbol{y}_m}{L_{ss}}\boldsymbol{w}_{rm}\sin(RT\boldsymbol{q}_{rm}) + \frac{1}{L_{ss}}u_{as},\\ \frac{di_{bs}}{dt} &= -\frac{r_s}{L_{ss}}i_{bs} - \frac{RT\boldsymbol{y}_m}{L_{ss}}\boldsymbol{w}_{rm}\cos(RT\boldsymbol{q}_{rm}) + \frac{1}{L_{ss}}u_{bs},\\ \frac{d\boldsymbol{w}_{rm}}{dt} &= -\frac{RT\boldsymbol{y}_m}{J}[i_{as}\sin(RT\boldsymbol{q}_{rm}) + i_{bs}\cos(RT\boldsymbol{q}_{rm})] - \frac{B_m}{J}\boldsymbol{w}_{rm} - \frac{1}{J}T_L,\\ \frac{d\boldsymbol{q}_{rm}}{dt} &= \boldsymbol{w}_{rm}. \end{aligned}$$

The two-phase micro-stepper motor parameters are:

RT = 6,  $r_s = 60$  ohm,  $y_m = 0.0064$  N-m/A,  $L_{ss} = 0.05$  H,  $B_m = 1.3 \cdot 10^{-7}$  N-m-sec/rad, and the equivalent moment of inertia is  $J = 1.8 \cdot 10^{-8}$  kg-m<sup>2</sup>.

The phase voltages are bounded. In particular,

 $u_{\min} \pounds u_{as} \pounds u_{\max}$  and  $u_{\min} \pounds u_{bs} \pounds u_{\max}$ , where  $u_{\min} = -12$  V and  $u_{\max} = 12$  V.

Design the tracking control algorithm.

*Solution.* The nonlinear controller is given as

$$u = \begin{pmatrix} \dot{\boldsymbol{e}}_{as} \dot{\boldsymbol{u}} = \dot{\boldsymbol{e}} \\ \dot{\boldsymbol{e}} = \dot{\boldsymbol{e}} \\ \ddot{\boldsymbol{e}} = \dot{\boldsymbol{e}} \\ \ddot{\boldsymbol{e}} \\ \dot{\boldsymbol{e}} \\ \dot{\boldsymbol{e$$

$$y(t) = \boldsymbol{q}_{rm}(t)$$
. The tracking error is

$$e(t) = r(t) - y(t)$$

The Lyapunov candidate is found using (4.2.6).

Choosing a candidate Lyapunov function to be (letting  $\mathbf{h} = \mathbf{g} = 0$  and  $\mathbf{V} = \mathbf{b} = \mathbf{s} = \mathbf{m} = 1$ )

$$V(e,x) = \frac{3}{4}K_{e0}e^{4/3} + \frac{1}{2}K_{e1}e^{2} + \frac{3}{4}K_{ei0}e^{4/3} + \frac{1}{2}K_{ei1}e^{2} + \frac{1}{2}[i_{as} \ i_{bs} \ \mathbf{w}_{rm} \ \mathbf{q}_{rm}]K_{x0} \stackrel{\text{\acute{e}}i_{bs}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\text{\acute{e}}i_{bs}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\text{\acute{e}}i_{bs}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\text{\acute{e}}i_{bs}}}{\stackrel{\stackrel{\acute{e}i$$

and solving

$$\frac{dV(e,x)}{dt} \mathfrak{L} - ||e||^{4/3} - ||e||^2 - ||x||^2,$$

a bounded controller is found as

$$u_{as} = -\sin(RT\boldsymbol{q}_{rm}) \operatorname{sat}_{-12}^{+12} \overset{\textcircled{o}}{\overset{\textcircled{o}}{e}} 4e + 2.9e^{1/3} + \frac{1}{s} 6.1e + \frac{1}{s} 4.3e^{1/3} \overset{\textcircled{o}}{\overset{\textcircled{o}}{s}},$$
$$u_{bs} = \cos(RT\boldsymbol{q}_{rm}) \operatorname{sat}_{-12}^{+12} \overset{\textcircled{o}}{\overset{\textcircled{o}}{e}} 4e + 2.9e^{1/3} + \frac{1}{s} 6.1e + \frac{1}{s} 4.3e^{1/3} \overset{\textcircled{o}}{\overset{\textcircled{o}}{s}},$$

The sufficient conditions for robust stability are satisfied because

$$V(e,x) > 0$$
 and  $\frac{dV(e,x)}{dt} < 0$ .

Figures 4.2.5 and 4.2.6 document the dynamic if the reference (cammand) displacement was assigned 0.5 and 1 radians, respectively. From analytical and experimental results one concludes that the robust stability and tracking are guaranteed.



Figure 4.2.5. Transient output dynamics of microservo



Figure 4.2.6. Transient output dynamics of microservo

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# 4.3. INTRODUCTION TO INTELLIGENT CONTROL OF NANO-AND MICROELECTROMECHANICAL SYSTEMS

Hierarchical distributed closed-loop systems must be designed for largescale multi-node NEMS and MEMS in order to perform a number of complex functions and tasks in dynamic and uncertain environments. In particular, the goal is the synthesis of control algorithms and architectures which maximize performance and efficiency minimizing system complexity through

- intelligence, learning, evolution, and organization;
- · adaptive decision making,
- coordination and autonomy of multi-node NEMS and MEMS through tasks and functions generation, organization and decomposition,
- · performance analysis with outcomes prediction and assessment,
- real-time diagnostics, health monitoring, and estimation,
- real-time adaptation and reconfiguration,
- · fault tolerance and robustness,
- etc.

Control theory and engineering practice in the design and implementation of hierarchical hybrid (digital- and continuous-time subsystems are integrated, discrete and continuous events are augmented) real-time large-scale closed-loop systems have not matured. Synthesis of optimal controllers for elementary (single-input/single-output) single node NEMS and MEMS can be performed using conventional methods such as the Hamilton-Jacobi theory, Lyapunov's concept, maximum principle, dynamic programming, etc. However, these methods do not allow the designer to attain the desired features for complex multi-node NEMS and MEMS even though some methods (e.g., adaptive control, fuzzy logic, and neural networks) ensure performance assessment, diagnostics, adaptation, and reconfiguration. In fact, hierarchical architectures are needed to be designed and optimized to achieve intelligence, evolution, adaptive decision making, and performance analysis with outcome prediction. The design of intelligent systems can be mathematically formulated as a search problem in high-dimensional space, and the performance criteria form hypersurfaces. Efficient and robust search algorithms are used to perform optimization. Due to the complexity of large-scale systems and uncertainties, it is difficult to develop accurate analytic models, explicitly formulate performance specifications, derive regret functionals and performance indexes, design optimal architectures, synthesize hierarchical structures, as well as design control algorithms. The situation much more complex in the synthesis of robust closed-loop systems under uncertainties in dynamic environments.

Intelligence can be defined as the ability of closed-loop NEMS and MEMS achieve the desired goals (for example, maximize safety, stability, robustness, controllability, efficiency, reliability, and survivability, while minimizing failures, electromagnetic interference, and losses) in dynamic and uncertain environments through the NEMS and MEMS abilities to sense the

environment, learn and evolve, perform adaptive decision making with performance analysis and outcome prediction, and control.

Let us discuss the design of a control algorithms for *j*th level of *k*-level hierarchical NEMS and MEMS. The control law at *j*th level can be expressed as

$$u_{j}(t) = f \bigotimes_{i=0}^{\infty} P, \overset{j}{a} e_{i}(t), \overset{j}{a} x_{i}(t), \overset{j}{a} s_{i}(t), p_{j}(t) \underset{\downarrow}{\overset{\circ}{+}}, \overset{\circ}{a}$$

where

- $u_i(t)$  is the control vector (output);
- f is the nonlinear map;
- *P* is the system performance (stability, robustness, controllability, efficiency, reliability, losses, et cetera);
  - $\mathop{\mathsf{a}}_{i=0}^{\flat} e_i(t)$  is the error vector which represents the difference between the

assigned command and events  $r_i(t)$  and system outputs  $y_i(t)$ , and the end-toend error vector is e(t) = r(t) - y(t);

- $a_{i=0}^{j} x_{i}(t)$  is the state, event, and decision variable vector;
- $a_{i=0}^{j} s_{i}(t)$  is the sensed information (inputs, outputs, state and decision

variables, events, disturbances, noise, parameters, et cetera) measured by

*j*th and lower level sensors, and, in general, one can use  $a_{i=0}^{\kappa} s_i(t)$ ;

•  $p_j(t)$  is the parameter vector (for example, time-varying parameters as well as adjustable feedback coefficients which can be changed through the decision making, learning, evolution, intelligence, control, adaptation, and reconfiguration processes).

The simplest control algorithms are the proportional-integral-derivative (PID) controllers with state/event/decision feedback extension. For example, the linear analog PID control law is given by

$$u(t) = k_p e(t) + k_i \frac{e(t)}{s} + k_d s e(t) = k_p e(t) + k_i \overset{\bullet}{O}(t) dt + k_d \frac{de(t)}{dt},$$
proportional integral derivative

where  $k_p$ ,  $k_i$  and  $k_d$  are the proportional, integral and derivative feedback gains.

Nonlinear PID controllers can be designed as

$$u(t) = \bigotimes_{j=1}^{2N_p-1} k_{p(2j-1)} e^{2j-1}(t) + \bigotimes_{j=1}^{2N_i-1} k_{i(2j-1)} \frac{e(t)}{s^{2j-1}} + \bigotimes_{j=1}^{2N_d-1} k_{d(2j-1)} \frac{d^{2j-1}e(t)}{dt^{2j-1}},$$
*proportional integral*

where  $N_p, N_i$  and  $N_d$  are the positive assigned integers;  $k_{p(2j-1)}, k_{i(2j-1)}$ and  $k_{d(2j-1)}$  are the proportional, integral, and derivative feedback coefficients.

For  $N_p = 1$ ,  $N_i = 1$  and  $N_d = 1$ , one has

$$u(t) = k_p e(t) + k_i \overleftarrow{\mathbf{O}}(t) dt + k_d \frac{de(t)}{dt}$$

Assigning  $N_p = 2$ ,  $N_i = 2$  and  $N_d = 1$ , the PID-type controller is expressed as

$$u(t) = k_{p1}e(t) + k_{p3}e^{3}(t) + k_{p5}e^{5}(t) + k_{i1}\frac{e(t)}{s} + k_{i3}\frac{e(t)}{s^{3}} + k_{i5}\frac{e(t)}{s^{5}} + k_{d1}\frac{de(t)}{dt}$$

The feedback gains  $k_p$ ,  $k_i$  and  $k_d$  can be time-varying.

In addition,  $k_p$ ,  $k_i$  and  $k_d$  can be nonlinear functions of the state, event, and decision variables, error, disturbances, etc. For example,

$$u(t) = k_{p}(t)e(t) + k_{i}(e(t))\dot{\mathbf{c}}(t)dt$$
  
= -  $(2 + e^{-10t})e(t) - (3 + 4e^{-20t}) \tanh(|e(t)|)\dot{\mathbf{c}}(t)dt$ ,  
where  $k_{p}(t) = -2 - e^{-10t}$  and  $k_{i}(e(t)) = -(3 + 4e^{-20t}) \tanh(|e(t)|)$ 

Assume that in large-scale multi-node NEMS/MEMS, which have thousands of nodes (NEMS/MEMS with subsystems – sensors, actuators, and ICs), one sensor and actuator were failed. These types of failures must be identified in real-time (through diagnostics and health monitoring), and closedloop NEMS/MEMS must be reconfigurated through intelligence and adaptive decision making with performance analysis with outcome prediction and assessment. Hierarchically distributed closed-loop systems must be designed for large-scale multi-node NEMS and MEMS using hierarchical layers. For example, for three-layer configuration, the possible architecture consists of

- high-level layer (intelligent augmented/coordinated control with intelligence and adaptive decision making with performance analysis and outcome prediction and assessment),
- medium-level layer (intelligent coordinated or autonomous control),
- low-level layer (sensor processing, data acquisition, simple feedback, e.g., single-input/single-output system for single node with many the state, event, and decision variables).

Thus, the problem can be decomposed into sub-problems performed at different layers (which can operate at different sampling rates) with synthesized layouts and decomposed tasks and functions. The system architecture must be synthesized, and the tasks are decomposed by the high-level layer into narrow tasks/functions and fed (with or without defined adaptation, decision making, diagnostics, estimation, implementation, performance analysis, realization, as well as other details) to the medium-level layer, which further decomposes the tasks and supervises the low-level layer. This hierarchically distributed standardized control architecture is shown in Figure 4.3.1.



Figure 4.3.1 Three-layer hierarchically distributed architecture for large-scale multi-node NEMS and MEMS

Different operating systems, interfaces, and platforms should be supported by advanced software, and there is a critical need for novel high-performance robust software. The designer can

- lay out and support hierarchical controllers in if-then-else execution format,
- generate codes for different platforms,
- · add and remove layers,
- set up communication and networks based upon timing requirements (write data to the shared memory buffers and read data from the buffers, protocols development, code and encode data from the buffers using different file formats),
- · perform diagnostics,
- etc.

To perform these tasks, novel design tools are needed. At high-level, intelligence, evolution, coordination and autonomy through tasks generation/organization and decomposition, adaptive decision making with performance analysis and outcome prediction, diagnostics and estimation, adaptation and reconfiguration, fault tolerance and robustness, as well as other functions must be performed through sensing-actuation, learning, evolution, analysis, evaluation, behavioral (dynamic and steady-state performance) optimization and adaptation, etc.

Architectures for hierarchically distributed complex closed-loop systems can be synthesized based upon the decomposition of tasks and functions. The analysis of complexity, hierarchy, data flow (sensing and actuation), and controllers design, allows the designer to synthesize architectures starting from lowest structural level and then governing and augmenting lower levels to upper levels based on physical relationships, functional correlation, order, sequence, and arrays to attain the desired performance, capability, and efficiency.

Consider the closed-loop system to displace (move) the flight control surfaces as shown in Figure 4.3.2. Ailerons, elevators, canards, flaps, rudders, stabilizers and tips are controlled by MEMS-based microactuators.



Figure 4.3.2. Aircraft with MEMS-based translational and rotational flight microactuators

Three-layer architecture of the hierarchically distributed flight management system can integrate three layers: high, medium, and low. At the low level, the single MEMS-based node (actuator/sensor) is controlled using sensing data. The control can be generated using the PID or fuzzy logic control laws (single-input/single-output system) which are based on mathematical and logical (linguistic rules to describe the system operation) reasoning. The simple tasks that can be performed by a low-level layer are:

 "displace" in the clockwise or counterclockwise directions (microactuator is actuated by supplying the voltage which is controlled by microICs, and the duty ratio of high-frequency transistors is controlled using the tracking error, decision variables, and events);

- "measure the displacement",
- "compare the command and actual displacements" (obtain the tracking error),
- "diagnose and detect failures" (For example, positive or negative values of the duty ratio, which is bounded by ±1, correspond to the clockwise or counterclockwise angular deflections, respectively; an increase of the duty ratio must lead to an increase of the current and electromagnetic field intensity).

Thus, we have a set of commands to attain the desired tasks and functions. The low-level layer is primarily responsible for actuation, sensing, simple analysis, diagnostics, and decision making. It is evident that the internal decision making mechanism and local diagnostics can be performed at a low level. The medium-level layer (which controls all control surfaces, e.g., left and right horizontal stabilizers, right and left leading and trailing flaps, et cetera) coordinate the actions of hundreds of MEMS-based nodes (actuators/sensors). Aircraft control is performed by a supervisory flight management system (high-level layer), which, in addition to microactuators management, integrates many other functions (e.g., mission, path, position, propulsion control, et cetera), and the task analysis is accomplished by the high-level layer. In particular, based upon the information obtained from medium- and low-level layers, the high-level layer defines tasks (through intelligence, learning, evolution, analysis, adaptation, coordination, organization, decomposition, adaptive decision making with performance analysis and outcome prediction, diagnostics, et cetera) to guarantee safety, flying and handling requirements, mission effectiveness, etc. The commands to displace the control surfaces are generated by the high-level layer based upon the overall analysis and high-level decision making. It must be emphasized that high-, medium-, and low-level layers communicate with each other, and the high-level layer possesses a key role.

Decision-making theory must be applied to develop and integrate key enabling methods, algorithms, and tools for the use in intelligent large-scale multi-node NEMS and MEMS. These intelligent systems must make optimal (robust) decision based upon the evolution strategies using specified requirements and priorities, monitoring (sensing) the external environment for entities of interest, recognizing those entities and then infer high-level attributes about those entities, etc. The closed-loop systems use the data from different sensors, feedback commands (controls) are generated and executed, and intelligent updates and evolution are performed. The feedback for sensor and control mechanisms are integrated, and particular emphasis is concentrated to gather the critical and essential data from the agents (nodes) of a greatest interest. Extensive information data must be constantly updated to guarantee a complete situation awareness, graduate evolution, and intelligence using performance analysis, outcome evaluation, prediction, and assessment. Thus, qualitative and quantitative analysis is performed to study the overall system evolution. To perform the inferences required, to develop an assessment of the current situation, and to predict performance and outcomes, extensive knowledge and information about NEMS, MEMS, and environment are needed.

A multiple learning concept can be implemented to design high-, medium-, and low-level closed-loop systems. Agents (nodes) exhibit complex behavior which can be optimized using low-level evolutionary decision-making subsystems which use learning algorithms. Reinforcement learning can be performed based upon the prioritized objectives through upper level decisionmaking. The agents behavior and performance are analyzed by the high-level layer to collect and assess the evidence data. Decision trees are commonly used to provide a comprehensive set of strategies, simplify and improve (optimize) them, attain robustness and comprehensibility, and make the final decision. The low-level subsystems can perform the following functions: sensing, actuation, recognition, local diagnostics, local assessment, and local prediction with decision making.

Hierarchical distributed closed-loop systems can have different organization (architecture), and the number of layers is based upon the complexity of multi-node NEMS and MEMS to be controlled, e.g., the number of nodes their complexity. The level of control hierarchy is defined by hardware and software complexity (rate of tasks completion, rate of continuous/discrete events, bandwidth, sampling time, update rate, et cetera), as well as by the overall specifications and requirements imposed. Complex problems and tasks can be logically decomposed into simpler subproblems and subtasks which are easy to understand, support, and implement using the state table of rules (for each rule, the actuator or sensor action and operation are determined using the system state, decision, event, and performance variables). These subtasks must be performed in the defined sequence scenarios that lead to the desired operation, and the architecture is synthesized. Usually, low-level subsystem is designed for each NEMS and MEMS node (actuator/sensor) at the lower level of the hierarchy, and the layer level is defined based upon the overall objectives, analytical and numerical complexity of problems, information flow, etc. Thus, the complexity gradually arises form subsystems design (to control single node), to the synthesis of closed-loop architecture (layers).

Different intelligent concepts can be applied. For example, neural networks allow the designer to

• approximate unknown functions (function approximator neural networks);

• generalize control vector (control neural networks).

The backpropagation method is applied for training multilayer perceptron neural networks.

The multi-input/single-output neuron output is given by  $u = f(Wv + B_1)$ ,

where *u* is the neuron output,  $u\hat{\mathbf{l}} \stackrel{|_{1}}{}; f$  is the nonlinear function (*transfer function*); *W* is the weighting matrix,  $W = [w_{11}, w_{12}, \dots, w_{1k-1}, w_{1k}], W\hat{\mathbf{l}} \stackrel{|_{1}'k}{};$ 

*v* is the input vector (performance variables),  $v\hat{\mathbf{l}} \stackrel{k}{=} B_1$  is the bias variable.

It should be emphasized that W and  $B_1$  are adjusted through the training (learning) mechanism.

For a single-layer neural network of z neurons, one has

$$u = f(Wv + B),$$

where the weighting matrix and bias vector are  $\hat{W}$   $\hat{P}^{k}$  and  $\hat{B}$   $\hat{P}^{k}$ .

For multi-layer neural network of z neurons, one can find the following expression for the (i + 1) network outputs

 $u_{i+1} = f_{i+1}(W_{i+1}u_i + B_{i+1}), i = 0, 1, \dots, M - 2, M - 1,$ 

where M is the number of layers in the neural network.

For example, for three-layer network, we have

 $u_3 = f_3(W_3u_2 + B_3), i = 2, u_2 = f_2(W_2u_1 + B_2), i = 1,$ and  $u_1 = f_1(W_1v + B_1), i = 0.$ 

Hence, one obtains

$$u_3 = f_3(W_3u_2 + B_3) = f_3[W_3f_2(W_2f_1(W_1v + B_1) + B_2) + B_3],$$

where the corresponding subscripts 1, 2 and 3 are used to denote the layer variables.

To approximate the unknown functions, weighting matrix W and the bias vector B must be determined, and the procedure for selecting W and B is called the network training. Many concepts are available to attain training, and the backpropagation, which is based upon the gradient descent optimization methods, are commonly used. Applying the gradient descent optimization procedure, one minimizes a mean square error performance index using the end-to-end neural network behavior. That is, using the inputs vector v and the output vector c,  $c\hat{l} \models$ , the quadratic performance functional is given as

$$J = \mathop{\mathsf{a}}\limits^{p}_{j=1} \left( c_{j} - u_{j} \right)^{T} \mathcal{Q} \left( c_{j} - u_{j} \right) = \mathop{\mathsf{a}}\limits^{p}_{j=1} e_{j}^{T} \mathcal{Q} e_{j},$$

where  $e_j = c_j - u_j$  is the error vector;  $Q\hat{\mathbf{l}} \models \hat{\mathbf{p}}$  is the diagonal weighting matrix.

The steepest descent algorithm is applied to approximate the mean squire errors, and the learning rate and sensitivity have been widely studied for the quadratic performance indexes.

### References

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